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**QUANTUM MONTE CARLO STUDY OF POLARON
MOBILITY**

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**PROUČAVANJE POKRETLJIVOSTI POLARONA
KORISTEĆI KVANTNE MONTE KARLO METODE**

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Abstract

In this thesis, a numerically exact methodology is developed for calculating current–current correlation functions in electron–phonon coupled systems within the path-integral quantum Monte Carlo framework, with emphasis on mitigating the dynamical sign problem. This approach is used to determine the temperature dependence of the dc mobility of the Holstein polaron over a broad range of parameters. The resulting numerically exact data provide a basis for analyzing transport regimes and assessing the validity of approximate transport theories for the Holstein model.

The Holstein model, as the simplest microscopic model of a polaron with local electron–phonon interaction, is used to investigate mobility as a function of temperature and coupling strength. The path-integral Monte Carlo formalism enables a consistent treatment of real- and imaginary-time dynamics, but is limited by the sign problem and the instability of analytic continuation. These challenges are addressed by employing position and momentum representations of the electronic degrees of freedom, improving the accessible real-time range and statistical reliability. In addition, imaginary- and real-time data are combined to enhance the stability of the analytic continuation procedure.

The obtained numerically exact results are used to identify band, hopping, and polaron band transport regimes and to construct a transport regime diagram. Almost the entire explored parameter space is consistently described within these three transport mechanisms.

It is concluded that the proposed path-integral QMC framework provides a consistent description of charge transport within the Holstein model across different regimes and offers a reliable benchmark for assessing approximate theoretical approaches.

Keywords: Holstein model, polaron transport, electron-phonon interaction, quantum Monte Carlo, path-integral methods, current-current correlation function, mobility, transport regimes, dynamical sign problem, analytic continuation

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Sažetak:

U ovoj tezi, razvijena je numerički egzaktna metodologija za računanje struja-struja korelacionih funkcija u sistemima sa elektron-fonon interakcijom primenom kvantnog Monte Karlo metoda u okviru formalizma integrala po putanjama, sa fokusom na ublažavanju problema dinamičkog znaka. Ovaj pristup korišćen je za određivanje temperaturske zavisnosti pokretljivosti Holštajnovog polarona u širokom opsegu parametara. Dobijeni numerički egzaktni podaci predstavljaju osnovu za proučavanje transportnih režima i procenu validnosti približnih teorija transporta u Holštajnovom modelu.

Holštajnov model, kao najjednostavniji model polarona sa lokalnom elektron-fonon interakcijom, korišćen je za proučavanje pokretljivosti u zavisnosti od temperature i jačine interakcije. Kvantni Monte Karlo metod u kombinaciji sa formalizmom integrala po putanjama omogućava dosledan opis dinamike sistema u realnom i imaginarnom vremenu, ali je limitiran problemom dinamičkog znaka i poteškoćama analitičkog produženja. Ovi problemi se umanjuju korišćenjem bazisa položaja i impulsa elektrona. Na ovaj način povećan je domet simulacije u realnom vremenu kao i statistička tačnost rezultata. Dodatno, kombinacijom podataka u realnom i imaginarnom vremenu poboljšan je ishod analitičkog produženja.

Numerički egzaktni podaci korišćeni su za identifikaciju zonskog transporta, transporta preskakanjem i polaronskog zonskog transporta, te za konstruisanje dijagrama transportnih režima. Ispitani opseg parametara je velikim delom adekvatno opisan sa ova tri transportna mehanizma.

Zaključak je da kvantni Monte Karlo metod u kombinaciji sa formalizmom integrala po putanjama pruža adekvatan opis transporta Holštajnovog modela u različitim režimima i služi kao dobra referenca za procenu tačnosti približnih metoda.

Ključne reči: Holštajnov model, polaronski transport, elektron-fonon interakcija, kvantni Monte Karlo; metodi integrala po putanjama, struja-struja korelaciona funkcija, pokretljivost, transportni režimi, problem dinamičkog znaka, analitičko produženje

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Chapter 1

Introduction

The development of modern technology is deeply intertwined with the ability to understand and control the motion of charge carriers in solids. From the first semiconductor devices in the early twentieth century to today's highly integrated microprocessors, progress in electronics has been driven by advances in both fundamental physics and materials science. The emergence of quantum mechanics and solid-state physics provided the theoretical framework for describing the electronic properties of materials, thereby enabling the design of semiconductor devices that form the backbone of modern computing.

The invention of the transistor in the mid-twentieth century marked a decisive turning point, making it possible to miniaturize and mass-produce electronic components. This progress accelerated rapidly with the development of integrated circuits, ultimately leading to modern computers and digital technologies. Over the past several decades, the number of components that can be integrated onto a single chip has increased exponentially, a trend commonly referred to as Moore's law. This continuous scaling has enabled extraordinary growth in computational power and has profoundly shaped modern society, influencing communication, industry, science, and everyday life.

At the same time, advances in computational capabilities have transformed the way physical systems are studied. The increasing availability of powerful computing resources has enabled the development of sophisticated numerical methods for investigating complex materials and transport phenomena, complementing analytical approaches and experimental techniques. As a result, theoretical and computational physics have become indispensable tools for understanding existing materials and guiding the design of new ones with tailored properties [1].

However, as conventional semiconductor technology approaches its physical and technological limits, new challenges emerge. Further miniaturization becomes increasingly difficult, while there is a growing demand for electronic devices that are not only smaller but also flexible, lightweight, and compatible with large-area fabrication. Applications such as wearable electronics, flexible displays, bio-integrated sensors, and low-cost energy devices require materials with properties that differ fundamentally from those of traditional inorganic semiconductors [2].

In this context, organic semiconductors have emerged as a promising class of materials offering new possibilities. These materials are composed of molecular building blocks with rich and tunable electronic structure, whose properties can be engineered through chemical design. Their intrinsic mechanical flexibility and compatibility with large-area, low-cost fabrication techniques make them particularly attractive for next-generation electronic and optoelectronic applications [3]. Organic semiconductors are already widely used in technologies such as organic light-emitting diodes (OLEDs), organic field-effect transistors (OFETs), and organic solar cells [4–7]. In particular, OLED technology has become standard in modern displays, including smartphones, televisions, and emerging flexible or foldable devices, highlighting the growing technological relevance of these materials [8].

Despite their technological success, organic semiconductors also present fundamental challenges. Their electronic properties are governed not only by the motion of charge carriers but also by the intricate interplay between molecular structure, intermolecular interactions, and the dynamic nature of

the lattice. The weak van der Waals bonding between molecules leads to significant thermal motion, which strongly influences electronic coupling and transport properties [9, 10]. Understanding how charge carriers move in such environments is therefore essential both for improving device performance and for advancing the broader understanding of transport phenomena in condensed matter systems.

This thesis is devoted to the study of charge transport in organic molecular systems, with particular emphasis on how interactions between charge carriers and their local environment give rise to different transport regimes. Before introducing the theoretical framework in detail, it is useful to first examine the structural and physical properties of organic semiconductors that distinguish them from their inorganic counterparts.

1.1 Organic molecular semiconductors

Organic semiconductors are materials composed of molecules built primarily from carbon and hydrogen atoms arranged in conjugated π -electron structures where carbon atoms form alternating single and double bonds. In such systems, carbon atoms typically adopt sp^2 hybridization, forming three equivalent sp^2 orbitals and one remaining $2p_z$ orbital. The sp^2 orbitals form strong σ -bonds with neighboring atoms, establishing the structural backbone of the molecule, often in planar ring configurations. The remaining unhybridized $2p_z$ orbitals are oriented perpendicular to this molecular plane and overlap to form weak π bonds. A double carbon-carbon bond thus consists of one strong σ and one weak π bond. The alternating pattern of single and double bonds in conjugated systems leads to extended π -electron states that are delocalized across the molecule. From a molecular orbital perspective, this results in the formation of bonding (π) and antibonding (π^*) orbitals, commonly referred to as the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO). The energy difference between these orbitals plays a role analogous to the band gap between the valence and conduction bands in inorganic semiconductors and is central to the electronic properties of organic materials. In general, as the conjugated system extends over a larger number of connected carbon atoms, the HOMO–LUMO gap decreases [3, 10–12].

A fundamental building block of many organic semiconductors is the aromatic molecule, such as benzene, in which carbon atoms form planar ring-like structures with delocalized π -electron orbitals. These molecules typically exhibit a high degree of symmetry and planarity, which facilitates intermolecular π – π interactions when brought into proximity. In molecular solids, such aromatic units can stack or arrange in various geometries, allowing π -orbitals from adjacent molecules to overlap. This intermolecular overlap provides the primary pathway for charge transport in organic materials [3, 10, 11]. Representative molecular structures of organic materials are shown in Fig. 1.1, illustrating the progression from simple aromatic units to extended conjugated systems and more complex macromolecular architectures.

Unlike inorganic crystals, where atoms are connected through strong covalent bonds into rigid three-dimensional lattices, organic molecular solids consist of discrete molecules held together by relatively weak van der Waals interactions. As a consequence, organic crystals typically exhibit lattice constants on the order of 1 nm, comparable to molecular size, while in inorganic crystals lattice spacings are significantly smaller and determined by atomic dimensions. The relatively large intermolecular separation results in weak orbital overlap and small electronic coupling between neighboring molecules. Consequently, the electronic properties of organic semiconductors depend not only on the structure of individual molecules but also sensitively on their arrangement within the crystal [2, 10, 11].

The molecular nature of these materials has several important consequences. Organic molecules are relatively large, often consisting of tens to hundreds of atoms, and possess many internal degrees of freedom. These include vibrational modes associated with bond stretching, bending, and torsional motion, as well as rotational and translational motion of entire molecules within the crystal. The large

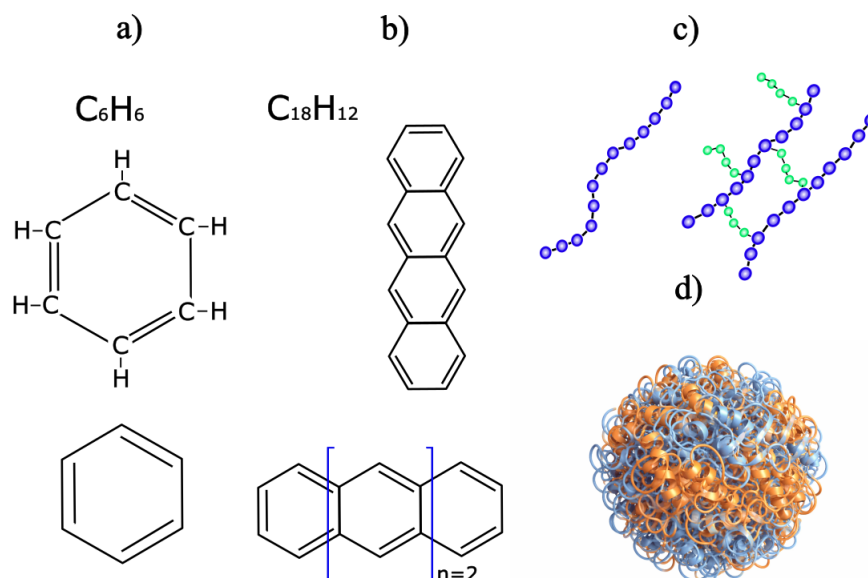


Figure 1.1: Representative molecular building blocks of organic materials. a) Benzene molecule as a fundamental aromatic unit; b) tetracene - polyacene consisting of four fused benzene rings; c) schematic polymer chain featuring repeating molecular units; d) schematic representation of a biomolecule-like structure showing enhanced structural complexity.

number of such degrees of freedom gives rise to a rich spectrum of lattice excitations that strongly influence the electronic properties of the material [9, 10].

Another key characteristic of organic molecules is their high polarizability. The electronic charge distribution is spatially extended and relatively soft, allowing the electron cloud to be easily distorted. When an electron or hole is introduced into the system, it modifies the local electrostatic environment and induces a rearrangement of charge density and molecular geometry in its surroundings. This strong coupling between charge carriers and their local environment is a defining feature of organic semiconductors and plays a central role in determining their transport properties [11, 13].

Charge carriers in these materials can be generated in several ways. In electronic devices, carriers are typically injected from metallic electrodes, while in optoelectronic applications they can be created through photoexcitation. The energy required to add or remove an electron from a molecule is determined by its ionization energy and electron affinity, typically on the order of a few electronvolts. Since thermal energy at room temperature is much smaller than this scale, free carriers are generally not present in significant numbers unless they are externally injected, optically generated, or introduced through doping [3, 11].

The weak intermolecular bonding, which decays rapidly with intermolecular distance (approximately as $1/R^6$), leads to relatively soft crystal structures. As a consequence, thermal motion at room temperature produces significant fluctuations in both the positions and orientations of molecules. Because the electronic coupling between neighboring molecules depends sensitively on their relative arrangement, even small displacements can lead to substantial variations in orbital overlap. Charge transport in organic semiconductors is therefore inherently sensitive to lattice dynamics [9, 10].

The arrangement of molecules within the crystal, commonly referred to as molecular packing, is a central factor in determining transport properties. Different packing motifs, such as slipped-stack, herringbone, or brick-wall structures, lead to distinct patterns of orbital overlap and define preferred pathways for charge motion. In many organic crystals, electronic coupling is significantly stronger along certain directions than others, resulting in strongly anisotropic transport. In some cases, charge carriers effectively propagate along a dominant direction, giving rise to quasi-one-dimensional transport behavior [3, 10, 11]. Representative molecular packing motifs are illustrated in Fig. 1.2,

highlighting how different arrangements give rise to anisotropic charge transport.

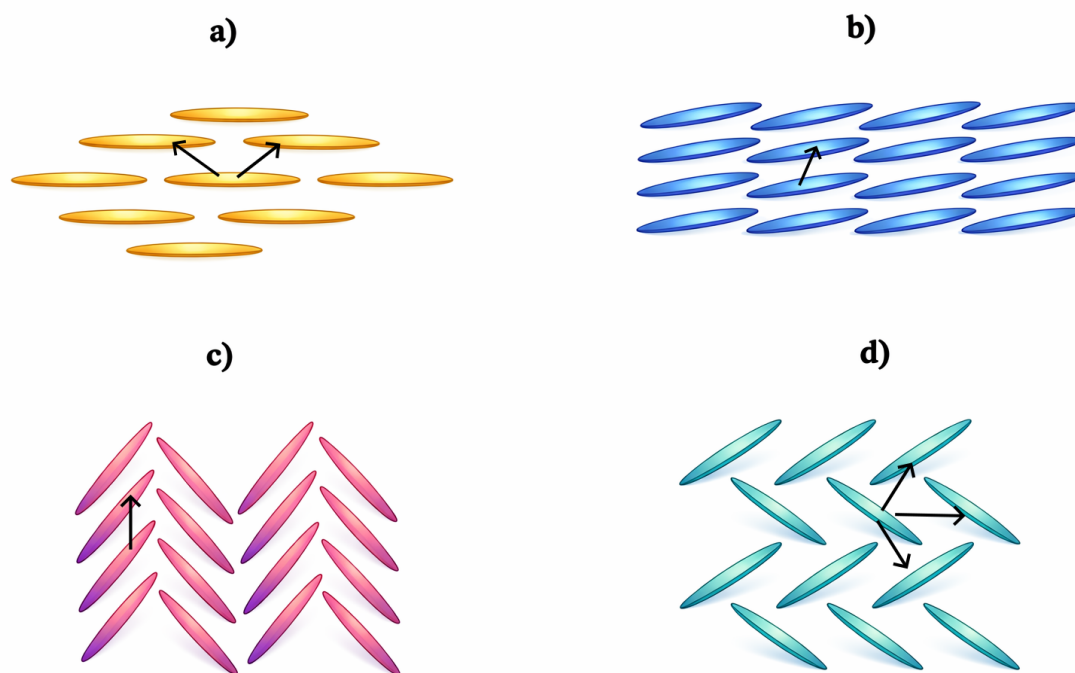


Figure 1.2: Representative molecular packing motifs commonly found in organic crystals. a) Brickwall packing; b) slipped-stack packing; c) slipped- π stack arrangement; d) herringbone packing. The arrows indicate the directions of the dominant intermolecular electronic coupling (transfer integral). The schematic representation of molecular packing motifs follows commonly observed structures reported in the literature [10].

A particularly illustrative example is the organic semiconductor rubrene, which exhibits some of the highest charge carrier mobilities among organic materials. Its crystal structure enables favorable π -orbital overlap along specific crystallographic directions, leading to enhanced electronic coupling and improved transport properties along those directions. At the same time, coupling remains much weaker in other directions, resulting in pronounced anisotropy. This example highlights how molecular packing directly governs transport behavior in organic crystals [10, 14]. The molecular structure of rubrene and its characteristic slipped π - π stacking arrangement are illustrated in Fig. 1.3, together with the direction of strongest intermolecular electronic coupling, which determines the anisotropy of charge transport.

It is instructive to compare the charge carrier mobilities of organic semiconductors with those of inorganic materials. High-quality silicon crystals exhibit electron mobilities on the order of $10^3 \text{ cm}^2/\text{Vs}$, while materials such as graphene can reach even higher values. In contrast, typical mobilities in organic semiconductors range from 10^{-3} to $10^1 \text{ cm}^2/\text{Vs}$. Although significantly lower, these values remain sufficient for many applications where flexibility, low cost, and large-area fabrication are more important than ultrafast electronic performance. At the same time, improving carrier mobility remains one of the central challenges in the development of organic electronic materials. A representative comparison across different material classes is summarized in Table 1.1 [7, 9, 10].

Another important distinction between organic and inorganic semiconductors lies in the comparable magnitude of several key energy scales. The electronic coupling between molecules, the energies of relevant vibrational modes, and the strength of their interaction typically all fall within the range of tens to hundreds of millielectronvolts. In particular, low-frequency intermolecular vibrational modes, associated with the relative motion of neighboring molecules, play a dominant role in modulating the

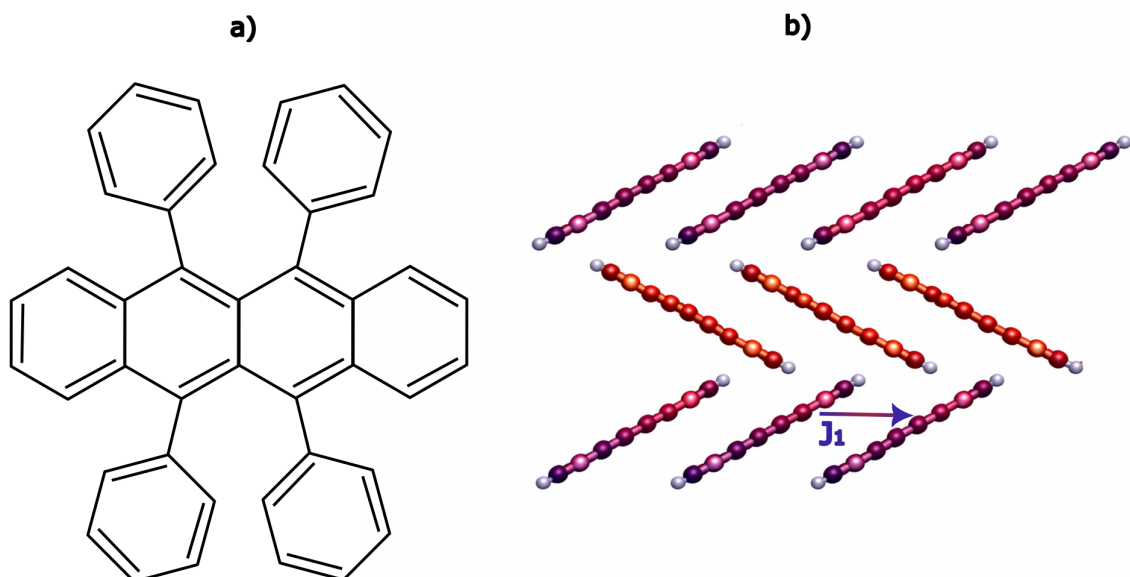


Figure 1.3: Structure and molecular packing of rubrene. a) Chemical structure of the rubrene molecule. b) Schematic representation of the slipped π - π stacking arrangement in rubrene crystals. The arrow indicates the direction of the dominant electronic coupling between neighboring molecules. The illustrated molecular packing motifs are based on structural arrangements that are frequently described in the literature [10].

Table 1.1: Representative charge carrier mobilities for different classes of semiconducting materials. Values are approximate and depend on material quality, temperature, and measurement conditions [4, 9–11, 14].

Material Class	Example Material	Mobility (cm^2/Vs)
<i>Inorganic semiconductors</i>		
Monocrystalline elemental semiconductor	Si (single crystal)	$\sim 10^3$
Amorphous elemental semiconductor	a-Si	$10^{-1} - 1$
Compound semiconductor	GaAs	$\sim 10^3 - 10^4$
Transition metal dichalcogenide	MoS ₂	$10^1 - 10^2$
<i>Low-dimensional / nanomaterials</i>		
Graphene (suspended)	Graphene	$10^4 - 10^6$
Graphene (supported)	Graphene on SiO ₂	$10^3 - 10^4$
Carbon nanotubes	CNTs	$10^3 - 10^5$
<i>Organic semiconductors</i>		
Small-molecule crystal	Rubrene	$1 - 20$
High-mobility OSC	DNTT, BTBT derivatives	$1 - 10$
Polymer semiconductor	P3HT	$10^{-4} - 10^{-1}$
Amorphous organic film	Disordered OSC	$10^{-6} - 10^{-3}$

electronic coupling. As a result, even modest thermal fluctuations can significantly influence charge transport [9, 11, 13].

These considerations demonstrate that charge transport in organic semiconductors cannot be understood solely in terms of static electronic structure. Instead, it is governed by a dynamic interplay between electronic motion and molecular vibrations. In the following section, this interplay is examined in more detail, with emphasis on how it gives rise to different transport mechanisms.

1.2 Charge transport in organic crystals

The problem of charge transport in solids has been a central topic in condensed matter physics since the early development of quantum theory. In the first half of the twentieth century, the emergence of band theory provided a successful framework for describing electronic motion in crystalline solids, particularly metals and inorganic semiconductors. Soon after, it became clear that interactions between charge carriers and the lattice play an essential role in many materials. Early theoretical work by Landau and Pekar introduced the concept of a charge carrier interacting with its surrounding medium, forming a composite object whose properties differ from those of a free electron. This idea was later developed in models describing the interaction between electrons and lattice vibrations, including the work of Fröhlich and, subsequently, Holstein, who formulated a model particularly suited for molecular crystals [15–19].

In inorganic semiconductors, the motion of charge carriers is often well described within the framework of band theory. When atoms are arranged in a periodic lattice and their electronic orbitals strongly overlap, the discrete energy levels of individual atoms broaden into continuous energy bands. In this picture, an electron is no longer associated with a single atom but is instead delocalized over the entire crystal, propagating as a Bloch wave through the periodic structure. This type of motion, commonly referred to as band transport, is characterized by relatively high mobility, with the carrier dynamics primarily limited by scattering from lattice vibrations or impurities. A typical signature of such transport is a decrease in mobility with increasing temperature, as enhanced lattice vibrations lead to more frequent scattering events [11, 20].

This physical picture relies on strong overlap between neighboring orbitals, which is a direct consequence of the rigid, closely packed atomic structure found in inorganic crystals. In contrast, organic molecular crystals are composed of relatively large molecules held together by weak intermolecular forces. As a result, the overlap between electronic orbitals on neighboring molecules is much smaller and highly sensitive to their relative positions. Furthermore, because the molecules are not rigidly fixed, they undergo significant thermal motion, continuously fluctuating around their equilibrium positions and orientations. These fluctuations dynamically modulate the already small orbital overlap, leading to narrow electronic bands or, in some cases, to states that are effectively localized on individual molecules [9, 11, 21, 22].

To describe these effects more precisely, it is useful to introduce the concept of phonons, which represent quantized modes of lattice vibrations. In organic materials, these include both internal molecular vibrations and intermolecular modes associated with the relative motion of entire molecules. Because of the weak binding and large molecular size, many of these modes occur at relatively low energies which can strongly influence electronic motion, as even small molecular displacements can significantly modify intermolecular orbital overlap [9, 11, 22, 23].

When a charge carrier moves through such a deformable and polarizable environment, it interacts with these lattice vibrations as well as with the surrounding molecular structure. Instead of moving independently of the lattice, the carrier modifies its local environment, and this modified environment in turn influences the carrier dynamics. In many cases, this mutual interaction leads to the formation of a polaron, a quasiparticle consisting of the charge carrier together with the lattice deformation it induces. Compared to a free carrier in a conventional band, a polaron behaves as an effectively heavier object, reflecting the fact that its motion is accompanied by the reorganization of the surrounding lattice [11, 15, 16, 18, 19, 24].

The nature of this coupling depends on its strength. In the case of relatively weak interaction, the carrier remains largely delocalized, and the lattice deformation extends over many sites, forming what is commonly referred to as a large polaron. In stronger coupling regimes, the deformation becomes more localized, and the carrier becomes effectively confined to a small region of the lattice, forming a small polaron. This distinction has important consequences for transport: while large polarons may still exhibit band-like motion, small polarons are typically associated with localized behavior [11, 17–19, 24].

A key consequence of strong coupling between the carrier and its environment is the possibility of self-trapping. In this case, the carrier induces a local lattice distortion that lowers its energy, effectively creating a potential well in which it resides. Unlike trapping by impurities or defects, which arises from external disorder, this localization is intrinsic, as it is generated by the carrier itself. Motion to a neighboring site requires the carrier to overcome this local binding, which typically occurs through interaction with lattice vibrations [11, 19, 24].

This mechanism leads to thermally activated hopping transport. Instead of moving continuously through the crystal, the carrier resides on a given molecular site and transitions to neighboring sites when it acquires sufficient energy from lattice vibrations to overcome the local binding potential. As temperature increases, these fluctuations become stronger and more frequent, facilitating such transitions. Consequently, the mobility in this regime typically increases with temperature, in contrast to band transport. This behavior is characteristic of processes governed by thermal activation over an energy barrier and is commonly described within polaron hopping and Marcus-type theories [11, 19, 22, 25].

Experimental studies of organic molecular crystals reveal signatures of both transport mechanisms. In highly ordered systems, such as high-quality single crystals, the mobility often decreases with increasing temperature, indicating that carriers retain a degree of coherent, band-like motion. In contrast, in less ordered systems or at higher temperatures, the mobility frequently increases with temperature, reflecting thermally activated hopping between localized states. These contrasting behaviors have been observed in a wide range of materials and experimental conditions and highlight the sensitivity of charge transport to structural order and thermal fluctuations. Together, these observations suggest that organic semiconductors often operate in an intermediate regime, where neither purely band-like nor purely hopping descriptions are fully adequate [2, 8, 9, 11, 26].

The origin of this complexity lies in the comparable magnitude of several key energy scales in these materials. The electronic coupling between neighboring molecules, the energies associated with lattice vibrations, and the strength of their interaction with charge carriers often fall within the same energy range (10–100 meV). As a result, even modest thermal motion, such as small displacements or reorientations of molecules, can significantly alter orbital overlap and, consequently, charge transport. In this sense, transport in organic semiconductors is inherently dynamic, continuously influenced by the fluctuating structure of the lattice [9, 11, 22, 23, 27].

Recent theoretical and experimental work has emphasized that charge carriers in such systems may occupy states that are neither fully localized nor completely delocalized. Instead, the carrier can transiently access more extended states while still interacting strongly with its environment, a picture often referred to as transient localization. This framework provides a useful way to understand transport behavior that lies between the traditional limits of band transport and hopping conduction [8, 9, 28].

To capture these effects theoretically, it is necessary to use models that explicitly include the interaction between electronic motion and lattice degrees of freedom. Among these, the Holstein model has become one of the most widely used frameworks for describing charge transport in molecular crystals. In this model, a charge carrier moves between discrete sites while interacting locally with vibrational modes associated with each site. Despite its simplicity, the model captures key features such as polaron formation, bandwidth renormalization, and the crossover between different transport regimes [11, 18, 19, 24].

Although simplified, Holstein-type models provide valuable insight into the fundamental mechanisms governing charge transport in organic semiconductors and serve as a foundation for many modern theoretical and numerical approaches. In the following chapter, a detailed theoretical description of polaron formation and transport based on this framework is presented, with particular emphasis on regimes relevant for organic molecular systems.

1.3 Theoretical and numerical approaches to electron-phonon coupled systems

The theoretical description of charge transport in systems where charge carriers interact strongly with their surrounding lattice remains a challenging problem that has been studied for many decades [18, 24]. The difficulty arises from the need to treat electronic and lattice degrees of freedom on equal footing, as their interplay can give rise to qualitatively different physical behavior depending on the interaction strength and the relevant energy scales [9, 11]. As a result, a wide range of theoretical and computational approaches have been developed, each applicable within a specific regime and based on different approximations [12, 29].

One of the earliest and most widely used approaches is based on band theory combined with a perturbative treatment of interactions [20]. Within this framework, electronic states remain largely delocalized, while lattice vibrations enter as a weak perturbation that gives rise to scattering processes [30]. Such approaches are highly successful in inorganic semiconductors, where the electronic bandwidths are large and the carrier-lattice coupling is relatively weak [20]. However, in organic molecular systems, where intermolecular electronic coupling is small and lattice fluctuations are significant, these methods often fail to capture essential features such as carrier localization and strong renormalization of transport properties [9, 11, 12].

An alternative class of approaches is provided by semiclassical transport theories, in which charge carriers are treated quantum mechanically, while lattice degrees of freedom are described classically [30]. Examples include Boltzmann transport equations and extensions that incorporate dynamic disorder [12, 27]. These methods offer useful insight into intermediate regimes, particularly when lattice fluctuations act as a time-dependent disorder potential [9, 27]. However, their applicability becomes limited when the quantum effects of lattice vibrations are important or when carrier-lattice coupling leads to the formation of composite quasiparticles [11, 29].

In the opposite limit of strong localization, transport is commonly described within the framework of hopping models [19, 24, 31]. In this picture, the system is viewed as a network of localized sites, and charge transport proceeds via transitions between them. The rates of these transitions depend on the coupling to lattice vibrations and the associated energy changes. A well-established example is the Marcus theory, which has been widely used to describe charge transfer in molecular systems [25]. Although such approaches successfully capture thermally activated transport and are particularly effective in disordered or high-temperature regimes, they inherently assume localized carriers and are therefore unable to describe coherent or partially delocalized motion [31].

To bridge the gap between these limiting descriptions, various polaron theories have been developed. Models such as the Holstein and Fröhlich Hamiltonians describe how charge carriers become coupled to lattice distortions, forming composite quasiparticles whose properties differ significantly from those of free carriers [17, 31, 32]. Depending on the coupling strength and the relative time scales of electronic and lattice motion, these models can describe both large and small polarons, as well as the crossover between coherent and incoherent transport regimes [24, 31]. However, analytical treatments are typically restricted to limiting cases, and approximate methods are required to address realistic parameter ranges [24].

The limitations of analytical approaches have motivated the development of a variety of numerical and semi-analytical methods for treating electron-phonon coupled systems. A large class of these methods relies on controlled or, in some cases, uncontrolled approximations, which makes them computationally efficient and applicable to complex or extended systems, but also limits their range of validity. This trade-off between efficiency and accuracy is well recognized in the study of electron-phonon models, where different approximate techniques often yield consistent results only within specific parameter regimes [33].

Among these approaches, diagrammatic and Green's-function-based methods such as the cumulant expansion and dynamical mean-field theory (DMFT) provide nonperturbative insight into spectral and

transport properties. In particular, DMFT becomes exact in the limit of infinite lattice coordination and allows one to capture the crossover from coherent band-like motion to incoherent hopping transport in polaronic systems. However, such approaches typically neglect nonlocal correlations and may fail in low-dimensional systems or in regimes with strong spatial fluctuations [34–38].

Another class of approximate methods is based on variational and diagrammatic resummation techniques. Variational approaches, including those based on systematically constructed Hilbert spaces or generalized Lang–Firsov transformations, can provide highly accurate results for ground-state and low-energy properties across a wide parameter range, but are often limited in their ability to describe dynamical quantities or finite-temperature behavior [39, 40]. Related diagrammatic approximations, such as the momentum-average method, sum large classes of self-energy diagrams in an efficient manner and yield accurate results for Green’s functions and spectral properties over broad parameter regimes, while remaining computationally inexpensive [41–44].

Stochastic approaches, such as kinetic Monte Carlo, provide an effective framework for simulating charge transport in disordered systems by describing the carrier motion as a sequence of thermally activated transitions between localized states. Despite their widespread use in the modeling of organic semiconductors, these methods inherently assume localized carriers and classical hopping dynamics and, therefore, cannot capture effects of quantum coherence or partial delocalization in intermediate regimes [45].

To overcome the limitations of approximate approaches, a variety of numerically exact or systematically controllable methods have been developed for electron–phonon systems. These methods aim to solve the model Hamiltonian without introducing uncontrolled approximations, at the cost of significantly increased computational effort.

Among these, wavefunction-based techniques such as exact diagonalization (ED) and density matrix renormalization group (DMRG) provide numerically exact results for finite systems. ED allows direct access to both ground-state and dynamical properties, but is restricted to small system sizes due to the exponential growth of the Hilbert space [46]. DMRG, on the other hand, enables simulations of much larger one-dimensional systems by efficiently truncating the Hilbert space and has proven highly successful in describing polaron formation and crossover behavior across different coupling regimes [47]. Extensions such as time-dependent DMRG further allow the investigation of real-time dynamics and finite-temperature properties in complex systems [48–51]. Complementary approaches based on open quantum system techniques, such as hierarchical equations of motion (HEOM), provide an alternative route to numerically exact dynamics by systematically incorporating system–bath correlations [48, 52–56].

Another important class of numerically exact methods is based on quantum Monte Carlo (QMC) techniques. These methods provide unbiased results for thermodynamic and dynamical quantities by statistically sampling the configurations of the system. Early implementations based on discrete path-integral formulations demonstrated that electron–phonon problems can be treated accurately by integrating out phonon degrees of freedom and sampling electron trajectories [57, 58]. Subsequent developments, including continuous-time QMC algorithms, eliminated systematic errors associated with time discretization and enabled simulations across a wide range of parameters and dimensionalities [59, 60]. More advanced approaches, such as diagrammatic Monte Carlo, directly sample Feynman diagram expansions of Green’s functions and can, in principle, yield exact results in the thermodynamic limit [61–63].

These methods are naturally formulated within the path integral framework of quantum mechanics, in which quantum statistical properties are expressed as sums over all possible trajectories of the system. Within this formalism, QMC techniques enable the stochastic evaluation of path integrals, allowing interacting quantum systems to be treated at finite temperature without relying on perturbative assumptions. In particular, path-integral QMC approaches are well suited for studying electron–lattice interaction models, as they incorporate both quantum fluctuations and thermal effects on equal footing and provide numerically exact results within statistical uncertainty [64–66].

Compared to many approximate methods, quantum Monte Carlo approaches offer the important

advantage of being numerically exact within statistical uncertainty. In particular, they do not rely on uncontrolled approximations regarding the interaction strength or the degree of carrier localization. This makes them especially valuable for systems such as organic semiconductors, where electronic coupling, lattice dynamics, and their mutual interaction occur on comparable energy scales and cannot be treated independently.

At the same time, these approaches are not without limitations. Their computational cost can be significant, and certain formulations, particularly those involving real-time evolution, may suffer from the dynamical sign problem, which severely restricts accessible timescales [67–70]. In addition, extracting transport properties often requires analytic continuation from imaginary-time data, an ill-posed problem that can introduce additional uncertainties [71–77]. Nevertheless, for a broad class of electron–phonon coupled systems, path-integral quantum Monte Carlo methods provide a powerful and reliable framework for investigating equilibrium properties and transport-related quantities.

In this thesis, a path integral quantum Monte Carlo approach is employed to study charge transport in systems described by electron–phonon interaction models. This framework enables a consistent treatment of quantum and thermal fluctuations and allows different transport regimes to be explored on equal footing, without restricting the analysis to a particular limiting case. In the following chapters, this approach is applied to investigate the behavior of charge carriers in model systems relevant to organic molecular semiconductors and to analyze the conditions under which different transport mechanisms emerge.

1.4 Motivation and thesis outline

The study of charge transport in organic semiconductors is motivated by both technological demands and fundamental scientific questions. On the applied side, these materials offer unique advantages such as mechanical flexibility, low-cost fabrication, and compatibility with large-area devices, making them promising candidates for next-generation electronic and optoelectronic technologies. However, their performance remains limited by relatively low charge carrier mobility compared to inorganic semiconductors. Improving transport properties therefore requires a deeper understanding of the microscopic mechanisms governing carrier motion in these systems.

From a fundamental perspective, organic molecular crystals represent a class of materials in which several key energy scales, including electronic coupling, lattice dynamics, and their mutual interaction, are of comparable magnitude. This leads to a rich variety of transport regimes that cannot be fully captured by traditional theories developed for inorganic semiconductors. Instead, charge carriers in these materials exhibit behavior ranging from coherent band-like motion to thermally activated hopping, with intermediate regimes that remain an active area of research. Understanding how these regimes emerge and how they depend on microscopic parameters is one of the central challenges in the field.

To address these questions, it is useful to adopt simplified theoretical models that capture the essential physical mechanisms while remaining tractable for detailed analysis. The Holstein model provides such a framework, describing a charge carrier locally coupled to vibrational degrees of freedom. This model is particularly well suited for organic molecular systems, where charge transport occurs via the overlap of molecular orbitals and where the interaction between the carrier and local molecular distortions plays a dominant role. Furthermore, the pronounced anisotropy of many organic crystals, arising from their molecular packing, often leads to transport that is effectively confined to one preferred direction. This motivates the use of a one-dimensional formulation of the model as a minimal yet physically meaningful representation of such systems.

A central difficulty in studying electron–phonon coupled systems lies in the fact that different theoretical approaches are typically valid only in limiting cases. Weak-coupling theories describe nearly free carriers, while strong-coupling approaches capture localized behavior. However, the intermediate regime, in which electronic coupling, lattice fluctuations, and their interaction are of

comparable magnitude, is particularly challenging because it cannot be reliably described by simple approximations. This regime is especially relevant for organic semiconductors, where these energy scales naturally coincide.

Charge transport in such systems can be investigated using a path integral quantum Monte Carlo (QMC) approach. This method enables a non-perturbative treatment of electron–phonon coupled systems and provides a consistent description across a wide range of coupling strengths and temperatures. In contrast to approaches that are restricted to specific regimes, the path integral formulation allows direct access to the intermediate regime, where many standard approximations break down. Within this framework, quantum and thermal fluctuations are treated on equal footing, enabling a detailed analysis of transport behavior and the emergence of different transport regimes. The numerical exactness of the method, within statistical uncertainty, makes it particularly well suited for studying the interplay between charge carriers and lattice dynamics in organic semiconductors.

The results presented in this thesis are divided into two parts. In the first part, a path integral quantum Monte Carlo approach is developed for evaluating charge transport properties of the Holstein polaron. Within this framework, a methodology for calculating carrier mobility is established and validated by reproducing known results obtained using independent theoretical methods. This provides a reliable foundation for studying transport across a wide range of interaction strengths and temperatures.

In the second part, this methodology is applied to a systematic investigation of the Holstein polaron model. By analyzing the dependence of the transport properties on the temperature, interaction strength, and phonon energy, distinct regimes of carrier motion are identified and the crossover between coherent and incoherent transport is examined. The results provide a unified picture of the transport behavior across a wide range of parameters, including the intermediate regime, where different mechanisms compete.

The structure of the thesis is as follows.

Chapter 2 provides the theoretical foundation for the study of charge transport in electron–phonon coupled systems and establishes the formal framework underlying the path-integral quantum Monte Carlo methodology. It introduces the Holstein model and the linear response formalism used to describe transport properties, with particular emphasis on the current–current correlation function as the central quantity governing transport. The polaron picture is then presented, together with an overview of the main transport mechanisms, including hopping, band, and polaron band transport. In addition, the path-integral formulation of quantum statistical mechanics is introduced, along with key mathematical tools required for its treatment. The chapter concludes with an overview of quantum Monte Carlo methods, including the path-integral approach employed in this work, the associated dynamical sign problem, and the analytic continuation procedure used to extract real-time transport quantities from imaginary-time data.

Chapter 3 presents the development of the computational methodology used to evaluate transport properties of the Holstein polaron within the path-integral quantum Monte Carlo framework. The path-integral representation of time-correlation functions is derived, where the quantum statistical problem is formulated in terms of discretized imaginary- and real-time evolution operators using the Trotter–Suzuki decomposition. Two complementary formulations are considered, based on the electron momentum and position representations. The analytic continuation procedure used to extract dc mobility from real- and imaginary-time correlation functions is then described and illustrated. The chapter concludes with the presentation of numerical results, including current–current correlation functions, analysis of statistical uncertainties, and the temperature dependence of the Holstein polaron mobility, demonstrating good agreement with independent theoretical approaches.

Chapter 4 presents the main results of this thesis, focusing on the identification of transport regimes in the one-dimensional Holstein model. Effective approximate theoretical descriptions corresponding to the three relevant transport mechanisms, namely hopping, band, and polaron band transport, are introduced and analyzed. The corresponding expressions for current–current correlation functions and dc mobility are presented and compared, providing insight into the crossover between different trans-

port regimes. Criteria for identifying transport regimes are then established based on the agreement between numerically exact quantum Monte Carlo results and the approximate theoretical descriptions. These criteria are applied through a systematic comparison of imaginary-time correlation functions and dc mobility, allowing for the identification of the regions of parameter space where each transport mechanism is applicable. The chapter concludes with the construction of the transport regime diagram for the one-dimensional Holstein model.

Chapter 5 provides a discussion of the results presented in Chapters 3 and 4, focusing on their physical interpretation and their relation to existing theoretical and experimental studies. The implications for charge transport in organic semiconductors are considered in the context of relevant literature.

Chapter 6 summarizes the main findings of the thesis and outlines their significance. The broader implications of the results are discussed, and possible directions for future research are briefly indicated.

Chapter 2

Theoretical background

The theoretical description of charge transport in organic molecular systems requires a framework capable of capturing the interplay between electronic motion and lattice dynamics. As discussed in the Introduction, this interplay gives rise to a rich variety of transport regimes, ranging from band-like motion to thermally activated hopping, as well as intermediate regimes where neither description is fully adequate.

A central challenge in developing such a framework lies in the comparable magnitude of the relevant energy scales. In organic semiconductors, the electronic coupling between neighboring molecules, the characteristic energies of lattice vibrations, and the strength of electron–phonon interaction are often of the same order. As a result, the motion of charge carriers cannot be treated independently of the lattice, and standard perturbative approaches become insufficient.

To address these challenges, it is necessary to adopt microscopic models that explicitly incorporate the coupling between electronic and vibrational degrees of freedom. Among these, the Holstein model has emerged as one of the most widely used minimal models for describing charge transport in molecular crystals. Despite its relative simplicity, it captures the essential physics of local electron–phonon interaction and provides a unified framework for studying different transport regimes.

In addition to selecting an appropriate model, it is equally important to employ theoretical and numerical methods capable of treating electron–phonon coupled systems across a broad range of parameters. In particular, approaches that do not rely on assumptions about the nature of transport, such as whether it is band-like or hopping, are especially valuable in regimes where multiple mechanisms compete. In this work, we adopt a path-integral quantum Monte Carlo approach, which enables a numerically exact treatment of the coupled electron–lattice system within statistical uncertainty.

In this chapter, we establish the theoretical framework used throughout this work. We begin by introducing the Holstein polaron model, which serves as a minimal microscopic description of charge carriers interacting with lattice vibrations in molecular systems. We then present the formalism of linear response theory and the Kubo formula, which provide the connection between microscopic dynamics and experimentally measurable transport coefficients such as electrical conductivity and mobility.

Building on this foundation, we discuss the principal transport mechanisms relevant for electron–phonon coupled systems, including band transport, thermally activated hopping, and polaron band transport, and outline the conditions under which each regime is expected to occur. We then introduce the path-integral formulation of quantum mechanics, which offers a natural framework for treating systems with coupled electronic and lattice degrees of freedom. Finally, we present the quantum Monte Carlo methodology employed in this work, with particular emphasis on path-integral Monte Carlo techniques used to evaluate current–current correlation functions. Special attention is given to key methodological aspects, including the dynamical sign problem that limits real-time simulations and the analytic continuation procedure required to extract real-frequency transport quantities from imaginary-time data. Together, these elements form the computational framework that enables a numerically exact evaluation of transport properties across a wide range of parameters.

2.1 Holstein polaron model

Charge transport in molecular and organic semiconductors is strongly influenced by the interaction between charge carriers and lattice vibrations. Due to the pronounced anisotropy and partial localization of electronic wave functions in such materials, charge motion is often adequately described within a tight-binding framework with local electron-phonon coupling. A minimal microscopic model capturing these effects is provided by the Holstein molecular crystal model, originally introduced by T. Holstein in the late 1950s.

The Holstein Hamiltonian is written as

$$H = H_e + H_{\text{ph}} + H_{\text{e-ph}} , \quad (2.1)$$

where H_e describes the electronic kinetic energy, H_{ph} the lattice degrees of freedom and $H_{\text{e-ph}}$ accounts for the electron-phonon coupling [24, 32].

Within the nearest-neighbor tight-binding approximation, the electronic part for a one-dimensional lattice reads

$$H_e = -J \sum_n \sum_{\gamma=\pm 1} c_{n+\gamma}^\dagger c_n , \quad (2.2)$$

where $c_n^\dagger$ and c_n are fermionic creation and annihilation operators at the lattice site n , and J is the electron transfer integral. The corresponding bare electronic bandwidth is $W = 4J$. In the absence of electron-phonon interaction, the eigenstates are Bloch waves with dispersion $\varepsilon(k) = -2J \cos k$, describing coherent band-like transport [24, 78].

The lattice is modeled as a set of independent, dispersionless optical phonons of frequency ω_0 , reflecting the local character of intramolecular vibrational modes. In coordinate representation, the phonon Hamiltonian is

$$H_{\text{ph}} = \sum_n \left[\frac{p_n^2}{2M} + \frac{1}{2} M \omega_0^2 x_n^2 \right] , \quad (2.3)$$

where x_n and p_n denote the displacement and conjugate momentum operators of an oscillator of mass M at the site n . Equivalently, the phonon Hamiltonian in second-quantization reads

$$H_{\text{ph}} = \hbar \omega_0 \sum_n b_n^\dagger b_n , \quad (2.4)$$

where $b_n^\dagger$ and b_n are phonon creation and annihilation operators at site n . The zero point energy $\hbar \omega_0/2$ has been omitted as an irrelevant constant energy shift. The two representations are related through operator relations

$$x_n = \sqrt{\frac{\hbar}{2M\omega_0}} (b_n^\dagger + b_n) , \quad p_n = i\sqrt{\frac{\hbar M \omega_0}{2}} (b_n^\dagger - b_n) , \quad (2.5)$$

which satisfy the canonical commutation relations $[x_n, p_m] = i\hbar \delta_{nm}$ [24, 78].

The electron-phonon interaction in the Holstein model is purely local, coupling the electronic density at a given site to the lattice displacement at the same site. In second-quantization, the interaction Hamiltonian is

$$H_{\text{e-ph}} = G \sum_n c_n^\dagger c_n (b_n^\dagger + b_n) , \quad (2.6)$$

where G is the electron-phonon coupling constant with dimensions of energy. Using the coordinate representation for phonon operators, the interaction term can be written as

$$H_{\text{e-ph}} = \alpha \sum_n c_n^\dagger c_n x_n , \quad (2.7)$$

with $\alpha = G\sqrt{2M\omega_0}/\hbar$. This representation is especially useful in the path-integral formalism, where phonon degrees of freedom naturally appear as lattice displacement fields and can be integrated out [24, 57, 78].

The properties of the model are governed by the competition between electronic movement and lattice response. Two dimensionless parameters are commonly used to characterize the system. The first is the adiabaticity ratio $J/(\hbar\omega_0)$, which compares the electronic hopping scale to the phonon energy. It distinguishes between the adiabatic regime, $J \gg \hbar\omega_0$, where lattice dynamics is slow compared to electronic motion, and the non-adiabatic regime, $J \ll \hbar\omega_0$, where quantum lattice fluctuations dominate. The second parameter is the dimensionless electron–phonon coupling strength $\lambda = 2G^2/(\hbar\omega_0 W)$, which measures the ratio of polaron binding energy $E_p = G^2/(\hbar\omega_0)$ to half electronic bandwidth $W/2$. In the weak coupling regime, $\lambda \ll 1$, the carrier remains relatively delocalized and forms a large polaron with moderate mass renormalization and predominantly band-like transport. In the strong coupling regime, $\lambda \gtrsim 1$, the electron becomes self-trapped by the lattice distortion it induces, forming a small polaron. In this regime, the effective bandwidth is exponentially reduced and charge transport is typically governed by thermally activated hopping [24, 31].

Over the past decades, the Holstein polaron model has been studied using a wide variety of theoretical and numerical methods, each suited to different parameter regimes. Approaches range from perturbative treatments in the weak-coupling limit to variational and canonical transformation techniques for intermediate coupling, and to nonperturbative methods such as exact diagonalization, density-matrix renormalization group, diagrammatic Monte Carlo, and path-integral Monte Carlo. The diversity of these methods reflects both the fundamental importance of the Holstein model and the intrinsic complexity of strongly coupled electron–phonon systems, especially in regimes where neither weak nor strong coupling approximations are quantitatively reliable.

The Holstein model thus provides a unified microscopic framework that continuously connects coherent band transport and incoherent hopping, making it particularly suitable for quantitative investigations of polaron dynamics over a broad range of temperatures, coupling strengths, and phonon frequencies. Although the model can be extended straightforwardly to higher spatial dimensions, in the present work, we restrict our analysis to the one-dimensional case. Even in one dimension, the Holstein Hamiltonian remains highly nontrivial and does not admit a general exact analytical solution.

2.2 Linear response theory and Kubo formula

Although theoretical descriptions of transport in terms of charge carriers, phonons, and their mutual interactions may appear abstract, the ultimate objective is to establish a direct connection between microscopic dynamics and experimentally measurable observables. In the context of charge transport, the relevant observable is the electrical current. More precisely, the material property of interest is the electrical conductivity, which characterizes the response of a system to an applied electric field and can be measured directly in experiments.

When a material is subjected to an external perturbation, such as an electric or magnetic field, pressure, or a temperature gradient, it exhibits a measurable response. In the regime of weak perturbations, the response is linear in the applied field. This statement constitutes the foundation of linear response theory. The proportionality factor relating the induced response to the perturbation defines a transport coefficient that encodes intrinsic properties of the material.

In the presence of an external electric field, the induced quantity is the electrical current density $J(\mathbf{r}, t)$. Within linear response theory, the current is related to the total electric field $E(\mathbf{r}, t)$ as

$$J_i(\mathbf{r}, t) = \int d\mathbf{r}' \int_{-\infty}^t dt' \sigma_{ij}(\mathbf{r}, \mathbf{r}'; t - t') E_j(\mathbf{r}', t'). \quad (2.8)$$

Here, $i, j = x, y, z$ denote spatial components and summation over repeated indices is implied. The conductivity tensor σ_{ij} depends on the time difference $t - t'$ due to time-translation invariance of the equilibrium system, while the restriction $t' \leq t$ reflects causality. The response is necessarily retarded with respect to the perturbation.

For a homogeneous system, the conductivity depends only on coordinate differences, $\sigma_{ij}(\mathbf{r}, \mathbf{r}'; t - t') \equiv \sigma_{ij}(\mathbf{r} - \mathbf{r}'; t - t')$. In crystalline solids, translational invariance allows one to perform a Fourier transformation to momentum-frequency space, yielding

$$J_i(\mathbf{q}, \omega) = \sigma_{ij}(\mathbf{q}, \omega) E_j(\mathbf{q}, \omega) . \quad (2.9)$$

A perturbation at frequency ω generates a response at that same frequency. In the linear regime, the different frequency components act independently and do not mix [78, 79].

2.2.1 Kubo formula for electric conductivity

The microscopic formulation of conductivity was originally introduced by Kubo in 1957 [78, 80]. The central result, commonly known as the Kubo formula, expresses the conductivity in terms of the autocorrelation functions of the current operator.

To establish a microscopic expression for conductivity, consider a system described by the Hamiltonian $H(t) = H_0 + H'(t)$, where H_0 is the unperturbed interacting part of the Hamiltonian and the term $H'(t)$ represents an external perturbation. In the nonrelativistic limit, the interaction of a system with an external electromagnetic field is given by $H'(t) = - \int d\mathbf{r} \, j(\mathbf{r}) \cdot A(\mathbf{r}, t)$, where $A(\mathbf{r}, t)$ is the vector potential and $j(\mathbf{r})$ is the current density operator. The total induced current is obtained as the average velocity of charged particles in the system. The velocity operator of a particle with charge q and mass m in the presence of a vector potential is given by [78]

$$v_i = \frac{1}{m} (p_i - qA(r_i, t)) . \quad (2.10)$$

The total current density is proportional to the average charge velocity. For a system with n carriers of charge q , the induced current density can be written as

$$J_i(\mathbf{r}, t) = nq \langle v_i(\mathbf{r}, t) \rangle . \quad (2.11)$$

Substituting the velocity operator and using $q = -e$ for the electron yields

$$J_i(\mathbf{r}, t) = -\frac{ne}{m} \langle p_i(\mathbf{r}, t) \rangle - \frac{ne^2}{m} A_i(\mathbf{r}, t) . \quad (2.12)$$

It is convenient to introduce the paramagnetic current density operator

$$j_i(\mathbf{r}, t) = -\frac{e}{m} p_i(\mathbf{r}, t) , \quad (2.13)$$

which allows the induced current to be written in the form

$$J_i(\mathbf{r}, t) = \langle j_i(\mathbf{r}, t) \rangle - \frac{ne^2}{m} A_i(\mathbf{r}, t) . \quad (2.14)$$

The first term represents the paramagnetic current, while the second term describes the diamagnetic contribution proportional to the vector potential.

Within the first-order time-dependent perturbation theory, the average value of the current density operator depends only on the perturbation Hamiltonian H'

$$\langle j_i(\mathbf{r}, t) \rangle \simeq -\frac{i}{\hbar} \int_{-\infty}^t dt' \langle [j_i(\mathbf{r}, t), H'(t')] \rangle . \quad (2.15)$$

where the expectation value is taken in thermal equilibrium with respect to the non-perturbed Hamiltonian. Substituting the perturbation Hamiltonian $H'(t') = - \int d\mathbf{r}' j_k(\mathbf{r}', t') A_k(\mathbf{r}', t')$, one obtains

$$\langle j_i(\mathbf{r}, t) \rangle = \frac{i}{\hbar} \int_{-\infty}^t dt' \int d\mathbf{r}' \langle [j_i(\mathbf{r}, t), j_k(\mathbf{r}', t')] \rangle A_k(\mathbf{r}', t') . \quad (2.16)$$

To express the response in terms of electric field, it is convenient to transform to momentum-frequency space. In general, the electric field is related to the vector and scalar potential as

$$E(\mathbf{r}, t) = -\frac{\partial A(\mathbf{r}, t)}{\partial t} - \nabla \phi(\mathbf{r}, t) . \quad (2.17)$$

Choosing the gauge $\phi = 0$ and Fourier transforming to momentum-frequency representation gives

$$E(\mathbf{q}, \omega) = i\omega A(\mathbf{q}, \omega) , \quad (2.18)$$

and equivalently

$$A(\mathbf{q}, \omega) = \frac{E(\mathbf{q}, \omega)}{i\omega} . \quad (2.19)$$

Using this relation and expressing the average of the current density operator in momentum-frequency space, one obtains

$$\langle j_i(\mathbf{q}, \omega) \rangle = \frac{1}{\hbar\omega V} \int_{-\infty}^t dt' e^{i\omega(t-t')} \langle [j_i(-\mathbf{q}, t), j_k(\mathbf{q}, t')] \rangle E_k(\mathbf{q}, \omega) \quad (2.20)$$

The proportionality coefficient between the induced current and the applied electric field defines the conductivity tensor. Including both the paramagnetic contribution and the diamagnetic term from Eq.(2.14), one obtains the Kubo formula for the conductivity[78–80]

$$\sigma_{ik}(\mathbf{q}, \omega) = \frac{1}{\hbar\omega V} \int_0^\infty dt e^{i\omega t} \left\langle \left[j_i^\dagger(\mathbf{q}, t), j_k(\mathbf{q}, 0) \right] \right\rangle + i \frac{ne^2}{m\omega} \delta_{ik} , \quad (2.21)$$

where the Hermiticity of the current operator implies $j(-\mathbf{q}, t) = j^\dagger(\mathbf{q}, t)$. The integrand in the first term of the Kubo formula can be identified with the retarded autocorrelation function of the current operator j_i which is defined as [78, 79]

$$C_{ik}^R(\mathbf{q}, t - t') = -\frac{i}{\hbar V} \theta(t - t') \langle [j_i^\dagger(t), j_k(t')] \rangle , \quad (2.22)$$

where V denotes the total volume of the system and $\theta(t)$ is the Heaviside step function indicating the time order of events $t > t'$. After Fourier transformation to frequency space, some cyclic permutations and time variable substitution $(t - t') \rightarrow t$, one obtains the retarded correlator in frequency representation

$$C_{ik}^R(\mathbf{q}, \omega) = \frac{-i}{\hbar V} \int_0^\infty dt \left\langle \left[j_i^\dagger(\mathbf{q}, t), j_k(\mathbf{q}, 0) \right] \right\rangle . \quad (2.23)$$

Consequently, the Kubo formula is expressed in terms of the retarded current-current correlation function

$$\sigma_{ik}(\mathbf{q}, \omega) = \frac{i}{\omega} \left[C_{ik}^R(\mathbf{q}, \omega) - \frac{ne^2}{m} \delta_{ik} \right] . \quad (2.24)$$

The principal quantity of interest in transport theory is the dc conductivity, obtained in the long-wavelength and zero-frequency limit,

$$\lim_{\omega \rightarrow 0} \lim_{\mathbf{q} \rightarrow 0} \sigma_{ik}(\mathbf{q}, \omega) . \quad (2.25)$$

The order of limits is important as reversing them corresponds to a static electric field and yields no net current. The dc conductivity is a real quantity and after taking the limit $\mathbf{q} \rightarrow 0$ it reads as

$$\sigma_{ik}|_{\omega \rightarrow 0} \propto - \lim_{\omega \rightarrow 0} \frac{1}{\omega} \text{Im} C_{ik}^R(\omega) . \quad (2.26)$$

To make the structure of the correlation function explicit, one introduces its spectral representation. The imaginary part of the retarded correlation function is related to the spectral function according to $\text{Im} C_{ik}(\omega) = -\frac{1}{2} R(\omega)$, where $R_{ik}(\omega)$ is the spectral function defined as [78]

$$R_{ik}(\omega) = 2\pi \left(1 - e^{-\beta\hbar\omega}\right) \frac{1}{Z} \sum_{n,m} e^{-\beta E_n} \langle n | j_i^\dagger | m \rangle \langle m | j_k | n \rangle \delta(\hbar\omega + E_n - E_m) . \quad (2.27)$$

Here, $\{|n\rangle\}$ denotes the eigenstates of the full Hamiltonian with the corresponding energies E_n and $Z = \sum_n \exp(-\beta E_n)$ is the partition function.

Substituting the spectral representation into the conductivity expression Eq. (2.21) and taking the limit $\omega \rightarrow 0$ yields the Kubo formula for dc conductivity [78]

$$\sigma_{ik}|_{\omega=0} = \frac{\pi\beta\hbar}{V} \frac{1}{Z} \sum_{n,m} e^{-\beta E_n} \langle n | j_i^\dagger | m \rangle \langle m | j_k | n \rangle \delta(E_n - E_m) . \quad (2.28)$$

This expression shows that the dc conductivity is determined by transitions between states that are very close in energy.

In macroscopic systems with finite carrier density n , electrical transport is characterized by conductivity $\sigma = ne\mu$, where μ denotes mobility. In the small carrier concentration limit, relevant in polaron physics, conductivity vanishes proportionally to $n \rightarrow 0$, while mobility remains a well-defined intrinsic transport coefficient.

An alternative representation of the transport coefficient can be obtained by invoking the fluctuation-dissipation theorem, which relates the spectral representation above to equilibrium time-correlation functions. Using the symmetry properties of equilibrium correlation functions, the dc conductivity can be expressed as a time integral of the current-current correlation function

$$\sigma_{ik} = \frac{\beta}{V} \int_0^\infty dt \langle j_i(t) j_k(0) \rangle , \quad (2.29)$$

where $j_i(t) \equiv j_i(\mathbf{q} = 0, t)$. Dividing this expression by the carrier density yields the Green-Kubo relation for mobility [80, 81]

$$\mu_{ik} = \frac{\beta}{neV} \int_0^\infty dt \langle j_i(t) j_k(0) \rangle . \quad (2.30)$$

Thus, mobility is determined by the time integral of the equilibrium current-current correlation function.

The equivalence of this form with the previously obtained Kubo expression Eq.(2.28) can be demonstrated by explicitly evaluating the correlation function in the eigenbasis of the Hamiltonian. In general, the conductivity is a tensor quantity, as indicated in Eq. (2.28), reflecting the possibility of anisotropic transport in different spatial directions. However, for the one-dimensional systems considered in this work, charge transport is confined to a single spatial direction. In this case, it

is sufficient to consider the longitudinal response, corresponding to the diagonal components of the conductivity tensor. Accordingly, in the following, the analysis is restricted to a single transport direction, with $i = k$ implicitly assumed, and explicit spatial indices omitted for notational simplicity.

Consider the current-current correlation function $C(t) = \langle j(t)j(0) \rangle$. Using the Heisenberg representation for time operators and inserting a complete set of Hamiltonian eigenstates, the correlation function can be written in the spectral form as

$$C(t) = Z^{-1} \sum_{n,m} e^{-\beta E_n} e^{\frac{i}{\hbar}(E_n - E_m)t} |\langle n|j|m \rangle|^2, \quad (2.31)$$

where $Z = \sum_n e^{-\beta E_n}$ is the partition function and E_n are the eigenvalues of the Hamiltonian. Integrating this expression over time yields

$$\int_{-\infty}^{\infty} dt C(t) = 2\pi\hbar Z^{-1} \sum_{n,m} e^{-\beta E_n} |\langle n|j|m \rangle|^2 \delta(E_n - E_m). \quad (2.32)$$

This result closely resembles the Kubo expression for dc conductivity Eq.(2.28), but to retrieve that exact expression one should consider the symmetry properties of correlation functions. For Hermitian operators such as the current operator,

$$C(-t) = C(t)^*. \quad (2.33)$$

Since the dc transport coefficient depends only on the real part of the correlation function, one effectively has $C(-t) = C(t)$. Consequently, the time integral over positive times can be written symmetrically as

$$\int_0^{\infty} dt C(t) = \frac{1}{2} \int_{-\infty}^{\infty} dt C(t). \quad (2.34)$$

Substituting this into the Green-Kubo formula gives

$$\mu_{\text{dc}} = \frac{\beta}{2neV} \int_{-\infty}^{\infty} dt \langle j(t)j(0) \rangle = \frac{\hbar\beta\pi}{neV} Z^{-1} \sum_{n,m} e^{-\beta E_n} |\langle n|j|m \rangle|^2 \delta(E_n - E_m), \quad (2.35)$$

which is equivalent to the Kubo expression in Eq.(2.28), up to the factor ne , with the understanding that only diagonal (longitudinal) components of the current operator are considered.

The Kubo formalism thus establishes a rigorous connection between equilibrium quantum fluctuations at the microscopic level and experimentally measurable transport coefficients. The mobility can be determined entirely from equilibrium current-current correlation functions, without requiring explicit knowledge of the system's eigenstates.

The Green-Kubo relation demonstrates that electrical transport is fundamentally governed by the temporal correlations of microscopic currents in thermal equilibrium. In practice, the evaluation of the current-current correlation function depends on the microscopic model describing the charge carriers and their interaction with the lattice. In systems with significant electron-phonon interaction, the appropriate quasiparticle description is that of a polaron. The dynamical properties of this quasiparticle determine the time evolution of the current operator and therefore the resulting transport coefficients.

The microscopic transport properties of a system are encoded in the time dependence of the current-current correlation function appearing in the Kubo formula. Different physical mechanisms of carrier motion produce distinct temporal behaviors of this correlation function and consequently lead to different transport regimes. In the following sections, the principal theoretical descriptions of polaron transport are introduced. Although the underlying microscopic description is provided

by the Holstein model introduced earlier, the resulting transport behavior depends sensitively on the electron-phonon coupling strength and the adiabaticity ratio. These parameters determine whether charge transport occurs predominantly through band motion, thermally activated hopping, or within a regime characterized by a renormalized polaron band. Understanding the conditions under which each of these regimes emerges is central to the theoretical description of charge transport in electron-phonon coupled systems.

2.2.2 Current-current correlation function

Since this study is based on the Holstein Hamiltonian presented in the preceding section, the explicit form of the current operator within this model should be defined.

For a tight-binding system, the current operator can be derived directly from the Heisenberg equation of motion applied to the polarization operator [78]

$$P = e \sum_n (an) c_n^\dagger c_n , \quad (2.36)$$

where an denotes the lattice site position. The current operator is defined as the time derivative of polarization,

$$j = \frac{\partial P}{\partial t} = \frac{i}{\hbar} [H, P] , \quad (2.37)$$

where the commutator is evaluated using the full interacting Hamiltonian.

For the one-dimensional Holstein model introduced in the previous section, this procedure yields

$$j = iJ \frac{ea}{\hbar} \sum_n (c_{n+1}^\dagger c_n - c_n^\dagger c_{n+1}) . \quad (2.38)$$

Therefore, the current operator is a Hermitian operator. The electron-phonon interaction term does not contribute explicitly to the current operator, as it is local in space. However, it strongly affects the dynamics of $j(t)$ through the full interacting Hamiltonian.

The current-current correlation function is defined as the expectation value of the product of two current operators. It is a two-particle correlation function, since each current operator is itself composed of one creation operator and one annihilation operator. Thus, the current-current correlation function characterizes two correlated microscopic processes, each involving the annihilation of a particle in one state and its creation in another. Because the particle is the charge carrier, these microscopic processes together underlie the electrical conductivity.

There are multiple ways to define time-correlation functions. Among them, the retarded correlation function, which appears in the Kubo formula expression Eq.(2.21), is the most physically intuitive, as it explicitly reflects the causality of physical processes. For numerous analytical applications, it is also convenient to define the advanced correlation function,

$$C^A(t) = \frac{i}{\hbar} \theta(-t) \langle [j(t), j(0)] \rangle , \quad (2.39)$$

where the time argument and the imaginary unit appear with signs opposite to those in the retarded function. Another important formulation is the time-ordered correlation function appearing in the Green–Kubo relation for mobility, Eq.(2.30), given by $C(t) = \langle j(t)j(0) \rangle$, where $t \geq 0$. The standard definitions of correlation functions are related to each other through their spectral representations. These spectral representations also exhibit a number of useful analytic properties, which are discussed in detail in [79].

The central quantity examined in this thesis is the time-ordered current-current correlation function, defined as the thermal average

$$C(t) = \langle j(t)j(0) \rangle = Z^{-1} \text{Tr} \left[e^{-\beta H} e^{\frac{i}{\hbar} t H} j e^{-\frac{i}{\hbar} t H} j \right] , \quad (2.40)$$

where $Z = \text{Tr} [e^{-\beta H}]$ is the canonical partition function and the time dependence of the operators is given in the Heisenberg representation. This formulation is particularly well suited to path-integral and Monte Carlo methods [78, 79].

For numerical approaches based on imaginary-time path integrals, it is convenient to introduce the imaginary-time current–current correlation function obtained by substitution $t \rightarrow -i\tau$, where both t and τ are real. The imaginary time correlation function reads [79, 82]

$$C(\tau) = \langle j(\tau)j(0) \rangle, \quad 0 \leq \tau \leq \hbar\beta, \quad (2.41)$$

where τ takes values in the interval $[0, \hbar\beta]$ and the imaginary-time correlation function is periodic in imaginary time with period $\hbar\beta$. The τ -dependence is defined through the Heisenberg relations

$$j(\tau) = \exp\left(-\frac{\tau}{\hbar}H\right) j \exp\left(\frac{\tau}{\hbar}H\right). \quad (2.42)$$

The quantity $C_{jj}(\tau)$ can typically be determined straightforwardly in path-integral quantum Monte Carlo simulations. The dc mobility is obtained from a zero-frequency limit of the real-frequency mobility, which requires analytic continuation of $C(\tau)$ from imaginary time to real frequencies [75]. The ill-posed nature of this inversion procedure constitutes a central numerical challenge in studying quantum system dynamics.

2.3 Transport theories for polarons

The electron-phonon (e-ph) interaction constitutes one of the fundamental interactions in condensed matter physics. The coupling between the charge carriers and lattice vibrations plays a decisive role in determining the dynamical and transport properties of solids and strongly influences their electrical, thermal, and optical response. When this interaction becomes significant, the motion of a carrier can no longer be described independently of the lattice degrees of freedom. Instead, the appropriate quasiparticle description is that of a polaron rather than a bare carrier [24, 78].

The term polaron was introduced by Pekar in the 1940s [16], although the underlying idea of a charge carrier interacting with a polarizable medium had already been formulated earlier by Landau [15]. Subsequent microscopic theories were developed by Fröhlich for large (continuum) polarons [17] and by Holstein for small (lattice) polarons [18, 19] in the 1950s. These pioneering works established the theoretical framework within which electron-phonon coupled systems are understood today [24].

A polaron represents a composite quasiparticle consisting of a charge carrier together with the lattice deformation it induces through the e-ph interaction. The presence of the carrier locally polarizes the surrounding medium, modifying the equilibrium positions of the ions. Rather than treating the carrier as moving through a dynamically fluctuating lattice, it is therefore more appropriate to regard the carrier and its accompanying lattice distortion as a single entity. The carrier thus propagates together with a phonon cloud, whose spatial extent and dynamical properties determine the nature of the polaron [24, 31, 83].

The primary distinction between different types of polarons is based on the spatial extent of the lattice deformation associated with the charge carrier. In the case of a large polaron, the deformation extends over many lattice sites and the carrier remains relatively delocalized. Such behavior typically arises in the regime of weak e-ph coupling ($\lambda < 1$) or when the interaction is long-ranged. By contrast, a small polaron is characterized by a highly localized lattice distortion confined to one or a few lattice sites. In this case, strong e-ph coupling ($\lambda \gtrsim 1$) leads to partial or complete self-trapping of the carrier. The resulting spatial confinement substantially increases the effective mass of the polaron quasiparticle and strongly modifies its transport properties [24, 31].

The transport properties in these two limits differ qualitatively. Large polarons generally move coherently through the crystal in a band-like manner. Their motion can be described in terms of

delocalized Bloch states, while the mobility is primarily limited by scattering processes involving phonons or other sources of disorder. As a consequence, the mobility of large polarons typically decreases with increasing temperature due to enhanced phonon scattering. In contrast, small polarons propagate predominantly through thermally assisted hopping between localized states [18, 19]. In this regime, the carrier motion is largely incoherent, and the corresponding mobility often exhibits activated behavior of Arrhenius type. The temperature dependence of the mobility therefore provides an important indicator of the dominant transport mechanism [24, 83].

It is important to emphasize, however, that the nature of charge transport is not determined solely by the spatial extent of the polaron. While large polarons are often associated with coherent band-like motion and small polarons with incoherent hopping, this correspondence is not universal. Strong scattering by lattice vibrations or disorder may significantly reduce the carrier mean free path, leading to incoherent transport even when the electronic states remain relatively delocalized. Conversely, localized states may still support coherent motion under suitable conditions. As a result, many realistic materials exhibit transport behavior that lies between the two limiting pictures of band conduction and thermally activated hopping, reflecting the complex interplay between e-ph coupling, lattice dynamics, and thermal fluctuations [24, 31].

From a microscopic standpoint, the character of polaron motion is governed by the competition between the electronic transfer integral J and the phonon energy scale $\hbar\omega_0$, commonly expressed through the adiabaticity ratio $J/(\hbar\omega_0)$. In the adiabatic regime, $J \gg \hbar\omega_0$, the carrier can continuously adjust to the instantaneous lattice configuration, which favors coherent motion. In the non-adiabatic regime, $J \ll \hbar\omega_0$, the carrier cannot follow rapid lattice fluctuations and transport becomes increasingly incoherent. Together with the e-ph coupling strength λ , these parameters determine whether the system exhibits band transport, hopping transport, or an intermediate regime characterized by a narrow polaronic band [24].

In the following subsections, the principal theoretical descriptions of polaron transport are reviewed. Starting with the hopping transport mechanism characteristic of strongly localized small polarons, followed by band transport in the weak-coupling regime and finally polaron band transport, which describes coherent motion of small polarons at sufficiently low temperatures.

2.3.1 Hopping transport

In the strong-coupling limit of the short-range e-ph interaction, a charge carrier tends to become self-trapped by the local lattice distortion it induces. The resulting quasiparticle, known as a small polaron, is spatially localized around a lattice site with a characteristic extent of the order of the lattice constant. In this regime, the electronic wavefunction is strongly coupled to the lattice degrees of freedom, and coherent propagation through the crystal lattice is strongly suppressed. Instead, charge transport occurs through occasional transitions between localized states centered on neighboring lattice sites. Because each transition requires a rearrangement of the surrounding lattice distortion, the elementary transport process is intrinsically coupled to phonon dynamics and the resulting motion is largely incoherent. In the simplest approximation, this dynamics may be described as a Markovian random walk of independent hopping events [18, 24, 83].

A key physical aspect of small-polaron hopping is that the lattice deformation associated with the carrier must be transferred from one site to another during a hop. In general, the equilibrium lattice configurations corresponding to a carrier localized on neighboring sites differ from one another, and direct tunneling between them would violate energy conservation. Hopping therefore becomes possible only during rare lattice fluctuations that temporarily bring the energies of the two configurations into resonance. These so-called coincidence configurations play a central role in small-polaron transport. Once such a configuration is reached, the carrier may tunnel between the two sites with an amplitude determined by the electronic transfer integral. After the transition, the lattice relaxes toward the new equilibrium configuration around the final state. Because the formation of coincidence configurations

requires thermal lattice fluctuations, the hopping rate typically exhibits thermally activated behavior [19, 24, 31, 83].

An important consequence of the Green-Kubo relation is that microscopic transport processes enter the conductivity through the time dependence of the current-current correlation function [78]. In systems where transport proceeds via localized charge carriers, the decay of correlation function is governed by the stochastic hopping events between neighboring sites. In this situation the current operator changes only when a carrier performs a hop, and the temporal decay of the current-current correlation function is directly related to the hopping transition rate.

Within this framework, the carrier mobility can be related to the characteristic hopping rate that governs the diffusion of carriers through the lattice. The derivation presented below for a two-site system provides a simple microscopic illustration of this connection [19, 83, 84]. In this approach, the hopping rate obtained from Fermi's golden rule is expressed as a time integral of a correlation function of the perturbation operator. This correlation function can be directly related to the current-current correlation function appearing in the Kubo formalism. This derivation therefore demonstrates how the microscopic dynamics of phonon-assisted hopping processes determine the macroscopic transport coefficients. The following derivation of the hopping rate for a two-site system closely follows the treatment presented in Ref.[84], adapted here to the notation used in the present work.

The essential physics of small-polaron hopping can be illustrated by the minimal model of a carrier transferring between two identical sites [19, 84]. In this picture, the carrier is strongly localized and a transition between sites becomes possible only when lattice fluctuations allow for a phonon-assisted process that conserves the total energy of the system. From a quantum-mechanical perspective, the electronic transfer integral J is assumed to be small compared to the other energy scales of the problem, allowing the hopping term of the tight-binding Hamiltonian to be treated as a perturbation. For a two-site system ($n = 2$), the Holstein Hamiltonian can therefore be written in the form

$$H = H_1 + H_2 + V = H_0 + V , \quad (2.43)$$

where H_0 represents the unperturbed Hamiltonian and V denotes the hopping perturbation. The two contributions read

$$H_n = \hbar\omega_0 b_n^\dagger b_n + G c_n^\dagger c_n (b_n^\dagger + b_n), \quad n = 1, 2 , \quad (2.44)$$

$$V = -J(c_1^\dagger c_2 + c_2^\dagger c_1) , \quad (2.45)$$

where c_n are electron operators, b_n are phonon operators, G is the e-ph coupling constant, and ω_0 is the phonon frequency.

The hopping rate between two sites n and m is obtained from Fermi's golden rule [19, 84],

$$w = \frac{2\pi}{\hbar} \sum_n p_n \sum_m |V_{nm}|^2 \delta(E_n - E_m), \quad (2.46)$$

where p_n is the probability of occupying the initial state n , and E_n and E_m are the eigenenergies of the unperturbed Hamiltonian $H_0 = H_1 + H_2$. The central task is therefore the evaluation of matrix elements of the perturbation operator V .

Using the integral representation of the delta function,

$$\delta(E_n - E_m) = \frac{1}{2\pi\hbar} \int_{-\infty}^{\infty} dt e^{\frac{i}{\hbar}(E_n - E_m)t} , \quad (2.47)$$

the hopping rate can be rewritten as

$$w = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \sum_n p_n \sum_m e^{\frac{i}{\hbar}(E_n - E_m)t} \langle n|V|m\rangle \langle m|V|n\rangle. \quad (2.48)$$

Equivalently, introducing the time-dependent perturbation operator $V(t)$, the hopping rate may be written in the form

$$w = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \sum_n p_n \sum_m \langle n | e^{\frac{i}{\hbar} H_0 t} V e^{-\frac{i}{\hbar} H_0 t} | m \rangle \langle m | V | n \rangle = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \sum_n p_n \sum_m \langle n | V(t) | m \rangle \langle m | V | n \rangle, \quad (2.49)$$

where $|n\rangle$ denotes the full direct-product state of the electronic and phonon degrees of freedom, $|n\rangle = |\text{electron}\rangle |\text{phonon}\rangle$. This representation expresses the hopping rate as the time integral of a correlation function of the perturbation operator [19, 84].

To evaluate the transition rate, it is convenient to diagonalize the unperturbed Hamiltonian H_0 so that the electronic and phononic degrees of freedom become separated. This can be achieved by performing the unitary Lang-Firsov transformation [85], defined by

$$U = \exp \left(\frac{G}{\hbar\omega_0} \sum_n c_n^\dagger c_n (b_n^\dagger - b_n) \right). \quad (2.50)$$

Using the Baker-Campbell-Hausdorff formula, the transformed operators and the corresponding transformed Hamiltonian can be obtained. In the transformed representation, the unperturbed Hamiltonian becomes

$$\tilde{H}_0 = -\frac{G^2}{\hbar\omega_0} \sum_n c_n^\dagger c_n + \hbar\omega_0 \sum_n b_n^\dagger b_n = \tilde{H}_e + \tilde{H}_{ph}, \quad (2.51)$$

which explicitly separates the electronic and phononic contributions. The e-ph interaction is thus removed from the unperturbed part of the Hamiltonian and reappears as phonon-dependent dressing factors in the hopping perturbation [19, 85].

The transformed hopping operator becomes

$$\tilde{V} = -J \left[c_1^\dagger c_2 e^{\frac{G}{\hbar\omega_0}(b_1^\dagger - b_1)} e^{-\frac{G}{\hbar\omega_0}(b_2^\dagger - b_2)} + c_2^\dagger c_1 e^{-\frac{G}{\hbar\omega_0}(b_1^\dagger - b_1)} e^{\frac{G}{\hbar\omega_0}(b_2^\dagger - b_2)} \right]. \quad (2.52)$$

The corresponding time-dependent perturbation operator is

$$\tilde{V}(t) = e^{\frac{i}{\hbar} \tilde{H}_0 t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_0 t} = e^{\frac{i}{\hbar} \tilde{H}_e t} e^{\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_e t} e^{-\frac{i}{\hbar} \tilde{H}_{ph} t}. \quad (2.53)$$

Since the eigenstates of the unperturbed Hamiltonian factorize into electronic and phononic parts, $|n\rangle = |n\rangle_e |n\rangle_{ph}$, and the electronic Hamiltonian satisfies $H_e |n\rangle_e = \varepsilon_n |n\rangle_e$, the corresponding matrix element becomes

$$\langle n | \tilde{V}(t) | m \rangle = e^{\frac{i}{\hbar} (\varepsilon_n - \varepsilon_m) t} \langle n | e^{\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_{ph} t} | m \rangle. \quad (2.54)$$

For two identical lattice sites, the unperturbed electronic states are degenerate, so that $\varepsilon_n = \varepsilon_m$ and the electronic phase factor reduces to unity. The hopping rate is therefore determined entirely by the phonon contribution. Introducing the phonon statistical weights p_n^{ph} , the transition rate can be written as

$$w = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \sum_n p_n^{ph} \sum_m \langle n | e^{\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_{ph} t} | m \rangle \langle m | \tilde{V} | n \rangle, \quad (2.55)$$

which can be rewritten as

$$w = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \sum_n p_n^{ph} \langle n | e^{\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} | n \rangle. \quad (2.56)$$

In compact form, the hopping rate becomes

$$w = \frac{1}{\hbar^2} \int_{-\infty}^{\infty} dt \langle e^{\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} e^{-\frac{i}{\hbar} \tilde{H}_{ph} t} \tilde{V} \rangle, \quad (2.57)$$

where

$$\tilde{V}' = -J \left[\exp \left(\frac{G}{\hbar\omega_0} (b_1^\dagger - b_1 - b_2^\dagger + b_2) \right) + \exp \left(-\frac{G}{\hbar\omega_0} (b_1^\dagger - b_1 - b_2^\dagger + b_2) \right) \right] \quad (2.58)$$

represents the phonon-dependent part of the perturbation.

The required thermodynamic averages are evaluated using standard bosonic occupation numbers,

$$\langle b_n \rangle = \langle b_n^\dagger \rangle = 0, \quad (2.59)$$

$$\langle b_n^\dagger b_n \rangle = n_{ph} = (e^{\beta\hbar\omega_0} - 1)^{-1}, \quad (2.60)$$

$$\langle b_n b_n^\dagger \rangle = n_{ph} + 1. \quad (2.61)$$

This yields the hopping rate in the form

$$w = \frac{J^2}{\hbar^2} \int_{-\infty}^{\infty} dt \exp \left[-2 \frac{G^2}{\hbar\omega_0} (2n_{ph} + 1 - (n_{ph} + 1)e^{-i\omega_0 t} - n_{ph}e^{i\omega_0 t}) \right]. \quad (2.62)$$

The transition rate is therefore expressed as a time integral of a correlation function of the perturbation operator. In this representation the hopping rate can be directly related to the current-current correlation function C_{jj} , so that formally

$$w = \frac{1}{2} \int_{-\infty}^{\infty} dt C_{jj}(t). \quad (2.63)$$

For the isolated two-site system considered here, however, the correlation function is periodic in time and the dc limit of the Kubo formula is not well defined. A meaningful transport coefficient emerges only in the thermodynamic limit or when dissipative processes are included [20, 30, 78].

Despite this limitation, the two-site model remains useful because it yields a transparent limiting expression under well-controlled approximations. In the high-temperature limit $\beta\hbar\omega_0 \ll 1$, the phonon occupation number reduces to

$$n_{ph} \simeq 1/(\beta\hbar\omega_0). \quad (2.64)$$

Moreover, in the strong-coupling, high-temperature regime, the dominant contributions arise from short real times, allowing the expansion $\exp(i\omega_0 t) \simeq 1 + i\omega_0 t - \frac{1}{2}\omega_0^2 t^2$. Under these approximations the current-current correlation function decays sufficiently rapidly for the integral to converge, and the hopping rate reduces to the well-known Marcus formula,

$$w = \frac{J^2}{\hbar} \sqrt{\frac{\beta\pi}{\Lambda}} \exp \left(-\frac{\beta\Lambda}{4} \right) \quad (2.65)$$

where $\Lambda = \frac{2G^2}{\hbar\omega_0}$ is the lattice reorganization energy.

The Marcus formula shows that small-polaron hopping is governed by the interplay between the electronic transfer integral J and the lattice reorganization energy Λ , which represents the energy required to transfer the accompanying lattice distortion from the initial site to the final one [19, 31, 83, 84].

The corresponding current-current correlation function takes the form

$$C_{jj}(t) = 2J^2 \exp \left(-\frac{1}{\hbar^2} \sigma_0^2 t^2 \right) \exp \left(-\frac{i}{\hbar} \beta \sigma_0^2 t \right), \quad (2.66)$$

where

$$\sigma_0^2 = \frac{2G^2}{\beta\hbar\omega_0} = \Lambda/\beta. \quad (2.67)$$

The Gaussian factor describes the decay of the current-current correlation function caused by thermal lattice fluctuations, whereas the oscillatory phase reflects the energy shift associated with lattice reorganization during the hopping process.

Within the random-walk picture, charge transport proceeds through a sequence of statistically independent hopping events between neighboring lattice sites. In this limit, the carrier motion can be described as a diffusion process characterized by the diffusion coefficient

$$D = a^2 w, \quad (2.68)$$

where a denotes the hopping distance and w the transition rate between adjacent sites. Using the Einstein diffusion relation for mobility $\mu = e\beta D = ea^2\beta w$ [30, 78], the mobility can therefore be expressed as

$$\mu = \frac{ea^2\beta J^2}{\hbar} \sqrt{\frac{\beta\pi}{\Lambda}} \exp\left(-\frac{\beta\Lambda}{4}\right). \quad (2.69)$$

Although this result is derived from a minimal toy model, it captures the central feature of small-polaron transport, namely its thermally activated character. The exponential factor in Eq.(2.69) implies an Arrhenius-type temperature dependence with activation energy $\Lambda/4$.

The quantity Λ represents the lattice reorganization energy associated with transferring the local lattice distortion from one site to another. Within the Holstein model, this energy is directly related to the polaron binding energy, $\Lambda = 2E_p$, and reflects the lattice deformation that must be created at the target site before the carrier can successfully complete the hop. The activation barrier therefore arises from the energetic cost of rearranging the surrounding lattice configuration during the hopping process [19, 83].

An additional complication arises from the fact that individual hopping events do not necessarily contribute equally to long-range transport. In a realistic lattice environment, a carrier may repeatedly hop back and forth between two neighboring sites before eventually escaping to a different site. Such correlated hopping processes increase the number of microscopic transitions without producing a proportional increase in the net diffusion of the carrier. Consequently, the diffusion constant and the resulting mobility depend not only on the local hopping rate but also on the probability that a hop leads to escape from the local potential environment. This effect becomes particularly important at elevated temperatures, where lattice fluctuations increase the hopping frequency but also enhance the probability of rapid back-and-forth transitions [83].

While the two-site derivation and its high-temperature Marcus limit provide a physically transparent description of activated hopping, they rely on several simplifying assumptions, including strong e-ph coupling, classical phonon statistics, and a short-time decay of the current-current correlation function. Outside this regime, the transport cannot, in general, be reduced to a simple Arrhenius law.

At intermediate temperatures and for more general phonon spectra, the temporal evolution of lattice fluctuations entering the current-current correlation function becomes nontrivial. These fluctuations determine the probability that the lattice reaches coincidence configurations and may substantially modify the activation behavior.

A more general description of charge transport can be formulated within the framework of linear-response theory, where transport coefficients are obtained from the current-current correlation function through the Kubo formula [78, 80]. Within this approach, the correlation function can be expressed in terms of electronic Green's functions. Different approximation schemes correspond to different diagrammatic truncations of the resulting expressions. The simplest treatment corresponds to the so-called bubble approximation, which retains only single-particle Green's functions, while more refined descriptions include vertex corrections arising from correlated scattering processes. This formalism provides a systematic framework for describing transport beyond the simple activated hopping limit and allows one to interpolate between incoherent hopping and more coherent transport regimes[24, 78].

2.3.2 Band transport

In the weak e-ph coupling regime, the lattice distortion induced by a charge carrier extends over many lattice sites and does not lead to self-trapping. The carrier therefore remains delocalized and its motion can be described in terms of extended Bloch states. In crystalline materials, the overlap of electronic orbitals on neighboring sites leads to the formation of energy bands, within which the electronic states are coherent superpositions of localized atomic or molecular orbitals. As a result, the carrier propagates through the lattice as a quasiparticle characterized by a well-defined momentum and an increased effective mass [20, 78]. In this regime the lattice deformation associated with the carrier acts primarily as a weak perturbation that scatters the otherwise delocalized electronic states, rather than localizing the carrier into a small polaron [31].

In realistic crystalline structures, the motion of the carrier is interrupted by occasional scattering processes that change its momentum. The dominant scattering mechanisms include interactions with phonons, structural disorders and impurities in the lattice. Consequently, the carrier propagates coherently only over a finite time between successive scattering events. This situation is commonly described within the semiclassical Boltzmann transport framework, where the carrier dynamics are characterized by an average scattering time between collisions [30, 78].

Under the assumption of weak electric field, as considered in linear response theory, the distribution function of carriers with momentum k acquires a small deviation from equilibrium. The nonequilibrium distribution can therefore be written as

$$f_k = f_k^0 + \delta f_k, \quad (2.70)$$

where f_k^0 is the equilibrium distribution and δf_k represents the small correction induced by the electric field. In thermal equilibrium, the occupation of Bloch states is given by the Fermi-Dirac distribution

$$f_k^0 = \left(e^{\beta(\varepsilon_k - \mu)} + 1 \right)^{-1}, \quad (2.71)$$

where ε_k is the band dispersion and μ is the chemical potential.

Within the relaxation-time approximation, the stationary Boltzmann equation in one dimension takes the form [30, 78]

$$f_k = f_k^0 - \frac{1}{\hbar} e \tau_k E \frac{\partial}{\partial k} f_k^0 = f_k^0 - e v_k \tau_k E \frac{\partial f_k^0}{\partial \varepsilon_k}, \quad (2.72)$$

where

$$v_k = \frac{1}{\hbar} \frac{\partial \varepsilon_k}{\partial k} \quad (2.73)$$

is the band velocity and τ_k is the transport relaxation time.

The electric current density is proportional to the average velocity of the carriers. In thermal equilibrium, where no external electric field is present, the distribution function is symmetric in momentum, and the net current therefore vanishes. Consequently, only the nonequilibrium correction δf_k contributes to the electric current. The electric current density is then given by

$$J = \frac{e^2}{V} \sum_k \tau_k v_k^2 \left(-\frac{\partial f_k^0}{\partial \varepsilon_k} \right) E. \quad (2.74)$$

The conductivity is defined as the proportionality factor between the current density and the applied electric field, which yields

$$\sigma = \frac{e^2}{V} \sum_k \tau_k v_k^2 \left(-\frac{\partial f_k^0}{\partial \varepsilon_k} \right). \quad (2.75)$$

Finally, using the relation $\sigma = ne\mu$, the carrier mobility can be written as

$$\mu = \frac{e}{nV} \sum_k \tau_k v_k^2 \left(-\frac{\partial f_k^0}{\partial \varepsilon_k} \right), \quad (2.76)$$

where n is the carrier density.

In the low carrier concentration limit relevant for polaron transport, the chemical potential lies well below the band edge, $\mu_{\text{chem}} \rightarrow -\infty$, and the Fermi-Dirac distribution reduces to the Maxwell-Boltzmann form

$$f_k^0 \simeq e^{-\beta(\varepsilon_k - \mu_{\text{chem}})} . \quad (2.77)$$

The derivative of the distribution function with respect to energy then becomes

$$-\frac{\partial f_k^0}{\partial \varepsilon_k} = \beta f_k^0 = \beta e^{-\beta \varepsilon_k} e^{\beta \mu_{\text{chem}}} . \quad (2.78)$$

The carrier density can be written explicitly as

$$n = \frac{1}{V} \sum_k f_k^0 = \frac{1}{V} \sum_k e^{-\beta \varepsilon_k} e^{\beta \mu_{\text{chem}}} . \quad (2.79)$$

Substituting these expressions into the mobility formula shows that the factors containing the chemical potential cancel between the numerator and denominator. As a result, the mobility becomes independent of the chemical potential and depends only on the Boltzmann weights of the band states.

The standard band-transport mobility formula in low carrier density limit therefore takes the form [30, 78]

$$\mu = e\beta \frac{\sum_k n_k \tau_k v_k^2}{\sum_k n_k} , \quad (2.80)$$

where $n_k = \exp(-\beta \varepsilon_k)$ is the Boltzmann factor. For a one-dimensional tight-binding system with dispersion $\varepsilon_k = -2J \cos(ka)$, the corresponding band velocity is $v_k = 2Ja \sin(ka)/\hbar$.

The same expression for the mobility as in Eq. (2.80) can also be obtained from the Kubo formula Eq. (2.30) by evaluating the current-current correlation function within a single-particle framework [78], as will be described in the following text.

In momentum representation, the current operator can be written as [20, 78]

$$j = e \sum_k v_k a_k^\dagger a_k , \quad (2.81)$$

where $a_k^\dagger$ and a_k are creation and annihilation operators of an electron with momentum k , and v_k denotes the band velocity. Substituting this operator into the current-current correlation function leads to a four-operator average

$$C(t) = \langle j(t)j(0) \rangle = e^2 \sum_{k,q} v_k v_q \langle a_k^\dagger(t) a_k(t) a_q^\dagger(0) a_q(0) \rangle . \quad (2.82)$$

This correlation function describes the correlated propagation of two fermionic lines and therefore contains, in general, all many-body scattering processes induced by the e-ph interaction. In diagrammatic approach, its exact evaluation involves an infinite series of diagrams in which the two current vertices are connected by dressed single-particle propagators. In addition, vertex corrections appear that account for correlated multi-phonon scattering processes [78].

In the weak-coupling regime, where the carrier remains a quasiparticle with well-defined momentum and scattering events are relatively rare, the dominant contribution arises from diagrams that neglect vertex corrections and retain only the product of two single-particle propagators. This approximation is known as the bubble approximation, since its diagrammatic representation consists of two propagator lines connecting the two current vertices and forming a closed loop [31, 78].

Within this approximation, the four-operator average factorizes into a product of two-operator averages corresponding to single-particle Green's functions,

$$\langle a_k^\dagger(t) a_k(t) a_q^\dagger(0) a_q(0) \rangle \approx \delta_{k,q} \langle a_k^\dagger(t) a_k(0) \rangle \langle a_k(t) a_k^\dagger(0) \rangle , \quad (2.83)$$

and the current-current correlation function reduces to

$$C(t) \simeq e^2 \sum_k v_k^2 \langle a_k^\dagger(t) a_k(0) \rangle \langle a_k(t) a_k^\dagger(0) \rangle . \quad (2.84)$$

Physically, this approximation assumes that the current response is governed by the independent propagation of quasiparticles dressed by phonons, while correlated processes that modify the coupling between the external and the quasiparticles are neglected. The effects of electron-phonon scattering are incorporated through the self-energy entering the single-particle Green's function [78].

The two-point correlation functions appearing in the current-current correlator can be expressed in terms of the spectral function $A_k(\omega)$. Using the spectral representation of the single-particle Green's functions, one obtains [78]

$$\langle a_k^\dagger(t) a_k(0) \rangle = \frac{1}{2\pi} \int_{-\infty}^{\infty} d\omega e^{i\omega t} A_k(\omega) f(\hbar\omega) , \quad (2.85)$$

$$\langle a_k(t) a_k^\dagger(0) \rangle = \frac{1}{2\pi} \int_{-\infty}^{\infty} d\omega e^{-i\omega t} A_k(\omega) (1 - f(\hbar\omega)) , \quad (2.86)$$

where

$$f(E) = \left(e^{\beta(E - \mu_{\text{chem}})} + 1 \right)^{-1} \quad (2.87)$$

is the Fermi-Dirac distribution.

It is also convenient to express the particle number as $N = \sum_k \langle a_k^\dagger a_k \rangle$, with

$$\langle a_k^\dagger a_k \rangle = \frac{1}{2\pi} \int_{-\infty}^{\infty} d\omega A_k(\omega) f(\hbar\omega) . \quad (2.88)$$

Substituting these expressions into the current-current correlation function in the Green-Kubo relation for mobility, Eq. (2.30), and using the identity

$$\int_{-\infty}^{\infty} dt e^{i(\omega_1 - \omega_2)t} = 2\pi \delta(\omega_1 - \omega_2) , \quad (2.89)$$

one obtains the dc mobility in the form

$$\mu = \frac{\beta e}{2nV} \sum_k v_k^2 \int \frac{d\omega}{2\pi} A_k(\omega)^2 f(\hbar\omega) (1 - f(\hbar\omega)) . \quad (2.90)$$

Using the identity

$$f(E)(1 - f(E)) = -\frac{1}{\beta} \frac{\partial f(E)}{\partial E} , \quad (2.91)$$

this expression can be rewritten as

$$\mu = \frac{e}{nV} \sum_k v_k^2 \int \frac{d\omega}{2\pi} A_k(\omega)^2 \left(-\frac{1}{\beta} \frac{\partial f(E)}{\partial E} \Big|_{E=\hbar\omega} \right) . \quad (2.92)$$

The spectral function is related to the retarded Green's function by [78]

$$A_k(\omega) = -2\text{Im} G_k^R(\omega) . \quad (2.93)$$

The retarded Green's function itself is determined by the Dyson equation [78]

$$G_k^R(\omega) = [\hbar\omega - (\varepsilon_k - \mu_{\text{chem}}) - \Sigma_k^R(\omega)]^{-1} , \quad (2.94)$$

where $\Sigma_k^R(\omega)$ is the retarded self-energy.

In the weak e-ph interaction limit, scattering processes are relatively rare and the spectral function is narrow and sharply peaked around the quasiparticle energy [31, 78]. In this case it can be approximated by delta function,

$$A_k(\omega) \simeq 2\pi\delta(\hbar\omega - \varepsilon_k) . \quad (2.95)$$

and the square of spectral function in this limit behaves as

$$A_k(\omega)^2 = \frac{\pi}{-\text{Im} \Sigma_k^R(\omega)} \delta(\hbar\omega - \varepsilon_k) , \quad (2.96)$$

where ε_k denotes the renormalized quasiparticle excitation energy.

The dc mobility then takes the form

$$\mu = \frac{e}{nV} \sum_k v_k^2 \tau_k \left(-\frac{\partial f(\varepsilon_k)}{\partial \varepsilon_k} \right) , \quad (2.97)$$

where the scattering relaxation time is identified with the imaginary part of the retarded self-energy,

$$\tau_k^{-1} = -\frac{2}{\hbar} \text{Im} \Sigma_k^R(\omega) \Big|_{\hbar\omega = \varepsilon_k - \mu_{\text{chem}}} . \quad (2.98)$$

The imaginary part of the self-energy determines the linewidth of the spectral peak and therefore the inverse lifetime of the quasiparticle excitation, while the real part of the self-energy represents the renormalization shift of quasiparticle energy caused by interactions [78]. In this way the microscopic scattering processes induced by the e-ph interaction enter the transport coefficients through the self-energy of the single-particle Green's function [31, 78].

In the low carrier concentration limit relevant for polaron transport, the Fermi-Dirac distribution reduces to the Maxwell-Boltzmann form [30, 78]

$$f(\varepsilon_k - \mu_{\text{chem}}) \approx \exp(-\beta(\varepsilon_k - \mu_{\text{chem}})) . \quad (2.99)$$

The particle number entering the mobility equation becomes

$$nV \equiv N \simeq \sum_k \exp(-\beta(\varepsilon_k - \mu_{\text{chem}})) . \quad (2.100)$$

Because the chemical potential appears in both the numerator and denominator, the corresponding factors cancel. As a result, the mobility obtained from the Kubo formalism reduces to the same expression as derived previously within the semiclassical Boltzmann approach,

$$\mu = e\beta \frac{\sum_k n_k v_k^2 \tau_k}{\sum_k n_k} , \quad (2.101)$$

where $n_k = \exp(-\beta\varepsilon_k)$ is the Boltzmann factor.

Within the band-transport picture, the charge carrier propagates through the lattice as a delocalized quasiparticle whose motion is periodically interrupted by scattering on thermally excited phonons. As the temperature increases, the phonon population grows and scattering processes become more frequent, leading to a gradual reduction of the carrier mobility. This temperature dependence is a characteristic feature of band transport and is commonly observed in systems where electron-phonon interaction is relatively weak and the electronic bandwidth remains large compared to the characteristic phonon energy [30, 78].

When the e-ph interaction becomes stronger, however, the lattice distortion accompanying the carrier can no longer be treated as a small perturbation. The carrier then becomes strongly dressed by phonons and forms a polaronic quasiparticle. At sufficiently low temperatures such quasiparticles may still propagate coherently through the lattice, but with a substantially renormalized bandwidth [24, 31]. This intermediate regime, in which transport remains coherent but the electronic motion is strongly influenced by lattice dressing, is commonly referred to as polaron band transport and is discussed in the following subsection.

2.3.3 Polaron band transport

In the strong e-ph coupling limit, the lattice distortion accompanying the charge carrier becomes sufficiently large that the polaron binding energy $E_p = G^2/(\hbar\omega_0)$ exceeds half the bare electronic bandwidth. For the one-dimensional Holstein model, the electronic dispersion is $\varepsilon_k = -2J \cos(ka)$, corresponding to a bandwidth $W = 4J$, so the condition for strong coupling may be written as $E_p > W/2 = 2J$ [18, 24].

Under these conditions, the carrier forms a small polaron, in which the electronic state is strongly dressed by a local lattice deformation. Despite the strong coupling, coherent motion of the carrier may still occur at very low temperatures in a perfect crystal without impurities. In this regime, the carrier is not confined to a single lattice site but instead forms delocalized Bloch states associated with a narrow polaronic band. The resulting transport mechanism is commonly referred to as polaron band transport [18, 24, 83].

In contrast to the incoherent hopping mechanism discussed in the previous subsection, the motion of the carrier in this regime remains coherent and adiabatic. The lattice distortion accompanying the carrier moves together with the electron as it propagates through the lattice, forming a composite quasiparticle whose dynamics reflect the interplay between electronic motion and the accompanying lattice deformation [24, 31].

A convenient theoretical description of this regime is obtained by applying the canonical Lang-Firsov transformation applied to the Holstein Hamiltonian, defined by the unitary transformation [18, 24, 85]

$$\tilde{H} = e^S H e^{-S} . \quad (2.102)$$

The Hamiltonian is written as $H = H_e + H_{e-ph} + H_{ph}$, with H_e the tight-binding electronic term, H_{ph} describes the phonons, and H_{e-ph} represents the e-ph interaction. The transformation is generated by the operator

$$S = \frac{G}{\hbar\omega_0} \sum_n c_n^\dagger c_n (b_n^\dagger - b_n) . \quad (2.103)$$

This transformation shifts the equilibrium positions of the lattice oscillators and eliminates the explicit e-ph interaction from the unperturbed Hamiltonian. The transformed Hamiltonian can then be written as

$$\tilde{H} = \tilde{H}_0 + \tilde{V} . \quad (2.104)$$

The first term describes a localized polaron together with the phonon bath, while the second term represents the phonon-assisted hopping between neighboring lattice sites. The transformed terms are given as

$$\tilde{H}_0 = -E_p \sum_n c_n^\dagger c_n + \hbar\omega_0 \sum_n b_n^\dagger b_n , \quad (2.105)$$

$$\tilde{V} = -J \sum_n c_{n+1}^\dagger c_n X_{n+1}^\dagger X_n + \text{h.c.} , \quad (2.106)$$

where the polaron binding energy is

$$E_p = \frac{G^2}{\hbar\omega_0} , \quad (2.107)$$

and the phonon dressing operator is

$$X_n = \exp\left(-\frac{G}{\hbar\omega_0}(b_n^\dagger - b_n)\right) . \quad (2.108)$$

The operator X_n describes the phonon cloud accompanying the carrier and accounts for the overlap between lattice distortions associated with neighboring sites. In the transformed representation, the hopping term therefore acquires phonon-dependent dressing factors that renormalize the effective electronic transfer integral.

In the strong-coupling regime, the polaron binding energy E_p greatly exceeds the electronic transfer energy J . For the one-dimensional tight-binding band $\varepsilon_k = -2J \cos(ka)$ with bandwidth $W = 4J$, the dimensionless coupling parameter may be written as

$$\lambda = \frac{E_p}{W/2} . \quad (2.109)$$

Consequently, the ratio $J/E_p \sim 1/\lambda$ is small, allowing the hopping term $\tilde{V}$ to be treated perturbatively. This forms the basis of the $1/\lambda$ expansion commonly used in small-polaron theory [18, 24].

The unperturbed Hamiltonian $\tilde{H}_0$ describes a polaron localized on a lattice site with the associated lattice deformation. The corresponding ground state localized at the n -th site can be written as

$$|n\rangle = c_n^\dagger |0\rangle_e |0\rangle_{ph} , \quad (2.110)$$

where $|0\rangle_e$ and $|0\rangle_{ph}$ denote the electronic and phononic vacuum states, respectively. All states $|n\rangle$ are degenerate with energy $-E_p$. The perturbation $\tilde{V}$ lifts this degeneracy and produces a coherent polaron band.

To first order in perturbation theory, the effective hopping amplitude between neighboring localized polaron states is given by

$$\langle n+1 | \tilde{V} | n \rangle = -J \langle 0 | X_{n+1}^\dagger X_n | 0 \rangle . \quad (2.111)$$

At zero temperature the phonon vacuum expectation value evaluates to

$$\langle 0 | X_{n+1}^\dagger X_n | 0 \rangle = e^{-g^2} , \quad (2.112)$$

where $g = G/(\hbar\omega_0)$. The hopping integral is therefore renormalized to

$$\tilde{J} = J e^{-g^2} . \quad (2.113)$$

Using the relation $g^2 = E_p/(\hbar\omega_0)$, the renormalized hopping amplitude may also be written as

$$\tilde{J} = J \exp\left(-\frac{E_p}{\hbar\omega_0}\right) . \quad (2.114)$$

The coherent small-polaron band is then

$$\tilde{\varepsilon}_k = -2\tilde{J} \cos(ka) , \quad (2.115)$$

with corresponding bandwidth

$$\tilde{W} = W e^{-g^2} = W \exp\left(-\frac{E_p}{\hbar\omega_0}\right) . \quad (2.116)$$

This result shows that the reduction of the electronic bandwidth is controlled by the ratio of the polaron binding energy to the phonon energy scale. When the lattice deformation energy greatly exceeds the characteristic phonon energy $\hbar\omega_0$, the overlap between the neighboring phonon clouds becomes exponentially small, leading to a very narrow polaron band.

The exponential reduction of the hopping amplitude directly implies a strong renormalization of the quasiparticle dispersion and its effective mass. The effective mass of a quasiparticle is determined from the curvature of the dispersion relation at the band minimum,

$$\frac{1}{m^*} = \frac{1}{\hbar^2} \frac{\partial^2 \varepsilon_k}{\partial k^2} \bigg|_{k=0} . \quad (2.117)$$

For the bare tight-binding dispersion $\varepsilon_k = -2J \cos(ka)$, the electronic effective mass is

$$m^* = \frac{\hbar^2}{2Ja^2} . \quad (2.118)$$

Using the renormalized small-polaron dispersion $\tilde{\varepsilon}_k = -2\tilde{J} \cos(ka)$ gives

$$\tilde{m}^* = m^* e^{g^2} = m^* \exp\left(\frac{E_p}{\hbar\omega_0}\right) . \quad (2.119)$$

The effective mass of the small polaron therefore increases exponentially with the e-ph coupling strength. Compared with the bare band mass, relevant for conventional band transport, the small-polaron mass is exponentially larger, which strongly suppresses the mobility of coherent small polarons. In the limit of very strong e-ph coupling, the coherent polaron bandwidth collapses and the effective mass diverges, indicating that the carrier becomes effectively localized. Under such conditions coherent band motion is no longer possible, even at very low temperatures, and charge transport proceeds through incoherent hopping[24, 31].

In the coherent small-polaron regime, the lattice distortion surrounding the carrier moves together with the electron as it propagates through the crystal. Because the polaron motion is slow compared to the characteristic phonon dynamics, the phonon bath remains close to equilibrium. Under these conditions, the phonon operators in the transformed hopping term can be replaced by their thermal expectation value. Evaluating this average yields

$$\langle X_{n+1}^\dagger X_n \rangle = \exp\left(-g^2(2n_{ph} + 1)\right) , \quad (2.120)$$

where $n_{ph} = (e^{\beta\hbar\omega_0} - 1)^{-1}$ is the phonon occupation number [19, 24]. This approximation makes the effective hopping integral temperature dependent,

$$\tilde{J}(T) = J e^{-g^2(2n_{ph}+1)} . \quad (2.121)$$

The polaron dispersion therefore becomes

$$\tilde{\varepsilon}_k(T) = -2\tilde{J}(T) \cos(ka) = -2J \exp\left(-\frac{E_p}{\hbar\omega_0}(2n_{ph} + 1)\right) \cos(ka) , \quad (2.122)$$

with bandwidth

$$\tilde{W}(T) = 4\tilde{J}(T) = 4J \exp\left(-\frac{E_p}{\hbar\omega_0}(2n_{ph} + 1)\right) . \quad (2.123)$$

The polaron bandwidth therefore decreases exponentially with temperature, reflecting the increasing strength of thermal lattice fluctuations surrounding the carrier.

The temperature dependence of mobility in the polaron band regime therefore differs qualitatively from both conventional band transport and thermally assisted hopping. At very low temperatures, the polaron propagates coherently through the lattice with a strongly renormalized effective mass. As the temperature increases, thermal lattice fluctuations progressively disrupt the coherence of the polaron motion and reduce the effective transfer integral through the temperature-dependent narrowing of the polaron band. Consequently, the bandwidth continues to shrink and the delocalized polaron picture eventually breaks down. Under such conditions, the carrier motion becomes dominated by phonon-assisted transitions between localized configurations, and transport crosses over to the incoherent hopping regime.

The theoretical frameworks discussed in this section illustrate how the charge transport in e-ph coupled systems emerges from the interplay between coherent electronic motion and the dynamical response of the lattice. Depending on the strength of the e-ph interaction and the temperature of the

system, transport may occur through distinct mechanisms ranging from band-like motion of weakly dressed carriers, to coherent propagation of heavy polarons within a narrow band, and finally to incoherent hopping between localized lattice configurations. Understanding the conditions under which these regimes arise is essential for interpreting transport properties in materials where e-ph interaction plays a dominant role, and provides the theoretical foundation for the analysis of polaron dynamics within the Holstein model presented in the following chapters.

2.4 Path-Integral formalism

The path integral formalism represents a fundamental formulation of quantum mechanics [79, 86–88], complementary to the canonical approach based on operator algebra and wave functions. Although the formalism is most commonly associated with the work of Feynman, its conceptual roots can be traced to earlier developments in both classical probability theory and quantum mechanics [89–91]. These early contributions laid the groundwork for a formulation of quantum theory in which physical processes are described in terms of ensembles of trajectories in phase space rather than an individual deterministic path.

One of the earliest appearances of something that resembles the integrals over paths arose in the work of Wiener, who studied the Brownian motion as a stochastic process [86, 91, 92]. Brownian motion can be viewed as a continuum limit of a Markovian random walk with discrete time steps. In Wiener’s construction, the probability for a particle initially located at position x_0 at time t_0 to be found at position x_n at a later time t_n is described by a set of integrals over all possible variables x_i , $i = 0, 1, \dots, n$, reflecting the absence of a unique trajectory in stochastic motion.

$$P(x_n, x_0) = \int dx_1 dx_2 \dots dx_{n-1} p(x_n - x_{n-1}) \dots p(x_2 - x_1) p(x_1 - x_0) .$$

In the continuum limit $n \rightarrow \infty$, this construction leads to a probability measure defined over a space of continuous paths, known as the Wiener measure. A key feature of Wiener’s formulation is that the probability weight $p(x' - x)$ with which each path contributes to the total probability measure is determined by a Gaussian distribution $\exp(-(x - x')^2/2)$. This result follows from the central limit theorem, which ensures that the cumulative effect of an infinitely large number of random steps converges to a Gaussian process. Although Wiener’s work was purely classical and probabilistic in nature, it introduced mathematical structures that later proved essential for the development of path integrals in quantum mechanics [88, 89].

Around the same period, Dirac introduced ideas that pointed toward a path-based formulation of quantum dynamics. Dirac considered the quantum time-evolution operator and expressed it as a product of infinitesimal evolution operators over discrete time intervals [93]. This representation implicitly suggests a decomposition of quantum evolution into a sequence of short-time transitions, each contributing to the total amplitude. Although Dirac did not explicitly formulate a sum over continuous paths, his approximation of the evolution operator provided a crucial conceptual step toward the discretized time-slicing approach that underlies the path integral formulation [88, 90].

Closely related ideas also appeared in the work of Wentzel, who studied transition amplitudes in quantum optics [86]. Wentzel proposed that transition probability amplitudes could be expressed as sums over possible paths, each weighted by a phase factor determined by the action. In this picture, destructive interference suppresses contributions from paths that deviate strongly from the classical equations of motion, while constructive interference occurs near classical trajectories. This insight foreshadowed a central principle of the path integral formulation [88, 89]. The classical behavior emerges not from the exclusion of non-classical paths, but from the coherent cancelation of their contributions.

Building on these ideas, Feynman formulated the path integral approach as a complete and self-consistent framework for quantum mechanics [89, 90]. In this formulation, the transition amplitude

between an initial and a final state is expressed as a sum over all possible trajectories connecting the two configurations. Each trajectory contributes with a phase determined by the classical action S , typically through a factor of the form $\exp(iS/\hbar)$. Unlike classical mechanics, which singles out a unique trajectory determined by the equations of motion and conservation laws, quantum mechanics admits contributions from an infinite set of paths [79, 86, 88]. Observable quantities arise from the coherent superposition of these contributions, rather than from a single deterministic history.

This multiplicity of contributing paths reflects a fundamental distinction between classical and quantum descriptions of motion. In classical mechanics, conservation laws constrain the system's evolution locally and single out a unique trajectory. In quantum mechanics, by contrast, the uncertainty principle limits the simultaneous specification of conjugate variables, so that the transition amplitude receives contributions from configurations that do not correspond to classical solutions at intermediate times [89]. While energy is conserved globally, the energy–time uncertainty relation allows non-classical configurations to contribute to the quantum amplitude over sufficiently short time intervals, rendering classically forbidden processes dynamically relevant. In the classical limit $\hbar \rightarrow 0$, only paths in close proximity to the classical trajectory contribute constructively, and classical mechanics is recovered [87, 88].

The role of non-classical paths becomes particularly evident in quantum tunneling phenomena [88]. Classically, a particle encountering a potential barrier with energy lower than the barrier height cannot access the forbidden region. However, quantum mechanically, the uncertainty principle allows configurations in which the particle explores regions that are classically inaccessible. In the path integral picture, tunneling arises from trajectories that traverse the forbidden region and contribute coherently to the transition amplitude. The finite tunneling probability thus emerges naturally from the sum over histories, without invoking any explicit modification of classical laws.

A defining structural feature of the path integral formalism is its reliance on classical Lagrangian mechanics as the starting point for quantization [88, 90]. Rather than introducing operator commutation relations as fundamental postulates, the formalism begins with the classical action functional and constructs quantum amplitudes by summing over histories weighted by that action. This approach is particularly advantageous for systems with constraints or nontrivial configuration spaces, where canonical quantization may be ambiguous. It also provides a natural route to the quantization of fields [94, 95], in which the dynamical variables are continuous functions of space and time.

The principal strength of the path integral formalism emerges in the description of systems with many degrees of freedom. In quantum field theory and quantum statistical physics, operator-based approaches often become cumbersome, whereas the path integral formulation offers a unified and flexible framework [79, 82]. Physical observables are expressed as expectation values, that is, statistical averages over ensembles of paths or configurations, closely paralleling the structure of classical statistical mechanics.

A crucial step in connecting quantum dynamics with statistical physics is the introduction of imaginary time [79, 86, 88, 89]. The unitary time-evolution operator,

$$U(t) = \exp\left(-\frac{i}{\hbar}Ht\right),$$

describes the evolution of a system described by a Hamiltonian H in real time t . The path integral representation of evolution operator in real time suffers from highly oscillatory character due to the imaginary part in the exponent. This imaginary (or complex) nature of the exponent makes both the analytic and numerical evaluation of the transition amplitudes quite problematic. By performing the Wick rotation $t \rightarrow -i\tau$, one obtains an evolution operator in imaginary time,

$$U(t) = \exp\left(-\frac{1}{\hbar}H\tau\right),$$

which closely resembles the statistical operator of equilibrium quantum mechanics $\exp(-\beta H)$, where $\beta = 1/k_B T$ is the inverse temperature [96]. This correspondence allows the path integral formulation

to be applied directly to the quantum partition function $Z = \text{Tr} \exp(-\beta H)$, with the Euclidean action S_E replacing the real-time action and serving as a weighting factor for each configuration [86, 88, 89]. In the zero-temperature limit $\beta \rightarrow \infty$, the statistical operator projects on the ground state of the system, establishing a direct connection between imaginary-time evolution and the properties of the ground state of the system [82, 86]. This correspondence is of particular importance in low-energy quantum systems, where ground-state correlations dominate the physical behavior.

In the remainder of this chapter, the focus is on the explicit construction of the path-integral representation of the quantum transition amplitude for a general single-particle Hamiltonian of the form $H = p^2/2m + V$, as well as the path integral formulation of the many-body partition function. The presentation largely follows the exposition of Altland and Simons [79], with notation and emphasis adapted to the present context. Complementary treatments of path-integral methods can be found in Refs. [86–88].

2.4.1 Derivation of the path integral from the quantum transition amplitude

The time evolution of an autonomous quantum system is described by the time-dependent Schrödinger equation [97]:

$$i\hbar \frac{\partial}{\partial t} |\Psi(t)\rangle = H |\Psi(t)\rangle, \quad (2.124)$$

where $|\Psi(t)\rangle$ denotes the system's wave function and H is the (time-independent) Hamiltonian. A formal solution of this equation over a finite time interval defines the time-evolution operator $U(t', t)$ through [79, 93, 97]

$$|\Psi(t')\rangle = U(t', t) |\Psi(t)\rangle, \quad U(t', t) = \exp\left(-\frac{i}{\hbar} H(t' - t)\right) \Theta(t' - t). \quad (2.125)$$

The unitary operator $U(t', t)$ describes the dynamical evolution of the system from time t to t' . The inclusion of the Heaviside step function $\Theta(t' - t)$ emphasizes forward time evolution with $t' > t$.

For a single-particle system governed by the Hamiltonian H , the particle may evolve from a position eigenstate $|q\rangle$ at time t to another position eigenstate $|q'\rangle$ at time t' . The probability amplitude for this transition is given by the matrix element of the evolution operator $\langle q' | U(t', t) | q \rangle = \langle q' | e^{(-\frac{i}{\hbar} H(t' - t))} | q \rangle$, which is commonly referred to as the propagator of the system [90].

The central idea behind Feynman's path integral approach is to simplify the calculation of the propagator by first considering an infinitesimally small time interval Δt , rather than attempting to evaluate the propagator over a finite time interval directly [90, 93]. Such a direct calculation can be highly nontrivial, depending on the form of the Hamiltonian. Introducing a sufficiently small time step Δt in the exponential of the evolution operator enables the use of series expansions and perturbative approaches. To extend this idea to a general propagation time, the total time interval is divided into N equal slices, $t = N\Delta t$. For simplicity, the notation t is used to denote the time interval $t' - t$, since only the duration of the interval is relevant. In the limit $N \rightarrow \infty$, the continuum description of time is restored. With this time slicing, the evolution operator can be written as [90]

$$e^{-iHt/\hbar} = \left(e^{-iH\Delta t/\hbar} \right)^N. \quad (2.126)$$

The introduction of a small time step is particularly useful for Hamiltonians of the simple but general form [88, 90]

$$H = \frac{p^2}{2m} + V(q), \quad (2.127)$$

which consist of a kinetic and a potential energy term. For a Hamiltonian of this form and a sufficiently small time step Δt , the short-time evolution operator can be factorized as

$$e^{-iH\Delta t/\hbar} \simeq e^{-ip^2\Delta t/2m\hbar} e^{-iV(q)\Delta t/\hbar} + O(\Delta t^2). \quad (2.128)$$

This factorization follows from the Baker-Campbell-Hausdorff formula [86, 88, 90]. The higher-order commutator terms that involve $[p^2, V(q)]$ can be neglected, since they contribute only on the order of $(\Delta t)^2$. This factorization of the short-time evolution operator allows the kinetic and potential energy operators to act independently on their respective eigenstates. The full evolution operator over a finite time interval may be expressed as a product of short-time evolution operators.

The corresponding transition amplitude can be expressed as

$$\langle q_f | \left(e^{-iH\Delta t/\hbar} \right)^N | q_i \rangle = \langle q_f | (I_q I_p) e^{-iH\Delta t/\hbar} (I_q I_p) \dots (I_q I_p) e^{-iH\Delta t/\hbar} | q_i \rangle, \quad (2.129)$$

where $|q_i\rangle$ and $|q_f\rangle$ denote the initial and final position eigenstates, respectively. Here, resolutions of the identity in terms of position and momentum eigenstates [90], defined as

$$I_q = \int dq_n |q_n\rangle \langle q_n|, \quad I_p = \int dp_n |p_n\rangle \langle p_n|, \quad (2.130)$$

have been inserted before each short-time evolution operator in the product. The index $n = 1, \dots, N$ labels the intermediate time slices, with equalities $q_i \equiv q_0$ and $q_f \equiv q_N$.

Employing the standard dyadic product of position and momentum eigenstates

$$\langle q | p \rangle = \langle p | q \rangle^* = \frac{1}{\sqrt{2\pi\hbar}} e^{iqp/\hbar}, \quad (2.131)$$

together with the short-time factorization of the evolution operator given in Eq. (2.128), the transition amplitude can be written in the form

$$\langle q_f | e^{-iHt/\hbar} | q_i \rangle \simeq \int \prod_{n=1}^{N-1} dq_n \prod_{n=1}^N \frac{dp_n}{2\pi\hbar} \exp \left[-i \frac{\Delta t}{\hbar} \sum_{n=0}^{N-1} \left(V(q_n) + \frac{p_{n+1}^2}{2m} - p_{n+1} \frac{q_{n+1} - q_n}{\Delta t} \right) \right]. \quad (2.132)$$

In this representation, the propagator is expressed as a $(2N-1)$ -dimensional integral over discrete phase space variables (q_n, p_n) [79, 88, 90]. The discretization of time, $\Delta t = t/N$, induces a corresponding discretization of a path in phase space. To describe the propagator in terms of continuous paths, the continuum limit $N \rightarrow \infty$ is taken [79, 86, 88]. In this limit, the discrete set of phase-space points (q_n, p_n) approaches a smooth curve $Q(t) \equiv (q(t), p(t))$.

Accordingly, sums over discrete time slices become integrals, and finite differences become time derivatives,

$$\Delta t \sum_{n=0}^{N-1} \rightarrow \int_0^t dt', \quad \frac{q_{n+1} - q_n}{\Delta t} \rightarrow \partial_t q(t) \equiv \dot{q}(t). \quad (2.133)$$

The terms in the exponent corresponding to the kinetic and potential energies combine into the classic Hamiltonian $H(p, q) = (p(t))^2/2m + V(q(t))$, which is now a functional of the phase-space variables $q(t)$ and $p(t)$.

In the continuum limit, this motivates the definition of the functional integration measure as [79, 86, 94]

$$\lim_{N \rightarrow \infty} \int \prod_{n=1}^{N-1} dq_n \prod_{n=1}^N \frac{dp_n}{2\pi\hbar} \rightarrow \int_{q(0)=q_i}^{q(t)=q_f} Dq Dp = \int_{q(0)=q_i}^{q(t)=q_f} DQ. \quad (2.134)$$

Summarizing these results yields the Hamiltonian form of the path integral representation of the propagator [79, 88, 90],

$$\langle q_f | e^{-iHt/\hbar} | q_i \rangle = \int_{q_i=q(0)}^{q_f=q(t)} DQ \exp \left[\frac{i}{\hbar} \int_0^t dt' (p\dot{q} - H(p, q)) \right]. \quad (2.135)$$

The functional integration extends over all phase-space paths that begin at q_i and end at q_f . Each path contributes with a weight determined by the exponential of the classical action. The classical action is defined as the time integral of the Lagrangian [90, 93],

$$S(p, q) = \int_0^t dt' L(p, q) = \int_0^t dt' (p\dot{q} - H(p, q)) . \quad (2.136)$$

In this way, the path integral formulation of the quantum transition amplitude is expressed directly in terms of classical phase-space variables, providing a natural bridge to classical mechanics.

For the class of Hamiltonians considered here, where the kinetic and potential energy terms are separated and the potential $V(q)$ is independent of the momentum, the momentum integration can be performed explicitly. In this case, the propagator can be written as

$$\langle q_f | e^{-iHt/\hbar} | q_i \rangle = \int_{q_i=q(0)}^{q_f=q(t)} Dq e^{-\frac{i}{\hbar} \int_0^t dt' V(q)} \int Dp \exp \left[-\frac{i}{\hbar} \int_0^t dt' \left(\frac{p^2}{2m} - p\dot{q} \right) \right] . \quad (2.137)$$

Since the Hamiltonian is quadratic in the momentum, the integral over the momentum variables is of Gaussian form and can be calculated straightforwardly [86, 90]. Upon performing the momentum integration, the phase-space path integral reduces to a coordinate-space path integral, and the transition amplitude may be written as

$$\langle q_f | e^{-iHt/\hbar} | q_i \rangle = \int_{q(0)=q_i}^{q(t)=q_f} Dq \exp \left[\frac{i}{\hbar} \int_0^t dt' L(q, \dot{q}) \right] , \quad (2.138)$$

where the Lagrangian is given by

$$L(q, \dot{q}) = \frac{m\dot{q}^2}{2} - V(q) . \quad (2.139)$$

This expression defines the path integral as an infinite-dimensional integral over trajectories in coordinate space that connect the initial position q_i to the final position q_f within the time interval t , with each trajectory weighted by the exponential of the classical action [86, 88]. The resulting numerical factors arising from momentum integration are absorbed into the constant included in the formal functional integration measure Dq . Such constants are typically irrelevant for normalized transition amplitudes and expectation values, where they cancel by construction. The evaluation of integrals of Gaussian type, such as the one appearing in Eq. (2.137), will be addressed in a subsequent subsection, after introducing the path integral representation of the quantum partition function.

2.4.2 Path-integral representation of quantum partition function

In quantum statistical physics, the partition function plays a central role, as it provides direct access to all equilibrium thermodynamic properties of a system [82, 86]. Fundamental physical quantities such as internal energy, free energy, entropy, and correlation functions can be obtained from appropriate derivatives of the partition function. In the context of interacting many-body systems, it serves as the primary object from which the collective and emergent behavior arises.

The canonical partition function of a quantum system is defined as the trace of the statistical operator [82, 86]

$$Z = \text{Tr} \left(e^{-\beta H} \right) , \quad (2.140)$$

where $\beta = 1/(k_B T)$ is the inverse temperature and H is the Hamiltonian of the system. The trace is taken over the full Hilbert space of the system, and any complete set of basis states can be chosen to evaluate it.

For quantum many-body systems, a natural choice of basis is the set of coordinate eigenstates $\{|q_n\rangle\}$, where state q_n denotes the configuration of the n -th degree of freedom [86, 88, 90]. In this representation, the partition function can be written as

$$Z = \sum_n \int dq_n \langle q_n | e^{-\beta H} | q_n \rangle. \quad (2.141)$$

The construction of a path-integral representation of the partition function closely parallels the derivation of the quantum transition amplitude discussed in the previous section [88, 90]. In both cases, the central object is a matrix element of the exponential operator, either the time-evolution operator $\exp(-itH)$ or the statistical operator $\exp(-\beta H)$. The essential difference lies in the nature of the exponent. Whereas real-time evolution involves a purely imaginary exponent, the statistical operator is governed by a real and negative exponent.

This distinction has important mathematical and practical consequences. In real time, the path integral is weighted by an oscillatory phase factor of the form $e^{iS/\hbar}$, where S is the classical action. Such oscillatory integrals are not absolutely convergent and are therefore mathematically ill-defined without additional prescriptions [86, 88]. Their highly oscillatory nature also poses severe difficulties for numerical evaluation.

A standard procedure to overcome these issues is the Wick-rotation from real to imaginary time [79, 88, 98], defined by the transformation

$$t \rightarrow -i\tau, \quad (\tau \in \mathbb{R}), \quad (2.142)$$

which may be interpreted as a rotation by $\pi/2$ in the complex time plane. Under this transformation, the oscillatory phase factor $\exp(iS/\hbar)$ is replaced by a real damping factor $e^{-S_E/\hbar}$, where S_E is the Euclidean action [86, 90]. For a single-particle system with the Hamiltonian $H = p^2/(2m) + V(q)$, the Euclidean action takes the form [86, 88]

$$S_E = \int d\tau \left(m\dot{q}^2/2 + V(q) \right). \quad (2.143)$$

Compared to the real-time action, the potential energy term enters with the opposite sign. The resulting path integral is well defined and convergent, making it suitable for both analytical treatment and numerical evaluation. Real-time quantities can subsequently be recovered by analytic continuation from imaginary to real time.

The connection between imaginary time evolution and statistical mechanics becomes explicit by identifying the total extent of imaginary time with the inverse temperature according to $\tau = \beta\hbar$ [79, 82, 90]. With this identification, the statistical operator $\exp(-\beta H)$ may be interpreted as an evolution operator in imaginary time over an interval of length $\beta\hbar$ [82, 86, 94]. The matrix element $\langle q_n | e^{-\beta H} | q_n \rangle$ therefore corresponds to an imaginary-time propagator that begins and ends in the same configuration.

Taking the trace over all states enforces this identification of initial and final configurations and naturally leads to periodic boundary conditions in imaginary time, $q(0) = q(\beta)$. The partition function can therefore be expressed in path-integral form as [86, 88, 90]

$$Z = \sum_n \int_{q(0)=q(\beta\hbar)} Dq e^{-S_E[q]/\hbar}, \quad (2.144)$$

where the Euclidean action is given by

$$S_E = \sum_n \int_0^{\beta\hbar} d\tau \left(\frac{m}{2} (\dot{q}_n)^2 + V(q_n) \right). \quad (2.145)$$

In this representation, the quantum partition function is expressed as an integral over closed trajectories in coordinate space, with each path weighted by the exponential of the Euclidean action [82, 88].

This formulation establishes a direct and transparent connection between quantum statistical mechanics and the path-integral formalism. It provides a natural framework for the description of interacting many-body systems and forms the basis for both analytical approximations and numerical methods [82, 86]. In later sections, this formalism will be specialized to the Holstein Hamiltonian, with particular emphasis on discretized path-integral techniques relevant for numerical applications.

2.4.3 Gaussian integrals

Gaussian integrals play a central role as a technical tool in the evaluation of path integrals in quantum and statistical physics [86, 94]. They arise whenever the exponent contains a quadratic form, which occurs naturally in the action functionals underlying the path-integral formulation. As already encountered in the derivation of the path-integral representations of the quantum transition amplitude and the partition function for Hamiltonians of the form $H = p^2/2m + V(q)$, the momentum-dependent contributions typically appear as quadratic terms. More generally, Gaussian structures characterize non-interacting theories, harmonic approximations to interacting systems, and fluctuations around classical or mean-field solutions [82, 88]. For these reasons, Gaussian integrals constitute a fundamental building block of the path-integral formalism.

The simplest Gaussian integral is of the form [79, 86, 94]

$$\int_{-\infty}^{\infty} dx e^{-ax^2} = \sqrt{\frac{\pi}{a}}, \quad (2.146)$$

where x is a real variable and $a > 0$ is a real positive constant. This result generalizes straightforwardly to a quadratic form with linear terms $-ax^2 + bx + c$,

$$\int_{-\infty}^{\infty} dx \exp(-ax^2 + bx + c) = \sqrt{\frac{\pi}{a}} \exp\left(\frac{b^2}{4a} + c\right), \quad (2.147)$$

where $a > 0$ and b and c are real parameters. This expression is obtained by completing the square in the exponent [79, 86]. Quadratic forms of this type commonly arise when external sources or constraints are introduced to the system.

Another family of integrals that frequently appears is the one that involves the polynomial factor next to the exponential. This type of integrals can be generated by the differentiation with respect to auxiliary parameters in Gaussian exponent. For example, integrals of the form

$$\int_{-\infty}^{\infty} dx x^{2n} e^{-ax^2} \quad (2.148)$$

can be obtained by differentiation of the basic Gaussian integral given in Eq. (2.146) with respect to the parameter a [79, 88]. This property is widely used in perturbative expansions and in the computation of correlation functions [82, 94]. Due to symmetry of the integrand, only integrals with even powers of x evaluate as non-zero.

Gaussian integrals over complex variables are equally important in quantum and statistical field theories [79, 86, 94]. Let $z = x + iy$ be a complex variable and let w be a complex number with $\text{Re}(w) > 0$. The complex Gaussian integral then evaluates

$$\int d(z^*, z) e^{-z^* w z} = \frac{\pi}{w}, \quad (2.149)$$

where $z^* = x - iy$ and the integration measure is defined as $d(z^*, z) = dx dy$. Under this parameterization, the quadratic form reduces to $w(x^2 + y^2)$, and the complex Gaussian integral becomes equivalent

to a two-dimensional real Gaussian integral. Including linear source terms yields

$$\int d(z^*, z) e^{-z^* w z + u^* z + z^* v} = \frac{\pi}{w} \exp\left(\frac{u^* v}{w}\right), \quad (2.150)$$

where u and v are, in general, independent complex numbers and $\text{Re}(w) > 0$ ensures convergence.

These results generalize naturally to multivariate Gaussian integrals [79, 82, 86]. For a set of N real variables collected in a vector $\mathbf{v} = (v_1, v_2, \dots, v_N)^T$ and a real, symmetric, positive-definite matrix $\mathbf{A}$, the N -dimensional Gaussian integral is given by

$$\int d^N v \exp\left(-\frac{1}{2} \mathbf{v}^T \mathbf{A} \mathbf{v} + \mathbf{j}^T \mathbf{v}\right) = \frac{(2\pi)^{N/2}}{\sqrt{\det \mathbf{A}}} \exp\left(\frac{1}{2} \mathbf{j}^T \mathbf{A}^{-1} \mathbf{j}\right), \quad (2.151)$$

where $\mathbf{j}$ is arbitrary N -component source vector. The appearance of the determinant $\det \mathbf{A}$ follows from the diagonalization of the quadratic form. Since $\mathbf{A}$ is real and symmetric, it can be decomposed as $\mathbf{A} = \mathbf{O}^T \mathbf{D} \mathbf{O}$, where $\mathbf{O}$ is an orthogonal matrix, and $\mathbf{D}$ is diagonal with positive elements [94]. A change in variables $\mathbf{v}' = \mathbf{O} \mathbf{v}$ reduces the integral to a product of N independent one-dimensional Gaussian integrals, producing the stated result.

The formula given in Eq. (2.151) serves as a generating functional for correlation functions [82, 86]. By differentiating with respect to the components of the source vector j_i , one obtains expectation values, for example $\langle v_i v_k \rangle = A_{i,k}^{-1}$. Interpreting the Gaussian weight as a probability distribution, these expectation values are given by

$$\langle \dots \rangle = \frac{\det \mathbf{A}^{1/2}}{(2\pi)^{N/2}} \int d\mathbf{v} e^{-\frac{1}{2} \mathbf{v}^T \mathbf{A} \mathbf{v}} (\dots). \quad (2.152)$$

By differentiating the generating functional $2n$ times with respect to the source vector $\mathbf{j}$, one obtains higher-order correlation functions, which directly leads to Wick's theorem for bosonic fields [79, 86, 98]. Wick's theorem states that the expectation value of a product of $2n$ bosonic fields can be represented as a sum over all possible pairings into 2-point contractions, such as $\langle v_i v_k \rangle$. As an illustration, the four-point function $\langle v_m v_n v_p v_q \rangle$ can be computed from the multivariate Gaussian integral and yields $\langle v_m v_n v_p v_q \rangle = A_{mn}^{-1} A_{pq}^{-1} + A_{mp}^{-1} A_{qn}^{-1} + A_{mq}^{-1} A_{np}^{-1}$. Recognizing that each matrix element represents a corresponding contraction, this expression can equivalently be written as

$$\langle v_m v_n v_p v_q \rangle = \langle v_m v_n \rangle \langle v_p v_q \rangle + \langle v_m v_p \rangle \langle v_n v_q \rangle + \langle v_m v_q \rangle \langle v_n v_p \rangle,$$

which coincides precisely with the result given by Wick's theorem.

Multivariate Gaussian integrals can also be extended to include complex vectors and matrices [94]. If $\mathbf{v}$ is a complex N -component vector and $\mathbf{A}$ is a positive-definite Hermitian matrix, one obtains

$$\int d(\mathbf{v}^\dagger \mathbf{v}) e^{-\mathbf{v}^\dagger \mathbf{A} \mathbf{v}} = \pi^N \det \mathbf{A}^{-1}, \quad (2.153)$$

where $\mathbf{v}^\dagger$ denotes the Hermitian conjugate of $\mathbf{v}$. As in the real case, diagonalization of quadratic form by unitary transformation reduces the problem to a product of independent integrals. Gaussian integrals can also be generalized to certain non-Hermitian matrices, provided the quadratic form can be brought into diagonalizable form with convergent eigenvalues.

Finally, Gaussian integration extends to infinite-dimensional functional integrals, where the integration variables are continuous fields $\phi(x)$ [86, 88]. For a quadratic action, the functional Gaussian integral takes the formal form

$$\begin{aligned} \int D\phi(x) \exp \left[-\frac{1}{2} \int dx dx' \phi(x) A(x, x') \phi(x') + \int dx J(x) \phi(x) \right] \\ \propto (\det A)^{-1/2} \exp \left[\frac{1}{2} \int dx dx' J(x) A^{-1}(x, x') J(x') \right], \end{aligned} \quad (2.154)$$

where the inverse operator satisfies $\int dx' A(x, x') A^{-1}(x', x'') = \delta(x - x'')$. The overall normalization factor is omitted, as it is divergent in the infinite-dimensional limit and cancels in normalized observables [86]. This integral can be generalized to the case with complex fields and Hermitian operators. With this discussion, the use of the continuum limit in defining the path integral for the transition amplitude is validated, as is the momentum integration appearing in the final expression for the path integral. These functional integrals provide the basis for the path-integral formalism and for continuum field theories. However, in this thesis, the emphasis will be on finite-dimensional Gaussian integrals, reflecting the inherently discrete character of computational numerical methods.

2.5 Quantum Monte Carlo methods

The path-integral approach to studying quantum many-body systems naturally leads to the evaluation of extremely high-dimensional integrals. Upon discretization of the time or imaginary-time interval, the partition function or time-dependent correlation functions are expressed as integrals over configurations defined on the discretized time grid. The dimensionality of these integrals grows rapidly with the number of time slices and the number of degrees of freedom in the system. As a result, direct deterministic numerical evaluation of such integrals becomes computationally impractical as the discretization is refined. In this context, Monte Carlo stochastic integration techniques offer an efficient alternative [99, 100].

The term *Monte Carlo* was introduced in the early 1940s at the Los Alamos Laboratory by Stanislaw Ulam, in collaboration with John von Neumann and others, in the context of nuclear physics calculations [101–103]. The name reflects the central role of randomness in the method and was inspired by games of chance. Although initially regarded primarily as a tool for obtaining approximate numerical estimates, Monte Carlo methods gained widespread acceptance with the advent of digital computing [99, 100] and have since become an essential computational technique in many areas of science. In physics, Monte Carlo methods are particularly valuable for the study of classical and quantum many-body systems, where high-dimensional integrals arise naturally.

The basic idea underlying Monte Carlo methods can be illustrated by a simple example. Consider a unit circle inscribed within a square of unit side length. The ratio of the area of the circle to that of the square is equal to $\pi/4$. By uniformly sampling points within the square and counting the fraction that fall inside the circle, this ratio, or equivalently the value of π , can be estimated statistically. As the number of sampled points increases, the estimate approaches the true value. Since the method is probabilistic in nature, the estimate is never exact for a finite number of samples. However, it can be made sufficiently accurate by increasing the sample size.

The value of a definite integral can be estimated in a similar way. Monte Carlo integration is primarily based on drawing random samples from the integration domain and then taking the average of the integrand's values at the sampled points. Unlike deterministic quadrature methods, which rely on structured grids and whose computational cost grows rapidly with the dimensionality of the integral, Monte Carlo integration employs probabilistic sampling and remains effective in high-dimensional settings. The trade-off associated with this probabilistic approach is the presence of an intrinsic statistical error in the estimator. Nevertheless, this statistical uncertainty is controllable as the Monte Carlo error decreases inversely with the square root of the number of samples [99, 100].

To make this discussion more explicit, consider a definite integral of a real-valued function $f(x)$ over a domain $x \in \Omega$,

$$I = \int_{\Omega} dx f(x) . \quad (2.155)$$

The integrand can be written in the form $f(x) = P(x)f(x)P(x)^{-1} = P(x)F(x)$, where $P(x)$ is a non-negative function defined over a domain $\Omega_0 \supseteq \Omega$, normalized such that $\int_{\Omega_0} dx P(x) = 1$. The

integral I can then be rewritten as

$$I = \int_{\Omega} dx P(x) F(x) \equiv \langle F \rangle_P, \quad (2.156)$$

where $\langle \dots \rangle_P$ denotes an expectation value with respect to the probability density $P(x)$. To estimate the value of the integral I , a set of N random variables $\{x_i\} \in \Omega$ is sampled from the distribution $P(x)$ and the Monte Carlo estimator is defined as

$$I_N = \frac{1}{N} \sum_{i=1}^N F(x_i). \quad (2.157)$$

If the expectation value of $F(x)$ with respect to the probability density $P(x)$ exists, the Monte Carlo estimator is unbiased, meaning that its expectation value satisfies $\langle I_N \rangle = I$. For any finite number of samples, a particular realization of the estimator fluctuates around the exact value and can therefore be written as $I_N = I + \epsilon$, where ϵ denotes the statistical error. The magnitude of these fluctuations is characterized by the variance of the estimator, defined as $\sigma^2 = \langle F^2 \rangle_P - \langle F \rangle_P^2$, whose square root σ is the standard deviation. For N statistically independent samples, the standard deviation of the estimator decreases as $\epsilon \sim \sigma/\sqrt{N}$, explicitly demonstrating how the statistical error decreases with increasing sample size [99, 100].

While increasing the number of samples reduces the statistical uncertainty, this approach is often computationally inefficient, particularly for high-dimensional integrals. A more effective strategy is to reduce the variance of the estimator itself, thereby achieving a desired accuracy with fewer samples. Since the variance depends explicitly on the choice of the probability density function, it can be minimized by selecting a sampling distribution that reflects the structure of the integrand. This principle, known as importance sampling, forms the basis of most practical Monte Carlo algorithms [99, 100].

All Monte Carlo evaluations are based on random number generation. To obtain reliable convergence and accurate statistical estimates, it is essential to use high-quality random samples. Standard programming environments provide random number generators for uniformly distributed random numbers in the interval $[0, 1]$, and often also include generators for specific distributions such as the normal distribution. It is important to note that all random numbers generated on a computer are pseudo-random, as truly random numbers arise only from inherently stochastic physical processes. Pseudo-random number generators produce sequences of random numbers based on an initial input known as the *seed*. Changing the seed results in a different sequence, while fixing it allows for reproducibility of numerical simulations [99, 100, 104].

Given a generator for uniformly distributed random numbers, samples from other distributions can be generated using various transformation techniques. In the simplest case, when the target distribution is specified by a continuous probability density function $f_Y(y)$, one may generate a uniformly distributed random variable $0 \leq x \leq 1$ with density $f_X(x)$ and define a deterministic mapping $y = y(x)$. If this mapping is known and invertible, the target distribution follows from the change of variables formula

$$f_Y(y) = f_X(x) \left| \frac{dy}{dx} \right|^{-1}. \quad (2.158)$$

In cases where the target distribution cannot be expressed analytically or Jacobian $|dy/dx|$ cannot be evaluated, alternative sampling methods are used. One such method is rejection sampling. The basic idea is to enclose the target distribution within a larger known distribution from which samples can be easily drawn. Random points are generated from this enclosing distribution and accepted if they fall under the curve of the target distribution and rejected otherwise. While conceptually simple, this method can be inefficient, particularly in high-dimensional spaces, as a large fraction of proposed samples may be rejected. Its efficiency improves when the enclosing distribution closely approximates the target distribution while remaining everywhere larger than it [99, 100, 104].

In many physical applications, however, the optimal sampling distribution is not known a priori or cannot be sampled from directly. In such cases, sample configurations are generated using Markov Chain Monte Carlo methods, in which a sequence of correlated samples is constructed to reproduce the desired probability distribution. The most widely used algorithm in this class is the Metropolis acceptance-rejection method, which provides an efficient and general procedure for importance sampling without requiring explicit knowledge of the normalization constant of the target distribution function [99–101, 105].

The Metropolis algorithm generates configurations distributed according to a target probability density $P(X)$ defined over a configuration space of dimension d . Starting from an initial configuration point $X \equiv \{x_i\} = (x_1, x_2, \dots, x_d)$, a trial configuration $X' \equiv \{x'_i\}$ is proposed by introducing a small change to one or more components of X . The new proposed configuration X' is accepted with probability

$$r = \min \left(1, \frac{P(X')}{P(X)} \right). \quad (2.159)$$

If $P(X') > P(X)$, the new configuration is accepted with probability one. Otherwise, it is accepted with probability equal to $P(X')/P(X)$. In practice, this acceptance rule is implemented by drawing a random number n uniformly from the interval $[0, 1]$. The proposed move is accepted if $n < r$. If this condition is not met, the move is rejected, and the system remains in its original configuration [99–101].

This acceptance probability follows from the requirement of detailed balance with respect to the target distribution $P(X)$, under the assumption that the proposal probabilities for moves $X \rightarrow X'$ and $X' \rightarrow X$ are symmetric. Provided that the proposal moves are ergodic, the resulting Markov chain converges to the stationary distribution $P(X)$ independently of the initial configuration [99–101].

Because successive configurations are generated by local updates, the samples produced by the Metropolis algorithm are generally correlated. These correlations are particularly strong during the initial stages of the simulation, when the system has not yet equilibrated. Furthermore, the arbitrary choice of the initial configuration may cause early samples to deviate significantly from the target distribution. To mitigate these effects, it is standard practice to discard an initial portion of the Markov chain, referred to as the thermalization or "warm up" period, during which the algorithm is allowed to reach equilibrium [99, 100].

To reduce correlations between sampled configurations, one may retain only every n -th configuration generated by the algorithm, discarding the intermediate ones. Although this increases the total number of Monte Carlo steps required for a given number of effective samples, it improves the statistical independence of the data. As a result, the Metropolis algorithm typically constitutes the most computationally demanding part of a Monte Carlo simulation. Nevertheless, it remains highly efficient and well suited to many problems in physics, where the stochastic dynamics of the algorithm naturally mirrors the behavior of the underlying physical system [99, 100, 105].

Convergence of a Monte Carlo simulation is an essential prerequisite for obtaining reliable and physically meaningful results. In practice, convergence tests are performed by examining the behavior of measured observables as functions of Monte Carlo time and by comparing results obtained using different thermalization lengths, sampling intervals, and total numbers of samples [99, 100, 105].

The general framework of Monte Carlo sampling can be applied directly to the discretized paths introduced in the path-integral formulation. In this approach, each path represents a configuration of the system along the real or imaginary-time axis, and the probability weight of a configuration is determined by the corresponding action functional. The resulting Path Integral Monte Carlo (PIMC) method allows for efficient stochastic evaluation of quantum statistical averages in high-dimensional configuration spaces [58, 106, 107].

2.5.1 Path integral Monte Carlo

In the path-integral formulation introduced in the previous section, quantum partition functions and correlation functions are expressed as sums or integrals over discretized trajectories defined on a time or imaginary-time grid. Upon discretization into N time slices, a configuration X corresponds to a specific realization of the system variables on each time slice, collectively defining a discretized path. Each configuration is assigned a statistical weight proportional to $\exp(-S[X])$, where $S[X]$ is the action associated with the path [58, 106, 107]. Monte Carlo algorithms generate configurations distributed according to this weight, allowing the stochastic evaluation of otherwise intractable high-dimensional integrals.

Physical observables are evaluated as ensemble averages over sampled configurations. For an observable O defined on the discretized path, its expectation value is given as

$$\langle O \rangle = \frac{1}{Z} \sum_{\{x\}} O(\{x\}) e^{-S[\{x\}]} \approx \frac{1}{N_s} \sum_{i=1}^{N_s} O(X_i) ,$$

where the right-hand side represents the Monte Carlo estimator, X_i is a configuration generated by the Monte Carlo simulation, and N_s is the total number of sampled paths. This thesis focuses particularly on time correlation functions

$$C(t) = \langle A(t)A(0) \rangle = \frac{1}{Z} \text{Tr} [e^{-\beta H} e^{itH} A(0) e^{-itH} A(0)] , \quad (2.160)$$

where the trace is expanded in a complete basis. The choice of basis determines the form of the action functional and influences the optimal sampling distribution for the correlation function. As discussed previously, the real time variable can be transformed to imaginary time via $t \rightarrow -i\tau$, yielding the corresponding imaginary-time correlation function. Imaginary-time correlation function can then be analytically continued to real-time or real-frequency quantities [59, 108]. This illustrates how path-integral Monte Carlo allows direct computation of quantum correlation functions in high-dimensional systems, including many-body polaron models [66, 109].

A schematic of the path-integral Monte Carlo algorithm, widely used in the literature and relevant to this work, proceeds as follows. A path configuration X_0 is initialized. At each Monte Carlo step, a trial move X' is proposed by introducing a local modification to one or more time slices of the current path. The corresponding change in action, $\Delta S = S[X'] - S[X]$, is evaluated, and the trial configuration is accepted with probability $\min(1, e^{-\Delta S})$. This ensures the convergence of the Markov chain to the stationary distribution defined by the path-integral weight [57, 109]. Because successive configurations generated in this manner are generally correlated, an initial thermalization period is discarded and the observables $O(X)$ are sampled at selected intervals to reduce the correlations between successive configurations. This process is repeated until a sufficient number of statistically independent samples have been collected to estimate expectation values with the desired accuracy. In practice, the efficiency of the Metropolis algorithm can be reduced if the Markov chain becomes trapped in local minima of configuration space, resulting in poor phase space exploration, long autocorrelation times and significantly biased estimates even for long simulation times.

While the Metropolis acceptance-rejection algorithm is widely used method in path-integral Monte Carlo simulations, it is not the only approach. Depending on the system under study and the desired efficiency, alternative path sampling strategies can be employed. These include multi-level or bisection moves [58], staging and normal-mode updates [106], worm algorithms [107], and continuous-time formulations [68], among others. Each method is designed to efficiently explore the path configuration space while respecting the statistical weights defined by the action, and can be combined with importance sampling or other variance-reduction techniques. The choice of algorithm often depends on the dimensionality of the system, the nature of the interactions, and the observables of interest [57, 58, 68, 106, 107, 109].

Implementing path-integral Monte Carlo methods in practice requires careful attention to discretization errors and convergence. The number of time slices N must be sufficient to accurately approximate the continuous path integral. Convergence should be verified by testing the stability of sampled observables against the number of Monte Carlo steps, thermalization period, and sampling intervals. In many-body systems, the configuration space grows rapidly with system size, making importance sampling essential for efficient exploration of relevant paths [68, 110].

Path integral Monte Carlo has been successfully applied to a variety of condensed-matter systems, including lattice and continuum polarons, electrons coupled to phonon baths and strongly correlated lattice models [57–59, 66, 107–109]. Its combination of stochastic integration and path discretization provides a versatile framework that naturally extends to evaluating real-time correlation functions either directly or via analytic continuation, making it a central tool in the methodology employed in this thesis.

2.5.2 Dynamical sign problem

The Monte Carlo framework described previously relies fundamentally on the existence of a non-negative, normalizable weight that can be interpreted as a probability density. In imaginary-time Path Integral formulations, this requirement is typically satisfied, as the Euclidean action is real and the associated weight $e^{-S[X]}$ is positive. This property underlies the success of Path Integral Monte Carlo methods for equilibrium and thermodynamic quantities [57, 58, 106].

The situation changes qualitatively when one considers real-time dynamics. Real-time correlation functions and dynamical observables are expressed in terms of path integrals weighted by the real-time action, leading to oscillatory integrands of the form

$$w[X] = e^{iS[X]}. \quad (2.161)$$

Since this weight is complex in general, it cannot be interpreted as a probability density and the direct application of standard Monte Carlo sampling methods is therefore not valid [68, 111].

A common formal workaround is to introduce a positive reference distribution by separating the magnitude and phase of the weight, $w[X] = |w[X]|e^{i\theta[X]}$ [68, 111]. The expectation values of the observables may then be written as

$$\langle O \rangle = \frac{\langle O e^{i\theta} \rangle_{|w|}}{\langle e^{i\theta} \rangle_{|w|}}, \quad (2.162)$$

where $\langle \dots \rangle_{|w|}$ denotes an average with respect to the positive weight $|w[X]|$. While this reweighting restores a probabilistic sampling procedure, it introduces a severe numerical difficulty. The phase factor $\exp(i\theta[X])$ exhibits strong fluctuations across configuration space, leading to extensive cancellations between sampled contributions [106].

This phenomenon is commonly referred to as the dynamical sign problem or phase problem [68, 111]. In contrast to the fermionic sign problem encountered in equilibrium simulations [112], the dynamical sign problem is intrinsic to real-time evolution and arises irrespective of particle statistics. Its severity increases rapidly with the real time extent of the path integral as the accumulated phase fluctuations grow with propagation time leading to exponential growth of the variance of Monte Carlo estimators [68, 110, 113]. Achieving a fixed statistical accuracy therefore requires a number of samples that increases exponentially with the real-time propagation length. As a result, the real-time Monte Carlo simulations become impractical beyond relatively short time lengths.

Over the past decades, a variety of approaches have been proposed to mitigate the dynamical sign problem and to extend the accessible real-time regime. Early studies of real-time path-integral Monte Carlo already identified the exponential growth of statistical noise as a fundamental limitation of direct sampling schemes [57, 58, 68, 111].

Significant progress was achieved for quantum dissipative systems through the use of influence-functional techniques, where environmental degrees of freedom are analytically integrated out, leading

to effective non-local actions with finite memory. These approaches allow controlled real-time simulations up to intermediate times by systematically truncating bath-induced correlations [107, 109, 113, 114].

Other strategies include reformulations of real-time correlation functions aimed at reducing phase cancellations, as well as stochastic sampling schemes with modified estimators [106, 110]. While such approaches can substantially improve convergence for specific models and parameter regimes, the statistical error in real-time Monte Carlo simulations generally continues to grow rapidly with propagation time. As a result, no universally applicable solution to the dynamical sign problem is currently known.

A widely adopted way to circumvent this difficulty is to avoid explicit real-time sampling altogether by formulating the problem in imaginary time and subsequently performing an analytic continuation to real frequencies or times [57, 106]. This approach eliminates the dynamical sign problem at the level of Monte Carlo sampling at the cost of introducing an ill-posed inversion problem. The principles and limitations of this strategy will be discussed in the following subsection.

2.5.3 Analytic continuation

As discussed in the previous subsection, direct Monte Carlo evaluation of real-time dynamical observables is severely limited by the dynamical sign problem. A widely adopted alternative strategy is therefore to reformulate the problem in imaginary time, where Path Integral Monte Carlo methods are well controlled, and to subsequently recover real-time or real-frequency information via analytic continuation [72, 75, 106].

In the imaginary-time formalism, dynamical correlation functions are defined along the imaginary-time axis $\tau \in [0, \beta]$, where $\beta = 1/(k_B T)$. Under transformation $t \rightarrow -i\tau$, the oscillatory real-time weight $e^{iS[X]}$ is converted into a non-negative real Euclidean weight $e^{-S[X]}$. As a result, imaginary-time correlation functions can be sampled efficiently using standard Monte Carlo techniques without encountering the dynamical sign problem [57, 106].

The connection between imaginary-time and real-time dynamics is established through analytic continuation. Formally, correlation functions defined in imaginary time correspond to values of an analytic function evaluated along the imaginary axis in the complex-time plane. Real-time or real-frequency observables are obtained by continuing this function to the real axis. In the frequency domain, this relation is usually formulated using integral transforms that link imaginary-time data to real-frequency spectral functions through specific kernels. Schematically, this relation may be written as

$$G(\tau) = \int_0^\infty d\omega K(\tau, \omega) A(\omega), \quad (2.163)$$

where $G(\tau)$ denotes the imaginary-time correlation function, $A(\omega)$ is the corresponding real-frequency spectral function, and $K(\tau, \omega)$ is a known kernel determined by the statistical ensemble and the definition of the observable. The problem of analytic continuation then amounts to reconstructing $A(\omega)$ from noisy and discretized data for $G(\tau)$. Owing to the structure of the integral transform, the kernel $K(\tau, \omega)$ acts as a smoothing operator that suppresses the high-frequency features of $A(\omega)$, so that the fine structures in the spectral function contribute only weakly to $G(\tau)$. As a result, their reconstruction is extremely sensitive to statistical noise and discretization errors [106, 115, 116]. In the absence of statistical noise and discretization, this correspondence is exact and uniquely defines the real-time dynamics.

In practice, however, Monte Carlo simulations provide correlation functions at a finite number of discrete points with statistical uncertainty. Analytic continuation then becomes an ill-posed inverse problem, in which small fluctuations in the input data can result in large variations in the continued function. A key aspect underlying this instability is the limited information content of the available data. For analytic continuation to be meaningful and stable, the known portion of the function must contain sufficient structure, in the sense that it exhibits significant variation relative to the extent of

the domain on which it is known. Data that are nearly featureless, slowly varying, or dominated by statistical noise carry little information about the analytic structure of the function and therefore provide only weak constraints on its continuation [75, 117].

From this perspective, the quality of an analytic continuation is not determined solely by the length of the imaginary-time interval or the number of sampled points, but rather by how sensitively the data reflect the underlying functional dependence. Correlation functions that display pronounced curvature, decay, or other nontrivial behavior in imaginary time impose stronger constraints on the continuation than those that are nearly linear or constant over the sampled range. Conversely, large statistical errors can obscure such features and further reduce the effective information content available for continuation.

While analytic continuation is often discussed in the context of purely imaginary-time data, the procedure is not fundamentally restricted to this case. More generally, analytic continuation may be performed from data known along contours in the complex-time plane, which may include combinations of imaginary and real time data [71, 118, 119]. In such formulations, additional information obtained away from the imaginary axis can, in principle, improve the conditioning of the continuation problem by providing stronger constraints on the analytic structure of the underlying function. However, in practice, acquiring reliable data at complex times is often challenging, and the benefits depend sensitively on the accuracy and coverage of the sampled domain.

A variety of numerical techniques have been developed to address the ill-posed nature of analytic continuation, each introducing regularization or additional constraints to stabilize the inversion. Maximum Entropy (MaxEnt) methods formulate analytic continuation as a Bayesian inference problem in which a spectral function is chosen to maximize the information entropy subject to consistency with the imaginary-time data. This approach incorporates prior knowledge such as positivity and sum rules and is among the most widely used and robust methods for spectra extraction, although it can sometimes oversmooth fine features of the spectrum [71–76, 120]. Padé approximants reconstruct the Green’s function or correlation function by fitting a rational function (ratio of polynomials) to the imaginary-time or Matsubara data and analytically continuing this fit to real frequencies. When data are highly precise, Padé can capture sharper spectral structures, but it is particularly sensitive to statistical noise and can produce spurious poles, limiting its reliability for typical Monte Carlo results [73, 77, 116, 121]. Stochastic continuation techniques parametrize the spectral function using an ensemble of basis functions, such as delta functions, and sample this space using Monte Carlo or other statistical criteria, generating an average spectrum along with an uncertainty estimate. Such methods can resolve sharp features and provide explicit error quantification, but are more computationally intensive and require careful sampling strategies [122, 123].

The singular value decomposition (SVD) method provides a linear-algebraic approach to regularization. The Kernel matrix is decomposed into singular values and corresponding vectors. By discarding the contributions associated with small singular values that amplify noise, one obtains a regularized estimate of the spectral function. Schematically, this can be expressed as

$$G = \mathbf{K} \cdot \rho \xrightarrow{\text{SVD: } \mathbf{K}=\mathbf{U}\mathbf{\Sigma}\mathbf{V}^T} \rho_{\text{reg}} = \sum_i \frac{\mathbf{U}_i^T \cdot G}{\sigma_i} \mathbf{V}_i, \quad \sigma_i > \sigma_{\text{cut}}, \quad (2.164)$$

where vector G holds discretized imaginary time data, ρ is unknown spectral density and kernel matrix $\mathbf{K}$ is decomposed into orthogonal matrices $\mathbf{U}$ and $\mathbf{V}$ and diagonal matrix $\mathbf{\Sigma}$ whose entries are called singular values σ_i . The regularized spectral density ρ_{reg} is obtained by summing only over singular values larger than the cut-off σ_{cut} , effectively filtering out components that would otherwise amplify noise of data contained in G [66, 74, 115, 124, 125]. Among these methods, SVD provides a transparent and flexible regularization framework that will be exploited in the context of Kubo formula in the next chapter of this thesis.

More recent developments include Bayesian parametric analytic continuation, sparse modeling techniques, and machine-learning or neural-network approaches, which introduce alternative regularization strategies beyond classic MaxEnt or Padé methods [126–130]. Each technique has strengths

and limitations, depending on quality of the input data and the functional features of the underlying correlation function. Nevertheless, all these approaches illustrate the central challenge of analytic continuation which is balancing fidelity to noisy or incomplete input data with the stability and physical plausibility of the continued solution. The choice of continuation method and the handling of statistical noise are therefore crucial considerations in any practical implementation.

Chapter 3

Path-Integral Quantum Monte Carlo method for obtaining polaron mobility

The evaluation of charge transport properties in electron–phonon coupled systems requires a framework that connects microscopic dynamics with experimentally measurable quantities such as electrical conductivity and mobility. Within linear response theory (Sec. 2.2), these transport coefficients are expressed in terms of current–current correlation functions. In the present work, the microscopic description is provided by the Holstein model (Sec. 2.1), while the corresponding quantum statistical problem is formulated within the path-integral approach introduced in Sec. 2.4.

The central quantity of interest is the current–current correlation function, which encodes the transport properties of the system. In interacting electron–phonon systems, this quantity cannot generally be evaluated analytically, which requires the use of numerical methods. As discussed in Sec. 2.5.1, path-integral quantum Monte Carlo provides a numerically exact approach for computing such correlation functions at finite temperature. Here, this framework is extended to evaluate both real-time and imaginary-time correlation functions within a unified formalism, enabling access to dynamical properties relevant for charge transport. Based on this formulation, the current–current correlation function of the Holstein polaron is evaluated through stochastic sampling, and the corresponding carrier mobility is obtained either by direct integration or by analytic continuation.

The first step of this procedure is the construction of a path-integral representation of the current–current correlation function. This is achieved by expressing the quantum evolution operators in a discretized form using the Trotter–Suzuki decomposition, which allows the exponential of the Hamiltonian to be factorized into short-time propagators corresponding to its non-commuting components. Within this representation, two complementary formulations are considered, corresponding to the choice of basis for the electronic degrees of freedom: the electron momentum basis and the electron position basis. Although these formulations are formally equivalent, the choice of basis influences the statistical properties of the Monte Carlo sampling, leading to different levels of numerical efficiency and uncertainty.

The second step involves the extraction of transport coefficients from the computed correlation functions. In the present approach, both real-time and imaginary-time correlation functions are obtained. However, the accessible real-time interval is limited by the dynamical sign problem, which restricts the direct evaluation of long-time behavior of correlation functions. To address this limitation, the real-time data are complemented by imaginary-time data. The charge carrier mobility is then extracted from the combined real and imaginary correlation function data using an analytic continuation procedure. This procedure plays a central role in the methodology and is outlined in the main text, while its technical details are presented in Appendix B.

The numerical implementation is based on stochastic sampling of electron trajectories within the path-integral formalism. The Monte Carlo scheme used to evaluate the current–current correlation function was developed specifically for this work. Detailed aspects of the implementation, including the simulation algorithm and its numerical realization, are presented in Appendix C.

3.1 Path integral representation for current-current correlation functions

The starting point of the calculation is the current–current correlation function, defined as the thermal expectation value of the product of current operators evaluated at different times,

$$C(t) = \langle j(t)j(0) \rangle = Z^{-1} \text{Tr} \left[e^{-\beta H} e^{iHt} j e^{-iHt} j \right], \quad (3.1)$$

where $Z = \text{Tr}(\exp(-\beta H))$ is the partition function, $\beta = 1/T$ is the inverse temperature and

$$j(t) = e^{iHt} j e^{-iHt}, \quad (3.2)$$

denotes the current operator in the Heisenberg picture with $j(0) \equiv j$.

To obtain a representation suitable for numerical evaluation, this expression is reformulated within the path-integral framework by discretizing both imaginary- and real-time evolution. This is achieved using the Trotter–Suzuki decomposition [57, 131],

$$e^{H_1+H_2+\dots+H_P} = \lim_{n \rightarrow \infty} \left[e^{H_1/n} e^{H_2/n} \dots e^{H_P/n} \right]^n, \quad (3.3)$$

where H_p denote generally non-commuting contributions to the Hamiltonian. This decomposition allows the exponential of the Hamiltonian to be expressed as a product of short-time evolution operators.

The physical system considered consists of a single electron interacting locally with lattice vibrations and is described by the Holstein model. Throughout this chapter, a system of units is used in which the lattice constant a and the fundamental constants $\hbar$, e_0 and k_B are equal to unity, and periodic boundary conditions are assumed. In the presentation of results, energies are expressed in units of the electronic transfer integral J , which sets the natural energy scale of the problem.

The Holstein Hamiltonian, introduced in Sec. 2.1, is written as the sum of the electronic, phononic, and electron–phonon interaction contributions. In order to apply the Trotter–Suzuki decomposition, it is convenient to rewrite the Hamiltonian in a form that separates contributions according to their operator structure,

$$H = H_0 + H_1 + H_2, \quad (3.4a)$$

$$H_0 = \sum_n \frac{P_n^2}{2M}, \quad (3.4b)$$

$$H_1 = \sum_n \left(\sqrt{2M\omega_n} G c_n^\dagger c_n X_n + \frac{1}{2} M \omega_n^2 X_n^2 \right), \quad (3.4c)$$

$$H_2 = -J \sum_n \left(c_n^\dagger c_{n+1} + c_{n+1}^\dagger c_n \right). \quad (3.4d)$$

This representation enables efficient evaluation of the short-time propagators. Here, the index n runs from 0 to $N-1$, where N is the number of lattice sites. The parameter J denotes the electronic transfer integral between neighboring sites. The operators $c_n^\dagger$ (c_n) are electron creation and annihilation operators, while X_n and P_n are phonon position and momentum operators. The phonon frequency at site n is denoted by ω_n and M is the oscillator mass. The electron-phonon interaction strength is represented by constant G .

The term H_2 is diagonal in electron momentum representation and can be written as

$$H_2 = \sum_k \varepsilon(k) c_k^\dagger c_k, \quad (3.5)$$

where the bare electronic dispersion is given as $\varepsilon(k) = -2J \cos(k)$.

To discretize the problem, the imaginary-time interval of length β and the real-time interval of length t are divided into small slices. Using the Trotter–Suzuki decomposition, the correlation function is expressed as a trace over a sequence of short-time evolutions. This discretized formulation maps the quantum-mechanical problem onto a multidimensional integral over configurations defined along a contour consisting of imaginary and real time segments, which can be evaluated using Monte Carlo sampling.

3.1.1 Path integral with momentum representation for electrons

In order to construct the path-integral representation, a specific basis is chosen in which the short-time evolutions can be evaluated efficiently. In the present case, a mixed representation is used, consisting of electron momentum states and phonon states in the coordinate representation,

$$|q; \{X_n\}\rangle \equiv |q\rangle |\{X_n\}\rangle. \quad (3.6)$$

The electron momentum takes discrete values $q = 2n\pi/N$, while the phonon coordinates are continuous real variables $X_n \in \mathbb{R}$.

To obtain a form suitable for numerical evaluation of current-current correlation function given with Eq. (3.1), the imaginary-time interval β is divided into m subintervals, while the real-time interval t is divided into Q subintervals. The corresponding time steps are defined as $\tau = \beta/m$ and $\Delta t = t/Q$.

Applying the Trotter–Suzuki decomposition to the correlation function, the trace can be expressed as

$$\langle j(t)j \rangle = \lim_{m, Q \rightarrow \infty} Z_m^{-1} \text{Tr} \left[\left(e^{-\tau H_0} e^{-\tau H_1} e^{-\tau H_2} \right)^m \left(e^{i\Delta t H_0} e^{i\Delta t H_1} e^{i\Delta t H_2} \right)^Q j \left(e^{-i\Delta t H_0} e^{-i\Delta t H_1} e^{-i\Delta t H_2} \right)^Q j \right], \quad (3.7)$$

where $\lim_{m \rightarrow \infty} Z_m = Z$.

In this representation, the correlation function is expressed as a product of short-time evolution operators, which enables the subsequent insertion of resolutions of identity in the chosen basis and the construction of the path-integral formulation

The trace of an operator O and the completeness relation in the basis defined in Eq. (3.6) are given by

$$\text{Tr}(O) = \sum_{q \in BZ} \int \left(\prod_{n=0}^{N-1} dX_n \right) \langle \{X_n\}; q | O | q; \{X_n\} \rangle, \quad (3.8a)$$

$$1 = \sum_{q \in BZ} \int \left(\prod_{n=0}^{N-1} dX_n \right) |q; \{X_n\}\rangle \langle \{X_n\}; q|. \quad (3.8b)$$

The trace from expression (3.7) from now on will be denoted with $C_{jj}^{m,Q}$. By using Eq. (3.8a) it can be written as

$$C_{jj}^{m,Q} = \sum_{q \in BZ} \int \left(\prod_{n=0}^{N-1} dX_n^0 \right) \langle \{X_n^0\}; q_0 | (\rho(-\tau))^m (\rho(i\Delta t))^Q j (\rho(-i\Delta t))^Q j | q_0; \{X_n^0\} \rangle, \quad (3.9)$$

where the introduction of index "0" on electron momentum and phonon coordinate variables will be clarified in following text. The shorthand notation was introduced for exponential operators

$$\rho(z) = e^{zH_0} e^{zH_1} e^{zH_2}, \quad (3.10)$$

where $z = -\tau, -i\Delta t, i\Delta t$ is the complex time variable.

For notational convenience, the phonon coordinates and integration measure are denoted as

$$\{X_n^i\} \rightarrow X^i,$$

$$\prod_{n=0}^{N-1} dX_n^i \rightarrow DX^i.$$

To evaluate the trace, resolutions of identity given in Eq. (3.8b) are inserted between all operators $\rho(z)$ and j . This procedure introduces independent integration variables at each time slice and transforms the trace into a multidimensional sum and integral over all intermediate configurations. As a result, the correlation function takes the form

$$\begin{aligned} C_{jj}^{m,Q} = & \sum_{q_0, \dots, q_{m+2Q+1}} \int \prod_{i=0}^{m-1} DX^i \prod_{p=m}^{m+Q} DX^p \prod_{l=m+Q+1}^{m+2Q+1} DX^l \left(\prod_{i=0}^{m-1} \langle X^i; q_i | \rho(-\tau) | q_{i+1}; X^{i+1} \rangle \right) \\ & \left(\prod_{p=m}^{m+Q-1} \langle X^p; q_p | \rho(i\Delta t) | q_{p+1}; X^{p+1} \rangle \right) \langle X^{m+Q}; q_{m+Q} | j | q_{m+Q+1}; X^{m+Q+1} \rangle \\ & \left(\prod_{l=m+Q+1}^{m+2Q} \langle X^l; q_l | \rho(-i\Delta t) | q_{l+1}; X^{l+1} \rangle \right) \langle X^{m+2Q+1}; q_{m+2Q+1} | B | q_0; X^0 \rangle, \end{aligned} \quad (3.11)$$

where the resolutions of identity are indexed in increasing order as "1", "2", ..., "m + 2Q + 1" from left to right.

The matrix elements appearing in the above expression can now be evaluated. Since the current operator acts only on the electronic degrees of freedom, it does not affect the phonon coordinates. As a result, the matrix elements factorize as

$$\langle X^{m+Q}; q_{m+Q} | j | q_{m+Q+1}; X^{m+Q+1} \rangle = \prod_{n=0}^{N-1} \delta(X_n^{m+Q+1} - X_n^{m+Q}) \langle q_{m+Q} | j | q_{m+Q+1} \rangle, \quad (3.12a)$$

$$\langle X^{m+2Q+1}; q_{m+2Q+1} | j | q_0; X^0 \rangle = \prod_{n=0}^{N-1} \delta(X_n^0 - X_n^{m+2Q+1}) \langle q_{m+2Q+1} | j | q_0 \rangle. \quad (3.12b)$$

The current operator in the momentum representation is given by

$$j = -2J \sum_k c_k^\dagger c_k \sin(k), \quad (3.13)$$

where $c_k^\dagger$ (c_k) are electron creation (annihilation) operators in momentum space. The diagonal structure of the current operator in momentum space significantly simplifies the evaluation of the corresponding matrix elements which take the form

$$\begin{aligned} \langle q_{m+Q} | j | q_{m+Q+1} \rangle &= -2J \sin(q_{m+Q+1}) \delta_{q_{m+Q}, q_{m+Q+1}}, \\ \langle q_{m+2Q+1} | j | q_0 \rangle &= -2J \sin(q_0) \delta_{q_0, q_{m+2Q+1}}. \end{aligned} \quad (3.14)$$

To evaluate the matrix elements of the form $\langle X^i; q_i | \rho(z) | q_{i+1}; X^{i+1} \rangle$, it is necessary to determine how the exponential operators act on the chosen basis states.

The operator e^{zH_2} acts only on the electronic degrees of freedom and is diagonal in the momentum representation. Its action is given by

$$e^{zH_2} | q_{i+1}; X^{i+1} \rangle = e^{z\varepsilon(q_{i+1})} | q_{i+1}; X^{i+1} \rangle, \quad (3.15)$$

where $\varepsilon(q)$ is the electronic dispersion.

The operator e^{zH_1} , which contains the e-ph interaction and phonon potential terms, is diagonal in the phonon coordinate representation but couples different electronic momentum states. Its action on the basis states can be written as

$$e^{zH_1}|q_{i+1}; X^{i+1}\rangle = e^{z\frac{M}{2}\sum_n \omega_n^2 (X_n^{i+1})^2} \frac{1}{N} \sum_k \sum_r e^{-ir\cdot(q_{i+1}-k)+z\sum_n \sqrt{2M\omega_n} G X_n^{i+1} \delta_{n,m}} |k; X^{i+1}\rangle. \quad (3.16)$$

Since the operator e^{zH_0} depends the phonon momentum, its action is most conveniently evaluated in the momentum representation of the phonon degrees of freedom. This requires inserting a resolution of identity in the phonon momentum basis. After performing the resulting Gaussian integration over the phonon momenta, the matrix elements can be expressed in terms of the phonon coordinates alone. The resulting expressions for matrix elements entering $C_{jj}^{m,Q}$ take the form

$$\langle X^i; q_i | \rho(-\tau) | q_{i+1}; X^{i+1} \rangle = C_1 f_{q_{i+1}, q_i}(-\tau; X^{i+1}) e^{-\tau \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{i+1})^2 + \frac{M}{2} \frac{(X_n^{i+1} - X_n^i)^2}{\tau^2} \right)}, \quad (3.17)$$

$$\langle X^p; q_p | \rho(i\Delta t) | q_{p+1}; X^{p+1} \rangle = C_2 f_{q_{p+1}, q_p}(i\Delta t; X^{p+1}) e^{i\Delta t \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} \right)}, \quad (3.18)$$

$$\langle X^l; q_l | \rho(-i\Delta t) | q_{l+1}; X^{l+1} \rangle = C_3 f_{q_{l+1}, q_l}(-i\Delta t; X^{l+1}) e^{i\Delta t \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{l+1})^2 + \frac{M}{2} \frac{(X_n^{l+1} - X_n^l)^2}{(i\Delta t)^2} \right)}, \quad (3.19)$$

where C_1, C_2 and C_3 are constants arising from the Gaussian integration over phonon momenta.

The functions $f_{q_i, q_j}(z; X^i)$ can be interpreted as effective fermionic propagators between momentum states q_i and q_j over a time interval z , which may correspond to either imaginary or real time. They are given by

$$f_{q_i, q_j}(z; X^i) = e^{z\varepsilon(q_i)} \frac{1}{N} \sum_m e^{-im\cdot(q_i - q_j) + z\sqrt{2M\omega_m} G X_m^i}. \quad (3.20)$$

This function describes the propagation of an electron coupled to lattice vibrations, i.e. a dressed (polaronic) quasiparticle, with the propagation amplitude determined by the instantaneous phonon configuration at a given time slice.

The path-integral representation of the correlator $C_{jj}^{m,Q}$ can now be written in the form

$$\begin{aligned} C_{jj}^{m,Q} = & C \int \prod_{i=0}^{m-1} DX^i \prod_{p=m}^{m+Q} DX^p \prod_{l=m+Q+1}^{m+2Q+1} DX^l e^{-S_1[\tau; X^i]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^l]} \times \\ & \times \sum_{\{q\}} \prod_{i=0}^{m-1} f_{q_{i+1}, q_i}(-\tau; X^{i+1}) \prod_{p=m}^{m+Q-1} f_{q_{p+1}, q_p}(i\Delta t; X^{p+1}) \prod_{l=m+Q+1}^{m+2Q} f_{q_{l+1}, q_l}(-i\Delta t; X^{l+1}) \times \\ & \times \langle X^{m+Q}; q_{m+Q} | j | q_{m+Q+1}; X^{m+Q+1} \rangle \langle X^{m+2Q+1}; q_{m+2Q+1} | j | q_0; X^0 \rangle, \end{aligned} \quad (3.21)$$

where C is a constant resulting from the Gaussian integration over phonon momenta, and $\sum_{\{q\}}$ denotes summation over all intermediate momentum variables.

The exponential terms define an effective discretized phonon action along the contour composed of imaginary-time evolution, followed by forward and backward real-time propagation. The corresponding contributions are given by

$$\begin{aligned} S_1[\tau; X^i] &= \tau \sum_{i=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{i+1})^2 + \frac{M}{2} \frac{(X_n^{i+1} - X_n^i)^2}{\tau^2} \right], \\ S_2[-i\Delta t; X^p] &= -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} \right], \\ S_3[i\Delta t; X^l] &= i\Delta t \sum_{l=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{l+1})^2 + \frac{M}{2} \frac{(X_n^{l+1} - X_n^l)^2}{(i\Delta t)^2} \right]. \end{aligned} \quad (3.22)$$

This representation provides the basis for the Monte Carlo evaluation of the correlation function.

In order to obtain a form suitable for numerical calculation, the trace $C_{jj}^{m,Q}$ is rewritten in a compact matrix form by introducing a vector variable that collects all phonon coordinates along the discretized contour,

$$C_{jj}^{m,Q} = C \int \mathbf{D}\mathbf{Y} \, e^{-\frac{1}{2}\mathbf{Y}^T \mathcal{D}\mathbf{Y}} F(\mathbf{Y}), \quad (3.23)$$

where the vector $\mathbf{Y}$ is defined as

$$\begin{aligned} \mathbf{Y} &= (Y^0, Y^1, \dots, Y^{m+2Q-1})^T \\ &= (X^1, X^2, \dots, X^{m+Q-1}, X^{m+Q+1}, \dots, X^{m+2Q-1}, X^{m+2Q}, X^0)^T. \end{aligned} \quad (3.24)$$

The identification of variables, such as $X^{m+Q} = X^{m+Q+1}$, follows from the delta functions in Eqs. (3.12a) and (3.12b). Each component X^j (and correspondingly Y^j) is itself an N -dimensional vector,

$$X^j = (X_0^j, X_1^j, \dots, X_{N-1}^j)^T. \quad (3.25)$$

The matrix $\mathcal{D}$ represents the discretized phonon action in the coordinate basis $\mathbf{Y}$ and its explicit form can be derived from Eq. (3.21).

An analogous change of variables is introduced for the electronic momentum indices,

$$(k^0, k^1, \dots, k^{m+2Q-1})^T = (q^1, q^2, \dots, q^{m+Q-1}, q^{m+Q+1}, \dots, q^{m+2Q-1}, q^{m+2Q}, q^0)^T \quad (3.26)$$

In this representation, the function $F(\mathbf{Y})$ is given by

$$\begin{aligned} F(\mathbf{Y}) &= \sum_{k_0} \cdots \sum_{k_{m+2Q-1}} f_{k_0, k_{m+2Q-1}}(-\tau; Y^0) \prod_{i=1}^{m-1} f_{k_i, k_{i-1}}(-\tau; Y^i) \prod_{p=m}^{m+Q-2} f_{k_p, k_{p-1}}(i\Delta t; Y^p) \times \\ &\times \tilde{f}_{k_{m+Q-1}, k_{m+Q-2}}(i\Delta t; Y^{m+Q-1}) \prod_{l=m+Q}^{m+2Q-2} f_{k_l, k_{l-1}}(-i\Delta t; Y^l) \tilde{f}_{k_{m+2Q-1}, k_{m+2Q-2}}(-i\Delta t; Y^{m+2Q-1}), \end{aligned} \quad (3.27)$$

where

$$\tilde{f}_{k_j, k_l}(z; Y^j) = -2J \sin(k_j) f_{k_j, k_l}(z; Y^j). \quad (3.28)$$

To evaluate the real-time correlation function, the following estimator is used:

$$\langle j(t)j \rangle^{m,Q} = \frac{1}{C_{11}^{m,Q}} C_{jj}^{m,Q} \quad (3.29)$$

where $C_{11}^{m,Q}$ is obtained from (3.21) by replacing the current operator with the identity operator. This quantity serves as a normalization factor. In this formulation, the constant C cancels between numerator and denominator and does not need to be evaluated explicitly.

For sufficiently large values of m and Q , the estimator converges to the real correlation function $\langle j(t)j \rangle$.

The integrals appearing in $C_{jj}^{m,Q}$ are evaluated using a Monte Carlo approach by sampling configurations of the phonon variables according to the quadratic form defined by the phonon action,

$$S[\mathbf{Y}] = \frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y}. \quad (3.30)$$

The matrix $\mathcal{D}$ is a complex symmetric with positive definite real part, which ensures that the corresponding Gaussian form is well-defined. In the present formulation, the matrix $\mathcal{D}$ is found to be diagonalizable, yielding a decomposition of the form

$$\mathcal{D} = Q \Lambda Q^T, \quad (3.31)$$

where Λ is a diagonal matrix containing the eigenvalues of $\mathcal{D}$, and $QQ^T = I$, i.e. Q is a complex orthogonal matrix whose columns are the corresponding eigenvectors. This decomposition is used to transform the quadratic form into a sum of independent contributions, enabling efficient sampling of phonon configurations. The validity of this decomposition has been verified numerically for the matrices appearing in the calculation.

Introducing the change of variables

$$\mathbf{Z} = \Lambda^{1/2} Q^T \mathbf{Y}, \quad (3.32)$$

the quadratic form becomes

$$\mathbf{Y}^T \mathcal{D} \mathbf{Y} = \mathbf{Y}^T Q \Lambda Q^T \mathbf{Y} = \mathbf{Z}^T \mathbf{Z} = \sum_k Z_k^2. \quad (3.33)$$

In this representation, the components Z_k are independent variables and can be sampled directly. The original variables $\mathbf{Y}$ are then obtained via the inverse transformation

$$\mathbf{Y} = Q \Lambda^{-1/2} \mathbf{Z}. \quad (3.34)$$

Once a configuration $\mathbf{Y}$ is generated, the function $F(\mathbf{Y})$ can be evaluated. The summation over electronic momenta in $F(\mathbf{Y})$ can be expressed as the trace over products of matrices, leading to the representation

$$F(\mathbf{Y}) = \text{Tr} \left[\mathcal{F}(-\tau; Y^0) \cdot \mathcal{F}(-\tau; Y^1) \dots \mathcal{F}(-\tau; Y^{m-1}) \cdot \mathcal{F}(i\Delta t; Y^m) \dots \mathcal{F}(i\Delta t; Y^{m+Q-2}) \cdot \mathcal{G}(i\Delta t; Y^{m+Q-1}) \cdot \mathcal{F}(-i\Delta t; Y^{m+Q}) \dots \mathcal{F}(-i\Delta t; Y^{m+2Q-2}) \cdot \mathcal{G}(-i\Delta t; Y^{m+2Q-1}) \right], \quad (3.35)$$

where the matrices are defined as

$$\begin{aligned} [\mathcal{F}(-\tau; Y^k)]_{l,j} &= e^{-\tau \varepsilon (2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} - \tau \sqrt{2M\omega_n} G Y_n^k}, \\ [\mathcal{G}(i\Delta t; Y^{m+Q-1})]_{l,j} &= -2J \sin(2\pi j/N) e^{i\Delta t \varepsilon (2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} + i\Delta t \sqrt{2M\omega_n} G Y_n^{m+Q-1}}, \\ [\mathcal{G}(-i\Delta t; Y^{m+2Q-1})]_{l,j} &= -2J \sin(2\pi j/N) e^{-i\Delta t \varepsilon (2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} - i\Delta t \sqrt{2M\omega_n} G Y_n^{m+2Q-1}}. \end{aligned} \quad (3.36)$$

In the case of $C_{11}^{m,Q}$ the matrices $\mathcal{G}$ are replaced by the matrices $\mathcal{F}$.

This completes the construction of the path-integral representation in the momentum basis. The detailed evaluation of the exponential operator actions and the explicit construction of the matrix $\mathcal{D}$ are provided in Appendix A.

3.1.2 Path integral with position representation for electrons

In this case, a basis consisting of direct product states of electron position and phonon coordinates is used,

$$|r; \{X_n\}\rangle \equiv |r\rangle |\{X_n\}\rangle, \quad (3.37)$$

where the electron position index takes values $r = 0, \dots, N-1$, and the phonon coordinates satisfy $X_n \in \mathbb{R}$.

The expressions for the trace of an operator O and the resolution of identity in this basis are given by

$$\text{Tr}(O) = \sum_r \int \left(\prod_{n=0}^{N-1} dX_n \right) \langle \{X_n\}; r | O | r; \{X_n\} \rangle, \quad (3.38a)$$

$$1 = \sum_r \int \left(\prod_{n=0}^{N-1} dX_n \right) |r; \{X_n\} \rangle \langle \{X_n\}; r|. \quad (3.38b)$$

Following the same procedure as in the previous subsection, the trace $C_{jj}^{m,Q}$ can be written in a form analogous to Eq. (3.11),

$$\begin{aligned} C_{jj}^{m,Q} = & \sum_{r_0, \dots, r_{m+2Q+1}} \int \left(\prod_{j=0}^{m-1} DX^j \right) \left(\prod_{p=m}^{m+Q} DX^p \right) \left(\prod_{l=m+Q+1}^{m+2Q+1} DX^l \right) \left(\prod_{j=0}^{m-1} \langle X^j; r_j | \rho(-\tau) | r_{j+1}; X^{j+1} \rangle \right) \times \\ & \times \left(\prod_{p=m}^{m+Q-1} \langle X^p; r_p | \rho(i\Delta t) | r_{p+1}; X^{p+1} \rangle \right) \langle X^{m+Q}; r_{m+Q} | j | r_{m+Q+1}; X^{m+Q+1} \rangle \times \\ & \times \left(\prod_{l=m+Q+1}^{m+2Q} \langle X^l; r_l | \rho(-i\Delta t) | r_{l+1}; X^{l+1} \rangle \right) \langle X^{m+2Q+1}; r_{m+2Q+1} | j | r_0; X^0 \rangle. \end{aligned} \quad (3.39)$$

Evaluating the matrix elements and taking into account that the current operator acts only on the electronic degrees of freedom, the expression simplifies to

$$\begin{aligned} C_{jj}^{m,Q} = & C \sum_{r_0, \dots, r_{m+2Q+1}} \langle r_{m+Q} | j | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | j | r_0 \rangle \left(\prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \right) \times \\ & \times \left(\prod_{p=m}^{m+Q-1} I(-i\Delta t; r_{p+1} - r_p) \right) \left(\prod_{l=m+Q+1}^{m+2Q} I(i\Delta t; r_{l+1} - r_l) \right) \times \\ & \times \int \left(\prod_{j=0}^{m-1} DX^j \right) \left(\prod_{p=m}^{m+Q-1} DX^p \right) \left(\prod_{l=m+Q+1}^{m+2Q} DX^l \right) e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^l]}. \end{aligned} \quad (3.40)$$

The corresponding phonon actions are given by

$$\begin{aligned} S_1[\tau; X^j] = & \tau \sum_{j=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} + \sqrt{2M\omega_n} G \delta_{n,r_j} X_n^{j+1} \right], \\ S_2[-i\Delta t; X^p] = & -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} + \sqrt{2M\omega_n} G \delta_{n,r_p} X_n^{p+1} \right], \\ S_3[i\Delta t; X^l] = & i\Delta t \sum_{l=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{l+1})^2 + \frac{M}{2} \frac{(X_n^{l+1} - X_n^l)^2}{(i\Delta t)^2} + \sqrt{2M\omega_n} G \delta_{n,r_l} X_n^{l+1} \right]. \end{aligned} \quad (3.41)$$

The constant C results from Gaussian integration in the matrix elements.

The main difference in this representation is the appearance of the functions $I(z; r_{j+1} - r_j)$, which correspond to electron propagators transformed to coordinate space. In contrast to the momentum representation, where the propagators $f_{q_i, q_j}(z; X^i)$ depend explicitly on the phonon coordinates, the functions $I(z; r_{j+1} - r_j)$ are independent of the phonon variables. This property allows the integration over phonon coordinates in Eq. (3.40) to be carried out analytically.

These Fourier-transformed propagators are defined as

$$I(z; r_{j+1} - r_j) = \frac{1}{N} \sum_{k=0}^{N-1} \cos\left(\frac{2\pi}{N} k(r_{j+1} - r_j)\right) \exp(2zJ \cos(2\pi k/N)) . \quad (3.42)$$

As in the previous subsection, a vector variable for the phonon coordinates is introduced, allowing the expression to be written as

$$\begin{aligned} f(\{r\}) &= \int \left(\prod_{j=0}^{m-1} DX^j \right) \left(\prod_{p=m}^{m+Q-1} DX^p \right) \left(\prod_{l=m+Q+1}^{m+2Q} DX^l \right) e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^l]} \\ &= \int D\mathbf{Y} e^{-S[\mathbf{Y}]} \end{aligned} \quad (3.43)$$

where $\mathbf{Y}$ is defined in Eq. (3.24). The resulting action takes the form of a quadratic expression with an additional linear term,

$$S[\mathbf{Y}] = \frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y} + \mathbf{Y}^T \mathbf{d} , \quad (3.44)$$

where the vector $\mathbf{d}$ contains the contributions arising from the electron–phonon interaction terms in the actions given in Eq. (3.41).

To evaluate the integral over phonon coordinates, a shift of variables is introduced,

$$\mathbf{Z} = \mathbf{Y} + \mathcal{D}^{-1} \mathbf{d} , \quad (3.45)$$

which leaves the integration measure invariant. The action then transforms as

$$-\frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y} - \mathbf{Y}^T \cdot \mathbf{d} = -\frac{1}{2} \mathbf{Z}^T \mathcal{D} \mathbf{Z} + \frac{1}{2} \mathbf{d}^T \mathcal{D}^{-1} \mathbf{d} . \quad (3.46)$$

The integral over phonon coordinates can now be evaluated in closed form,

$$f(\{r\}) = \exp\left(\frac{1}{2} \mathbf{d}^T \mathcal{D}^{-1} \mathbf{d}\right) \int D\mathbf{Z} \exp\left(-\frac{1}{2} \mathbf{Z}^T \mathcal{D} \mathbf{Z}\right) , \quad (3.47)$$

yielding

$$f(\{r\}) = (2\pi)^{\frac{N_{\text{tot}}}{2}} [\det(\mathcal{D})]^{-\frac{1}{2}} \exp\left(\frac{1}{2} \mathbf{d}^T \mathcal{D}^{-1} \mathbf{d}\right) , \quad (3.48)$$

where $N_{\text{tot}} = (m + 2Q)N$ denotes the total number of phonon degrees of freedom in the vector $\mathbf{Y}$. Since the matrix $\mathcal{D}$ is complex symmetric with a positive definite real part, the integral is well-defined and yields the standard expression proportional to $[\det(\mathcal{D})]^{-1/2}$. This result is obtained by analytic continuation of the standard Gaussian integral for real symmetric positive-definite matrices [79].

This analytical integration over phonon coordinates reduces the problem to a sum over electron trajectories, which forms the basis of the Monte Carlo sampling in the position representation.

The trace $C_{jj}^{m,Q}$ can be written in the form:

$$C_{jj}^{m,Q} = C \sum_{\{r\}} w(\{r\}) F(\{r\}) , \quad (3.49)$$

where the weight function $w(\{r\})$ is real and non-negative, while the function $F(\{r\})$ contains the remaining phase factors and contributions arising from the current operators and the electron–phonon interaction. These functions are defined as

$$w(\{r\}) = \left(\prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \right) \left(\prod_{p=m}^{m+Q-1} |I(-i\Delta t; r_{p+1} - r_p)| \right) \left(\prod_{l=m+Q+1}^{m+2Q} |I(i\Delta t; r_{l+1} - r_l)| \right) , \quad (3.50)$$

$$F(\{r\}) = \langle r_{m+Q} | j | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | j | r_0 \rangle \exp \left(\frac{1}{2} \mathbf{d}(\{r\})^T \cdot \mathcal{D}^{-1} \cdot \mathbf{d}(\{r\}) \right) \\ \times \prod_{p=m}^{m+Q-1} e^{i\phi(-i\Delta t; r_{p+1} - r_p)} \prod_{l=m+Q+1}^{m+2Q} e^{i\phi(i\Delta t; r_{l+1} - r_l)} , \quad (3.51)$$

where the residual phase is defined as $\phi(z; r_i - r_j) = \arg [I(z; r_i - r_j)]$.

The real-time correlation function is then evaluated using the same estimator $\langle j(t)j \rangle^{m,Q}$ as in the previous subsection. This representation allows the correlation function to be computed by Monte Carlo sampling over configurations $\{r\}$, which are interpreted as electron trajectories along the discretized time contour. Configurations are generated with probability proportional to the weight $w(\{r\})$, and the estimator is obtained by averaging the corresponding values of $F(\{r\})$. The locality of the weight function in terms of differences $r_{j+1} - r_j$ enables efficient sampling using local updates.

The matrix elements of the current operator,

$$j = iJ \sum_{n=0}^{N-1} \left(c_n^\dagger c_{n+1} - c_{n+1}^\dagger c_n \right) , \quad (3.52)$$

are nonzero only for nearest-neighbor positions. Explicitly,

$$\langle r_i | j | r_j \rangle = \begin{cases} iJ, & r_i = r_j - 1, \\ -iJ, & r_i = r_j + 1, \\ 0, & \text{otherwise,} \end{cases} \quad (3.53)$$

where the equalities are understood modulo N due to periodic boundary conditions.

The path integral representation in imaginary time is obtained by replacing the real-time evolution with imaginary-time evolution, $t \rightarrow -it$, which corresponds to the substitution $\Delta t \rightarrow -i\Delta t$ in the discretized real-time expressions. It should be emphasized that this imaginary-time step is distinct from the thermal imaginary time $\tau = \beta/m$ introduced through the Boltzmann factor.

In this case, the weight function from Eq. (3.50) reduces to

$$w(\{r\}) = \prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \prod_{p=m}^{m+Q-1} I(-\Delta t; r_{p+1} - r_p) \prod_{l=m+Q+1}^{m+2Q} I(\Delta t; r_{l+1} - r_l) , \quad (3.54)$$

so that all contributions are real and non-negative.

In addition, the matrix $\mathcal{D}$ becomes real symmetric and the residual phase factors vanish. This significantly simplifies the numerical evaluation as the sign problem is absent in imaginary time.

This completes the construction of the path-integral representation of the current–current correlation function in both real and imaginary time in the position basis. The explicit construction of the matrix $\mathcal{D}$, the vector $\mathbf{d}$, and the implementation details of the sampling procedures are presented in Appendices A and C.

3.2 Analytic continuation procedure for obtaining dc mobility

The path-integral quantum Monte Carlo methodology described in the previous section provides access to the current–current correlation function $\langle j(z)j(0) \rangle$ evaluated either at imaginary times ($z = -it$, $0 \leq t \leq \beta$) or at short real times ($z = t$, $t \geq 0$). The quantity of primary interest, however, is the dc mobility $\mu = \mu(\omega = 0)$. The relation between the correlation function and the frequency-dependent mobility $\mu(\omega)$ follows from the standard Kubo formalism introduced in Sec. 2.2.1,

$$\langle j(z)j(0) \rangle = \int_{-\infty}^{\infty} d\omega \frac{1}{\pi} \frac{\omega e^{-i\omega z}}{1 - e^{-\beta\omega}} \text{Re} \mu(\omega) . \quad (3.55)$$

In the quantum many-body literature, this problem is typically addressed by evaluating the correlation function in imaginary time, where the sign problem is absent, and subsequently performing analytic continuation in order to obtain $\text{Re}\mu(\omega)$. Among the analytic continuation methods discussed in Sec. 2.5.3, the singular value decomposition (SVD) method is adopted.

Particular emphasis is placed on the combined use of imaginary-time and real-time data within the analytic continuation procedure. In addition to imaginary-time correlation functions, real-time data are incorporated only over time intervals for which the sign problem is not yet pronounced, such that the correlation function can be evaluated with sufficient accuracy. The analytic continuation procedure is therefore constructed using both imaginary-time and short real-time information obtained from the path-integral Monte Carlo simulations. This combined approach constitutes an important aspect of the present work, as it improves the stability and resolution of the continuation procedure compared to the use of imaginary-time data alone.

Since the analytic continuation procedure was not developed as part of the original contribution of this thesis, its technical details are presented in Appendix B for completeness. The method and its implementation follow the approach developed by Nenad Vukmirović [132], while a concise overview is provided here.

The singular value decomposition (SVD) method is employed to perform the analytic continuation. Upon discretization of Eq. (3.55), the problem is reduced to a linear system of the form

$$\mathbf{j} = \mathbf{K} \cdot \mathbf{m}, \quad (3.56)$$

where $\mathbf{K}$ is a known kernel matrix obtained from the discretization of Eq. (3.55). The vector $\mathbf{j}$ contains the values of the current–current correlation function at the discretized time points, while the vector $\mathbf{m}$ represents the unknown discrete form of $\text{Re}\mu(\omega)$. All quantities can be expressed in terms of real numbers by separating real and imaginary parts, allowing the problem to be treated within a real-valued linear algebra framework.

Any real matrix admits a singular value decomposition of the form

$$\mathbf{K} = \mathbf{U}\mathbf{S}\mathbf{V}^T, \quad (3.57)$$

where $\mathbf{U}$ and $\mathbf{V}$ are orthogonal matrices, and $\mathbf{S}$ is a diagonal matrix whose entries s_k are the singular values. The solution for $\mathbf{m}$ can then be formally written as

$$\mathbf{m} = \sum_k \frac{\mathbf{U}_{:,k}^T \cdot \mathbf{j}}{s_k} \mathbf{V}_{:,k}, \quad (3.58)$$

where $\mathbf{U}_{:,k}^T$ and $\mathbf{V}_{:,k}$ are the k -th column vectors of matrix $\mathbf{U}^T$ and $\mathbf{V}$ respectively.

The main difficulty in reconstructing $\mathbf{m}$ from Eq. (3.58) arises from the presence of very small singular values. These lead to a strong amplification of statistical noise originating from Monte Carlo sampling, as well as numerical errors present in the data contained in the vector $\mathbf{j}$. In practice, the summation in Eq. (3.58) is therefore truncated, and only contributions corresponding to sufficiently large singular values are retained.

It should be emphasized that combining real- and imaginary-time data is not exclusive to the SVD approach and can likewise be integrated into other analytic continuation methods. The SVD approach is adopted here due to its transparency, which allows for a clear illustration of the intrinsic difficulties associated with the analytic continuation procedure.

The performance of the analytic continuation procedure, including the effect of singular value truncation and the role of real-time data, is demonstrated in the following subsection.

3.2.1 Assessment of the SVD analytic continuation procedure

In this subsection, the analytic continuation procedure is assessed using controlled test data. In order to evaluate the accuracy and limitations of the method, it is advantageous to consider a case in which

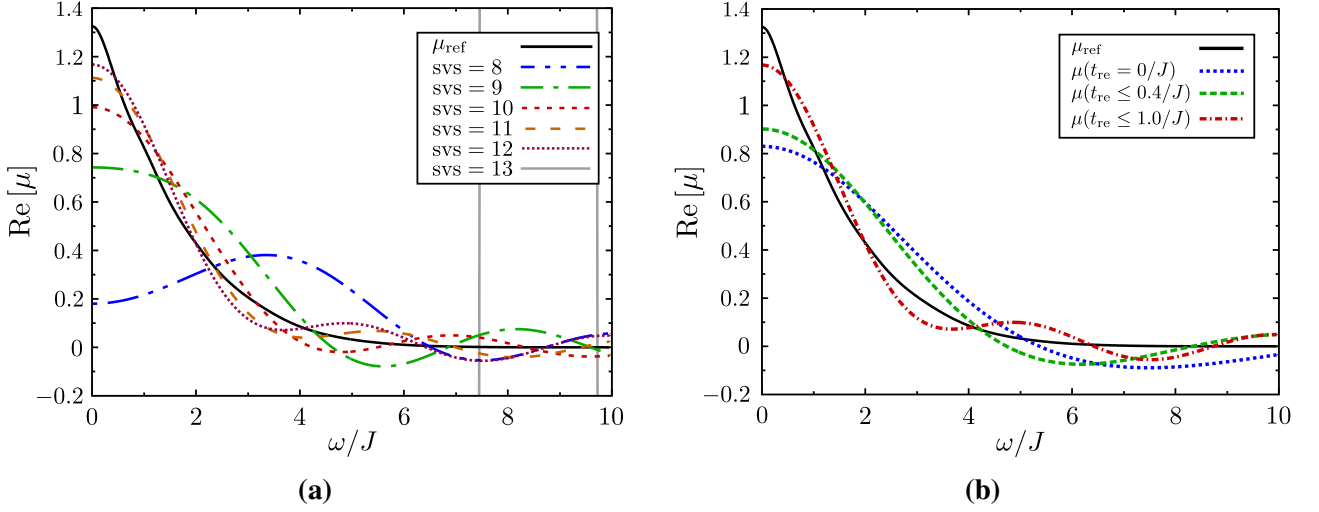


Figure 3.1: Examples illustrating the analytic continuation procedure. (a) Comparison between the reference mobility μ_{ref} and reconstructed results obtained using different numbers of singular values. (b) Comparison between μ_{ref} and reconstructed results obtained using imaginary-time data only (denoted as $\mu(t_{\text{re}} = 0)$), as well as using combined imaginary- and real-time data up to $t_{\text{re}} \leq 0.4/J$ and $t_{\text{re}} \leq 1/J$, respectively. Results are shown for $\omega_0/J = 1$, $G/J = 1$, and $T/J = 1$. Only positive frequencies are displayed, since $\text{Re}, \mu(\omega) = \text{Re}, \mu(-\omega)$.

the exact frequency dependence of the mobility is known. This allows a direct comparison between the reconstructed and exact results.

For this purpose, the procedure is not applied to Monte Carlo data. Instead, the frequency-dependent mobility obtained in Ref. [133] is used as a reference, denoted by μ_{ref} . Based on this reference mobility, the corresponding current–current correlation function is constructed in both imaginary and real time using Eq. (3.55). To mimic realistic conditions, statistical noise is then added to these data, with an amplitude comparable to that observed in the Monte Carlo simulations.

The analytic continuation procedure described in the previous section is subsequently applied to the noisy correlation function, yielding the reconstructed mobility $\text{Re}\mu_{\text{ac}}(\omega)$. By comparing $\text{Re}\mu_{\text{ac}}(\omega)$ with the reference result $\text{Re}\mu_{\text{ref}}(\omega)$, the performance of the continuation procedure can be quantitatively assessed. Since the primary quantity of interest is the dc mobility, particular attention is given to the value at $\omega = 0$.

The results are presented for model parameters $\omega_0/J = 1$, $G/J = 1$ and $T/J = 1$ in Fig. 3.1. This choice corresponds to an intermediate regime in which the electron–phonon coupling, phonon energy, and temperature are all of comparable magnitude, avoiding both weak- and strong-coupling limits as well as low- and high-temperature regimes. In Fig. 3.1a, the reconstruction is performed using imaginary-time data up to $0.6/J$ and real-time data up to $1/J$. The imaginary-time range is chosen to slightly exceed $\beta/2$, beyond which the correlation function does not provide additional independent information due to its symmetry in imaginary time. The real-time range is selected to reflect the typical time window accessible in Monte Carlo simulations, thereby mimicking the typical range over which reliable real-time data can be obtained in Monte Carlo simulations. In Fig. 3.1b, the same imaginary-time data are used, while the range of included real-time data is varied, as specified in the figure caption.

Figure 3.1a illustrates the effect of the number of singular values retained in the truncated sum of Eq. (3.58). If too many singular values are included (e.g., $\text{svs} = 13$), the reconstructed mobility becomes dominated by amplified noise. Conversely, if too few singular values are retained (e.g., $\text{svs} = 8, 9, 10$), the reconstruction lacks sufficient information and fails to reproduce the qualitative features of the reference mobility. In practice, an optimal choice corresponds to retaining the largest possible number of singular values before the onset of noise amplification.

Figure 3.1b demonstrates the effect of incorporating real-time data into the analytic continuation procedure. When only imaginary-time data are used, the reconstructed mobility deviates significantly

from the reference result. By progressively including real-time data over increasing time intervals, the reconstruction improves and approaches the reference mobility. This clearly indicates that the combined use of imaginary- and real-time data enhances the stability and accuracy of the analytic continuation procedure, particularly in the low-frequency domain relevant for dc mobility.

To quantify the accuracy of the analytic continuation procedure, an estimate of the associated reconstruction error is introduced. This estimate is based on a comparison between the reconstructed mobility and the known reference result at zero frequency.

The relative error is defined as

$$\delta = \frac{\text{Re}\mu_{\text{ac}}(\omega = 0) - \text{Re}\mu_{\text{ref}}(\omega = 0)}{\text{Re}\mu_{\text{ref}}(\omega = 0)}, \quad (3.59)$$

and is used as a quantitative measure of the accuracy of the analytic continuation procedure.

This estimate is subsequently employed to assign an uncertainty to the dc mobility values obtained from Monte Carlo data. For each set of model parameters, the same discrete time grid (both imaginary and real) used in the Monte Carlo calculations is applied to the reference mobility, allowing the error introduced by the analytic continuation procedure to be evaluated under conditions that closely match those of the actual simulations.

In this way, the error estimate reflects the combined effect of limited time-domain data, discretization, and statistical noise, and provides a realistic assessment of the uncertainty associated with the reconstructed dc mobility. It is further observed that the reconstructed values $\text{Re}\mu_{\text{ac}}(\omega = 0)$ systematically underestimate the reference values $\text{Re}\mu_{\text{ref}}(\omega = 0)$. This indicates that, within the present implementation and for finite data sets, the analytic continuation procedure introduces a bias towards lower mobility values.

3.3 Choice of parameters values in QMC calculations

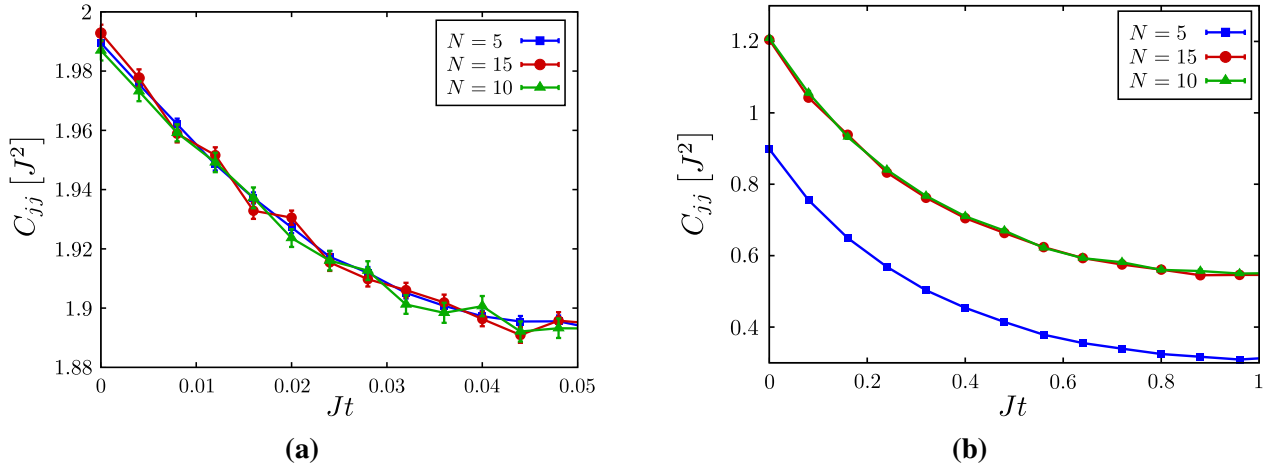


Figure 3.2: Dependence of the imaginary-time current–current correlation function on the system size N for $\omega_0/J = 1$ and $G/J = 1$. (a) High temperature, $T/J = 10$; (b) low temperature, $T/J = 0.5$. Results are shown for $0 \leq t \leq \beta/2$, exploiting the symmetry $C_{jj}(t) = C_{jj}(\beta - t)$. Error bars represent the estimated standard deviation.

In order to ensure the reliability of the quantum Monte Carlo (QMC) results, particular attention was devoted to the choice of simulation parameters. These parameters were determined based on systematic convergence tests, with the aim of achieving high numerical accuracy while maintaining computational efficiency.

The statistical accuracy of the results was controlled by the number of Monte Carlo samples and independent repetitions. In most cases, 10^6 Monte Carlo samples were generated, while smaller

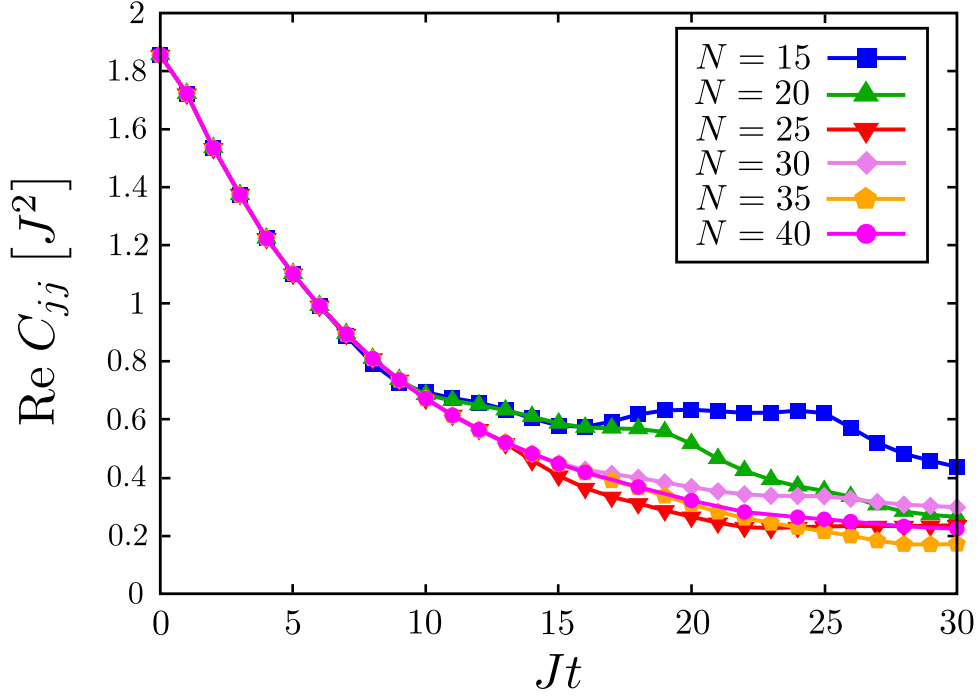


Figure 3.3: Real part of the real-time current–current correlation function for different system sizes N . Results are shown for $\omega_0/J = 1$, $G/J = 0.141$, and $T/J = 2.5$.

or larger sample sizes were used when required by the parameter regime. Each simulation was repeated 100 times. These repetitions improve the statistical reliability of the results by allowing for averaging over independent realizations, and enable the estimation of statistical uncertainties through the standard deviation. The number of samples was adjusted as needed to ensure that the relative standard deviation of the computed quantities remains below approximately 1% of the corresponding mean value.

The discretization of both imaginary and real time introduces additional numerical parameters, namely the time steps τ and Δt . Convergence tests show that the choice $\tau = \Delta t = \frac{0.1}{J}$ is sufficient, as further reduction of the time step does not lead to a significant change in the results. However, the time discretization was adjusted depending on the parameter regime and the time interval considered. In cases involving small temperatures (large β) or longer real-time intervals, slightly larger time steps were employed when verified to have no impact on the results. Conversely, for shorter time intervals or smaller β , smaller time steps were used in order to achieve adequate resolution of the correlation functions. In practice, the time intervals were discretized so as to include a sufficient number of data points, typically exceeding 15, ensuring both numerical stability and accurate representation of the time dependence.

A key parameter in the simulations is the system size, determined by the number of lattice sites N . The objective is to obtain results representative of the thermodynamic limit, $N \rightarrow \infty$. In practice, this is achieved by selecting N large enough such that further increases do not affect the computed correlation functions.

The dependence of the imaginary-time current–current correlation function on the system size is shown in Fig. 3.2 for $\omega_0/J = 1$ and $G/J = 1$, at both high temperature ($T/J = 10$) and low temperature ($T/J = 0.5$). It is observed that at high temperature, a relatively small system size ($N = 5$) is sufficient to reach convergence, whereas at low temperature a larger system ($N = 10$) is required. This behavior reflects the reduction of spatial correlations at higher temperatures, where the system becomes more local and finite-size effects are less pronounced.

The influence of system size on real-time correlation functions is illustrated in Fig. 3.3 for the case of weak electron–phonon interaction ($G/J = 0.141$), $\omega_0/J = 1$, and $T/J = 2.5$. In this regime, the carrier mean free path is large, and correspondingly larger system sizes are required to accurately

capture the dynamics. The results indicate that a system with $N = 30$ sites is necessary to obtain reliable data for times up to $Jt \approx 15$.

In practice, for each set of model parameters, short convergence checks were performed in which the system size and the time discretization were varied within a narrow range around estimated optimal values. This procedure was sufficient to verify that the chosen parameters do not affect the resulting correlation functions.

In order to reduce computational cost, simulations at shorter times were performed using smaller system sizes, as justified by these convergence tests. This is particularly advantageous since the computational effort increases rapidly with system size. In the path-integral formulation, the dimensions of the matrices and vectors grow with both the number of time slices and the number of lattice sites N resulting in a substantial increase in numerical cost for larger systems. For example, $N = 20$ was used for the time interval $5 \leq Jt \leq 10$, while $N = 30$ was used for $10 \leq Jt \leq 15$. This approach allows for efficient calculations without compromising the accuracy of the results.

Additional implementation details of the Monte Carlo simulations, including the algorithmic procedure and pseudocode, as well as a detailed overview of the parameter choices used in individual calculations (such as system size, time discretization, and number of samples), are provided in Appendix C.

3.4 Results

3.4.1 Current-current correlation function

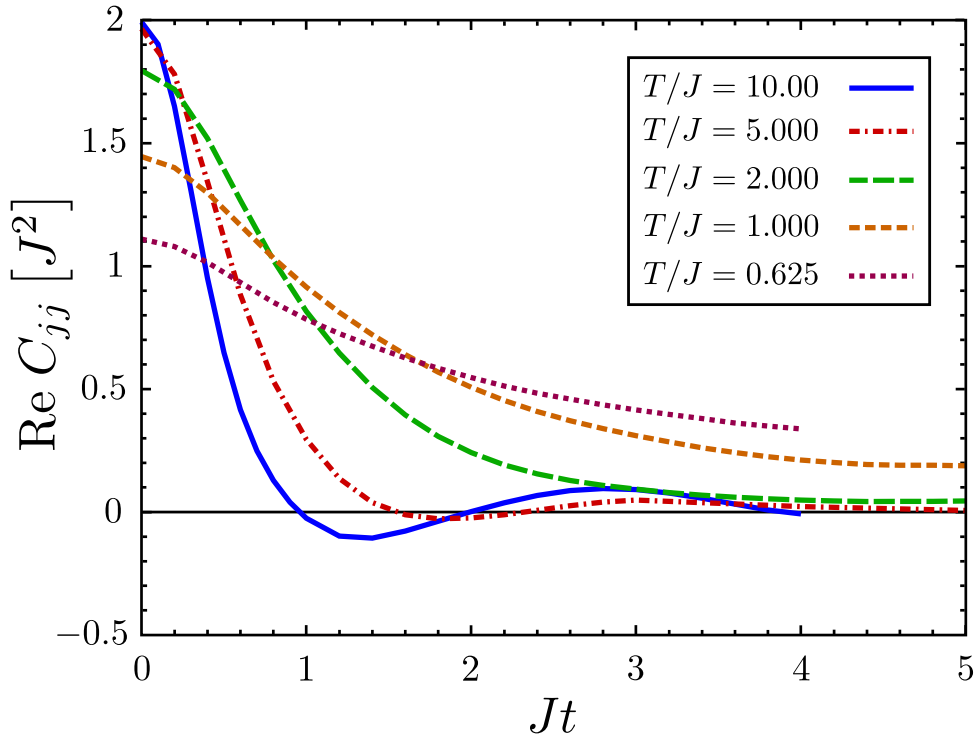


Figure 3.4: Time decay of the real part of the current–current correlation function at different temperatures. Results are shown for $\omega_0/J = 1$ and $G/J = 0.5$.

The time dependence of the current–current correlation function provides direct insight into the transport properties of the system. In this subsection, the time evolution of the correlation function in both real and imaginary time is analyzed as a function of temperature and electron–phonon interaction strength. The resulting behavior reflects the underlying transport mechanisms and determines how reliably the mobility can be extracted, as discussed in the following subsection.

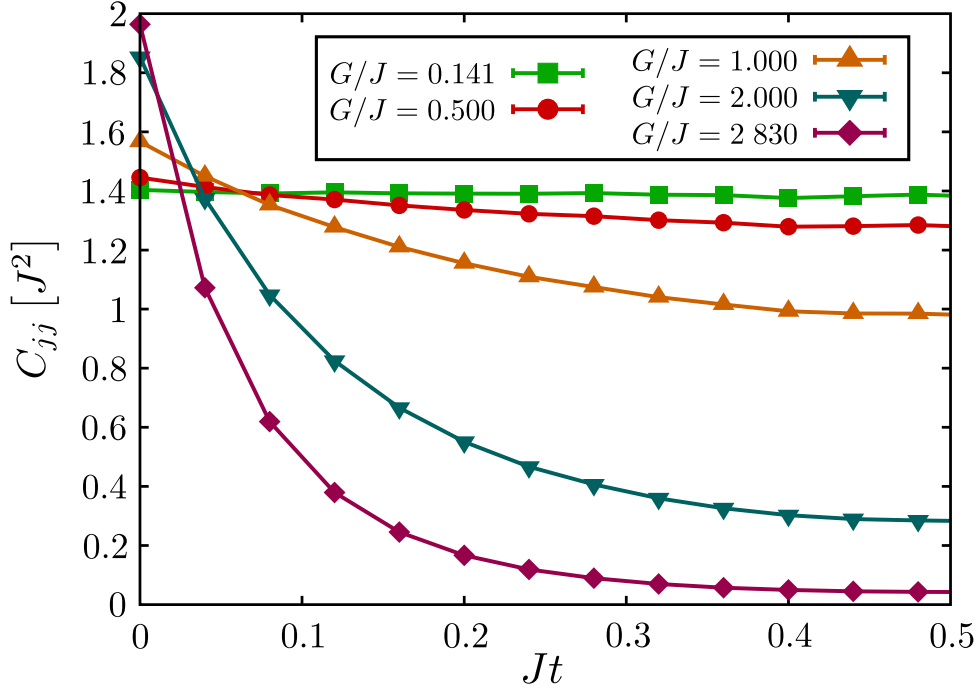


Figure 3.5: Imaginary-time current–current correlation function for different interaction strengths. Results are shown for $T/J = 1$ and $\omega_0/J = 1$. The data are presented for $0 \leq t \leq \beta/2$, exploiting the symmetry $C_{jj}(t) = C_{jj}(\beta - t)$.

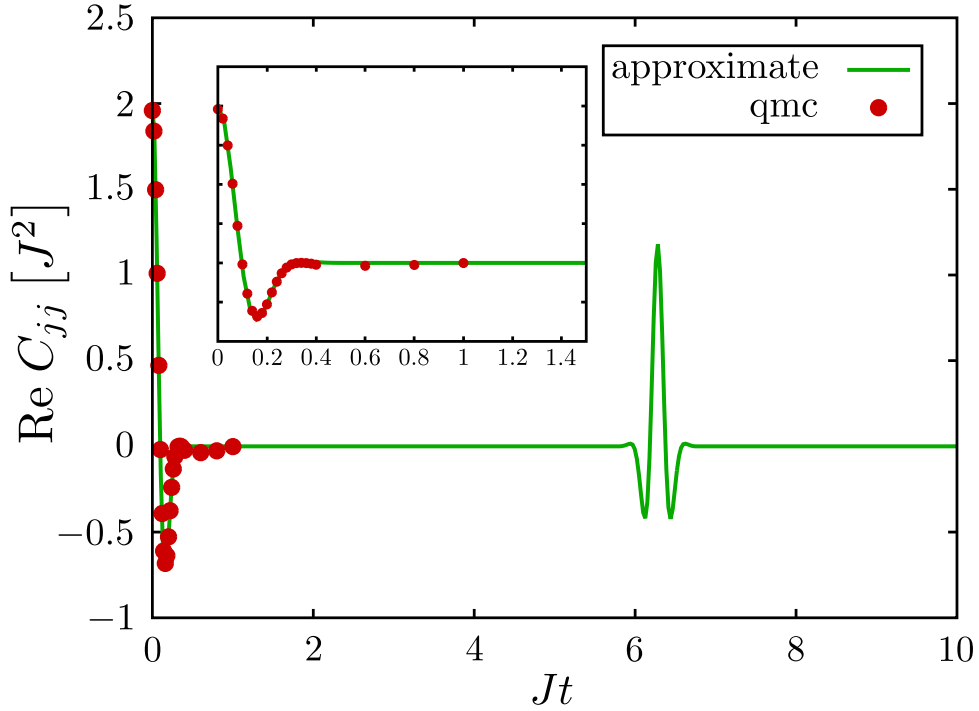


Figure 3.6: Time dependence of the real part of the current–current correlation function for $G/J = 2.83$. Results are shown for $T/J = 2$, obtained using an approximate method from Ref. [133] (labeled “approximate”) and from QMC calculations (labeled “qmc”). The inset shows a detailed view for times $Jt \leq 1.5$.

The time decay of the real part of the real-time current–current correlation function for $\omega_0/J = 1$ and $G/J = 0.5$ is shown in Fig. 3.4 for a range of temperatures from low ($T/J=0.625$) to high ($T/J=10$). The results are displayed as continuous lines to highlight their functional dependence on time, and the statistical uncertainty is below 1%, making it invisible at the scale of the figure. The chosen interaction strength $G/J = 0.5$ allows both rapid decay at high temperatures and slow decay at low temperatures to be clearly observed within the accessible time intervals.

At higher temperature ($T/J \geq 2$), the correlation function decays rapidly and reaches zero within the accessible simulation time window, indicating that the relevant dynamics are confined to short times. In this regime, the full time dependence is captured, which enables a direct evaluation of the dc mobility via the Kubo formula, with the uncertainty determined primarily by the small statistical error of the data. For the highest temperature ($T/J = 10$), it is observed that the correlation function crosses zero, exhibits a shallow minimum, and then converges back to zero. This type of behavior is also observed at stronger electron–phonon interactions, as shown in Fig. 3.6.

At lower temperatures ($T/J < 2$), the decay of the correlation function becomes significantly slower, and within the accessible time interval the correlation function appears nearly asymptotic to zero, indicating that a significant portion of the long-time behavior is not captured. These contributions cannot be fully resolved as the dynamical sign problem becomes increasingly pronounced, limiting the accessible time range. The data are therefore shown only up to times where the statistical uncertainty remains controlled. As a result, the correlation function is only partially captured, and direct integration of the Kubo formula would lead to a substantial underestimation of the mobility. For weaker interactions, this effect is even more pronounced, as the decay is slower and the full time dependence is generally inaccessible except at the highest temperatures. In contrast, for stronger interactions the decay becomes faster and more structured, but the accessible time interval is more severely restricted. The chosen interaction strength ($G/J = 0.5$) considered here therefore provides a representative balance between these two cases.

The time dependence of the current–current correlation function in imaginary time is shown in Fig. 3.5 for $T/J = 1$ and $\omega_0/J = 1$, for a range of interaction strengths. The results are presented as data points connected by lines to illustrate the functional dependence on imaginary time, while statistical uncertainties remain negligible on the scale of the figure. A clear qualitative difference is observed between weak and strong electron–phonon coupling. For weak interactions ($G/J = 0.141$), the correlation function exhibits only a very weak dependence on imaginary time and appears nearly constant over the entire interval. With increasing interaction strength, the variation with imaginary time becomes more pronounced, indicating a stronger functional dependence.

This behavior directly reflects the amount of information contained in the imaginary-time data. In the weak-coupling regime, the nearly constant behavior provides only limited information on the underlying dynamics, making analytic continuation based on imaginary-time data alone highly unreliable. In this case, the real-time correlation functions remain accessible over longer time intervals and therefore provide the main source of information. In contrast, for stronger interactions, the pronounced variation in imaginary time provides a more informative input for analytic continuation. Temperature, in this case, primarily affects the overall time scale and magnitude of the correlation function, while the qualitative behavior remains governed by the interaction strength.

Additional insight into the behavior of the real-time correlation function at strong coupling is provided in Fig. 3.6, shown for $G/J = 2.83$ and $T/J = 2$, where the QMC results are compared with those obtained by an approximate method from Ref. [133]. A good qualitative agreement is observed, confirming that the QMC results capture the main features of the correlation function. In particular, the approximate result exhibits a sequence of oscillatory peaks at times $t_n = n \frac{2\pi}{\omega_0}$ ($n \geq 1$) each accompanied by smaller minima. The QMC data reproduce the initial peak around $Jt = 0$, which has a similar structure to that observed at weaker interaction strength in Fig. 3.4.

The accessible time interval in the QMC calculations is limited by the dynamical sign problem, and therefore only the short-time behavior is reliably captured. As a result, the additional peaks present at longer times in the approximate solution are not resolved in the QMC data. This comparison demonstrates that while the essential short-time structure of the correlation function is accurately reproduced, longer-time contributions remain inaccessible within the simulation.

3.4.2 Standard deviation of QMC results depending on choice of electron basis

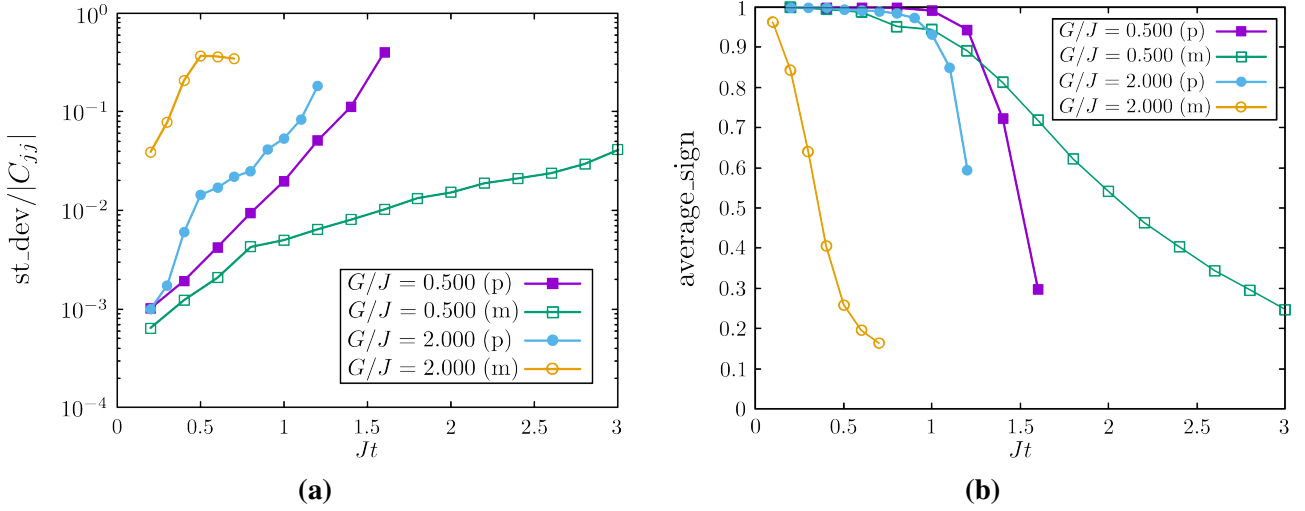


Figure 3.7: Real-time dependence of the relative standard deviation and the average sign of the current–current correlation function. Results are shown for $\omega_0/J = 1$ and $T/J = 2$. Panel (a) corresponds to the relative standard deviation and panel (b) to the average sign. The label “m” denotes results obtained in the momentum representation, while “p” denotes results obtained in the position representation.

In this subsection, the influence of the choice of electron basis on the statistical accuracy of QMC calculations and the severity of the sign problem is examined quantitatively. This is illustrated in Fig. 3.7, where the relative standard deviation of the current–current correlation function, defined as the ratio of the standard deviation to its absolute value, is shown as a function of real time for calculations performed in both the momentum and position representations.

The results are presented up to times where the statistical uncertainty becomes comparable to the value of the correlation function. A clear dependence on both interaction strength and choice of basis is observed. For weak electron–phonon interaction ($G/J = 0.5$), the momentum representation yields significantly smaller statistical fluctuations. In contrast, for stronger interaction ($G/J = 2$), the position representation becomes more favorable, resulting in a noticeably reduced standard deviation. This demonstrates that the efficiency of the Monte Carlo sampling strongly depends on the basis in which the electronic degrees of freedom are represented.

To clarify the origin of this behavior, the average sign of the Monte Carlo estimator is shown in Fig. 3.7(b) for the same set of parameters. The average sign is defined as

$$s_{\text{av}} = \left\langle \left| \frac{A_i}{|A_i|} \right| \right\rangle, \quad (3.60)$$

where A_i denotes the individual contributions to the Monte Carlo sum. The value $s_{\text{av}} = 1$ corresponds to the absence of a sign problem, while $s_{\text{av}} = 0$ indicates a completely random distribution of phases and thus a severe sign problem.

A direct correlation between the average sign and the statistical uncertainty is observed. In regimes where the average sign remains close to unity, the standard deviation is small and reliable results can be obtained. As the average sign decreases, the statistical fluctuations increase rapidly, and the results become unreliable once the standard deviation becomes comparable to the result. This confirms that the observed dependence of the statistical accuracy on the choice of basis originates from the severity of the sign problem in the corresponding representation.

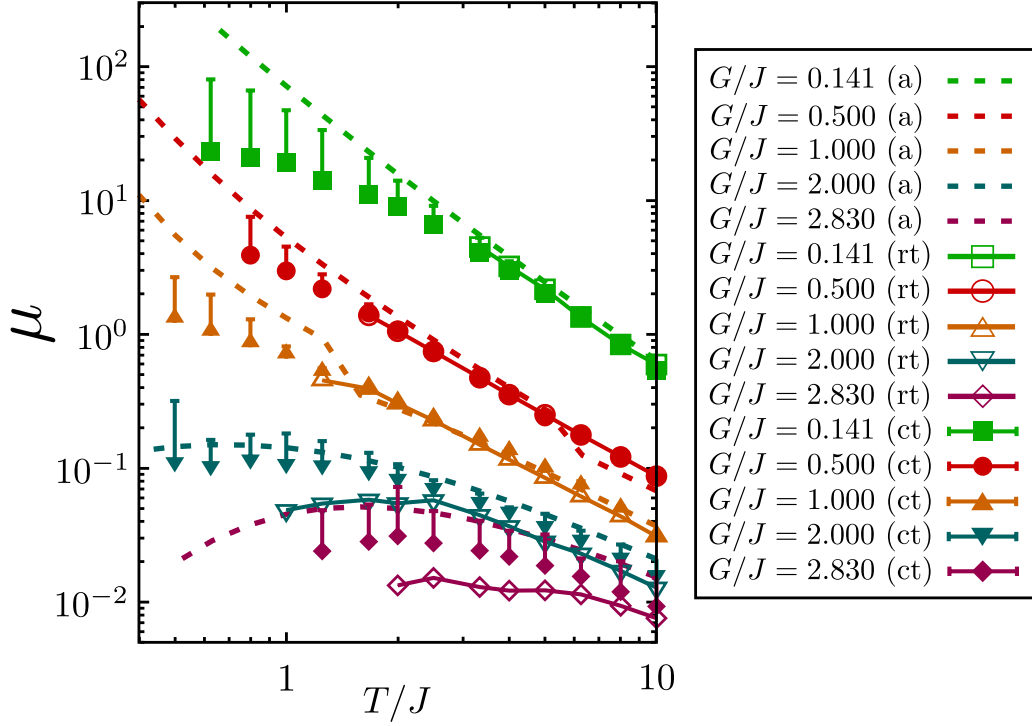


Figure 3.8: Temperature dependence of the Holstein polaron mobility obtained from path-integral QMC calculations for different electron–phonon interaction strengths at $\omega_0/J = 1$. Results labeled “ct” are obtained by analytic continuation from combined real- and imaginary-time data. Results labeled “rt” are obtained by direct integration of the real-time current–current correlation function (full lines are guides to the eye). Results labeled “a” correspond to approximate calculations from Ref. [133].

3.4.3 Temperature dependence of Holstein polaron mobility

In this subsection, the temperature dependence of the polaron mobility is presented as the main result of the analysis developed in the preceding sections. The temperature dependence of mobility for the one dimensional Holstein model is shown in Fig. 3.8 for e-ph interaction strengths ranging from weak ($G/J = 0.141$) to strong ($G/J = 2.830$) at $\omega_0/J = 1$.

The results labeled “ct” correspond to mobilities obtained using the analytic continuation procedure, which combines imaginary-time data with real-time data up to times where the QMC results remain reliable. The associated error bars are estimated following the procedure introduced in the previous subsection. In brief, the relative error of analytic continuation is first evaluated using reference correlation functions constructed from the dynamic mobility obtained in Ref. [133]. This relative error, defined by Eq. (3.59), is then used as an estimate for the uncertainty when the procedure is applied to QMC data for the same set of parameters, which is justified by the close similarity of the approximate and QMC correlation functions. The resulting relative error is subsequently converted into an estimate of the absolute error of the mobility. It is observed that analytic continuation systematically tends to underestimate the mobility. For this reason, the error bars shown in Fig. 3.8 are presented as one-sided.

The results labeled “rt” are obtained by direct integration of the real-time current–current correlation function over the time interval where reliable data are available. The corresponding statistical uncertainty is very small and remains negligible on the scale of the results. For comparison, results from the approximate method of Ref. [133], labeled “a”, are also shown.

The reliability of the obtained results depends strongly on both interaction strength and temperature. The most accurate results are obtained for relatively weak interactions $G/J \lesssim 1$ and higher temperatures $T/J \gtrsim 2$, where the full time decay of the correlation function can be captured and direct integration yields reliable values of mobility. In this regime, analytic continuation produces results consistent with those obtained from real-time integration. For stronger interactions ($G/J > 1$)

at higher temperatures, reasonably accurate results can still be obtained, although the accessible time interval becomes more restricted. In contrast, at low temperatures ($T/J < 1$), the slow decay of the correlation function and the severity of the sign problem significantly limit the accuracy of both approaches.

A comparison with the results of Ref. [133] shows good overall agreement across the parameter range considered. In most cases, the reference results lie within the estimated error bars of the QMC-based results. The consistency between two independent approaches provides mutual validation of the obtained results. In particular, since the QMC method employed here is numerically exact within statistical uncertainty, this agreement further supports the reliability of the approximate method used in Ref. [133] in describing the temperature dependence of the mobility.

The choice of electronic basis in the path-integral calculations is influenced by the interaction strength. For weak electron–phonon coupling ($G/J < 1$), the momentum representation is used in real-time calculations. In this case, the residual phase appearing in the estimator for the real-time current–current correlation function is proportional to the factor $\Delta t G$, and remains sufficiently small for efficient Monte Carlo sampling. As the interaction strength G increases, however, the dynamical sign problem becomes more pronounced, making this representation less effective. This limitation is further exacerbated at low temperatures, where longer time intervals become relevant, as discussed in the previous subsection.

The position representation is used for the evaluation of the current–current correlation function in imaginary time for all interaction strengths, and in real time for stronger interactions ($G/J \geq 1$), where it provides a more stable numerical approach. Additional details on the calculations for each parameter set shown in Fig. 3.8, including the choice of basis, are provided in Appendix C.

A comparison is also made with the results of Ref. [66], which, to the best of current knowledge, represents the only study of the temperature dependence of Holstein polaron mobility obtained using a methodology that is, in principle, numerically exact. For the weakest interaction ($G/J = 0.141$), good agreement is observed within the temperature range where the estimated error of the present results remains small. However, for stronger interactions ($G/J = 1, 2, 2.83$), the values reported in Ref. [66] are consistently lower than those obtained here.

For example, at $G/J = 2.83$, $\omega_0/J = 1$ and $T/J = 2$, mobility values in the range $\mu \in (2.8, 8.1) \times 10^{-3}$ are reported in Ref. [66], while the present results show $\mu \in (3.1, 7.2) \times 10^{-2}$. It is noted that direct integration of the QMC current-current correlation function over the first peak alone (for $0 \leq Jt \leq 1$, see Fig. 3.6) already gives $\mu \approx 1.5 \cdot 10^{-2}$, while contributions from subsequent peaks can only increase this value.

The results of Ref. [66] are obtained using analytic continuation based solely on imaginary-time data. As discussed previously, the limited information content of imaginary-time correlation functions in certain parameter regimes can lead to an underestimation of the mobility. This is therefore considered a plausible explanation for the observed discrepancy between the two sets of results.

In this chapter, the temperature dependence of the polaron mobility in the one-dimensional Holstein model has been obtained using a path-integral quantum Monte Carlo approach combined with analytic continuation. The analysis of current–current correlation functions in both real and imaginary time has enabled a detailed understanding of the regimes in which reliable results can be achieved. The methodology is shown to provide accurate results for weak to intermediate interaction strengths and higher temperatures, while its applicability becomes limited at low temperatures due to the dynamical sign problem and the restricted accessible time intervals. These findings establish a consistent framework for the calculation of transport properties within the considered model and provide the basis for further analysis presented in the following chapter.

Chapter 4

Transport regimes of Holstein polaron

The Holstein model represents a prototypical framework for studying systems with electron–phonon interaction. Despite its simplicity, a complete understanding of its transport properties across the full parameter space remains an open problem. In the preceding chapters, the theoretical framework for describing charge transport in such systems has been established, and a numerically exact path-integral quantum Monte Carlo (QMC) method has been developed to evaluate current–current correlation functions and carrier mobility.

As discussed in Chapter 2, the mobility of charge carriers in systems with electron–phonon interaction is governed by the interplay between coupling strength and temperature, which gives rise to qualitatively different transport regimes (see Section 2.3). In the weak-coupling limit, carriers remain delocalized and transport is well described within the band transport picture (Section 2.3.2). In contrast, in the regime of strong coupling and sufficiently high temperatures, carriers become localized and propagate via thermally activated hopping processes (Section 2.3.1), while at low temperatures a coherent but strongly renormalized motion may occur within a narrow polaron band (Section 2.3.3). These regimes form the basis of most theoretical descriptions of charge transport in such systems.

However, these transport theories are typically derived under restrictive assumptions and are valid only within limited regions of parameter space. In practice, approaches based on band or hopping transport are often applied beyond their formal range of validity, particularly in situations where the relevant energy scales are comparable and the dominant transport mechanism is not known a priori. At the same time, numerically exact methods that do not rely on such assumptions are generally restricted by computational limitations and can typically be applied only within a limited range of parameters.

For this reason, it is of interest to examine the range of validity of the different transport regimes and to assess whether they provide a consistent description of transport behavior across the parameter space of the Holstein model. In principle, this could be achieved by comparing numerically exact results for dynamical quantities, such as current–current correlation functions or carrier mobility, with the predictions of the corresponding transport theories. In practice, however, numerically exact approaches based on real-time or real-frequency formulations are computationally demanding and therefore limited in their applicability, primarily due to the dynamical sign problem and the need for analytic continuation.

In contrast, imaginary-time quantities can be evaluated reliably over a much broader range of parameters within the path-integral QMC framework developed in Chapter 3. In the present chapter, path-integral QMC calculations of the imaginary-time current–current correlation function are used as a primary tool for analyzing transport behavior. For the same set of parameters, the corresponding quantities are evaluated within the approximate descriptions of band transport, hopping transport, and polaron band transport. This enables a direct comparison between the QMC results and the corresponding approximate descriptions, allowing the regions of validity of these transport regimes to be examined.

In cases where the comparison of imaginary-time correlation functions does not provide a conclusive classification, the analysis can be further supplemented by considering real-time correlation

functions or by comparison with available numerically exact results for dc mobility, providing an additional basis for examining the transport regimes across the parameter space. Based on this analysis, a transport regime diagram for the Holstein model can be constructed.

4.1 Current-current correlation function and dc mobility in different transport regimes

The different transport regimes are associated with distinct microscopic mechanisms of carrier motion, which are reflected in the temporal behavior of the current–current correlation function. The analysis in this section is therefore formulated in terms of these correlation functions and the corresponding expressions for dc mobility.

In the strong-coupling regime, where small polarons are formed, transport may proceed either through coherent motion within a narrow polaron band at low temperatures or through thermally activated hopping between localized states at higher temperatures. In contrast, in the weak-coupling regime, transport is governed by band-like motion of delocalized carriers, with scattering by lattice vibrations determining the temperature dependence of mobility.

These qualitatively different mechanisms give rise to distinct forms of the current–current correlation function, which in turn determine the corresponding transport coefficients within the Kubo formalism. In the following subsections, the expressions for the current–current correlation function and the associated dc mobility are presented for the three relevant regimes, namely hopping transport of small polarons, coherent transport within a narrow polaron band, and conventional band transport of large polarons.

4.1.1 Hopping transport at all temperatures and in high-temperature limit

In the strong-coupling regime of the Holstein model, charge carriers form small polarons, whose transport is governed by thermally activated hopping between localized states, as discussed in Section 2.3.1. In this regime, the electronic transfer integral is treated as a perturbation, while the coupling to lattice vibrations determines the dynamics of the hopping process.

Following the derivation presented in Chapter 2, the transition rate between two neighboring sites is obtained within Fermi’s golden rule framework and can be written as [84, 134, 135]

$$W = J^2 \int_{-\infty}^{\infty} dt e^{-2(\frac{G}{\omega_0})^2 [2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t} - n_{\text{ph}}e^{i\omega_0 t}]}, \quad (4.1)$$

where $n_{\text{ph}} = (e^{\beta\omega_0} - 1)^{-1}$ denotes the phonon occupation number.

The corresponding current–current correlation function takes the form [136]

$$C_{jj}(t) = 2J^2 e^{-2(\frac{G}{\omega_0})^2 [2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t} - n_{\text{ph}}e^{i\omega_0 t}]}. \quad (4.2)$$

In the high-temperature limit, these expressions reduce to the Marcus form of the hopping rate [137–141],

$$W = J^2 \sqrt{\frac{\beta\pi}{\lambda}} e^{-\frac{\beta\lambda}{4}}, \quad (4.3)$$

with $\lambda = \frac{2G^2}{\omega_0}$. The corresponding mobility is then given by

$$\mu = \beta J^2 \sqrt{\frac{\beta\pi}{\lambda}} e^{-\frac{\beta\lambda}{4}}. \quad (4.4)$$

In this limit, the current–current correlation function assumes a Gaussian form [136],

$$C_{jj}(t) = 2J^2 e^{-\sigma_0^2 t^2} e^{-i\beta\sigma_0^2 t}, \quad (4.5)$$

where $\sigma_0^2 = \frac{2G^2}{\beta\omega_0}$.

However, for the Holstein model with a single dispersionless phonon mode, the expression in Eq. (4.1) leads to a divergence of the hopping rate and the corresponding dc mobility. This behavior originates from the fact that the correlation function in Eq. (4.2) does not decay to zero in the long-time limit, reflecting the implicit assumption of infinitely long-lived small-polaron states.

To account for finite lifetimes, an improved description can be obtained by including self-energy corrections that introduce a broadening of polaron states. This removes the unphysical long-time behavior of the correlation function and provides a more realistic description of hopping dynamics. Following the approach presented in Ref. [136], the current–current correlation function is modified to

$$C_{jj}(t) = g(t)e^{-2(\frac{G}{\omega_0})^2[2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t}-n_{\text{ph}}e^{i\omega_0 t}]}, \quad (4.6)$$

where the prefactor $g(t)$ accounts for the finite lifetime effects and introduces an effective decay of the correlation function. It is given by

$$g(t) = 2J^2 \frac{\beta}{t(\beta - it)} \frac{1}{\sqrt{c_0}} \frac{I_1(-2(\beta - it)\sqrt{c_0}) J_1(2t\sqrt{c_0})}{I_1(-2\beta\sqrt{c_0})}, \quad (4.7)$$

with I_1 and J_1 denoting the modified and ordinary Bessel functions of the first kind, respectively, both of order 1. The parameter c_0 is defined as

$$c_0 = 2J^2 e^{-2(\frac{G}{\omega_0})^2(2n_{\text{ph}}+1)} I_0(\alpha), \quad (4.8)$$

$$\alpha = 4(\frac{G}{\omega_0})^2 \sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)}. \quad (4.9)$$

The corresponding dc mobility, obtained with the Kubo formula (Eq. (2.30)), is then given by

$$\mu = 2J^2 \beta \pi e^{-2(\frac{G}{\omega_0})^2(2n_{\text{ph}}+1)} \frac{\sum_{l=-\infty}^{\infty} \int d\omega e^{-\beta\omega} A(\omega) A(\omega + l\omega_0) I_l(\alpha) e^{-\frac{l\omega_0\beta}{2}}}{\int d\omega e^{-\beta\omega} A(\omega)}, \quad (4.10)$$

where the spectral function $A(\omega)$ is given by

$$A(\omega) = \frac{\sqrt{4c_0 - \omega^2}}{2\pi c_0} \theta(4c_0 - \omega^2), \quad (4.11)$$

and I_l denotes the modified Bessel function of order l . This expression provides a finite and well-defined mobility by incorporating the broadening of polaron states.

In the following, Eqs. (4.6) and (4.10) are used as the reference expressions for the current–current correlation function and dc mobility in the hopping regime. Their high-temperature limits, given by Eqs. (4.5) and (4.4), are used for comparison. Imaginary-time correlation functions are obtained by the substitution $t \rightarrow -i\tau$.

For the presentation of results, all energies are expressed in units of the transfer integral J , while the electron–phonon interaction strength is parameterized by the dimensionless coupling $\lambda = G^2/(2J\omega_0)$.

As shown in Fig. 4.1, the mobility obtained from Eq. (4.10) approaches the high-temperature result given by Eq. (4.4) with increasing temperature, and the two expressions eventually converge. This behavior reflects the expected crossover to the Marcus regime at sufficiently high temperatures.

The influence of the phonon frequency is also clearly visible. Comparison of Figs. 4.1a and 4.1b shows that for smaller values of ω_0/J , the high-temperature Marcus limit is reached at lower temperatures, while for larger phonon frequencies this shift occurs at higher temperatures. This reflects the fact that the onset of high-temperature effects is controlled by the ratio of thermal energy to the phonon energy scale.

The current–current correlation functions shown in Fig. 4.2 exhibit good agreement between the full expressions and their high-temperature limits at elevated temperatures, both in imaginary time

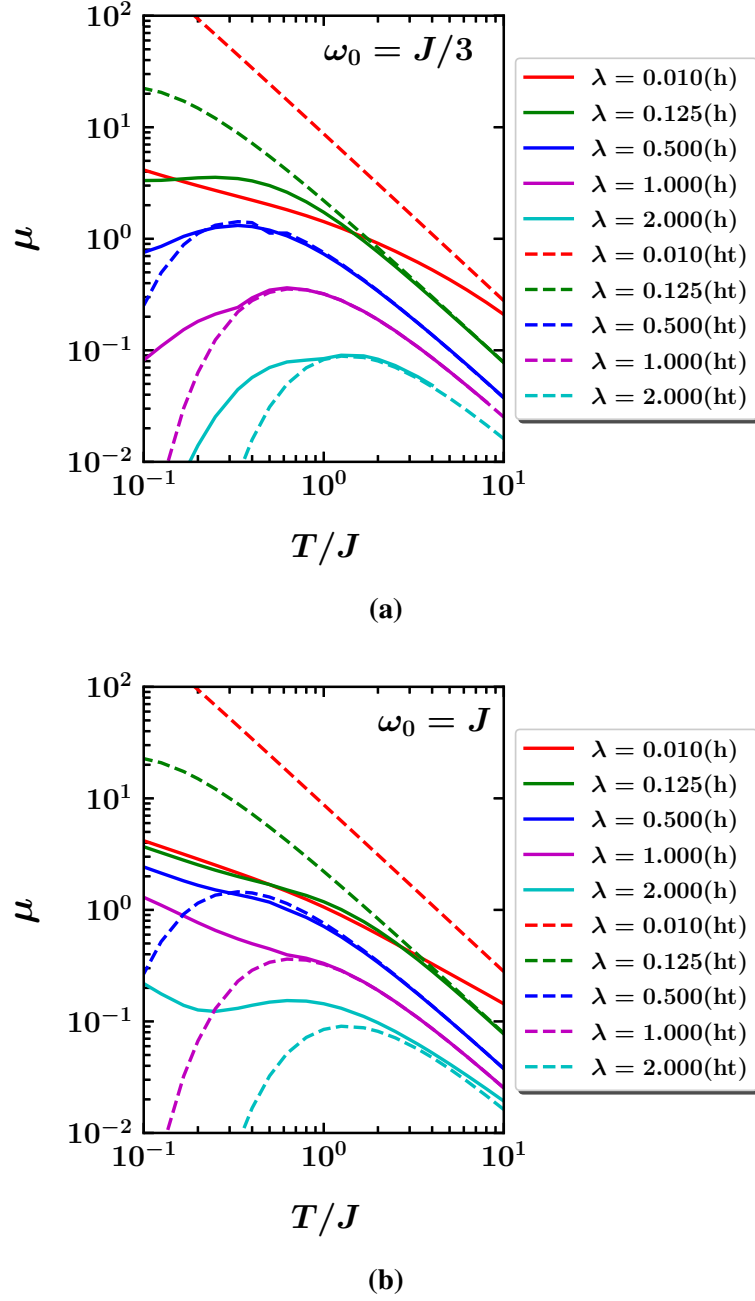


Figure 4.1: Temperature dependence of the hopping mobility for different interaction strengths λ . Results obtained from Eq. (4.10) are shown with solid lines (label “h”), while the high-temperature approximation given by Eq. (4.4) is shown with dashed lines (label “ht”). Panel (a) corresponds to $\omega_0 = J/3$ and panel (b) to $\omega_0 = J$.

and in the real parts of the real-time correlation functions, while clear deviations appear at lower temperatures. This behavior is consistent with the trends observed for the mobility, where agreement with the high-temperature limit is likewise obtained only in the appropriate temperature range.

Such agreement confirms that the high-temperature approximation captures the essential transport behavior in the appropriate regime. At the same time, the deviations observed at lower temperatures highlight the limitations of the Marcus description outside its range of validity.

Overall, these results are consistent with the theoretical expectations established in Section 2.3.1, where the hopping transport picture is shown to reduce to the Marcus form in the high-temperature limit.

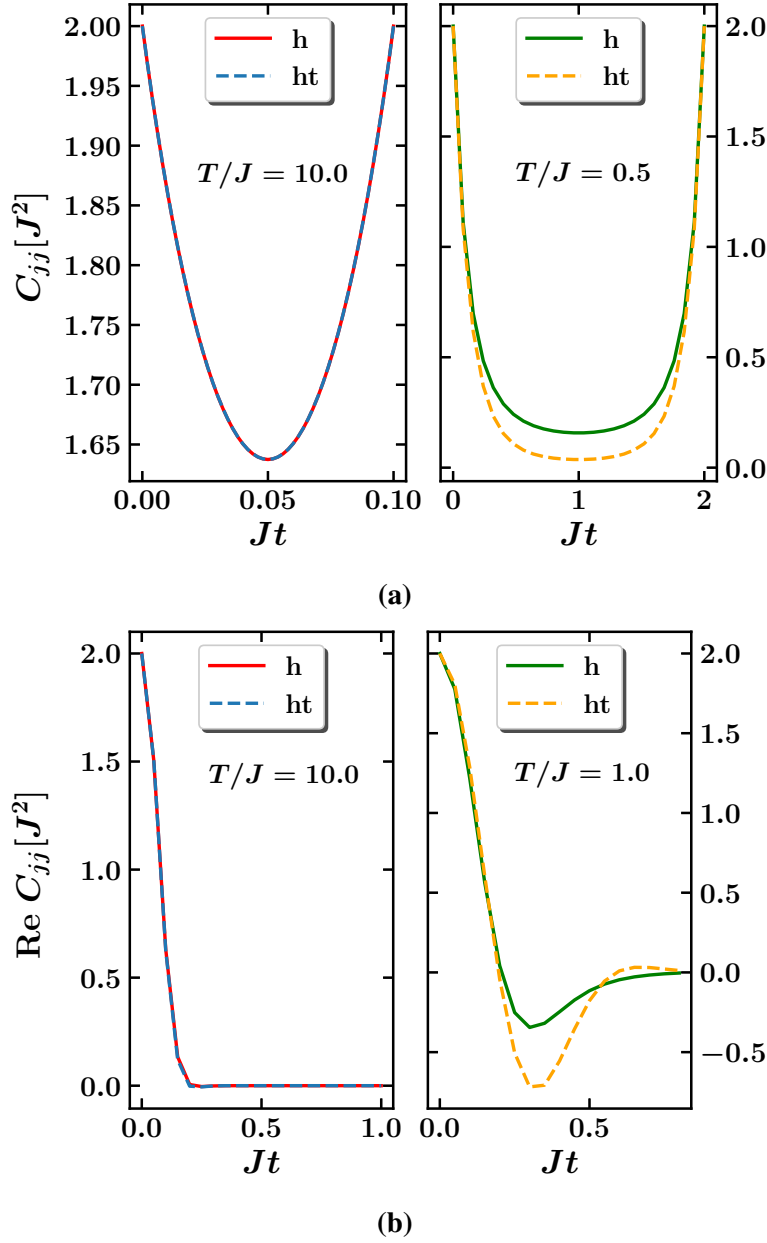


Figure 4.2: Imaginary-time and real-time current–current correlation functions in the hopping regime. Panel (a) shows the imaginary-time correlation function, while panel (b) shows the real part of the real-time correlation function. Solid lines (label “h”) correspond to Eq. (4.6), while dashed lines (label “ht”) correspond to its high-temperature limit, Eq. (4.5). Results are shown for $\omega_0 = 3J$ and $\lambda = 2.000$, with temperatures $T/J = 10.0$ and $T/J = 0.5$ in (a), and $T/J = 10.0$ and $T/J = 1.0$ in (b)

4.1.2 Polaron band transport and crossover to hopping regime

In the strong-coupling regime at low temperatures, charge carriers form polarons that retain a degree of coherence and propagate within a narrow polaron band, as discussed in Section 2.3.3. This regime is commonly referred to as polaron band transport and is characterized by a strong renormalization of the electronic bandwidth due to the coupling to lattice vibrations.

A convenient description of this regime is obtained within the Lang–Firsov transformed framework introduced in Section 2.3.3, in which the Hamiltonian is expressed in terms of polaron quasiparticles. The transformed Hamiltonian describes a renormalized band with dispersion

$$\tilde{\epsilon}_k = -\frac{G^2}{\omega_0} - 2\tilde{J} \cos k, \quad (4.12)$$

where the effective transfer integral is given by

$$\tilde{J} = J e^{-(2n_{\text{ph}}+1)\frac{G^2}{\omega_0^2}}. \quad (4.13)$$

In this representation, the Hamiltonian can be written as $\tilde{H} = \tilde{H}_0 + \tilde{V}$, where $\tilde{H}_0$ describes noninteracting polarons, while $\tilde{V}$ contains residual coupling between polarons and lattice fluctuations. These residual interactions give rise to a finite lifetime of polaron states and are treated perturbatively. Their effect is incorporated at the level of the self-energy, while the dominant coherent contributions to transport are treated explicitly, following the approach of Ref. [133].

Within this framework, the current–current correlation function can be expressed in terms of single-particle Green’s functions and an interaction-dependent vertex contribution [136]. The resulting expression contains contributions from both coherent processes, in which no phonons are exchanged, and incoherent phonon-assisted processes. In the polaron band transport regime, coherent processes are dominant. Accordingly, only the leading contribution is retained, corresponding to the independent-particle (bubble) approximation.

Within this approximation, the current–current correlation function takes the form

$$C_{jj}(t) = \frac{\sum_{k_1 k_2} \langle a_{k_1}^\dagger(t) a_{k_1} \rangle \langle a_{k_2}(t) a_{k_2}^\dagger \rangle Y_{k_1 k_2}(t)}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (4.14)$$

The quantity $Y_{k_1 k_2}(t)$ encodes the phonon dressing of the current operator, which arises from the Lang–Firsov transformation. Its explicit form follows from the evaluation of phonon correlation functions associated with the transformed hopping operators and has been derived in Ref. [133]. It can be written as

$$Y_{k_1 k_2}(t) = -\frac{\tilde{J}^2}{N} \sum_{X,Y=\pm 1} \sum_Z XY e^{ik_1(X+Z)} e^{ik_2(X-Z)} \theta_{XYZ}(t), \quad (4.15)$$

where X , Y , and Z denote lattice-site displacements entering the transformed hopping processes, and $\theta_{XYZ}(t)$ describes the corresponding phonon correlations.

To distinguish between coherent and incoherent contributions, the function $\theta_{XYZ}(t)$ is decomposed as

$$\theta_{XYZ}(t) = \theta_{XYZ}^{(0)} + \theta_{XYZ}^{(1)}(t). \quad (4.16)$$

The term $\theta_{XYZ}^{(1)}(t)$ contains oscillatory factors of the form $e^{i l \omega_0 t}$, corresponding to processes involving phonon emission and absorption. Since polaron band transport is dominated by coherent motion, such processes are neglected, and only the static contribution $\theta_{XYZ}^{(0)}$ is retained in the following.

The expectation values entering the correlation function can be expressed in terms of the polaron spectral function $\tilde{A}_k(\omega)$ as

$$\langle a_k^\dagger(t) a_k \rangle = \int d\omega e^{i\omega t} \tilde{A}_k(\omega) e^{-\beta\omega}, \quad (4.17)$$

$$\langle a_k(t) a_k^\dagger \rangle = \int d\omega e^{-i\omega t} \tilde{A}_k(\omega). \quad (4.18)$$

Using the Kubo formalism, the dc mobility can then be expressed in terms of the spectral function and the renormalized band velocity $\tilde{v}_k = -2\tilde{J} \sin k$. In the low-temperature regime relevant for polaron band transport, the phonon occupation number is small, and the Bessel-function contributions entering $\theta_{XYZ}^{(0)}$ can be approximated by unity, so that multi-phonon processes are effectively suppressed and the dominant coherent contribution is retained. This leads to the simplified expression

$$\mu_{\text{dc}} = \pi\beta \frac{\sum_k \tilde{v}_k^2 \int d\omega \tilde{A}_k(\omega)^2 e^{-\beta\omega}}{\sum_k \tilde{n}_k}, \quad (4.19)$$

where $\tilde{n}_k = e^{-\beta\tilde{\epsilon}_k}$.

Assuming a narrow spectral function, which corresponds to long-lived quasiparticles with weak scattering, the integral can be evaluated as

$$\int d\omega \tilde{A}_k(\omega)^2 e^{-\beta\omega} = -\frac{e^{-\beta\omega}}{2\pi\text{Im}\Sigma_k(\omega)} \Big|_{\omega=\tilde{\epsilon}_k} = \frac{\tilde{n}_k \tilde{\tau}_k}{\pi}, \quad (4.20)$$

where $\tilde{\tau}_k$ denotes the polaron lifetime, determined by the imaginary part of the self-energy (see Section 2.3). The explicit form of the self-energy $\Sigma_k(\omega)$ is provided in Appendix D.

The dc mobility then takes the form

$$\mu_{\text{dc}} = \beta \frac{\sum_k \tilde{n}_k \tilde{\tau}_k \tilde{v}_k^2}{\sum_k \tilde{n}_k}, \quad (4.21)$$

which has the same formal structure as the band transport expression derived in Section 2.3.2, with all quantities replaced by their renormalized counterparts.

To evaluate the imaginary-time current–current correlation function, an additional approximation can be introduced by treating the spectral function as sharply peaked, $\tilde{A}_k(\omega) \approx \delta(\omega - \tilde{\epsilon}_k)$, effectively neglecting lifetime effects and retaining only the quasiparticle energy. While this approximation is not sufficient for describing real-time dynamics or dc mobility, it is adequate for imaginary-time quantities, which are primarily sensitive to the energy distribution rather than the detailed spectral broadening.

The corresponding correlation function is then given by

$$C_{jj}(z) = \frac{\sum_{k_1 k_2} e^{-\beta\tilde{\epsilon}_{k_1}} e^{i(\tilde{\epsilon}_{k_1} - \tilde{\epsilon}_{k_2})z} Y_{k_1 k_2}^{(0)}}{\sum_k e^{-\beta\tilde{\epsilon}_k}}, \quad (4.22)$$

where $z = -i\tau$ ($0 \leq \tau \leq \beta$), and $Y_{k_1 k_2}^{(0)}$ denotes the contribution corresponding to coherent processes, obtained from Eq. (4.15) by replacing θ_{XYZ} with $\theta_{XYZ}^{(0)}$.

As discussed in Section 2.3, polaron band transport is expected to dominate at low temperatures in the strong-coupling regime. To compare the two transport mechanisms, the mobility obtained from Eq. (4.21) is considered alongside the hopping mobility given by Eq. (4.10). The intersection of the corresponding curves can be used as a rough estimate of the crossover between the two transport mechanisms.

The comparison between the mobilities obtained within the polaron band and hopping transport descriptions is shown in Fig. 4.3. A clear trend can be observed as the interaction strength λ increases: the intersection between the polaron band and hopping mobilities progressively shifts towards lower temperatures. This indicates that, for stronger electron–phonon coupling, the system transitions to hopping transport already at relatively low temperatures. In this regime, the increased coupling leads to stronger localization of charge carriers, which suppresses coherent motion within the polaron band and favors thermally activated hopping processes.

The role of the phonon frequency is also evident from the figure. As ω_0 increases, the crossover shifts to higher temperatures. This behavior is consistent with the trend already observed in the hopping regime and reflects the fact that larger phonon energies require higher thermal energy for incoherent, phonon-assisted processes to become dominant. In other words, for higher phonon frequencies, the system remains in the coherent, band-like regime over a wider temperature range.

Finally, it is important to emphasize that this comparison is physically meaningful primarily in the strong-coupling regime. For weaker interaction strengths, the assumptions underlying both the hopping and the polaron band descriptions are not strictly satisfied, and the interpretation of the crossover becomes less reliable. For this reason, only results corresponding to sufficiently large interaction strengths (e.g., $\lambda \gtrsim 0.5$) are considered when identifying the crossover between polaron band and hopping transport.

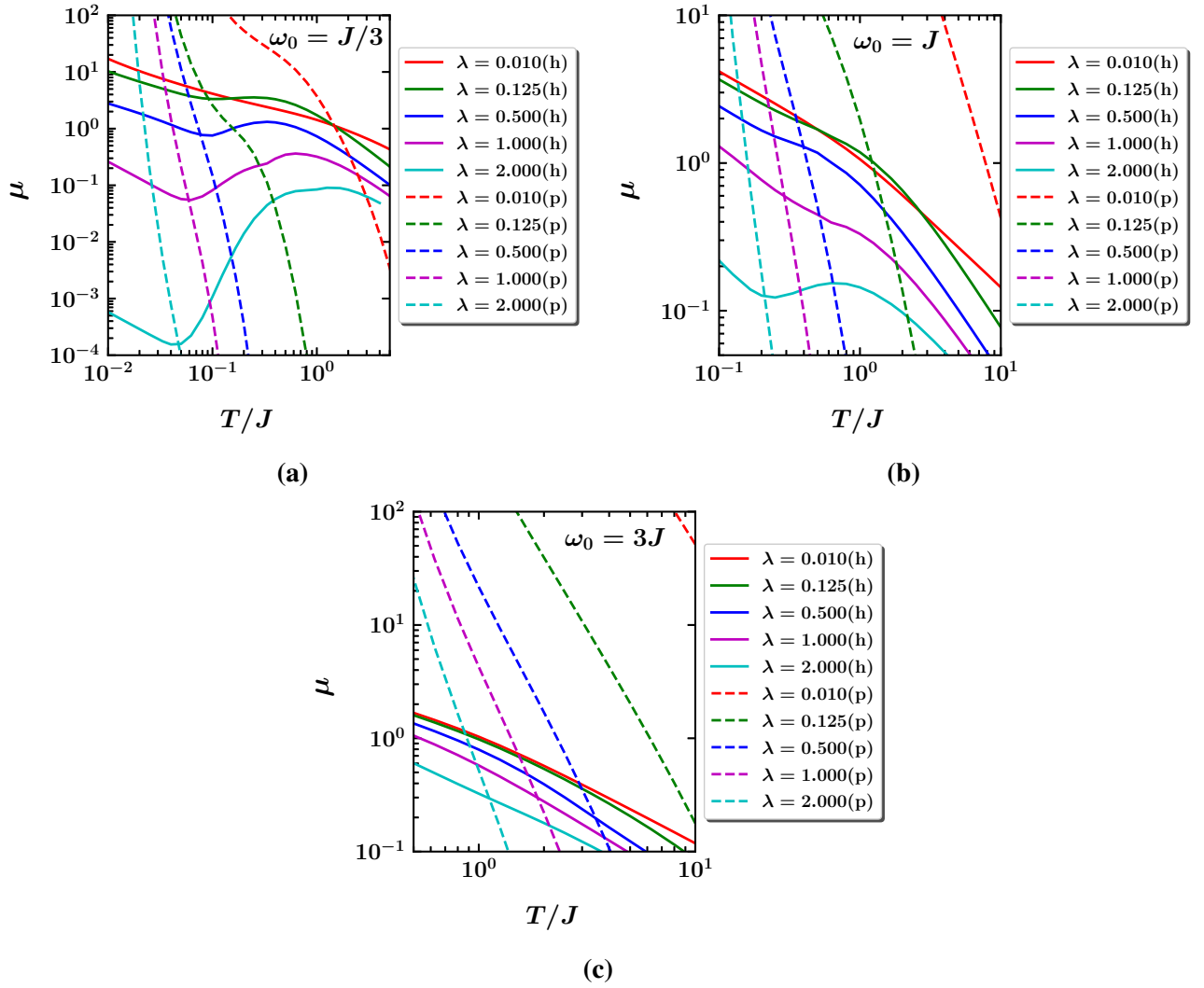


Figure 4.3: Temperature dependence of the mobility in the hopping and polaron band transport regimes for different interaction strengths λ . Solid lines (label “h”) correspond to hopping transport (Eq. (4.10)), while dashed lines (label “p”) correspond to polaron band transport (Eq. (4.21)). Panels (a)–(c) correspond to $\omega_0 = J/3$, $\omega_0 = J$, and $\omega_0 = 3J$, respectively.

4.1.3 Band transport regime and crossover to hopping regime

Transport in the weak-coupling regime is well described within the conventional band transport picture, as outlined in Section 2.3.2. In this regime, charge carriers remain delocalized over many lattice sites and form large polarons, whose spatial extent is significantly larger than the lattice spacing. Their motion therefore retains a coherent, band-like character and can be described in terms of Bloch states associated with a relatively wide electronic band. The electron–phonon interaction leads only to a weak renormalization of this band, resulting in a moderate increase of the effective mass, so that the polaron behaves similarly to a nearly free particle with only slight dressing by lattice vibrations.

At the same time, coupling to phonons introduces scattering processes that limit the lifetime of these delocalized states. The probability of such scattering events increases with temperature due to the growing phonon population, leading to a progressive suppression of coherent motion. In contrast to the strong-coupling regime, where the bandwidth is strongly reduced and carriers become localized, the relatively large bandwidth in this case still allows for extended motion across the lattice. The resulting transport behavior is therefore governed by the interplay between coherent band propagation and temperature-dependent phonon scattering.

In the band transport picture, the current operator is diagonal in momentum space, so that charge

transport can be expressed in terms of contributions from individual momentum states. As a result, the current–current correlation function naturally takes a momentum-resolved form, which can be written as

$$C_{jj}(t) = \frac{\sum_{k,k'} v_k v_{k'} \langle a_k^\dagger(t) a_k(t) a_{k'}^\dagger a_{k'} \rangle}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (4.23)$$

For sufficiently weak electron–phonon interaction, the current–current correlation function can be evaluated within the independent-particle (bubble) approximation. In this approximation, scattering processes are weak enough that different momentum states evolve independently, so that the two-particle correlation function factorizes into a product of two single-particle expectation values. The four-operator average then reduces to the form adopted in Ref. [136],

$$\langle a_k^\dagger(t) a_k(t) a_{k'}^\dagger a_{k'} \rangle = \delta_{kk'} \langle a_k^\dagger(t) a_k \rangle \langle a_k(t) a_{k'}^\dagger \rangle, \quad (4.24)$$

which yields

$$C_{jj}(t) = 4J^2 \frac{\sum_k \langle a_k^\dagger(t) a_k \rangle \langle a_k(t) a_k^\dagger \rangle \sin^2(k)}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (4.25)$$

The expectation values entering the current–current correlation function can be expressed in terms of the electronic spectral function as

$$\langle a_k^\dagger(t) a_k \rangle = \int_{-\infty}^{\infty} d\omega e^{i\omega t} A_k(\omega) e^{-\beta\omega}, \quad (4.26)$$

$$\langle a_k(t) a_k^\dagger \rangle = \int_{-\infty}^{\infty} d\omega e^{-i\omega t} A_k(\omega). \quad (4.27)$$

The spectral function is defined as

$$A_k(\omega) = -\frac{1}{\pi} \text{Im} G_k^R(\omega), \quad (4.28)$$

where $G_k^R(\omega)$ denotes the retarded Green’s function, which incorporates the effects of the electron–phonon interaction through the self-energy and is related to it through the Dyson equation,

$$G_k^R(\omega) = \frac{1}{\omega - \varepsilon_k - \Sigma_k(\omega)}. \quad (4.29)$$

Within the weak-coupling regime, the self-energy $\Sigma_k(\omega)$ is evaluated within the Migdal approximation, where only processes involving a single phonon line are retained. The self-energy is then written as [37, 142]

$$\Sigma_k(\omega) = \frac{G^2}{N} \sum_q \left[(n_{\text{ph}} + 1) G_{k-q}^{(0)}(\omega - \omega_0) + n_{\text{ph}} G_{k-q}^{(0)}(\omega + \omega_0) \right], \quad (4.30)$$

where $G_k^{(0)}(\omega) = (\omega - \varepsilon_k + i0^+)^{-1}$ denotes the Green’s function of a free particle. Performing the summation over momentum yields

$$\Sigma(\omega) = G^2 (n_{\text{ph}} + 1) S(\omega - \omega_0) + G^2 n_{\text{ph}} S(\omega + \omega_0), \quad (4.31)$$

where the function $S(\omega)$ corresponds to the contribution of single-phonon processes and is given by

$$S(\omega) = \begin{cases} \frac{\text{sgn}(\omega)}{\sqrt{\omega^2 - 4J^2}}, & \text{if } \left| \frac{\omega}{2J} \right| > 1, \\ \frac{-i}{\sqrt{4J^2 - \omega^2}}, & \text{if } \left| \frac{\omega}{2J} \right| < 1. \end{cases} \quad (4.32)$$

Details of the evaluation of Eq. (4.30), as well as the derivation of the resulting expressions, are provided in Appendix D.

It is important to note that, for $\omega > 2J$, energy conservation restricts single-phonon scattering processes for certain momenta. In this case, the imaginary part of the self-energy vanishes within the Migdal approximation, implying an infinite quasiparticle lifetime and, consequently, a divergent mobility. This indicates that the present approximation becomes insufficient in this regime, and that higher-order processes must be taken into account. In particular, contributions involving two phonon lines restore a finite scattering rate and provide a consistent description of carrier dynamics. The corresponding expressions are presented in Appendix D.

With these considerations in mind, the dc mobility in the band transport regime is given by the standard expression [133]

$$\mu_{\text{dc}} = \beta \frac{\sum_k n_k \tau_k v_k^2}{\sum_k n_k}, \quad (4.33)$$

where $n_k = e^{-\beta \varepsilon_k}$ denotes the occupation of electronic states and the scattering time is defined as $\tau_k^{-1} = -2 \text{Im} \Sigma_k(\omega)|_{\omega=\varepsilon_k}$.

This expression has the same formal structure as that obtained for polaron band transport (Eq. (4.21)), with the key difference that the quantities entering the expression correspond to the bare electronic band. In contrast to the strong-coupling regime, where transport is governed by localized or strongly renormalized states, the mobility here reflects the dynamics of delocalized carriers subject to phonon-induced scattering.

Even in the weak-coupling regime, a crossover from band transport to hopping transport may occur at sufficiently high temperatures. As the temperature increases, phonon scattering becomes more pronounced, leading to a rapid decrease of the band mobility. In contrast, the hopping mobility exhibits a weaker temperature dependence in this regime, so that the two transport mechanisms become comparable at elevated temperatures.

This behavior is illustrated in Fig. 4.4. With increasing temperature, the hopping mobility gradually approaches the band mobility, and the two curves eventually intersect. This intersection provides a rough estimate of the crossover from coherent band-like transport to incoherent hopping dynamics at high temperatures.

It should be emphasized that this comparison is meaningful primarily in the weak-coupling regime. For larger interaction strengths, the assumptions underlying the band transport description are no longer valid, and the interpretation of the crossover becomes less reliable. For this reason, only results corresponding to sufficiently small interaction strengths (e.g., $\lambda \lesssim 0.5$) are considered when analyzing this behavior.

4.2 Identification of the transport regimes in parameter space of Holstein model based on numerically exact calculations

The analysis presented in the previous section establishes the expected ranges of validity of the different transport regimes across the parameter space of the one-dimensional Holstein model. In particular, at low temperatures and strong electron–phonon coupling, transport is expected to occur through coherent motion within a narrow polaron band. In contrast, at high temperatures and strong coupling, thermally activated hopping becomes the dominant transport mechanism. For weak electron–phonon interaction, transport is generally well described within the conventional band picture, although deviations may arise at sufficiently high temperatures.

To identify these regimes in a more precise manner and determine their ranges of validity in parameter space, it is necessary to compare the approximate descriptions introduced in the previous section with numerically exact results obtained without assuming a specific transport mechanism.

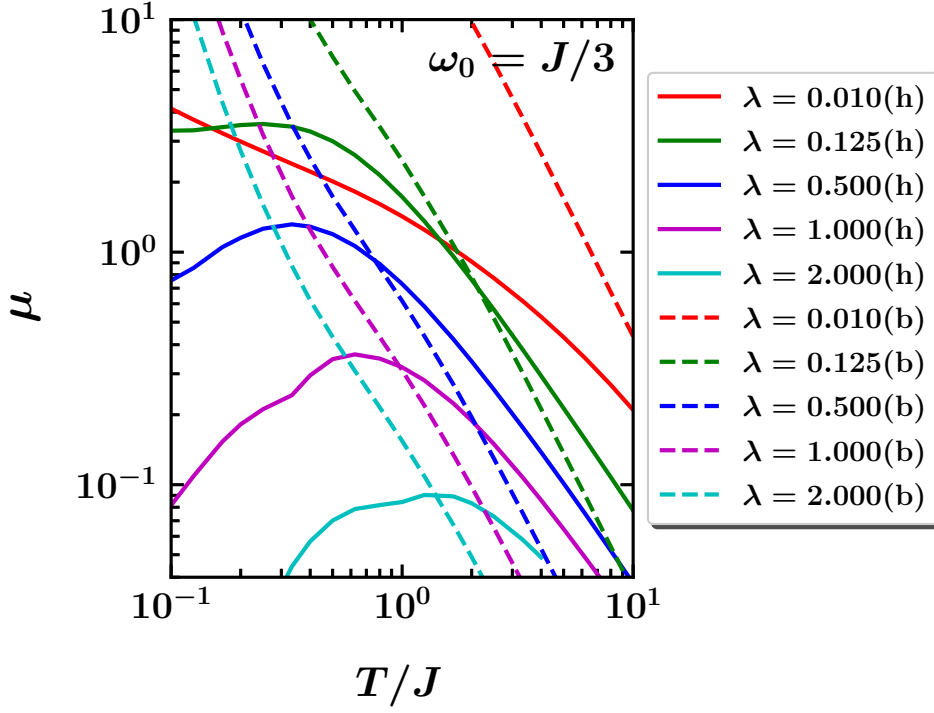


Figure 4.4: Temperature dependence of the mobility in the band and hopping transport regimes for several interaction strengths λ at $\omega_0 = J/3$. The band transport results [Eq. (4.33)] are shown as solid lines (labeled “b”), while the hopping results [Eq. (4.10)] are shown as dashed lines (labeled “h”)

To this end, numerically exact results for the imaginary-time current–current correlation function are obtained using the path-integral quantum Monte Carlo (QMC) method developed in Chapter 3. These results are compared with the corresponding expressions derived for each transport regime. The calculations are performed over a broad region of parameter space, covering temperatures in the range $0.1 \leq T/J \leq 10$, interaction strengths $0.01 \leq \lambda \leq 2.0$, and three representative phonon frequencies, $\omega_0/J = 1/3$, $\omega_0/J = 1$, and $\omega_0/J = 3$.

A direct comparison at the level of real-time correlation functions or dc mobility would be desirable, but such numerically exact results are not available over the full parameter range due to computational limitations. For a restricted set of parameters where these quantities can be evaluated, additional comparisons are performed. In particular, the dc mobility obtained within the different transport regimes is compared with numerically exact results reported in Ref. [33], obtained using the hierarchical equations of motion (HEOM) method, as well as with real- and imaginary-time QMC results presented in Chapter 3.

4.2.1 Imaginary time current-current correlation function in different regimes compared to QMC results

To compare the imaginary-time current–current correlation functions obtained from approximate transport theories with the numerically exact QMC results, a quantitative measure of the deviation between the two is introduced.

For the hopping and conventional band transport regimes, a numerical criterion is introduced to quantify the deviation between an approximate correlation function $C_{jj}^{(a)}(t)$ and the numerically exact result $C_{jj}^{\text{QMC}}(t)$, defined as

$$\mathcal{D}_{C_{jj}} = \frac{\int dt \left| C_{jj}^{\text{QMC}}(t) - C_{jj}^{(a)}(t) \right|}{\left| \int dt C_{jj}^{\text{QMC}}(t) \right|}, \quad (4.34)$$

where C_{jj}^{QMC} is taken as the reference. The two functions are considered to be in agreement when $\mathcal{D}_{C_{jj}} < 0.2$. This tolerance is chosen to be sufficiently small to ensure meaningful agreement, while still being large enough to account for numerical uncertainties and the inherent limitations of the approximate theoretical descriptions.

In the case of polaron band transport, a different numerical criterion must be employed. This is because the approximate expressions derived for this regime retain only coherent contributions, corresponding to processes within a narrow energy window determined by the renormalized bandwidth (see Section 4.1.2). In contrast, the exact correlation function obtained from QMC calculations contains additional contributions arising from multiphonon processes at higher energies. As a result, a direct comparison over the full time domain does not provide a reliable measure of agreement.

Instead, the comparison is performed at imaginary time $t = -i\beta/2$, which selectively probes the low-frequency part of the spectrum [73, 143]. As discussed in these works, the imaginary-time correlation function at $\tau = \beta/2$ is predominantly sensitive to frequencies around $\omega = 0$, with a resolution set by temperature. This makes it particularly suitable for assessing the low-energy behavior relevant for dc transport. Consequently, this choice directly targets the frequency range governing polaron band transport. The corresponding deviation is defined as

$$\mathcal{D}_{C_{jj}} = \frac{|C_{jj}^{\text{QMC}}(-i\beta/2) - C_{jj}^{(\text{p})}(-i\beta/2)|}{|C_{jj}^{\text{QMC}}(-i\beta/2)|}. \quad (4.35)$$

A threshold value $\mathcal{D}_{C_{jj}} < 0.5$ is chosen to identify the polaron band transport regime. This criterion is less restrictive than in the cases of hopping and band transport, reflecting both the stronger approximations underlying the polaron band description and the fact that the approximate and exact correlation functions include different contributions. Despite this, the chosen threshold remains sufficiently stringent to identify the regime where the approximate description captures the relevant low-energy behavior.

In the limit of weak electron–phonon interaction, the expressions for polaron band transport and conventional band transport coincide. In this limit, the interaction-dependent factors reduce to their noninteracting values, and the correlation function simplifies to

$$C_{jj}(z) = 4J^2 \frac{\sum_k e^{-\beta\varepsilon_k} \sin^2 k}{\sum_k e^{-\beta\varepsilon_k}}. \quad (4.36)$$

This expression is identical to that obtained for band transport. Consequently, in parameter regions where both numerical criteria indicate agreement with polaron band and conventional band transport, the system is assigned to the conventional band transport regime.

The deviation $\mathcal{D}_{C_{jj}}$ across the parameter space for all three transport regimes is shown in Fig. 4.5. Agreement between the approximate and numerically exact correlation functions is identified using the numerical criterion $\mathcal{D}_{C_{jj}} < 0.2$ for hopping and band transport.

To clarify the interpretation of this criterion, representative imaginary-time correlation functions for QMC, hopping, and band transport are shown in Fig. 4.6 for $\omega_0 = J/3$ and $\lambda = 0.5$. At high temperature ($T/J = 10.0$), the QMC results closely follow the hopping transport correlation function. This behavior is consistent with the small values of $\mathcal{D}_{C_{jj}}$ observed in Fig. 4.5, indicating that the hopping description captures the dominant transport mechanism in this regime.

At low temperature ($T/J = 0.1$), the situation is quite different. Neither the hopping nor the band transport expressions reproduce the QMC results, and clear deviations are visible over the entire time interval. This is reflected in Fig. 4.5, where the deviation exceeds the chosen threshold for both regimes, indicating that neither approximation provides a reliable description in this region of parameter space.

Certain regions of the parameter space are not covered in Fig. 4.5. In particular, the absence of data at low temperatures and strong coupling reflects the increasing difficulty of QMC calculations in

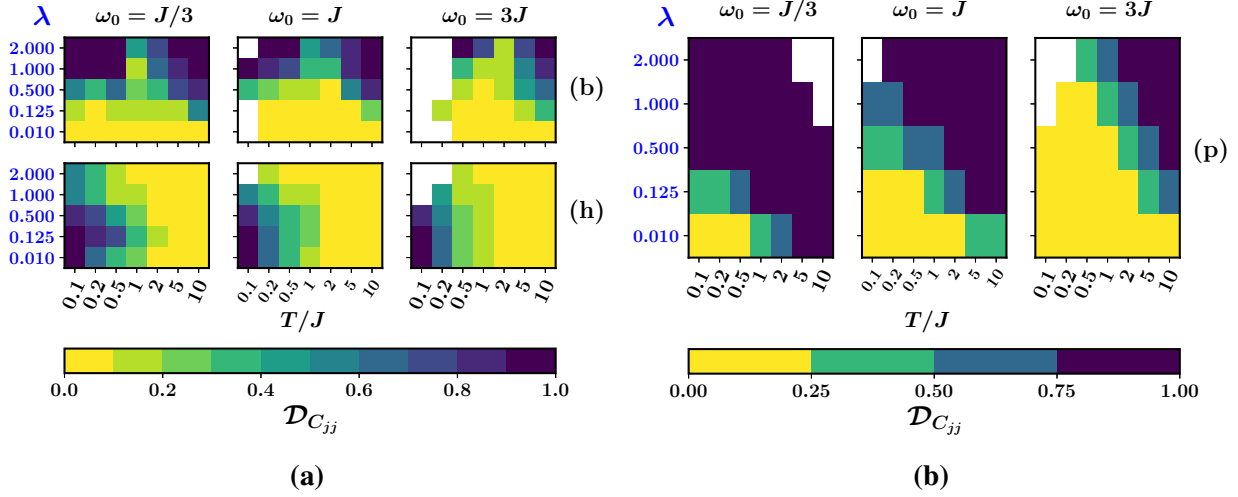


Figure 4.5: Relative deviation $\mathcal{D}_{C_{jj}}$ between approximate and numerically exact (QMC) imaginary-time current–current correlation functions as a function of temperature T and interaction strength λ for different phonon frequencies ω_0 . Each column corresponds to a different value of ω_0 . Panel (a) shows results for band transport (“b”) and hopping transport (“h”), while panel (b) shows results for polaron band transport (“p”).

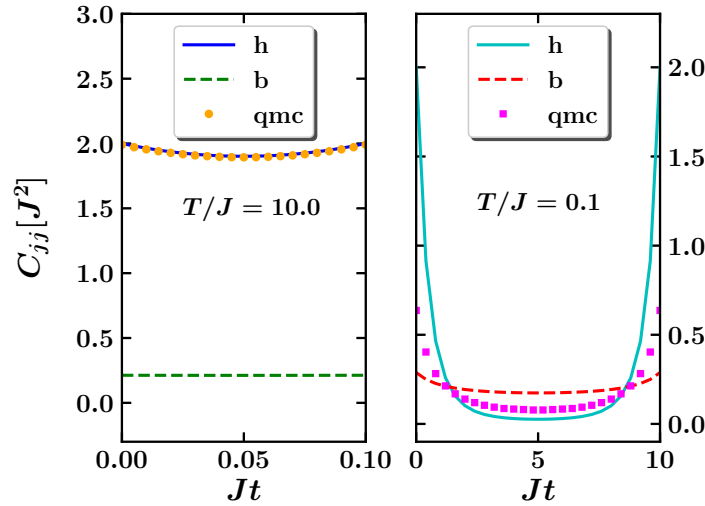


Figure 4.6: Imaginary-time current–current correlation functions for $\omega_0 = J/3$ and $\lambda = 0.5$. Panels (a) and (b) correspond to temperatures $T/J = 10.0$ and $T/J = 0.1$, respectively. Results for hopping transport (denoted by “h”) and band transport (denoted by “b”) are compared with numerically exact QMC results (points).

this regime. Additional limitations arise in the evaluation of the approximate correlation functions. For band transport, the spectral function becomes extremely narrow at low temperatures, which makes its numerical treatment increasingly challenging. In the case of polaron band transport, numerical instabilities related to the evaluation of Bessel functions appear at high temperatures and strong coupling for $\omega_0 = J/3$. However, this corresponds to a parameter region where this transport regime is not expected to play a significant role.

Figure 4.5 is therefore used as a basis for identifying the dominant transport mechanisms across a broad region of the parameter space. In most cases, the numerical criterion provides a clear indication of which transport description is applicable. However, there are regions where more than one transport regime appears to be consistent with the chosen criterion. In such cases, the classification is further refined by incorporating additional information from real-time correlation functions and dc mobility. This combined analysis provides a more complete characterization of the transport behavior and enables a clear reconstruction of the transport regime diagram in the following sections.

4.2.2 DC mobility in different transport regimes compared to numerically exact results

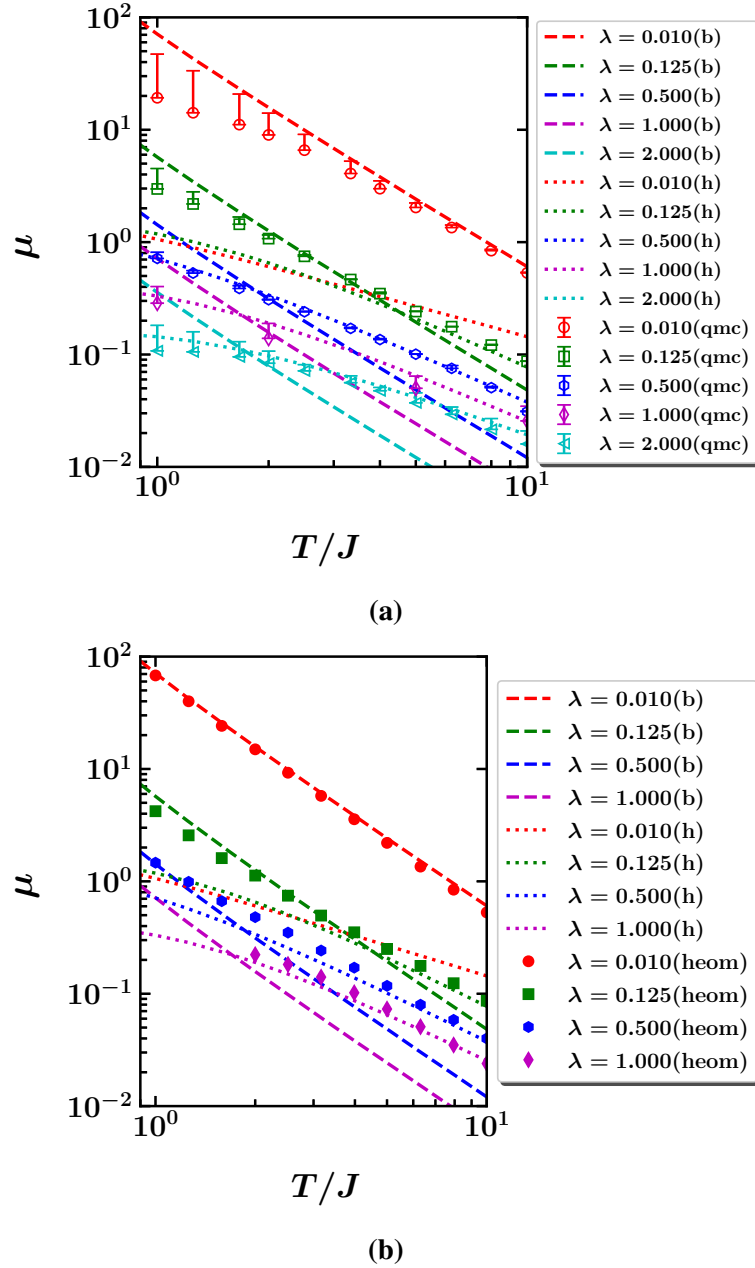


Figure 4.7: Temperature dependence of the mobility for hopping and band transport at $\omega_0/J = 1$. Results labeled “h” and “b” are compared with numerically exact data from (a) QMC and (b) HEOM, shown as symbols. Error bars for the QMC results are estimated as described in the previous chapter.

Figure 4.7 shows the temperature dependence of the mobility for different interaction strengths at $\omega_0 = J$. This value of phonon frequency is chosen because comprehensive and reliable numerically exact results are available from both QMC and HEOM [33] methods. The solid lines correspond to the approximate expressions for mobility derived in previous section, while the symbols represent the numerical data.

A clear level of agreement between the approximate and numerically exact results is observed within the parameter regions where the respective transport descriptions are expected to be valid. In the weak-coupling regime, the band transport expression, given with Eq. (4.33), follows the numerical data over the entire temperature range considered, reflecting the fact that charge carriers remain delocalized and retain a coherent, band-like character.

With increasing interaction strength, this behavior gradually changes. The coupling to lattice vibrations becomes more pronounced, leading to stronger renormalization and reduced carrier mobility. In this regime, the numerical results are more closely captured by the hopping transport expression, defined in Eq. (4.10), particularly at elevated temperatures, where transport is governed by thermally activated, incoherent motion between localized states.

These results confirm that the approximate transport theories capture the correct limiting behavior in their respective regimes. At the same time, they reveal the limitations of the criterion based on imaginary-time correlation functions, shown in Fig. 4.5, when distinguishing between band and hopping transport in certain regions of the parameter space. In particular, for weak interaction strengths at high temperatures, both approximate descriptions may appear consistent with the correlation-function-based criterion ($\mathcal{D}_{C_{jj}} < 0.2$), even though the mobility comparison clearly favors the band transport picture. This illustrates that the imaginary-time correlation-function-based criterion alone is not sufficient to unambiguously distinguish between these regimes in this parameter range.

Due to the difficulty of obtaining numerically exact results at very low temperatures, the crossover from polaron band transport to hopping transport is not visible in Fig. 4.7. However, as discussed in the previous section, the position of this crossover depends on the phonon frequency. For larger phonon frequencies, the crossover shifts to higher temperatures, where it becomes accessible within the range of the present calculations.

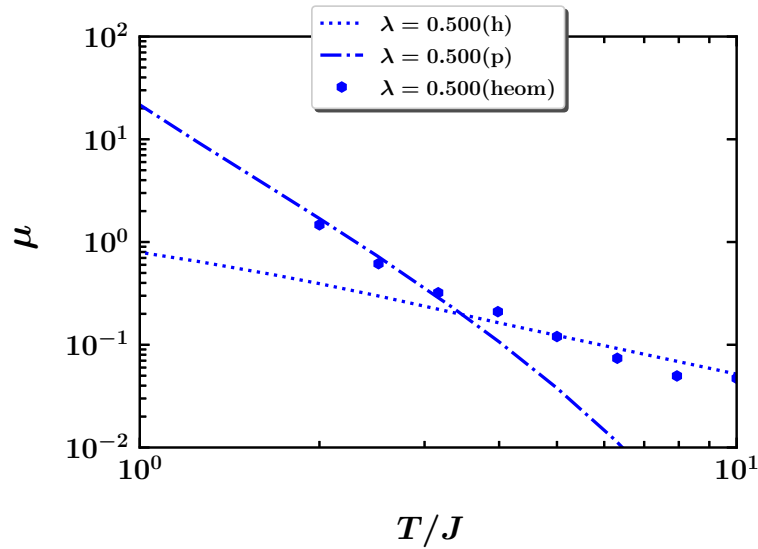


Figure 4.8: Temperature dependence of the mobility for hopping and polaron band transport at $\omega_0 = 3J$ and $\lambda = 0.5$. Hopping (“h”) and polaron band transport (“p”) results are compared with numerically exact HEOM data (symbols).

The crossover between polaron band and hopping transport is illustrated in Fig. 4.8. In this case, the intersection between the two approximate expressions occurs within the temperature range accessible to numerically exact calculations. The numerical data follow the polaron band transport curve at lower temperatures, while at higher temperatures they approach the hopping transport curve, with the crossover occurring in the vicinity of their intersection. This behavior provides direct support for identifying the crossover based on the intersection of the respective approximate mobility curves, as discussed in the previous section.

The combined analysis of imaginary-time correlation functions and dc mobility thus provides a consistent picture of transport across a broad region of the parameter space. While the imaginary-time correlation-function-based criterion offers a useful first indication of the relevant transport regime, the comparison of mobility allows for a more refined identification, particularly in regions where different descriptions appear to overlap. Taken together, these results establish a reliable basis for mapping out

the transport regimes of the Holstein model, which is presented in the following section in the form of a transport regime diagram.

4.2.3 Transport regime diagram for one-dimensional Holstein model

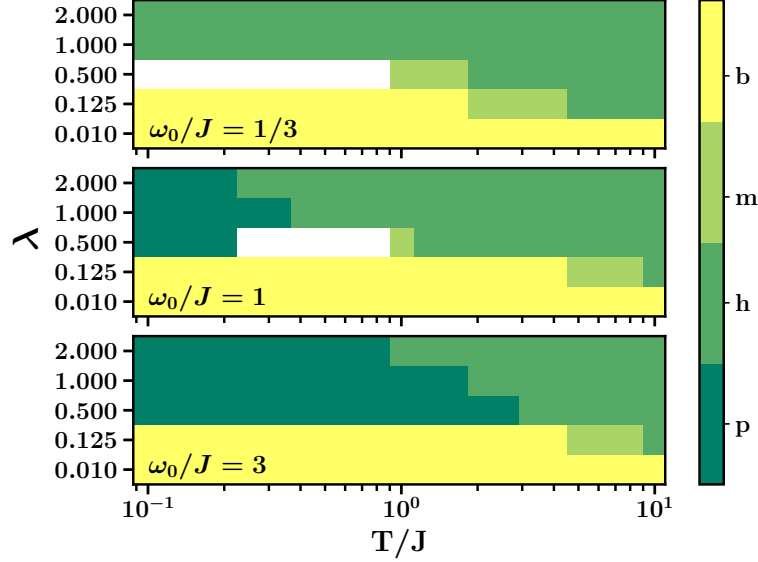


Figure 4.9: Transport regime diagram of the one-dimensional Holstein model for different phonon frequencies ω_0/J . The results are shown in the $(T/J, \lambda)$ parameter space. The regimes are labeled as conventional band transport (“b”), hopping transport (“h”), and polaron band transport (“p”). Regions marked as “m” indicate an intermediate regime where no single transport theory provides a fully consistent description.

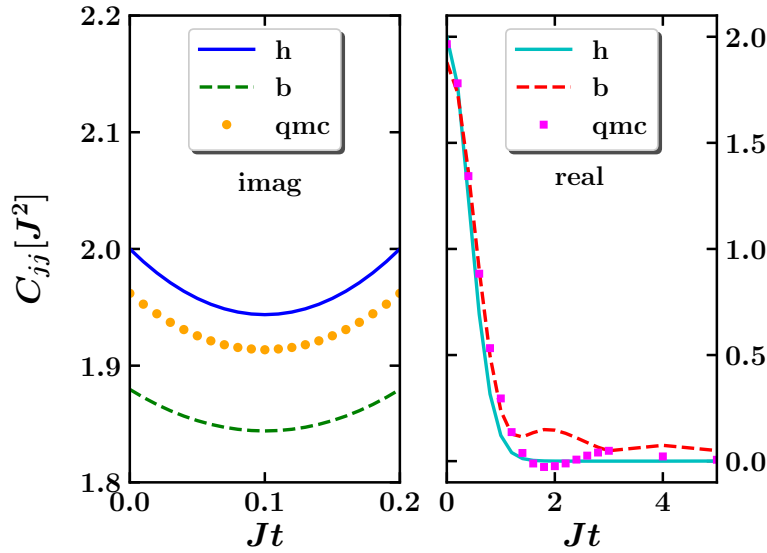


Figure 4.10: Imaginary- and real-time current-current correlation functions for $\omega_0 = J$, $\lambda = 0.125$, and $T/J = 5.0$. Results for hopping transport (“h”) and band transport (“b”) are compared with numerically exact QMC data (points).

The transport regime diagram obtained from the combined analysis is shown in Fig. 4.9. In the following, the construction of this diagram is described in detail for the representative case $\omega_0 = J$, while analogous results for other phonon frequencies are presented in Appendix E.

The identification of the different transport regimes proceeds by combining the information from the numerical criterion $\mathcal{D}_{C_{jj}}$ shown in Fig. 4.5 with the mobility comparison in Fig. 4.7. From

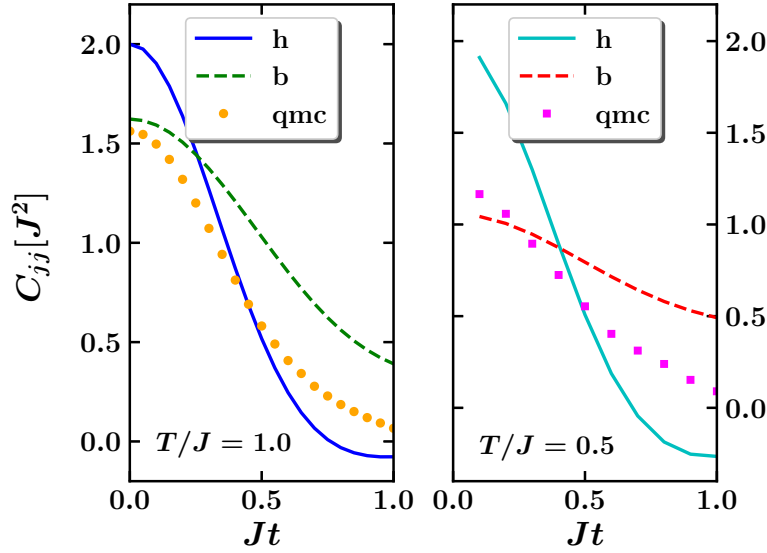


Figure 4.11: Real-time current–current correlation functions for $\omega_0 = J$, $\lambda = 0.5$, and temperatures $T/J = 1.0$ and $T/J = 0.5$. Results for hopping transport (“h”) and band transport (“b”) are compared with numerically exact QMC data (points)

Fig. 4.5, it is evident that the band transport regime dominates at low temperatures and weak interaction strengths. As the temperature increases, the deviation measure $\mathcal{D}_{C_{jj}}$ indicates that both band and hopping transport may be consistent with the numerically exact results, leading to an ambiguous classification in this region.

This ambiguity is resolved by considering the mobility. For the weakest interaction strength, the numerical data follow the band transport expression over the entire temperature range, and no intersection between the band and hopping mobility curves is observed. This confirms that transport remains governed by the band transport regime in this region of parameter space.

For the next interaction strength, $\lambda = 0.125$, the distinction between band and hopping transport becomes less clear. As shown in Fig. 4.7, both approximate expressions yield very similar results and remain consistent with the numerically exact data. This ambiguity is also reflected in the comparison of real-time correlation functions in Fig. 4.10, where both transport descriptions provide a comparable level of agreement with the QMC results.

This behavior indicates that the system cannot be unambiguously assigned to a single transport regime in this region, and it is therefore identified as an intermediate regime between band and hopping transport. At the highest temperatures, however, a transition toward hopping behavior is indicated, as the imaginary-time correlation function for the band transport approximation begins to deviate from the QMC results.

For stronger interaction strength, $\lambda = 0.500$, Fig. 4.5 indicates that hopping transport dominates at temperatures above $T/J \approx 2.0$, while at low temperatures ($T/J \lesssim 0.2$) the system is found in the polaron band transport regime. In the intermediate temperature range, the numerical criterion $\mathcal{D}_{C_{jj}}$ suggests possible agreement with band transport. However, the real-time correlation functions shown in Fig. 4.11 reveal that, although band transport provides a better approximation than hopping, noticeable deviations from the QMC results persist.

This indicates that neither description is fully adequate in this region, and it is therefore classified as an undefined regime. In Fig. 4.9, regions shown in white correspond to parameter ranges where none of the considered transport descriptions are in satisfactory agreement with the numerical results. In contrast, the region around $T/J \approx 1.0$ is denoted as an intermediate band–hopping regime, where both band and hopping transport provide a comparable level of agreement with the numerical data.

For $\lambda = 1.000$, Fig. 4.5 clearly identifies hopping transport as the dominant mechanism for temperatures $T/J \gtrsim 0.5$. The crossover between polaron band and hopping transport is estimated

from the intersection of the corresponding mobility curves (Fig. 4.3), which occurs in the range $T/J \approx 0.2\text{--}0.3$. In this case, the intersection of the approximate expressions is used as an indicator of the crossover between the two regimes. As discussed in the previous analysis, this approach is supported by the comparison with numerically exact results, where the crossover is found to occur in the vicinity of the intersection point (see Fig. 4.8). Below this temperature range, transport is therefore assigned to the polaron band regime.

The same reasoning applies to the case $\lambda = 2.000$, where the crossover occurs at slightly lower temperatures, reflecting the stronger electron–phonon coupling and the enhanced localization of charge carriers.

The results confirm the anticipated limiting behavior, showing that band transport prevails for weak coupling at low temperatures, hopping transport becomes dominant at strong coupling and high temperatures, while at strong coupling and low temperatures, transport proceeds via a polaronic band mechanism. These three regimes are found to account for the transport behavior over most of the parameter space considered in this work, which spans a broad and physically relevant range of conditions, from low to high temperatures ($0.1 \leq T/J \leq 10$) and from weak to strong interaction strengths ($0.01 \leq \lambda \leq 2$).

Only a limited portion of the parameter space exhibits intermediate or undefined behavior, corresponding to parameter ranges in which the relevant energy scales are of comparable magnitude. In the present case, this occurs for temperatures of the order $T/J \sim 1$ and interaction strengths around $\lambda \sim 0.5$. In this regime, no single transport theory provides a fully consistent description, which reflects the intrinsic difficulty of capturing transport in this crossover region.

Nevertheless, even in this case, the combined analysis allows for a consistent characterization of transport behavior across the physically relevant part of the parameter space, particularly in the region around $T/J \sim 1$ and intermediate interaction strengths $\lambda \sim 0.5\text{--}1.0$. In addition, a systematic shift of temperature effects with phonon frequency is observed. For larger phonon frequencies, the crossover between polaron band and hopping transport occurs at higher temperatures, allowing the full transition to be resolved, as in the case $\omega_0 = 3J$. For smaller phonon frequencies, such as $\omega_0 = J/3$, the same crossover is shifted beyond the accessible temperature range, leading to a competition between band and hopping transport expected at high temperatures.

For intermediate phonon frequency $\omega_0 = J$, all three transport regimes are captured and provide a consistent description over nearly the entire parameter space, with only a small region around $\lambda \sim 0.5$ and $T/J \sim 1$ exhibiting intermediate or undefined behavior. This parameter range closely corresponds to the regime relevant for molecular crystals, indicating that the transport behavior in these systems can, to a large extent, be described within the theoretical framework considered in this work.

These results provide a consistent and physically grounded description of transport across the relevant parameter space of the one-dimensional Holstein model, completing the identification of transport regimes in this system.

Chapter 5

Conclusions

This thesis has presented a comprehensive study of charge transport in electron–phonon coupled systems within the framework of the Holstein model, with particular emphasis on the development and application of a numerically exact path-integral quantum Monte Carlo (QMC) methodology. The central objective was to establish a consistent and unbiased framework for the calculation of current–current correlation functions and the corresponding dc mobility, and to apply this approach to the investigation of transport properties over a broad range of parameters.

A key outcome of this work is the formulation and implementation of current–current correlation functions within the path-integral QMC framework and their use for the determination of dc mobility. By combining imaginary-time and real-time correlation functions, and by employing both the electron position basis and the momentum basis in the path-integral formulation, a methodology has been developed that mitigates the limitations imposed by the dynamical sign problem and improves the outcome of the analytic continuation procedure. This approach enables the determination of current–current correlation functions and mobility with controlled accuracy, and provides a consistent and quantitatively supported description of the dynamical behavior of charge carriers across different transport regimes.

The capabilities of this approach are demonstrated through its application to the calculation of dc mobility and the analysis of transport behavior across the parameter space of the Holstein model.

The results for the dc mobility obtained in Chapter 3 of this thesis show very good agreement with those reported in Ref. [133]. For almost all parameter values studied, the results of that reference, obtained using an unrelated approximate method, fall within the error bars of the QMC results presented in Chapter 3 (see Fig. 3.8). This level of agreement indicates that the approach of Ref. [133] provides a reliable description within the corresponding parameter ranges. At the same time, this comparison highlights the role of numerically exact QMC results as a benchmark for a broad class of approximate and computational methods. Although the QMC approach employed in this thesis remains limited by the dynamical sign problem and the challenges of analytic continuation, the extension to longer accessible real-time intervals, together with the achieved statistical precision, provides sufficiently reliable data over a broad portion of parameter space, making it well suited for such benchmarking purposes.

A similar comparison can be made with the results reported in Ref. [66], which presents the temperature dependence of the Holstein polaron mobility obtained using a similar unbiased numerical approach. For the weakest interaction ($G/J = 0.141$) and higher temperatures, the results of Ref. [66] are in good agreement with those obtained in Chapter 3 (see Fig. 3.8). These parameter regimes correspond to the cases in which the path-integral QMC method developed in this thesis achieves its highest accuracy, as the full real-time decay of the current–current correlation function can be captured within the accessible time window. Under these conditions, the mobility can be determined by direct integration of the real-time correlation function in accordance with the Kubo formula, yielding results with negligible uncertainty determined by the statistical error of the correlation function.

For stronger interactions and lower temperatures, clear differences emerge. In these regimes,

capturing the full time decay of the correlation function requires longer real-time intervals, while the analytic continuation procedure requires sufficiently extended and reliable data to reconstruct the real-time behavior faithfully. In this case, the comparison with Ref. [66] shows that the mobility values reported in that reference are consistently lower. For example, for the strongest interaction considered in Chapter 3, $G/J = 2.83$ and temperature $T/J = 2$, the method developed in this thesis yields mobility values in the range $\mu \in (3.1 \times 10^{-2}, 7.2 \times 10^{-2})$ (see Fig. 3.8), whereas Ref. [66] reports values in the range $\mu \in (2.8 \times 10^{-3}, 8.1 \times 10^{-3})$, i.e., approximately one order of magnitude smaller.

This difference can be understood by examining the structure of the current–current correlation function. For strong interactions, the correlation function exhibits multiple resonant peaks at times corresponding to integer multiples of the phonon period $2\pi/\omega_0$, with amplitudes that decrease with increasing time. This behavior is visible in the approximate results of Ref. [133] (see Fig. 3.6). The QMC method employed in this thesis captures the first and largest peak with high precision. Integration over this initial peak alone already yields a contribution of approximately 1.5×10^{-2} to the mobility, while inclusion of subsequent peaks would further increase the final value.

The lower values reported in Ref. [66] can therefore be attributed to the limitations of the analytic continuation procedure employed in that reference, which relies exclusively on imaginary-time QMC data. This provides a clear illustration of the limitations associated with analytic continuation procedures based solely on imaginary-time input, as the lack of direct real-time information restricts the accuracy of the reconstructed real-time dynamics. In contrast, the approach developed in this thesis incorporates additional input from real-time data, and even the simple SVD-based continuation scheme used here leads to a noticeable improvement in the resulting mobility values, indicating that the inclusion of real-time information plays an important role in improving the outcome of analytic continuation.

The results presented in Chapter 4 further demonstrate the role of the numerically exact QMC data obtained in this thesis as a benchmarking reference, in this case for established theoretical descriptions of polaron transport. The detailed analysis of current–current correlation functions and mobilities shows that almost the entire studied parameter space can be adequately described within the framework of three well-known transport mechanisms: hopping transport, conventional band transport, and polaron band transport. This represents an important result, as it confirms that the transport properties of the Holstein polaron can, to a large extent, be understood within existing theoretical frameworks, thereby reducing the need for computationally demanding methods in regimes where these theories are applicable.

The findings of Chapter 4 can be further compared with those reported in Refs. [49] and [144]. In Ref. [49], a Holstein–Peierls model, also relevant for organic semiconductors, is considered. That reference examines transport regimes as functions of electronic coupling strength and non-local electron–phonon interaction. However, temperature dependence is not explicitly addressed. Due to these differences in both the form of the Hamiltonian and the parameters considered, a direct quantitative comparison with the results obtained in this thesis is not possible. Nevertheless, the general conclusions of Ref. [49], namely the identification of band-like transport at large electronic coupling and phonon-assisted (hopping-type) transport at small electronic coupling, are in qualitative agreement with the results obtained in Chapter 4.

In Ref. [144], a two-site Holstein model is studied and crossovers between different transport regimes are analyzed as they evolve in time for various values of the adiabaticity ratio. The identified regimes include polaronic transport, soft-gating, and transient localization. The analysis presented in Chapter 4 of this thesis provides a complementary perspective to the results reported in these references. In particular, the analysis in this thesis systematically investigates the effect of temperature over a broad range, which is not considered in Ref. [49]. Furthermore, while Ref. [144] focuses on short-range transport in a two-site system, the results of this thesis address long-range charge transport thereby extending the scope of the analysis.

The results obtained in this work establish a numerically exact and internally consistent framework

for the investigation of charge transport in electron–phonon coupled systems. The combination of path-integral QMC methods with a correlation-function-based analysis enables a unified description of transport across different regimes of Holstein polaron model.

An important outcome of this work is the demonstration that numerically exact QMC data provide a reliable benchmark for assessing the validity of approximate theoretical and computational approaches. Such benchmarking is particularly valuable in parameter regimes where the assumptions underlying simplified models are no longer valid, while at the same time allowing the identification of regimes in which computationally less demanding methods can be applied with confidence.

The developed methodology also offers clear directions for future work. The combination of different representations in the path-integral formalism and the joint analysis of imaginary- and real-time data can be extended to other model Hamiltonians and, potentially, to more realistic systems. In particular, the application of this approach to Hamiltonians derived from *ab initio* calculations represents a promising route toward connecting microscopic modeling with material-specific transport properties.

Furthermore, the strategy of combining imaginary- and real-time data for analytic continuation is not limited to the specific numerical scheme employed in this work and can be integrated with other continuation methods. This suggests that improvements in analytic continuation may be achieved not only through algorithmic developments, but also through the inclusion of additional physically relevant input data.

In conclusion, this thesis provides both methodological advances and physical insight into charge transport in electron–phonon coupled systems. The developed framework enables a consistent interpretation of transport behavior across different regimes and establishes a foundation for future theoretical and computational studies in this field.

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Appendix A

Path-integral construction details

A.1 Action of exponential operators

In this appendix, the details of the evaluation of matrix elements of the exponential operators appearing in Sec. X are presented. For notational simplicity, explicit site indices are suppressed when no ambiguity arises, and the notation X^j is used to denote the set of phonon coordinates $\{X_n^j\}_{n=0}^{N-1}$ corresponding to all lattice sites at a given time slice j .

Evaluation of electronic matrix elements

Since the hopping Hamiltonian H_2 acts only on the electronic degrees of freedom, its action is determined entirely by the choice of electron basis. In the momentum representation, H_2 is diagonal and can be written as

$$H_2 = \sum_k \varepsilon(k) c_k^\dagger c_k, \quad \varepsilon(k) = -2J \cos(k). \quad (\text{A.1})$$

Its action on a momentum basis state is therefore immediate,

$$e^{-zH_2} |q; X\rangle = e^{-z\varepsilon(q)} |q; X\rangle. \quad (\text{A.2})$$

In the position representation, the operator e^{-zH_2} is no longer diagonal. Its matrix elements are obtained by inserting a resolution of identity in the momentum basis,

$$\langle r_j | e^{-zH_2} | r_{j+1} \rangle = \sum_k \langle r_j | k \rangle e^{-z\varepsilon(k)} \langle k | r_{j+1} \rangle. \quad (\text{A.3})$$

Using the Fourier-transform convention

$$\langle k | r \rangle = \frac{1}{\sqrt{N}} e^{ikr}, \quad \langle r | k \rangle = \frac{1}{\sqrt{N}} e^{-ikr}, \quad (\text{A.4})$$

one obtains

$$\langle r_j | e^{-zH_2} | r_{j+1} \rangle = \frac{1}{N} \sum_k e^{ik(r_{j+1}-r_j)} e^{2Jz \cos(k)}. \quad (\text{A.5})$$

The sum is invariant under $k \rightarrow -k$, because both $\cos(k)$ and $\cos(k(r_{j+1} - r_j))$ are even functions. The sine part therefore cancels in the sum, and the matrix element can be written in the form

$$I(z; r_{j+1} - r_j) = \frac{1}{N} \sum_k \cos(k(r_{j+1} - r_j)) e^{2Jz \cos(k)}. \quad (\text{A.6})$$

Since the momentum takes values

$$k = \frac{2\pi n}{N}, \quad n = 0, 1, \dots, N-1, \quad (\text{A.7})$$

one obtains exactly the expression in Sec.ref to the section

$$I(z; r_{j+1} - r_j) = \frac{1}{N} \sum_{n=0}^{N-1} \cos \left(\frac{2\pi n}{N} (r_{j+1} - r_j) e^{2Jz \cos(\frac{2\pi n}{N})} \right). \quad (\text{A.8})$$

The operator H_1 contains both the phonon potential term and the electron–phonon interaction term. For fixed phonon coordinates, the potential contribution acts as a scalar factor, while the electron–phonon interaction is diagonal in the electron site representation. It is therefore convenient to first evaluate the action of the electron-dependent part on the electronic basis states.

Using the relation

$$c_n^\dagger c_n |r\rangle = \delta_{n,r} |r\rangle, \quad (\text{A.9})$$

one obtains

$$\exp \left(z \sum_n \sqrt{2M\omega_n} G X_n c_n^\dagger c_n \right) |r; X\rangle = \exp \left(z \sum_n \sqrt{2M\omega_n} G X_n \delta_{n,r} \right) |r; X\rangle. \quad (\text{A.10})$$

Transforming this result to the momentum basis using

$$|q\rangle = \frac{1}{\sqrt{N}} \sum_r e^{iqr} |r\rangle, \quad (\text{A.11})$$

gives

$$\exp \left(z \sum_n \sqrt{2M\omega_n} G X_n c_n^\dagger c_n \right) |q; X\rangle = \frac{1}{N} \sum_{q'} \sum_r e^{-ir(q-q')} \exp \left(z \sqrt{2M\omega_r} G X_r \right) |q'; X\rangle. \quad (\text{A.12})$$

Including the phonon potential term then yields

$$e^{zH_1} |q; X\rangle = \exp \left[z \sum_n \frac{1}{2} M \omega_n^2 X_n^2 \right] \frac{1}{N} \sum_{q'} \sum_r e^{-ir(q-q')} \exp \left(z \sqrt{2M\omega_r} G X_r \right) |q'; X\rangle. \quad (\text{A.13})$$

Collecting the contributions arising from the action of e^{zH_2} and from the electronic part of e^{zH_1} on the electron momentum states, the electronic matrix elements can be written in terms of function $f_{q_i, q_j}(z; X)$, defined as

$$f_{q_i, q_j}(z; X) = e^{z\mathcal{E}(q_i)} \frac{1}{N} \sum_r e^{-ir(q_i - q_j)} e^{z\sqrt{2M\omega_r} G X_r} \quad (\text{A.14})$$

Evaluation of phonon matrix elements

To evaluate the phonon contribution to the matrix elements, we consider expressions of the form

$$\langle X^j; q_j | e^{zH_0} e^{zH_1} | q_{j+1}; X^{j+1} \rangle. \quad (\text{A.15})$$

Since the operator H_0 acts only on phonon momenta, we insert a resolution of identity in the phonon momentum basis,

$$1 = \int \left(\prod_{n=0}^{N-1} dP_n \right) |\{P_n\}\rangle \langle \{P_n\}|. \quad (\text{A.16})$$

Using the fact that

$$H_0 = \sum_{n=0}^{N-1} \frac{P_n^2}{2M}, \quad (\text{A.17})$$

its action in the momentum basis is diagonal,

$$e^{zH_0}|\{P_n\}\rangle = \exp\left(z \sum_{n=0}^{N-1} \frac{P_n^2}{2M}\right)|\{P_n\}\rangle. \quad (\text{A.18})$$

The coordinate-momentum overlaps are taken in the form

$$\langle X|P\rangle = \frac{1}{(2\pi)^{N/2}} \exp\left(i \sum_{n=0}^{N-1} P_n X_n\right), \quad \langle P|X\rangle = \frac{1}{(2\pi)^{N/2}} \exp\left(-i \sum_{n=0}^{N-1} P_n X_n\right). \quad (\text{A.19})$$

Using the previously derived action of e^{zH_2} and of the electronic part of e^{zH_1} , the matrix element factorizes into an electronic contribution encoded in the function $f_{q_{j+1},q_j}(z; X^{j+1})$, and a phonon-dependent contribution. The latter can be written as

$$\begin{aligned} \langle X^j; q_j | e^{zH_0} e^{zH_1} | q_{j+1}; X^{j+1} \rangle &= \exp\left[z \sum_{n=0}^{N-1} \frac{M}{2} \omega_n^2 (X_n^{j+1})^2\right] f_{q_{j+1},q_j}(z; X^{j+1}) \\ &\times \frac{1}{(2\pi)^N} \int \left(\prod_{n=0}^{N-1} dP_n\right) \exp\left[z \sum_{n=0}^{N-1} \frac{P_n^2}{2M} + i \sum_{n=0}^{N-1} P_n (X_n^j - X_n^{j+1})\right]. \end{aligned} \quad (\text{A.20})$$

Since the exponent is a sum over independent phonon modes, the integral factorizes,

$$\frac{1}{(2\pi)^N} \prod_{n=0}^{N-1} \int dP_n \exp\left[z \frac{P_n^2}{2M} + i P_n (X_n^j - X_n^{j+1})\right]. \quad (\text{A.21})$$

Each integral is evaluated by completing the square. For a fixed mode n ,

$$z \frac{P_n^2}{2M} + i P_n (X_n^j - X_n^{j+1}) = \frac{z}{2M} \left(P_n + \frac{M i}{z} (X_n^j - X_n^{j+1})\right)^2 + \frac{M}{2z} (X_n^j - X_n^{j+1})^2. \quad (\text{A.22})$$

Thus,

$$\begin{aligned} \int dP_n \exp\left[z \frac{P_n^2}{2M} + i P_n (X_n^j - X_n^{j+1})\right] &= \exp\left[\frac{M}{2z} (X_n^j - X_n^{j+1})^2\right] \\ &\times \int dP_n \exp\left[\frac{z}{2M} \left(P_n + \frac{M i}{z} (X_n^j - X_n^{j+1})\right)^2\right]. \end{aligned} \quad (\text{A.23})$$

The remaining integral is Gaussian and can be evaluated analytically. For each mode n , one has

$$\int dP_n \exp\left[z \frac{P_n^2}{2M} + i P_n (X_n^j - X_n^{j+1})\right] = C_n(z) \exp\left[\frac{M}{2z} (X_n^j - X_n^{j+1})^2\right], \quad (\text{A.24})$$

where $C_n(z)$ is the Gaussian normalization factor arising from the integration over P_n . Since the exponent is separable in the phonon modes, the full integral factorizes into a product of one-dimensional Gaussian integrals, yielding

$$\prod_{n=0}^{N-1} \int dP_n \exp\left[z \frac{P_n^2}{2M} + i P_n (X_n^j - X_n^{j+1})\right] = \left(\prod_{n=0}^{N-1} C_n(z)\right) \exp\left[\sum_{n=0}^{N-1} \frac{M}{2z} (X_n^j - X_n^{j+1})^2\right]. \quad (\text{A.25})$$

Introducing the shorthand

$$C(z) = \prod_{n=0}^{N-1} C_n(z), \quad (\text{A.26})$$

one obtains

$$\prod_{n=0}^{N-1} \int dP_n \exp \left[z \frac{P_n^2}{2M} + iP_n (X_n^j - X_n^{j+1}) \right] = C(z) \exp \left[\sum_{n=0}^{N-1} \frac{M}{2z} (X_n^j - X_n^{j+1})^2 \right]. \quad (\text{A.27})$$

The factor $C(z)$ depends only on the time step and not on the phonon coordinates, and is therefore absorbed into the overall constants C_1 , C_2 , and C_3 used for the different contour segments. The explicit normalization factor is not needed in the final estimator, since such constants cancel in the normalized Monte Carlo averages.

Substituting this result back, the matrix element takes the form

$$\begin{aligned} \langle X^j; q_j | e^{zH_0} e^{zH_1} | q_{j+1}; X^{j+1} \rangle &= C(z) f_{q_{j+1}, q_j}(z; X^{j+1}) \\ &\times \exp \left[z \sum_{n=0}^{N-1} \frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \sum_{n=0}^{N-1} \frac{M}{2z} (X_n^j - X_n^{j+1})^2 \right]. \end{aligned} \quad (\text{A.28})$$

The different contour segments are obtained by substituting the appropriate values of z . For example, for $z = -\tau$ one obtains

$$\begin{aligned} \langle X^j; q_j | \rho(-\tau) | q_{j+1}; X^{j+1} \rangle &= C_1 f_{q_{j+1}, q_j}(-\tau; X^{j+1}) \\ &\times \exp \left[-\tau \sum_{n=0}^{N-1} \left(\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} \right) \right], \end{aligned} \quad (\text{A.29})$$

which coincides with the expression used in the main text.

A.2 Structure of the phonon action matrix $\mathcal{D}$ and the vector $\mathbf{d}$

The action in the Eq. (ref to the equation) is given as

$$S[\mathbf{Y}] = \frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y} + \mathbf{Y}^T \cdot \mathbf{d}, \quad (\text{A.30})$$

where $\mathcal{D}$ is square matrix of dimension $(m + 2Q)N$, and $\mathbf{d}$ is vector of the same dimension.

The structure of vector $\mathbf{d}$ is defined as

$$\mathbf{d} = \Delta(\{r\}) \cdot \mathbf{L}, \quad (\text{A.31})$$

where vector $\mathbf{L}$ corresponds to the electron-phonon interaction strength and is given as

$$\mathbf{L} = \sqrt{2MG} \left(\mathbf{1}_{m+2Q} \otimes (\omega_0, \omega_1, \dots, \omega_{N-1})^T \right). \quad (\text{A.32})$$

Here the $\mathbf{1}_{m+2Q}$ represents the column vector of dimension $m + 2Q$ whose all components equal to one, $\mathbf{1}_{m+2Q} = (1, 1, 1, \dots, 1)^T$.

Matrix $\Delta(\{r\})$ is diagonal and its form depends on the configuration of electronic positions $\{r_0, r_1, \dots, r_{m+2Q}\}$. The matrix $\Delta(\{r\})$ can be composed as

$$\Delta(\{r\}) = (T \otimes I_{N \times N}) \cdot G, \quad (\text{A.33})$$

where $I_{N \times N}$ is unit matrix of dimension N , T diagonal square matrix of dimension $m + 2Q$, and G is a block-diagonal matrix of dimension $m + 2Q$. This construction ensures that the electron-phonon

interaction couples only to the phonon coordinate corresponding to the electron position at each time slice. The matrix G is given as

$$G = \begin{pmatrix} g(r_0) & 0 & 0 & \dots & 0 \\ 0 & g(r_1) & 0 & \dots & 0 \\ & & \ddots & & \\ & & & g(r_{m+Q-1}) & \\ & & & & g(r_{m+Q+1}) \\ & & & & & \ddots \\ & & & & & & g(r_{m+2Q}) \end{pmatrix},$$

where each block $g(r_j)$ selects the phonon coordinate at the electron position r_j . The matrix $g(r_j)$ is diagonal of dimension $N \times N$ and its elements are Kronecker delta functions

$$g(r_j) = \begin{pmatrix} \delta_{0,r_j} & & & \\ & \delta_{1,r_j} & & \\ & & \ddots & \\ & & & \delta_{N-1,r_j} \end{pmatrix}.$$

The matrix T encodes the time discretization along the contour and is given as

$$T = \begin{pmatrix} \tau & & & & \\ & \ddots & & & \\ & & \tau & & \\ & & & -i\Delta t & \\ & & & & \ddots \\ & & & & & -i\Delta t \\ & & & & & & i\Delta t \\ & & & & & & & \ddots \\ & & & & & & & & i\Delta t \end{pmatrix}.$$

Concisely, its components can be written as

$$(T)_{i,j} = \begin{cases} 0 & , i \neq j \\ \tau & , i = j \wedge 0 \leq i \leq m-1 \\ -i\Delta t & , i = j \wedge m \leq i \leq m+Q-1 \\ i\Delta t & , i = j \wedge m+Q \leq i \leq m+2Q-1 \end{cases}$$

With this, the vector $\mathbf{d}$ is fully defined. The construction of the matrix $\mathcal{D}$ is presented next.

The matrix $\mathcal{D}$ appears in the same form in both electron basis representations. The matrix $\mathcal{D}$ is constructed as a sum of contributions arising from different terms in the phonon action. The first part of action to consider is the one where the phonon frequency ω_n appears, and the second part contains the phonon coordinate differences.

Specifically, the first part of phonon action reads

$$\tau \sum_{j=0}^{m-1} \sum_n \frac{M}{2} \omega_n^2 \left(X_n^{j+1} \right)^2 + (-i\Delta t) \sum_{p=0}^{Q-1} \sum_n \frac{M}{2} \omega_n^2 \left(X_n^{m+p+1} \right)^2 + i\Delta t \sum_{l=0}^{Q-1} \sum_n \frac{M}{2} \omega_n^2 \left(X_n^{m+Q+2+l} \right)^2 = \frac{M}{2} \mathbf{Y}^T \cdot A \cdot \mathbf{Y}$$

Matrix A is the diagonal matrix given as

$$A = T \otimes \Omega^2,$$

where $\Omega^2 = \text{diag}(\omega_0^2, \omega_1^2, \dots, \omega_{N-1}^2)$ and matrix T encoding the time variables was defined above in the construction of the vector $\mathbf{d}$.

Second part of the phonon action reads

$$\sum_{j=0}^{m-1} \sum_n \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau} + \sum_{p=0}^{Q-1} \sum_n \frac{M}{2} \frac{(X_n^{m+p+1} - X_n^{m+p})^2}{(-i\Delta t)} + \sum_{l=0}^{Q-1} \sum_n \frac{M}{2} \frac{(X_n^{m+Q+2+l} - X_n^{m+Q+1+l})^2}{(i\Delta t)}.$$

This part is split into three terms by expanding the squares of coordinate differences. These three terms are

$$(1) = \sum_{j=0}^{m-1} \sum_n \frac{M}{2} \frac{-2}{\tau} X_n^{j+1} X_n^j + \sum_{p=0}^{Q-1} \sum_n \frac{M}{2} \frac{-2}{(-i\Delta t)} X_n^{m+p+1} X_n^{m+p} + \sum_{l=0}^{Q-1} \sum_n \frac{M}{2} \frac{-2}{(i\Delta t)} X_n^{m+Q+2+l} X_n^{m+Q+1+l}$$

$$= \frac{1}{2} \mathbf{Y}^T (-2M C) (B\mathbf{Y}) = \frac{1}{2} \mathbf{Y}^T (-2M C \cdot B) \mathbf{Y}$$

$$(2) = \sum_{j=0}^{m-1} \sum_n \frac{M}{2} \frac{1}{\tau} (X_n^{j+1})^2 + \sum_{p=0}^{Q-1} \sum_n \frac{M}{2} \frac{1}{(-i\Delta t)} (X_n^{m+p+1})^2 + \sum_{l=0}^{Q-1} \sum_n \frac{M}{2} \frac{1}{(i\Delta t)} (X_n^{m+Q+2+l})^2$$

$$= \frac{1}{2} \mathbf{Y}^T (M C) \mathbf{Y}$$

$$(3) = \sum_{j=0}^{m-1} \sum_n \frac{M}{2} \frac{1}{\tau} (X_n^j)^2 + \sum_{p=0}^{Q-1} \sum_n \frac{M}{2} \frac{1}{(-i\Delta t)} (X_n^{m+p})^2 + \sum_{l=0}^{Q-1} \sum_n \frac{M}{2} \frac{1}{(i\Delta t)} (X_n^{m+Q+1+l})^2$$

$$= \frac{1}{2} (B\mathbf{Y})^T (M C) (B\mathbf{Y}) = \frac{1}{2} \mathbf{Y}^T (B^T \cdot (M C) \cdot B) \mathbf{Y}$$

The matrix B is introduced to represent the cyclic shift of the phonon coordinates along the discretized contour,

$$B \cdot \mathbf{Y} = (Y^{m+2Q-1}, Y^0, \dots, Y^{m+2Q-2})^T = (X^0, X^1, \dots, X^{m+Q-1}, X^{m+Q+1}, \dots, X^{m+2Q})^T.$$

It is given by

$$B = B' \otimes I_{N \times N},$$

where

$$B' = \begin{pmatrix} 0 & 0 & 0 & \dots & 1 \\ 1 & 0 & 0 & \dots & 0 \\ 0 & 1 & 0 & \dots & 0 \\ & & \ddots & & \vdots \\ & & & 1 & 0 \end{pmatrix}.$$

The components of matrix B' are

$$(B')_{k,j} = \begin{cases} 1 & , k = 0 \wedge j = m + 2Q - 1, \\ 0 & , k = 0 \wedge j \neq m + 2Q - 1, \\ 0 & , k = 1, \dots, m + 2Q - 1 \wedge j \neq k - 1, \\ 1 & , k = 1, \dots, m + 2Q - 1 \wedge j = k - 1. \end{cases}$$

The matrix C can be written as

$$C = C' \otimes I_{N \times N}$$

where C' is the inverse of the diagonal matrix T . its components are therefore

$$(C')_{i,j} = \begin{cases} 0 & , i \neq j \\ (T_{i,j})^{-1} & , i = j \end{cases}$$

Combining the phonon-frequency contribution with the three terms above, the matrix $\mathcal{D}$ is obtained in the form

$$\mathcal{D}' = A - 2C \cdot B + C + B^T \cdot C \cdot B ,$$

and

$$\mathcal{D} = M \mathcal{D}' .$$

The matrix $\mathcal{D}$ is therefore complex symmetric and has a positive-definite real part.

In case of calculations in imaginary time where the substitution $-i\Delta t \rightarrow \Delta t$ is made, the elements of matrix T are real and consequently the matrix $\mathcal{D}$ is real symmetric.

Appendix B

Singular value decomposition method for analytic continuation

In this appendix, the derivation of the expressions used in the singular value decomposition (SVD) method for obtaining the mobility from time-dependent current–current correlation functions is presented. In addition, selected details regarding the numerical implementation are briefly discussed.

The real part of the optical conductivity is related to the imaginary part of the retarded current–current correlation function in the frequency domain as [78]

$$\text{Re } \sigma(\omega) = -\frac{\text{Im } C^R(\omega)}{\omega} . \quad (\text{B.1})$$

The retarded correlation function in the frequency domain is defined as

$$C^R(\omega) = \int_{-\infty}^{\infty} dt C^R(t) e^{i\omega t} , \quad (\text{B.2})$$

where the real-time retarded correlation function is given by

$$C^R(t) = -\frac{i}{V} \theta(t) \langle [j(t), j(0)] \rangle , \quad (\text{B.3})$$

with V denoting the system volume and $\theta(t)$ the Heaviside step function.

In the present approach, quantum Monte Carlo simulations provide the current–current correlation function in complex time,

$$C(z) = -\frac{1}{V} \langle j(z) j(0) \rangle , \quad (\text{B.4})$$

where the complex time variable is defined as $z = t_{\text{re}} - it_{\text{im}}$, with $-\beta \leq t_{\text{im}} \leq 0$ and $t_{\text{re}} \geq 0$.

To establish the relation between this correlation function and the frequency-dependent conductivity, it is convenient to introduce additional correlation functions. The advanced correlation function is defined as [79]

$$C^A(t) = -\frac{i}{V} \theta(-t) \langle [j(t), j(0)] \rangle , \quad (\text{B.5})$$

while the greater ($C^>(t)$) and lesser ($C^<(t)$) correlation functions are given by

$$C^>(t) = -\frac{i}{V} \langle j(t) j(0) \rangle , \quad (\text{B.6})$$

$$C^<(t) = -\frac{i}{V} \langle j(0) j(t) \rangle . \quad (\text{B.7})$$

The retarded and advanced functions can be expressed in terms of these as

$$C^R(t) = \theta(t) (C^>(t) - C^<(t)) , \quad (\text{B.8})$$

$$C^A(t) = -\theta(-t) (C^>(t) - C^<(t)) , \quad (\text{B.9})$$

while the time-ordered correlation function satisfies

$$C(t) = \frac{1}{i} C^>(t) . \quad (\text{B.10})$$

In the frequency domain, these functions obey the relations

$$C^>(\omega) = e^{\beta\omega} C^<(\omega) , \quad (\text{B.11})$$

$$C^R(\omega) = C^A(\omega)^* , \quad (\text{B.12})$$

$$C^R(\omega) - C^A(\omega) = C^>(\omega) - C^<(\omega) . \quad (\text{B.13})$$

From these relations, one obtains

$$\text{Im } C^R(\omega) = -\frac{1}{2i} (1 - e^{-\beta\omega}) C^>(\omega) , \quad (\text{B.14})$$

and equivalently

$$C^>(\omega) = \frac{2i \text{Im } C^R(\omega)}{1 - e^{-\beta\omega}} = \frac{-2i \omega \text{Re } \sigma(\omega)}{1 - e^{-\beta\omega}} . \quad (\text{B.15})$$

Using the spectral representation of the complex-time correlation function,

$$C(z) = -i C^>(z) = \frac{-i}{2\pi} \int_{-\infty}^{\infty} d\omega C^>(\omega) e^{-i\omega z} , \quad (\text{B.16})$$

one obtains the relation between the complex-time correlation function and the conductivity,

$$C(z) = \int_{-\infty}^{\infty} d\omega \frac{-1}{\pi} \frac{\omega e^{-i\omega z}}{1 - e^{-\beta\omega}} \text{Re } \sigma(\omega) . \quad (\text{B.17})$$

For the case of a single charge carrier, the conductivity can be expressed in terms of the mobility, yielding the final relation

$$\langle j(z) j(0) \rangle = \int_{-\infty}^{\infty} d\omega \frac{1}{\pi} \frac{\omega e^{-i\omega z}}{1 - e^{-\beta\omega}} \text{Re } \mu(\omega) . \quad (\text{B.18})$$

This expression defines the integral transform that relates the mobility in frequency space to the current–current correlation function in complex time. It serves as the basis for generating artificial correlation data from a known reference mobility, which is subsequently used to benchmark the analytic continuation procedure, as discussed in the main text.

Building on the previously introduced integral transform, the kernel is given by

$$K(z, \omega) = \frac{1}{\pi} \frac{\omega e^{-i\omega z}}{1 - e^{-\beta\omega}} , \quad (\text{B.19})$$

and the analytic continuation problem corresponds to the inversion of this integral relation.

In practice, the inverse problem of reconstructing the frequency-dependent mobility from the current–current correlation function evaluated at a discrete set of complex times is ill-posed and requires a careful numerical treatment. In the following, the singular value decomposition (SVD) approach to this problem is outlined.

The first step is to discretize Eq. (B.18) so that it corresponds to a finite set of complex time values. Let the vector $\mathbf{j}$ contain the values of the current–current correlation function, and let the vector $\mathbf{m}$ represent the mobility evaluated on a discrete frequency grid. The discretized version of Eq. (B.18) can then be written in the form

$$\mathbf{j} = \mathbf{K} \cdot \mathbf{m} , \quad (\text{B.20})$$

where $\mathbf{K}$ is a known kernel matrix obtained from the discretization of the integral transform. The problem can be formulated in terms of real-valued quantities by treating real and imaginary parts separately.

The difficulty in solving this inverse problem arises from the fact that the matrix $\mathbf{K}$ is ill-conditioned, with singular values spanning many orders of magnitude and approaching zero.

Any real matrix can be decomposed using singular value decomposition in the form

$$\mathbf{K} = \mathbf{U}\mathbf{S}\mathbf{V}^T, \quad (\text{B.21})$$

where $\mathbf{U}$ and $\mathbf{V}$ are orthogonal matrices, and $\mathbf{S}$ is a diagonal matrix whose entries s_i are the singular values. These are conventionally ordered as

$$s_1 \geq s_2 \geq \cdots \geq s_p \geq 0. \quad (\text{B.22})$$

By retaining only the p non-zero (or numerically significant) singular values, the matrix $\mathbf{G}$ can be written in reduced form as

$$\mathbf{K} = \mathbf{U}_p \mathbf{S}_p \mathbf{V}_p^T, \quad (\text{B.23})$$

where $\mathbf{U}_p$, $\mathbf{V}_p$ and $\mathbf{S}_p$ denote the truncated matrices.

The corresponding pseudoinverse of $\mathbf{K}$ is given by

$$\mathbf{K}^i = \mathbf{V}_p \mathbf{S}_p^{-1} \mathbf{U}_p^T, \quad (\text{B.24})$$

and the reconstructed mobility is obtained as

$$\mathbf{m}^i = \mathbf{K}^i \mathbf{j}. \quad (\text{B.25})$$

This expression can be written explicitly as

$$\mathbf{m}^i = \sum_{k=1}^p \frac{\mathbf{U}_{\cdot,i}^T \cdot \mathbf{j}}{s_i} \mathbf{V}_{\cdot,i}, \quad (\text{B.26})$$

where $\mathbf{U}_{\cdot,i}$ and $\mathbf{V}_{\cdot,i}$ denote the i -th columns of the matrices $\mathbf{U}$ and $\mathbf{V}$, respectively. A detailed discussion of the interpretation of the pseudoinverse solution can be found in Ref. [115].

In practice, the direct use of this expression is limited by the presence of very small singular values. Even a small amount of noise in the input data $\mathbf{j}$ can be strongly amplified by division by s_i , leading to unstable and noisy reconstructions. To address this issue, the sum is truncated by introducing a cutoff for singular values, such that only terms with sufficiently large s_i are retained.

The choice of cutoff is guided by the noise level in the data. Denoting the estimated relative noise level by α , a common criterion is to retain only singular values satisfying $s_i \gtrsim \alpha s_1$. Consequently, higher-quality data (i.e., lower noise) allow more singular values to be included, leading to improved reconstruction accuracy. Furthermore, increasing the number of informative input data enhances the stability of the solution. In particular, the inclusion of real-time data in addition to imaginary-time data significantly improves the quality of the analytic continuation, as demonstrated in the main text.

The numerical implementation of the procedure requires the specification of a discrete frequency grid. The choice of frequency range and resolution influences the reconstructed mobility. An example illustrating the dependence of the results on the selected frequency interval is shown in Fig. B.1.

Additional input parameters required for the implementation include the set of complex time points, the corresponding current–current correlation function values, the inverse temperature β , and the cutoff criterion for singular values (or equivalently, the number of retained singular values). The dependence of the results on the singular value truncation is discussed in the main text.

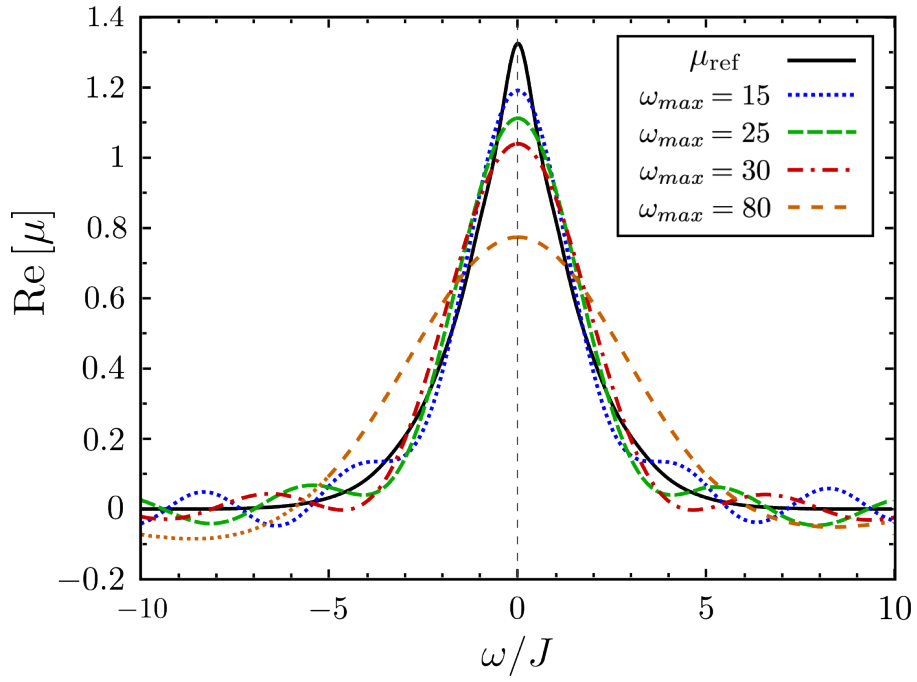


Figure B.1: Effect of frequency range on reconstructed mobility. The reference mobility (μ_{ref}) is shown together with reconstructions obtained using different intervals $[-\omega_{\text{max}}, \omega_{\text{max}}]$. The results are presented for model parameters $\omega_0/J = 1$, $G/J = 1$, and $T/J = 1$.

Appendix C

Monte Carlo simulation details

Technical aspects of the numerical calculations performed in this thesis are summarized in this appendix.

Data collection, analysis, and graphical representation were carried out using self-developed scripts written in C++, Python, Bash, and Gnuplot.

Quantum Monte Carlo (QMC) calculations of current–current correlation functions were performed on the PARADOX-IV supercomputing cluster at the Scientific Computing Laboratory, National Centre of Excellence for the Study of Complex Systems, Institute of Physics Belgrade.

The main QMC code used for the calculation of current–current correlation functions was implemented in C++. External libraries employed in the implementation include the GNU Scientific Library (GSL) and LAPACK, accessed through a C interface, for matrix diagonalization in the momentum-basis formulation.

Parallelization of the QMC simulations was achieved using the Message Passing Interface (MPI). All calculations were performed using 100 CPU cores in parallel. On each processor, the same QMC algorithm was executed with an independent random number generator seed determined by the processor index. The results obtained from individual processors were collected and aggregated on a master process, where mean values and corresponding statistical errors were evaluated. Statistical uncertainties were estimated using standard error analysis based on independent Monte Carlo samples. Typical simulation times ranged from few minutes to few hours depending on system size and parameter choice.

QMC algorithm in position representation

In this section, the numerical procedure used for the evaluation of current–current correlation functions in the position representation is described in detail.

Model parameters and discretization

The simulation is defined by the following parameters:

- system size N ,
- number of phonon modes N_b ,
- electron transfer integral J ,
- electron–phonon coupling λ ,
- phonon frequency ω ,
- oscillator mass M ,

- inverse temperature β ,
- number of imaginary-time slices m ,
- number of real-time slices Q .

The discretized time steps are defined as

$$\tau = \beta/m, \quad \Delta t = t/Q.$$

Phonon frequencies and coupling constants are stored as vectors

$$\omega(n, b), \quad \lambda(n, b),$$

where $0 \leq n < N$ labels lattice sites and $0 \leq b < N_b$ phonon modes.

Propagators

The imaginary-time propagator is defined as

$$I_0(l, \tau) = \frac{1}{N} \sum_{k=0}^{N-1} \cos\left(\frac{2\pi kl}{N}\right) \exp\left(2J\tau \cos\left(\frac{2\pi k}{N}\right)\right).$$

The real-time propagator is

$$I_1(l, \Delta t) = \frac{1}{N} \sum_{k=0}^{N-1} \cos\left(\frac{2\pi kl}{N}\right) \exp\left(-2iJ\Delta t \cos\left(\frac{2\pi k}{N}\right)\right).$$

For numerical implementation, the propagators are evaluated for all discrete lattice distances $l = 0, \dots, N-1$ and stored as vectors.

The imaginary-time propagator $I_0(l, \tau)$ is real-valued and is stored directly as $I_0[l]$.

The real-time propagator $I_1(l, \Delta t)$ is complex-valued and is decomposed into magnitude and phase separately for the forward and backward real-time branches. The corresponding vectors are defined as

$$I_1[l] = |I_1(l, -\Delta t)|, \quad I_2[l] = |I_1(l, \Delta t)|,$$

with phases

$$\phi_1(l) = \arg(I_1(l, -\Delta t)), \quad \phi_2(l) = \arg(I_1(l, \Delta t)).$$

Although the magnitudes of the two propagators are equal, separate vectors are introduced in order to distinguish explicitly between the forward and backward real-time branches.

The corresponding minimum and maximum values,

$$I_0^{\min} = \min_l I_0[l], \quad I_0^{\max} = \max_l I_0[l],$$

are determined from these arrays. Analogous definitions apply to the real-time propagators.

During the Monte Carlo sampling, $I_0[x]$ denotes the value of the propagator corresponding to the sampled lattice displacement x , i.e. the x -th entry of the precomputed array.

Phonon contribution

After integrating out the phonon degrees of freedom, the remaining contribution is expressed as a Gaussian form

$$d^T D^{-1} d,$$

where D is a complex symmetric matrix constructed from component matrices A , B , and C :

$$D = A - 2CB + C + B^T C B.$$

The inverse matrix D^{-1} is computed numerically.

The vector d is defined as

$$d = T \cdot G \cdot L,$$

where:

- L encodes the electron–phonon coupling along the discretized contour,
- G is the matrix arising from the discretized path integral and depends on the configuration of electron positions on the time contour,
- T is a diagonal matrix encoding the contour time structure, with diagonal entries given by

$$T_{jj} = \begin{cases} \tau & \text{for imaginary-time slices} \\ -i\Delta t & \text{for forward real-time slices} \\ i\Delta t & \text{for backward real-time slices} \end{cases}$$

Phase factor

The total phase factor originating from real-time propagation is given by

$$\text{phase} = \exp(i\Phi_1 + i\Phi_2),$$

where

$$\Phi_1 = \sum_{j=m+1}^{m+Q} \phi_1(l_j), \quad \Phi_2 = \sum_{j=m+Q+1}^{m+2Q} \phi_2(l_j).$$

Here, l_j denotes the lattice displacement between consecutive electron positions along the sampled configuration at time slice j , computed with periodic boundary conditions.

Monte Carlo sampling

Monte Carlo Sampling of Electron Position Configurations

for each Monte Carlo sample $s = 1, \dots, N_s$ do

• **Initial time-slice:**

– Sample:

$$z[0] \leftarrow \text{Uniform}(0, N)$$

• **Imaginary-time propagation:**

– **for $j = 1, \dots, m$ do**

* Sample trial position $x \leftarrow \text{Uniform}(0, N)$

* Sample $r \leftarrow \text{Uniform}(0, 1)$

* **if**

$$I_0^{\min} + (I_0^{\max} - I_0^{\min})r \leq I_0[x]$$

then accept: $z[j] = x$

• **Forward real-time propagation:**

– **for** $j = m + 1, \dots, m + Q$ **do**

* Sample trial position $x \leftarrow \text{Uniform}(0, N)$

* Sample $r \leftarrow \text{Uniform}(0, 1)$

* **if**

$$I_1^{\min} + (I_1^{\max} - I_1^{\min})r \leq I_1[x]$$

then accept: $z[j] = x$

• **Backward real-time propagation:**

– **for** $j = m + Q + 1, \dots, m + 2Q$ **do**

* Sample trial position $x \leftarrow \text{Uniform}(0, N)$

* Sample $r \leftarrow \text{Uniform}(0, 1)$

* **if**

$$I_2^{\min} + (I_2^{\max} - I_2^{\min})r \leq I_2[x]$$

then accept: $z[j] = x$

• **Trajectory construction:**

– $y[0] = z[0]$

– **for** $j = 1, \dots, m + 2Q$ **do**

$$y[j] = (y[j - 1] + z[j]) \bmod N$$

• **Estimator evaluation:**

– Compute $C_{11}^{(s)}$

– Compute $C_{jj}^{(s)}$

Output:

$$C_{11} = \frac{1}{N_s} \sum_{s=1}^{N_s} C_{11}^{(s)}, \quad C_{jj} = \frac{1}{N_s} \sum_{s=1}^{N_s} C_{jj}^{(s)}$$

Estimator:

$$\frac{C_{jj}}{C_{11}}$$

Averaging and statistics

The full calculation is repeated multiple times with independent random seeds. Final results are obtained as averages over these runs, with statistical uncertainties estimated from the standard deviation.

Since configurations are sampled directly from the weight distribution, no equilibration phase is required, which significantly improves computational efficiency.

QMC algorithm in momentum representation

In the momentum representation, the sampling procedure is simplified, as the phonon coordinates are sampled directly.

As in the position representation, all constants, vectors, and the matrix D are first constructed. The eigendecomposition of the matrix D is performed using the LAPACK library (accessed through a C interface), yielding eigenvalues $\text{eval}[]$ and eigenvectors $\text{evec}[]$, which are used in the sampling procedure.

This procedure corresponds to sampling from the Gaussian distribution defined by the quadratic form associated with the matrix D .

Monte Carlo Sampling of Phonon Coordinates

for each Monte Carlo sample $s = 1, \dots, N_s$ do

- **Sampling in eigenmode space:**

- **for $k = 0, \dots, (m + 2Q)NN_b - 1$ do**
 - * Sample $Z[k]$ from a normal distribution
 - * Rescale:

$$Z[k] \leftarrow \frac{Z[k]}{\sqrt{\text{eval}[k]}}$$

- **Transformation to phonon coordinates:**

- **for $k = 0, \dots, (m + 2Q)NN_b - 1$ do**

$$Y[k] = \sum_{j=0}^{(m+2Q)NN_b-1} \text{evec}[j(m + 2Q)NN_b + k] \cdot Z[j]$$

- **Compute:**

- $F(\mathbf{Y})$
- $C_{11}^{(s)}, C_{jj}^{(s)}$

- **Estimator evaluation:**

$$\begin{aligned} - C_{11} &= \frac{1}{N_s} \sum_{s=1}^{N_s} C_{11}^{(s)}, & C_{jj} &= \frac{1}{N_s} \sum_{s=1}^{N_s} C_{jj}^{(s)} \\ - \frac{C_{jj}}{C_{11}} \end{aligned}$$

C.1 Details of Monte Carlo Calculations

In the following tables, detailed information on the Monte Carlo calculations of the current-current correlation functions performed in this thesis is provided.

For each calculation, the relevant simulation parameters are listed, including the number of Monte Carlo samples, system size, discretization of imaginary and real time, choice of representation, and the maximum accessible time range.

The results are grouped according to the calculations presented in Chapters 3 and 4.

For the calculations presented in Chapter 3, the tables include representative parameter sets corresponding to selected temperatures, together with additional details of the analytic continuation

procedure. Additional calculations were performed at intermediate temperature values, ensuring dense coverage of the parameter space, but are not included explicitly for brevity.

Table C.1: Details of Monte Carlo calculations of real- and imaginary-time current-current correlation functions, and of the analytic continuation procedure, used in Chapter 3.

G/J	T/J	real-time calculations (QMC)					imaginary-time calculations (QMC)					analytic continuation	
		$t_{\max}$	time step	N_s	basis	N_d	$t_{\max}$	time step	N_s	basis	N_d	$\omega_{\max}$	svs
0.141	10	30	0.1	10^4	momentum	15	0.06	0.002	10^5	position	10	5	23
	5	30	0.1	10^4	momentum	25	0.12	0.004	10^5	position	10	5	40
	2	30	0.1	10^4	momentum	55	0.3	0.01	10^5	position	10	5	40
	1	30	0.1	10^4	momentum	55	0.6	0.02	10^5	position	10	5	43
	0.5	30	0.1	10^4	momentum	55	1.2	0.04	10^5	position	10	/	/
0.5	10	4	0.1	10^4	momentum	10	0.06	0.002	10^5	position	10	10	13
	5	5	0.1	10^4	momentum	10	0.12	0.004	10^5	position	10	10	17
	2	5	0.1	10^4	momentum	10	0.3	0.01	10^5	position	10	10	20
	1	5	0.1	10^4	momentum	10	0.6	0.02	10^5	position	10	10	20
	0.5	1	0.1	10^4	momentum	10	1.2	0.04	10^5	position	10	/	/
1	10	1.6	0.02	10^6	position	10	0.06	0.002	10^5	position	10	20	11
	5	1.6	0.02	10^6	position	10	0.12	0.004	10^5	position	10	20	10
	2	1.6	0.05	10^6	position	10	0.3	0.01	10^5	position	10	20	11
	1	1	0.1	10^6	position	10	0.6	0.02	10^5	position	10	20	10
	0.5	1	0.1	10^6	position	10	1.2	0.04	10^5	position	10	20	10
2	10	1	0.01	10^6	position	10	0.06	0.002	10^5	position	10	80	25
	5	1.2	0.01	10^6	position	10	0.12	0.004	10^5	position	10	150	48
	2	1.3	0.025	10^6	position	10	0.3	0.01	10^5	position	10	200	55
	1	1.3	0.025	10^6	position	10	0.6	0.02	10^5	position	10	200	54
	0.5	1.4	0.05	10^6	position	10	1.2	0.04	10^5	position	10	200	40
2.83	10	1	0.01	10^6	position	10	0.06	0.002	10^5	position	10	200	24
	5	1	0.01	10^6	position	10	0.12	0.004	10^5	position	10	300	34
	2	1	0.02	10^6	position	10	0.3	0.01	10^5	position	10	360	51
	1	1	0.025	10^6	position	10	0.6	0.02	10^5	position	10	300	45
	0.5	1	0.025	10^6	position	10	1.2	0.04	10^5	position	10	280	44

N_s denotes the number of Monte Carlo samples and N_d the system size.

For real-time calculations, data are calculated at time points that are multiples of the time step and lie in the interval $(0, t_{\max})$.

For $G/J = 0.141$, the column N_d gives the number of sites required to calculate the data at $t_{\max}$.

The analytic continuation procedure is performed on a frequency grid of $100 \omega_{\max}$ points in the interval $(-\omega_{\max}, \omega_{\max})$.

Table C.2: Details of Monte Carlo calculations of imaginary-time current-current correlation functions used in Chapter 4.

λ	T/J	$\omega_0 = J/3$				$\omega_0 = J$				$\omega_0 = 3J$			
		$J\Delta t$	N_s	N_d	basis	$J\Delta t$	N_s	N_d	basis	$J\Delta t$	N_s	N_d	basis
0.010	0.1	0.1	10^6	15	m	0.1	10^6	20	m	0.1	10^5	30	m
	0.2	0.1	10^5	15	m	0.1	10^5	15	m	0.1	10^5	25	m
	0.5	0.08	10^5	10	m	0.08	10^5	15	m	0.08	10^5	20	m
	1.0	0.05	10^2	80	m	0.05	10^3	60	m	0.04	10^5	15	m
	2.0	0.025	10^2	80	m	0.025	10^3	60	m	0.025	10^5	15	m
	5.0	0.01	10^2	80	m	0.01	10^3	60	m	0.01	10^5	15	m
	10.0	0.005	10^2	80	m	0.005	10^3	60	m	0.005	10^5	15	m
0.125	0.1	0.1	10^6	15	m	0.1	10^6	20	m	0.1	10^5	20	m
	0.2	0.1	10^5	15	m	0.1	10^5	15	m	0.1	10^5	15	m
	0.5	0.08	10^5	10	m	0.08	10^5	15	m	0.08	10^5	15	m
	1.0	0.05	10^3	10	m	0.05	10^3	20	m	0.04	10^5	15	m
	2.0	0.025	10^3	10	m	0.025	10^3	20	m	0.025	10^3	10	m
	5.0	0.01	10^3	10	m	0.01	10^3	20	m	0.01	10^3	10	m
	10.0	0.005	10^3	10	m	0.005	10^3	20	m	0.005	10^3	10	m
0.500	0.1	0.1	10^6	15	m	0.1	10^6	20	m	0.1	10^5	20	m
	0.2	0.1	10^5	15	m	0.1	10^5	15	m	0.1	10^5	15	m
	0.5	0.08	10^5	10	m	0.08	10^5	15	m	0.08	10^5	15	m
	1.0	0.05	10^4	7	m	0.05	10^4	10	m	0.05	10^5	15	m
	2.0	0.025	10^4	7	m	0.025	10^4	10	m	0.025	10^3	10	m
	5.0	0.01	10^4	7	m	0.01	10^4	10	m	0.01	10^3	10	m
	10.0	0.005	10^4	7	m	0.005	10^4	10	m	0.005	10^3	10	m
1.000	0.1	0.1	10^6	15	m	0.1	10^6	20	m	0.1	10^6	25	m
	0.2	0.1	10^5	15	m	0.1	10^5	15	m	0.1	10^6	20	m
	0.5	0.08	10^5	10	m	0.08	10^5	15	m	0.08	10^5	15	m
	1.0	0.02	10^5	7	p	0.02	10^5	7	m	0.02	10^5	15	m
	2.0	0.01	10^5	7	p	0.01	10^5	7	m	0.01	10^5	7	p
	5.0	0.004	10^5	7	p	0.004	10^5	7	m	0.004	10^5	7	p
	10.0	0.002	10^5	7	p	0.002	10^5	7	m	0.002	10^5	7	p
2.000	0.1	0.1	10^6	15	m	—	—	—	—	—	—	—	—
	0.2	0.1	10^5	15	m	0.1	10^6	20	m	—	—	—	—
	0.5	0.08	10^5	10	m	0.08	10^5	15	m	0.08	10^5	15	m
	1.0	0.02	10^5	7	p	0.02	10^5	10	p	0.02	10^5	7	p
	2.0	0.01	10^5	7	p	0.01	10^5	10	p	0.01	10^5	7	p
	5.0	0.004	10^5	7	p	0.004	10^5	10	p	0.004	10^5	7	p
	10.0	0.002	10^5	7	p	0.002	10^5	10	p	0.002	10^5	7	p

$J\Delta t$ denotes the time discretization step, N_s the number of Monte Carlo samples, and N_d the system size.

Basis labels: m denotes the electron momentum representation and p the electron position representation.

Appendix D

Self-Energy Expressions for Band and Polaron Band Transport

D.1 Self-energy in the band transport regime

In this section, the expressions for the self-energy in the band transport regime are summarized, together with the main steps of their evaluation. The detailed calculation of the momentum summation is based on standard contour integration techniques and is not reproduced here in full.

Within the Migdal approximation, where only processes involving a single phonon line are retained, the self-energy is given by

$$\Sigma_k(\omega) = \frac{G^2}{N} \sum_q \left[(n_{\text{ph}} + 1) G_{k-q}^{(0)}(\omega - \omega_0) + n_{\text{ph}} G_{k-q}^{(0)}(\omega + \omega_0) \right], \quad (\text{D.1})$$

where $G_k^{(0)}(\omega) = (\omega - \varepsilon_k + i0^+)^{-1}$ denotes the Green's function of a free particle.

The evaluation of the self-energy requires the summation over momentum of the free Green's function. This summation can be written as

$$S(\omega) = \frac{1}{N} \sum_k G_k^{(0)}(\omega), \quad (\text{D.2})$$

which, in the thermodynamic limit, is replaced by an integral over the Brillouin zone,

$$S(\omega) = \frac{1}{2\pi} \int_{-\pi}^{\pi} \frac{dk}{\omega + 2J \cos k + i\delta}, \quad \delta \rightarrow 0^+. \quad (\text{D.3})$$

The integral can be evaluated using contour integration in the complex plane by introducing the standard substitution $z = e^{ik}$, which maps the integration over k onto the unit circle $|z| = 1$. The integral then takes the form

$$S(\omega) = \frac{1}{2\pi} \oint_C \frac{dz}{iz \left[\omega + J \left(z + \frac{1}{z} \right) + i\delta \right]}, \quad (\text{D.4})$$

where C denotes the unit circle.

The integrand has two poles determined by the condition

$$\omega + J \left(z + \frac{1}{z} \right) + i\delta = 0, \quad (\text{D.5})$$

and the evaluation of the integral reduces to determining which of these poles lies inside the unit circle.

Two distinct cases arise depending on the relation $\omega/2J$.

For $|\omega/(2J)| > 1$, the poles lie on the real axis and the infinitesimal δ can be neglected in determining their position. In this case, only one of the poles lies inside the unit circle, and evaluation of the corresponding residue yields

$$S(\omega) = \frac{\text{sgn}(\omega)}{\sqrt{\omega^2 - 4J^2}}. \quad (\text{D.6})$$

For $|\omega/(2J)| < 1$, the infinitesimal δ plays a crucial role in determining the position of the poles. A careful expansion of the pole positions to linear order in δ shows that one of the poles lies inside the unit circle and the corresponding residue evaluates to

$$S(\omega) = -\frac{i}{\sqrt{4J^2 - \omega^2}}. \quad (\text{D.7})$$

The momentum summation in Eq. (D.1) thus yields the following expression for the sum

$$S(\omega) = \begin{cases} \frac{\text{sgn}(\omega)}{\sqrt{\omega^2 - 4J^2}}, & \text{if } \left| \frac{\omega}{2J} \right| > 1 \\ \frac{-i}{\sqrt{4J^2 - \omega^2}}, & \text{if } \left| \frac{\omega}{2J} \right| < 1 \end{cases}. \quad (\text{D.8})$$

Substituting this result into Eq. (D.1), the self-energy takes the form

$$\Sigma(\omega) = G^2(n_{\text{ph}} + 1)S(\omega - \omega_0) + G^2 n_{\text{ph}} S(\omega + \omega_0). \quad (\text{D.9})$$

The imaginary part of the self-energy defines the quasiparticle lifetime, which enters the expression for the mobility through the scattering time.

The retarded Green's function is then obtained from the Dyson equation,

$$G_k^R(\omega) = \frac{1}{\omega - \varepsilon_k - \Sigma_k(\omega)}, \quad (\text{D.10})$$

from which the spectral function follows as

$$A_k(\omega) = -\frac{1}{\pi} \text{Im } G_k^R(\omega). \quad (\text{D.11})$$

Analysis of the resulting spectral function shows that $A_k(\omega)$ vanishes outside a finite frequency range determined by the electronic bandwidth and phonon energy, $|\omega| \gtrsim 2J + \omega_0$. In practical calculations, the frequency integration can therefore be restricted to a finite interval $|\omega| \leq \omega_{\text{max}}$, with ω_{max} chosen slightly larger than $2J + \omega_0$.

The expectation values entering the current–current correlation function are expressed in terms of the spectral function as

$$\langle a_k^\dagger(t) a_k \rangle = \int_{-\infty}^{\infty} d\omega e^{i\omega t} A_k(\omega) e^{-\beta\omega}, \quad (\text{D.12})$$

$$\langle a_k(t) a_k^\dagger \rangle = \int_{-\infty}^{\infty} d\omega e^{-i\omega t} A_k(\omega). \quad (\text{D.13})$$

Substituting these expressions into the definition of the current–current correlation function yields

$$\langle j(t) j \rangle = \frac{J^2}{\pi} \frac{1}{N_c} \sum_k \sin^2(k) f_k(t) g_k(t), \quad (\text{D.14})$$

where

$$f_k(t) = \int_{-\infty}^{\infty} d\omega e^{i\omega' t} A_k(\omega') e^{-\beta\omega'}, \quad (\text{D.15})$$

$$g_k(t) = \int_{-\infty}^{\infty} d\omega e^{-i\omega' t} A_k(\omega'), \quad (\text{D.16})$$

and

$$N_c = \frac{1}{2\pi} \sum_k \int_{-\infty}^{\infty} d\omega A_k(\omega') e^{-\beta\omega'}. \quad (\text{D.17})$$

In the regime when $\frac{\omega_0}{2J} > 1$, single-phonon processes are suppressed for part of the spectrum, and the inclusion of higher-order contributions becomes necessary to obtain a finite scattering rate. The dominant correction arises from diagrams involving two phonon lines.

Within this approximation, the imaginary part of the self-energy can be written as

$$\text{Im}\Sigma(k, \omega) = \frac{G^4}{N^2} n_{\text{ph}}(n_{\text{ph}} + 1) \sum_{k_1} \text{Im} \left[\frac{1}{\omega - \varepsilon_{k_1} + i0^+} \right] \sum_{k_2} \left[\frac{1}{(\varepsilon_{k_2} + \omega_0 - \omega)^2} + \frac{1}{(\varepsilon_{k_2} - \omega_0 - \omega)^2} \right] \quad (\text{D.18})$$

Carrying out the momentum summations leads to the compact expression

$$\text{Im}\Sigma(\omega) = G^4 n_{\text{ph}}(n_{\text{ph}} + 1) S_1 [S_2(\omega - \omega_0) + S_2(\omega + \omega_0)] \quad (\text{D.19})$$

where

$$S_1 = \frac{1}{N} \sum_k \text{Im} \left[\frac{1}{\omega - \varepsilon_k + i0^+} \right], \quad (\text{D.20})$$

$$S_2(x) = \frac{1}{N} \sum_k \frac{1}{(\varepsilon_k - x)^2}. \quad (\text{D.21})$$

These sums can again be evaluated analytically. The function $S_1(\omega)$ is nonzero only within the electronic band and is given by

$$S_1(\omega) = \begin{cases} \frac{-1}{\sqrt{4J^2 - \omega^2}}, & \text{if } |\frac{\omega}{2J}| < 1, \\ 0, & \text{otherwise,} \end{cases} \quad (\text{D.22})$$

while $S_2(x)$ takes the form

$$S_2(x) = \begin{cases} -\frac{z_1 + z_2}{J^2(z_1 - z_2)^3}, & \text{if } \frac{x}{2J} > 1 \\ \frac{z_1 + z_2}{J^2(z_1 - z_2)^3}, & \text{if } \frac{x}{2J} < -1 \end{cases} \quad (\text{D.23})$$

with

$$z_{1,2} = \frac{1}{2} \left(-\frac{x}{J} \pm \sqrt{\frac{x^2}{J^2} - 4} \right). \quad (\text{D.24})$$

These contributions restore a finite imaginary part of the self-energy in the regime where single-phonon processes are suppressed.

D.2 Self-energy in polaron band transport regime

In this section, the self-energy in the polaron band transport regime is summarized in a form consistent with Ref. [133], specialized to the case where the Lang–Firsov transformation is employed.

The first nonvanishing contribution to the retarded self-energy arising from the transformed interaction $\tilde{V}$ is given by

$$\Sigma_k(\omega) = \frac{i}{2\pi} \frac{1}{N^2} \sum_q \int d\omega_1 G_{k-q}^R(\omega - \omega_1) D_{k-q,k,q}^>(\omega_1) \quad (\text{D.25})$$

where

$$D_{k-q,k,q}^>(\omega) = -i \sum_{R_1 S_1 R_2 S_2} b_{R_1 S_1 R_2 S_2 k q} \int dt e^{i\omega t} \left\{ e^{a_{R_1 R_2 S_1 S_2} [(n_{\text{ph}}+1)e^{-i\omega_0 t} + n_{\text{ph}} e^{i\omega_0 t}]} - 1 \right\}, \quad (\text{D.26})$$

and

$$b_{R_1 S_1 R_2 S_2 k q} = J^2 \delta_{R_1, S_1 \pm 1} \delta_{R_2, S_2 \pm 1} e^{i[kR_1 - (k-q)S_1]} e^{i[(k-q)R_2 - kS_2]}. \quad (\text{D.27})$$

To evaluate this expression, the exponential containing phonon operators is expanded using the identity

$$e^{a \cos \theta} = \sum_{l=-\infty}^{\infty} I_l(a) e^{il\theta} \quad (\text{D.28})$$

together with the relation

$$(n_{\text{ph}} + 1)e^{-i\omega_0 t} + n_{\text{ph}} e^{i\omega_0 t} = 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)} \cos \left[\omega_0 \left(t + i\frac{\beta}{2} \right) \right]. \quad (\text{D.29})$$

This allows the self-energy to be expressed as a sum over multiphonon processes, leading to

$$\begin{aligned} \Sigma_k(\omega) = & \frac{1}{N^2} \sum_q \sum_{R_1 S_1 R_2 S_2} b_{R_1 S_1 R_2 S_2 k q} \\ & \left\{ [I_0(a_{R_1 R_2 S_1 S_2} \cdot 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)}) - 1] G_{k-q}^R(\omega) + \right. \\ & \left. \sum_{l \neq 0} I_l(a_{R_1 R_2 S_1 S_2} \cdot 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)}) e^{-\frac{1}{2}l\omega_0\beta} G_{k-q}^R(\omega + l\omega_0) \right\}. \end{aligned} \quad (\text{D.30})$$

In the polaron band transport regime, the relevant energies are concentrated around the renormalized dispersion $\tilde{\varepsilon}_k$, which is relatively narrow. As a result, the dominant contribution to the self-energy at these energies arises from the term with $l = 0$, while terms with $l \neq 0$ are shifted by multiples of ω_0 and contribute at higher energies.

Retaining only the $l = 0$ contribution, and introducing the definition

$$S_0(R, \omega, J) = \frac{1}{N} \sum_k \frac{e^{ikR}}{\omega + 2J \cos k + i0^+} \quad (\text{D.31})$$

the self-energy reduces to

$$\begin{aligned} \Sigma_k(\omega) = & \sum_{R_1=0, S_1, R_2, S_2} J^2 \delta_{R_1, S_1 \pm 1} \delta_{R_2, S_2 \pm 1} e^{-2(\frac{g}{\omega_0})^2 (2n_{\text{ph}}+1)} e^{ik(R_1 - S_2)} \\ & S_0(R_2 - S_1, \omega, \tilde{J}) \left[I_0(2a_{R_1 R_2 S_1 S_2} \sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)}) - 1 \right]. \end{aligned} \quad (\text{D.32})$$

The function $S_0(R, \omega, J)$ can be evaluated analytically using the same contour integration techniques as in the band transport case. Introducing the notation $\tau = \frac{\omega}{2J}$, and the corresponding roots $z_1 = -\tau + \sqrt{\tau^2 - 1}$, $z_2 = -\tau - \sqrt{\tau^2 - 1}$, the result can be written as

$$S_0(R, \omega, J) = \begin{cases} \frac{z_1^R}{J(z_1 - z_2)} & \tau > -1 \text{ and } R \geq 0 \\ \frac{z_2^R}{J(z_2 - z_1)} & \tau < -1 \text{ and } R \geq 0 \\ \frac{z_1^R}{J(z_1 - z_2)} + \frac{1}{Jz_1 z_2} & \tau > -1 \text{ and } R = -1 \\ \frac{z_2^R}{J(z_2 - z_1)} + \frac{1}{Jz_1 z_2} & \tau < -1 \text{ and } R = -1 \\ \frac{z_1^R}{J(z_1 - z_2)} + \frac{1}{Jz_1 z_2} \left(\frac{1}{z_1} + \frac{1}{z_2} \right) & \tau > -1 \text{ and } R = -2 \\ \frac{z_2^R}{J(z_2 - z_1)} + \frac{1}{Jz_1 z_2} \left(\frac{1}{z_1} + \frac{1}{z_2} \right) & \tau < -1 \text{ and } R = -2 \end{cases} \quad (\text{D.33})$$

This form of the self-energy reflects the dominant role of coherent processes in the polaron band transport regime.

Appendix E

Transport regime crossovers

In this appendix, a detailed analysis of the transport regime crossovers shown in Fig. 4.9 is presented for the phonon frequencies $\omega_0/J = 1/3$ and $\omega_0/J = 3$.

E.1 Transport regime crossovers in Fig. 4.9 for $\omega_0 = J/3$.

In this section, the transport regime crossovers shown in Fig. 4.9 are analyzed in more detail for $\omega_0 = J/3$.

For the weakest interaction strength, $\lambda = 0.010$, the results in Fig. 4.5 indicate that both band and hopping transport may, in principle, be relevant at higher temperatures. A more detailed examination of Fig. E.1 shows that the numerically exact data closely follow the band transport mobility, while the hopping mobility remains below the band mobility curve (see also Fig. 4.4). This confirms that the transport is governed by the band transport regime across the entire temperature range.

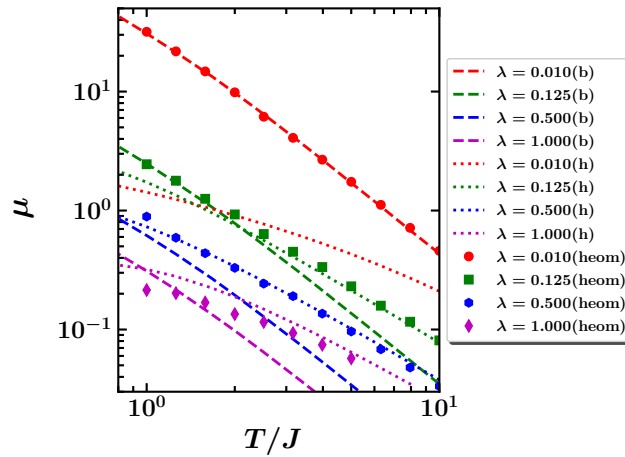


Figure E.1: Temperature dependence of the mobility for band and hopping transport at $\omega_0 = J/3$. Results for band transport (labeled “b”) and hopping transport (labeled “h”) are compared with numerically exact HEOM data (points).

At an interaction strength of $\lambda = 0.125$ and temperatures below $T/J = 1.0$, Fig. 4.5 indicates that band transport is the relevant regime. However, for temperatures $T/J = 2.0$ and 5.0 , the identification of the transport regime becomes ambiguous.

The mobility data shown in Fig. E.1 indicate that, within the temperature interval $1.0 \leq T/J \leq 10.0$, a clear distinction between band and hopping transport cannot be made. A similar conclusion is reached from the real-time correlation functions in Fig. E.2, where the QMC results remain close to both the band and hopping transport expressions.

This region is therefore classified as an intermediate regime between band and hopping transport. At the highest temperatures, the transport behavior is assigned to the hopping regime, based on the results from Fig. 4.5.

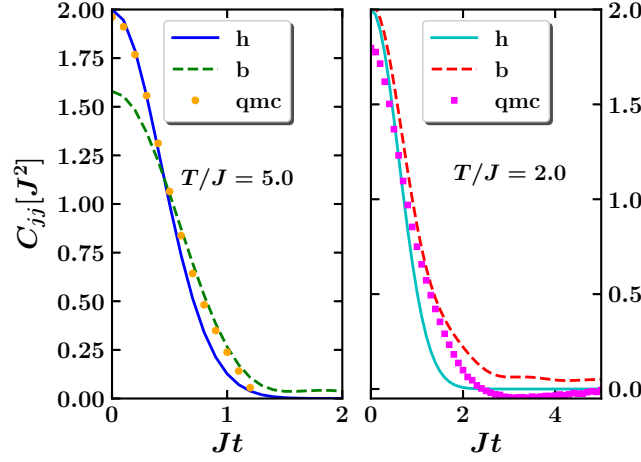


Figure E.2: Real time current-current correlation functions for $\omega_0 = J/3$, $\lambda = 0.125$, and the temperatures $T/J = 2.000$ and $T/J = 5.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

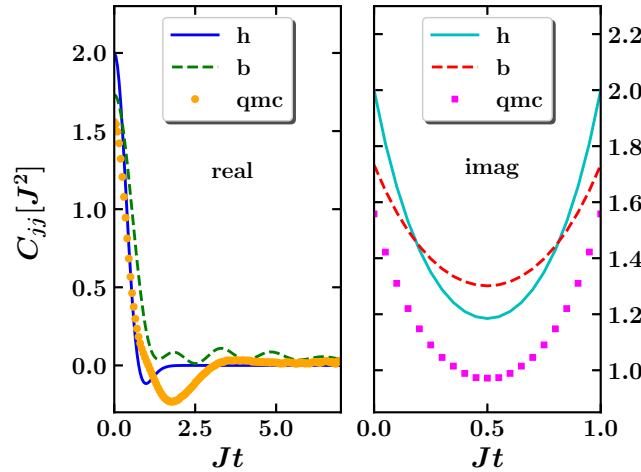


Figure E.3: Real and imaginary time current-current correlation functions for $\omega_0 = J/3$, $\lambda = 0.500$, and $T/J = 1.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

At an interaction strength $\lambda = 0.500$, Fig. 4.5 indicates that hopping transport becomes the dominant mechanism for temperatures $T/J > 1.0$. The mobility data shown in Fig. E.1 confirm this behavior, as the numerically exact results closely follow the hopping transport curve over the temperature range $1.0 \leq T/J \leq 10.0$.

However, the analysis of the real-time correlation functions (Fig. E.3) shows that the identification of the transport mechanism at $T/J = 1.0$ remains ambiguous, as the QMC results are consistent with both band and hopping transport. At lower temperatures, $T/J < 1.0$, the results from Fig. 4.5 indicate that none of the three transport regimes provides a consistent description. This region is therefore represented as a white region in Fig. 4.9.

For an interaction strength $\lambda = 1.000$, Figs. 4.5 and E.1 indicate that hopping transport is the dominant mechanism over the temperature interval $1.0 \leq T/J \leq 10.0$. The analysis of the imaginary-

time correlation functions further supports this conclusion, showing that the numerical results are most consistent with the hopping transport expressions down to temperatures of the order $T/J \sim 1.0$.

At lower temperatures, Fig. 4.3 indicates that the polaron band transport regime is realized only for $T/J \lesssim 0.1$. Consequently, within the temperature range $0.1 \leq T/J \leq 10.0$, transport is assigned to the hopping regime for this set of parameters.

The same conclusion applies to the case $\lambda = 2.000$.

E.2 Transport regime crossovers in Fig. 4.9 for $\omega_0 = 3J$.

In this section, the transport regime crossovers shown in Fig. 4.9 are analyzed for $\omega_0 = 3J$.

For $\lambda = 0.010$, Fig. 4.5 indicates that both band and hopping transport satisfy the numerical criterion within the temperature range $1.0 \leq T/J \leq 10.0$. The distinction between the two mechanisms is made based on the analysis of real-time current–current correlation functions (Fig. E.4), which show that the numerical results are most consistent with conventional band transport for temperatures $0.5 \leq T/J \leq 10.0$.

This conclusion can be extended to lower temperatures based on the physical argument that, for weak interaction strength, a reduction in temperature suppresses electron–phonon scattering, thereby preserving the band transport mechanism.

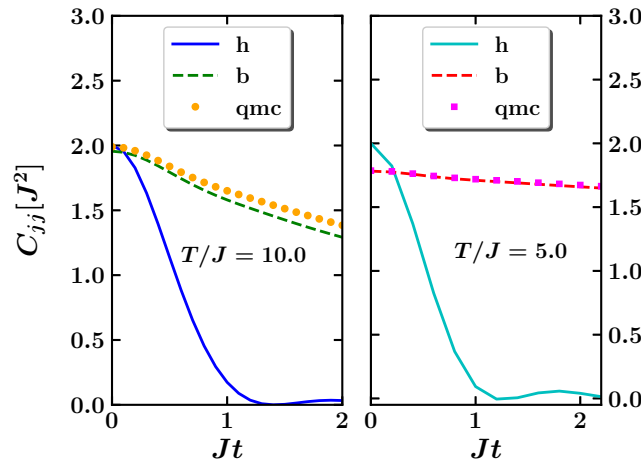


Figure E.4: Real time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.010$, and the temperatures $T/J = 2.000$ and $T/J = 10.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

For the next interaction strength, $\lambda = 0.125$, Fig. 4.5 shows that the imaginary-time criterion is satisfied for band transport in the temperature range $0.2 \leq T/J \leq 5$, and for hopping transport in the range $1 \leq T/J \leq 10$. The available mobility data (Fig. E.5) indicate that, for temperatures below $T/J = 5$, the transport behavior is best described by the band transport regime.

This conclusion is further supported by the real-time correlation functions shown in Fig. E.6 for $T/J = 2$, where the QMC results more closely follow the band transport curve. A more detailed analysis of the real-time current–current correlation functions (Fig. E.7) shows that, at $T/J = 5$, the system lies in an intermediate regime between band and hopping transport. At higher temperature, $T/J = 10.0$, both Fig. E.7 and Fig. 4.5 indicate that hopping transport becomes the relevant regime.

For the interaction strength $\lambda = 0.500$, the system can be considered to lie in the moderately strong coupling regime, where polaron band transport may be expected to occur. As shown in Fig. 4.5, the conditions for polaron band transport are satisfied in the temperature range $0.1 \leq T/J \leq 2$. In addition, the numerical criterion suggests possible agreement with band transport in the interval $0.5 \leq T/J \leq 2$, and with hopping transport for $1 \leq T/J \leq 10$.

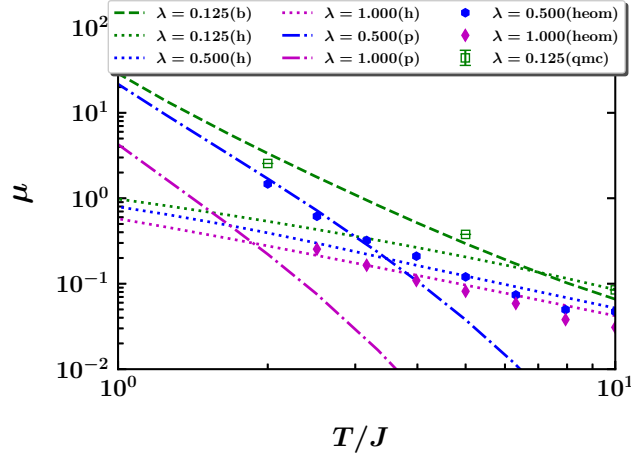


Figure E.5: Temperature dependence of the mobility for band, hopping, and polaron band transport at $\omega_0 = 3J$. Results labeled “b”, “h”, and “p” are compared with numerically exact HEOM data [33] (points).

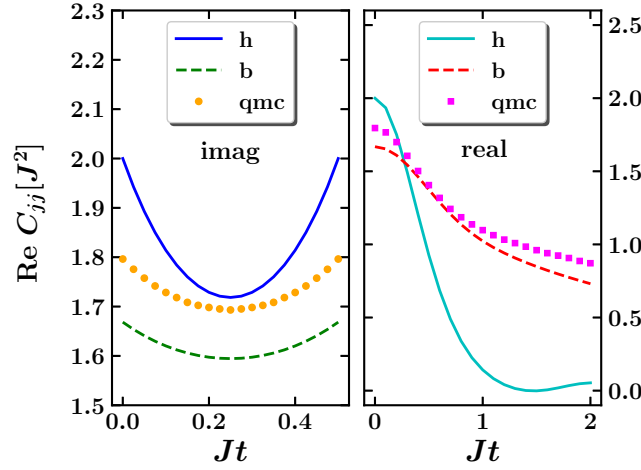


Figure E.6: Imaginary- and real-time current-current correlation functions shown for specified parameters $\omega_0 = 3J$, $\lambda = 0.125$, $T/J = 2.000$. Lines labeled with “h” correspond to functions obtained with Eq. 4.6 for hopping transport, lines labeled “b” correspond to functions obtained with expression for band transport and QMC results are represented with points.

The possibility of conventional band transport is ruled out based on the analysis of real-time current–current correlation functions. As illustrated in Fig. E.8, the QMC results deviate significantly from both the band and hopping transport expressions, indicating that neither description provides an adequate representation in this region.

Additional insight is provided by the available numerically exact HEOM data (Fig. E.5), which clearly demonstrate a crossover from polaron band to hopping transport. This transition occurs in the vicinity of the intersection between the corresponding mobility curves.

For the two strongest interaction strengths, $\lambda = 1.000$ and $\lambda = 2.000$, numerically exact data are not available at the lowest temperatures. The identification of transport regime transitions is therefore based on the conclusions established in the previous analysis.

For $\lambda = 1.000$, Fig. 4.5 indicates that the criterion for polaron band transport is satisfied in the temperature range $0.1 \leq T/J \leq 1.0$, while possible agreement with hopping transport is found for $0.5 \leq T/J \leq 10$. The possibility of conventional band transport is excluded for the same reasons as in the case of $\lambda = 0.500$. As shown in Figs. 4.3 and E.5, the mobility curves for polaron band and hopping transport intersect at approximately $T/J \approx 2$. This intersection is used to identify the crossover between the two regimes, with transport assigned to the polaron band regime for $T/J \lesssim 2$, and to the hopping regime for $T/J \gtrsim 2$.

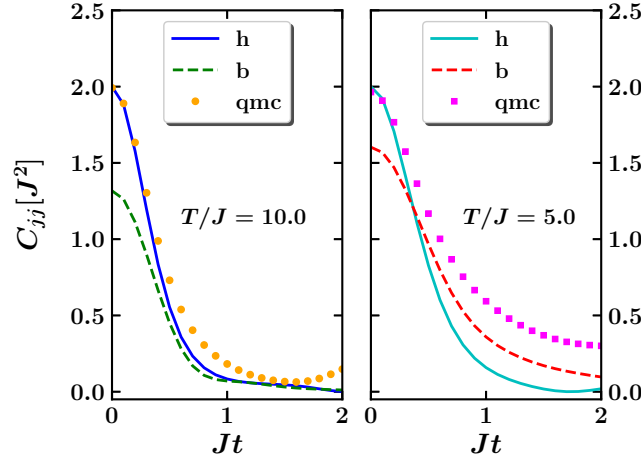


Figure E.7: Real-time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.125$, and the temperatures $T/J = 5.000$ and $T/J = 10.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

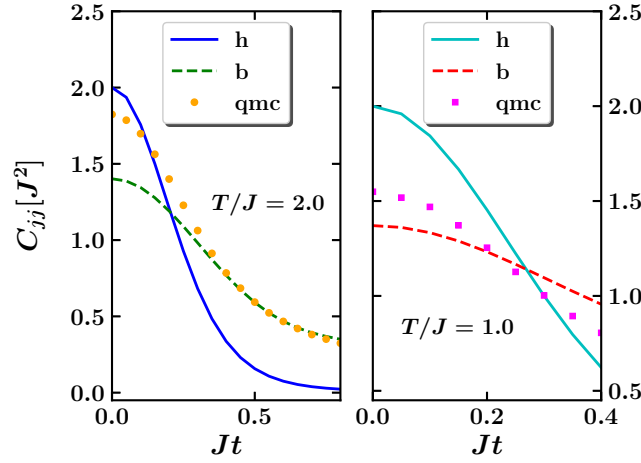


Figure E.8: Real-time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.500$, and the temperatures $T/J = 1.000$ and $T/J = 2.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

A similar analysis applies to $\lambda = 2.000$, where the intersection of the corresponding mobility curves occurs at approximately $T/J \approx 1.0$. Accordingly, transport is assigned to the polaron band regime for $T/J \lesssim 1.0$, and to the hopping regime for higher temperatures.

Biography

Suzana Miladić was born on January 3, 1995, in Novi Sad. She completed her elementary education in Bačka Palanka in 2010, after which she continued her schooling in Novi Sad, graduating from medical high school in 2014 as a physical therapist. She then enrolled at the Faculty of Sciences in Novi Sad, where she obtained her BSc degree in physics in 2018. She continued her studies at the Faculty of Physics in Belgrade, where she completed her MSc in September 2019 with a thesis titled "Spin resonance and relaxation in InSb nanowire quantum dots" under the supervision of Dr. Edib Dobardžić, for which she received the Faculty of Physics award "Prof. Dr. Ljubomir Ćirković".

In late 2019, she enrolled in PhD studies at the Faculty of Physics in Belgrade in the field of condensed matter physics. Since December 2019, she has been employed at the Institute of Physics Belgrade, in the Scientific Computing Laboratory, where she conducts research on polaron transport under the supervision of Dr. Nenad Vukmirović. During her PhD, she participated in several conferences and workshops and received two awards for poster presentations. She also proposed and completed a smaller research project on polaron transport, supported by the SAIGE SEED grant for young researchers. Her PhD research was primarily conducted within the PolMoReMa project, led by Dr. Nenad Vukmirović.

Her PhD work resulted in two publications:

1. S. Miladić and N. Vukmirović, *Method for obtaining polaron mobility using real and imaginary time path-integral quantum Monte Carlo*, Phys. Rev. B **107**, 184315 (2023)
2. S. Miladić and N. Vukmirović, *Identification of the transport regimes of the one-dimensional Holstein model*, Phys. Rev. B **112**, 054314 (2025)

Identification of the transport regimes of the one-dimensional Holstein model

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The Holstein model is a benchmark model of systems with electron-phonon interaction. However, its electrical transport properties are not yet fully understood. In this work, we performed numerically exact calculations of the imaginary-time current-current correlation function of the Holstein Hamiltonian for a broad range of model parameters. These calculations were performed using a path-integral-based quantum Monte Carlo method. We compared these results with the results obtained under the assumption of conventional band transport, small polaron hopping, and polaron band transport. From this comparison, we identified the regions in parameter space where each of these transport regimes is valid. In some cases when an imaginary-time comparison of current-current correlation functions could not give conclusive results, we complemented it with real-time comparisons or a comparison with the literature data on numerically exact dc mobilities. Overall, we found that the parameter space is almost completely covered by the three mentioned transport regimes.

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I. INTRODUCTION

The mobility of charge carriers in semiconductor materials is mainly governed by the interaction between electrons and phonons [1–3]. Depending on the strength of the interaction and the temperature, different carrier transport regimes can occur [4,5]. In scenarios where the electron-phonon interaction is weak, carriers are delocalized and sometimes scatter on the phonons, placing the system within the traditional band transport regime. This is the common regime observed in the conduction band of traditional semiconductors, where transport phenomena are described by the Boltzmann equation [6–12]. In conditions of strong electron-phonon interaction and high temperatures, the carriers become entirely localized and they move by occasionally hopping between neighboring sites [13–18]. This type of hopping behavior commonly occurs in small-molecule-based organic semiconductors [19]. The hopping rates and mobility in these systems are often modeled using the Marcus formula [20–24]. In cases where the interaction remains strong while the temperature is low, carriers delocalize and form a band, which is much narrower than the bare electron band. This scenario is known as the polaron band transport regime [25].

The mentioned regimes take place under conditions of either a weak or strong electron-phonon interaction, or in scenarios where the temperature is significantly high or low. The methods that have been developed to calculate the carrier mobility in real materials are typically based on the assumption of either band transport [6–12] or hopping mechanisms [20–24]. However, these methods are sometimes applied even when it is uncertain if one of these regimes is genuinely present within the material. On the other hand, the methods that do not make the assumption about the transport regimes are typically

limited to model Hamiltonians [26–47]. For these reasons, it is of significant interest to understand the range of validity of different transport regimes. Moreover, it is especially important to determine if the specified regimes cover the entire parameter space or if there are areas where carrier transport cannot be adequately explained by any of these regimes.

This research tackles these questions by examining a prototype model with electron-phonon interaction, i.e., the Holstein model [48]. An ideal approach to answering these questions would be to perform numerically exact calculations of carrier mobility or current-current correlation function using real-time or real-frequency methods throughout the whole parameter space and compare the results with the predictions of each of the theories corresponding to characteristic transport regimes. Although several numerically exact approaches have been applied to the Holstein model in recent years, their practical applicability is restricted to a limited part of the parameter space [49–54]. On the other hand, imaginary-time quantities can be reliably calculated across a significantly broader range of the parameter space.

In this work, we therefore perform numerically exact calculations of the imaginary-time current-current correlation function over a broad range of parameters. These calculations are conducted employing a path-integral-based quantum Monte Carlo (QMC) method [55–59]. For the same parameter sets, we calculate the same quantity under the assumptions of band transport, hopping, or polaron band transport mechanisms. The comparison of these results allows us to infer the range of validity of each of the transport regimes. In some cases where the comparisons of the imaginary-time correlation functions do not give conclusive results, we complement them with comparisons of real-time correlation functions or mobilities.

The structure of the paper is as follows. Section II presents the model and methods on which our work is based. In Sec. II A, we briefly introduce the Holstein Hamiltonian.

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Section II B outlines the QMC method employed to compute current-current correlation functions and dc mobilities, which are pivotal to our findings. In Sec. II C, we derive analytical expressions for various transport regimes and present some results based on these expressions. Specifically, Sec. II C 1 derives formulas for current-current correlation functions and dc mobility for strong electron-phonon interactions, with a particular emphasis on the high-temperature limit. Next, Sec. II C 2 derives expressions in the case of weak electron-phonon interaction and large polaron transport. Lastly, Sec. II C 3 addresses low-temperature polaron narrow band transport. In Sec. II C 4, we present some results obtained from the formulas presented in Secs. II C 1–II C 3. In Sec. III, we compare the results obtained using the expressions for different transport regimes to numerically exact QMC results and construct the transport regime diagram, which gives the information about the range of parameters where each of the transport regimes takes place. We finalize the paper with the conclusions in Sec. IV.

II. MODEL AND METHODS

A. Holstein Hamiltonian

We consider the model in one dimension consisting of one carrier (electron) interacting with a chain of equidistant motifs (ions). This simple model is described with one-dimensional Holstein Hamiltonian,

$$H = -J \sum_p \sum_{\gamma=\pm 1} a_{p+\gamma}^\dagger a_p + \sum_p \omega_0 b_p^\dagger b_p + \sum_p G a_p^\dagger a_p (b_p + b_p^\dagger), \quad (1)$$

where a_p and $a_p^\dagger$ are electronic operators that annihilate or create an electron at lattice site p , b_p and $b_p^\dagger$ are phonon operators that annihilate or create a phonon of angular frequency ω_0 at lattice site p , G is the electron-phonon coupling constant, and J is the electronic transfer integral. We use the system of units where the reduced Planck constant $\hbar$, the elementary charge e , the lattice constant a_l , and the Boltzmann constant k_B are set to 1.

B. QMC method

The main quantity that we evaluate in this work is the current-current correlation function which contains information about electronic transport properties. It reads

$$C_{jj}(t) = \langle j(t)j(0) \rangle = Z^{-1} \text{Tr}[e^{-\beta H} e^{itH} j e^{-itH} j], \quad (2)$$

where $Z = \text{Tr} e^{-\beta H}$ represents the partition function in the canonical ensemble, β is the inverse temperature, and the operator j is given by

$$j = iJ \sum_p (a_p^\dagger a_{p+1} - a_{p+1}^\dagger a_p). \quad (3)$$

The operator j can also be represented as

$$j = \sum_k v_k a_k^\dagger a_k, \quad (4)$$

where $v_k = -2J \sin k$ is the band velocity and the operators a_k ($a_k^\dagger$) annihilate (create) an electron of momentum k . When t is a real number, Eq. (2) defines the real-time current-current correlation function. For $t = -i\tau$, where the real number τ is from the interval $0 \leq \tau \leq \beta$, Eq. (2) defines the imaginary-time current-current correlation function. The dc mobility is related to the real-time current-current correlation function as [3]

$$\mu = \frac{\beta}{2} \int_{-\infty}^{\infty} dt \langle j(t)j(0) \rangle. \quad (5)$$

The system with a single electron in the canonical ensemble is equivalent to the system in the grand canonical ensemble with chemical potential $\mu \rightarrow -\infty$. This corresponds to the physical situation where the carrier concentration in the band is low and the chemical potential is well below the bottom of the band.

We perform a numerically exact calculation of the current-current correlation function using the path-integral quantum Monte Carlo method. The details of the methodology were presented in our previous work [59] and summarized in Ref. [60], so we discuss it here only briefly. Within the method, the real- or imaginary-time evolution operators ($e^{\pm iHt}$ or $e^{-\beta H}$) are divided into evolution operators over small time steps using the Suzuki-Trotter expansion. The path integral for the correlation function then reduces to a sum which is evaluated using a Monte Carlo procedure. The systematic error arising from the finite time step is controlled by choosing a sufficiently small time step. The statistical error coming from a finite number of samples in the Monte Carlo evaluation of the sum is controlled by choosing a sufficiently large number of samples. It is therefore more challenging to obtain results at extremely low temperatures (large β) or at greater real times (large t).

To perform more efficient calculations, it is also possible to exploit the fact that the trace in Eq. (2) can be expressed using any complete basis that spans the Hilbert space of the system, as we discussed in our previous work [59]. While the final result is independent of the choice of the basis, the basis does influence the statistical error in the Monte Carlo summation that is performed over a limited number of terms only [61]. This insight enables us to select a basis that reduces the statistical error of the Monte Carlo sums within certain parameter ranges. With such a choice, we can perform the simulation for longer real times before the dynamical sign problem [62–67] occurs and we can perform imaginary-time calculations at lower temperatures (larger β). We find that it is convenient to use the basis of electron momentum states and the coordinate representation for phonons in the case of weaker electron-phonon interactions. For stronger interaction, we find that it is more convenient to use the position representation for the electron and the coordinate representation for phonons. This basis gives an additional advantage that phonon coordinates can be integrated out.

In this paragraph, we give some technical details regarding our QMC calculations. We have performed calculations so that the standard deviation is no greater than about 1% of the result. To achieve such precision, we used from 10^3 to 10^6 MC samples in a single calculation. Full QMC calculations were repeated 10 or 100 times for better statistics and standard error

estimation. We have chosen the time discretization step values to be less or equal to $0.1/J$ since convergence tests showed us that for such small values, there is no significant change in the result. Finally, we discuss the system size parameter—the number of sites in the one-dimensional (1D) model. All our calculations were performed to be representative of the thermodynamic limit. We have chosen a sufficiently large number of sites so that its further increase does not affect the result. For the majority of the calculations for short real times ($Jt \leq 1.0$) and imaginary times (at higher temperatures), the number of about 10 sites was sufficient, while for longer real times and some lower temperatures, there was a need for a much larger system with several tens of sites. This also sets the limit to our calculations as these are not computationally feasible for larger systems. In Fig. S9 of the Supplemental Material [68], we present an example of the calculations for different system sizes when $\lambda = 0.01$, $T/J = 0.1$, and $\omega_0 = 3J$. We also present in Fig. S10 of the Supplemental Material [68] a detailed table with the parameter values (time steps, number of sites, number of MC samples, etc.). We refer the reader to Ref. [59] for a more detailed discussion regarding the choice of simulation parameters.

C. Transport regimes

In the case of a 1D Holstein model, the strong electron-phonon coupling causes the carrier to self-trap in the potential well, which is formed due to phonon displacements on the lattice site [5]. In such a way, a “localized small polaron” is formed. At very low, near-zero temperatures, a small polaron can tunnel between equal-energy neighboring sites with no change in energy (diagonal/coherent processes). This is similar to free carrier band transport, but in this case the polaron band is extremely narrow [25]. At higher temperatures, the polaron may move by phonon-assisted hopping between sites (nondiagonal/incoherent processes). On the other hand, in the case of weak electron-phonon coupling, the carrier is usually called a large polaron. It acts as a free carrier with somewhat increased effective mass that occasionally scatters on lattice vibrations. The phonon scattering of large polaron causes its mobility to decrease with increasing temperature and its transport is conventional band transport. The large polaron is, in general, more mobile compared to the small polaron. In this section, we present the expressions for a current-current correlation function in each of the three mentioned regimes: (small polaron) hopping, (small) polaron band transport, and (large polaron) band transport.

1. Hopping transport

The expression for the hopping rate between two neighboring sites can be obtained by treating the electronic coupling between the sites as a perturbation and applying the Fermi’s golden rule. Such an expression is expected to be valid when the electron-phonon interaction is sufficiently strong and when the temperature is not too low. This expression takes the form which is known in the literature [69–71]:

$$W = J^2 \int_{-\infty}^{\infty} dt e^{-2(\frac{G}{\omega_0})^2 [2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t}-n_{\text{ph}}e^{i\omega_0 t}]}, \quad (6)$$

where $n_{\text{ph}} = (e^{\beta\omega_0} - 1)^{-1}$ is the phonon occupation number. The derivation of this expression can be found in Ref. [69] or [70]. The corresponding current-current correlation function reads (see Eq. (24) in Ref. [60])

$$C_{jj}(t) = 2J^2 e^{-2(\frac{G}{\omega_0})^2 [2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t}-n_{\text{ph}}e^{i\omega_0 t}]}. \quad (7)$$

In the limit of high temperature, Eq. (6) reduces to the widely used Marcus formula [20–24],

$$W = J^2 \sqrt{\frac{\beta\pi}{\lambda}} e^{-\frac{\beta\lambda}{4}}, \quad (8)$$

with $\lambda = \frac{2G^2}{\omega_0}$ and the corresponding mobility,

$$\mu = \beta J^2 \sqrt{\frac{\beta\pi}{\lambda}} e^{-\frac{\beta\lambda}{4}}. \quad (9)$$

The corresponding current-current correlation function reads (see Eq. (26) in Ref. [60])

$$C_{jj}(t) = 2J^2 e^{-\sigma_0^2 t^2} e^{-i\beta\sigma_0^2 t}, \quad (10)$$

where $\sigma_0^2 = \frac{2G^2}{\beta\omega_0}$.

In the case of the Holstein model with a single dispersionless phonon mode that we are considering, Eq. (6) leads to a diverging result for the hopping rate and the dc mobility since the current-current correlation function from Eq. (7) does not decay to zero when $t \rightarrow \infty$. The origin of this divergence comes from the fact that small polarons are treated as quasiparticles with infinite lifetime in such considerations. An improvement over such approach where broadening of small polaron states is taken into account by calculating the relevant self-energies was presented recently in Appendix C of Ref. [60] and here we present the first application of that approach. One then obtains (see Eq. (25) in Ref. [60])

$$C_{jj}(t) = g(t) e^{-2(\frac{G}{\omega_0})^2 [2n_{\text{ph}}+1-(n_{\text{ph}}+1)e^{-i\omega_0 t}-n_{\text{ph}}e^{i\omega_0 t}]}, \quad (11)$$

where

$$g(t) = 2J^2 \frac{\beta}{t(\beta - it)} \frac{1}{\sqrt{c_0}} \frac{I_1[-2(\beta - it)\sqrt{c_0}]J_1(2t\sqrt{c_0})}{I_1(-2\beta\sqrt{c_0})}, \quad (12)$$

while I_1 (J_1) is the (modified) Bessel function of the first kind of order 1 and

$$c_0 = 2J^2 e^{-2(\frac{G}{\omega_0})^2 (2n_{\text{ph}}+1)} I_0(\alpha), \quad (13)$$

with

$$\alpha = 4 \left(\frac{g}{\omega_0} \right)^2 \sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)}. \quad (14)$$

The corresponding dc mobility, which is related to $C_{jj}(t)$ via Eq. (5), is then given as

$$\mu = 2J^2 \beta \pi e^{-2(\frac{G}{\omega_0})^2 (2n_{\text{ph}}+1)} \times \frac{\sum_{l=-\infty}^{\infty} \int d\omega e^{-\beta\omega} A(\omega) A(\omega + l\omega_0) I_1(\alpha) e^{-\frac{l\omega_0\beta}{2}}}{\int d\omega e^{-\beta\omega} A(\omega)}, \quad (15)$$

where

$$A(\omega) = \frac{\sqrt{4c_0 - \omega^2}}{2\pi c_0} \theta(4c_0 - \omega^2), \quad (16)$$

I_l denotes the modified Bessel function of the first kind of order l , and θ is the step function.

To summarize this section, in the rest of the paper we will use Eqs. (11) and (15) as the result for the current-current correlation function and the dc mobility in the hopping regime. We will also compare these results to their high-temperature limits given by Eqs. (10) and (9). The results for imaginary-time current-current correlation functions will be simply obtained by the replacement $t \rightarrow -i\tau$.

2. Band transport

In this section, we present the expressions for the current-current correlation function and the dc mobility in the band transport regime. This regime is expected to take place when the electron-phonon interaction is sufficiently weak and when the temperature is not too high. Starting from Eq. (4), we obtain

$$C_{jj}(t) = \frac{\sum_{k,k'} v_k v_{k'} \langle a_k^\dagger(t) a_k(t) a_{k'}^\dagger a_{k'} \rangle}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (17)$$

We then make use of the independent particle (also known as the bubble) approximation, which is known to be exact in the limit of weak electron-phonon interaction [60] for the Holstein model,

$$\langle a_k^\dagger(t) a_k(t) a_{k'}^\dagger a_{k'} \rangle = \delta_{kk'} \langle a_k^\dagger(t) a_k(t) \rangle \langle a_{k'}^\dagger a_{k'} \rangle, \quad (18)$$

and obtain

$$C_{jj}(t) = 4J^2 \frac{\sum_k \langle a_k^\dagger(t) a_k(t) \rangle \langle a_k^\dagger a_k \rangle \sin^2(k)}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (19)$$

The expectation values in Eq. (19) are found from the electronic spectral function which is related to the retarded Green's function as $A_k(\omega) = -\frac{1}{\pi} \text{Im} G_k^R(\omega)$. The Green's function is found from the self-energy in the Migdal approximation which includes the diagrams that describe single phonon emission and absorption processes. This is, in most cases, sufficient for weak electron-phonon interaction. However, when $\frac{\omega_0}{2J} > 1$, there are momenta k that satisfy $|\varepsilon_k \pm \omega_0| > 2J$ for which single-phonon processes are not allowed due to energy conservation. In these cases, we also include the diagrams that describe two-phonon processes. The detailed expressions for self-energies and for expectation values in Eq. (19) are given in Sec. S1 of the Supplemental Material [68].

The dc mobility in the band transport regime is obtained from the expression (see Ref. [72])

$$\mu_{\text{dc}} = \beta \frac{\sum_k n_k \tau_k v_k^2}{\sum_k n_k}, \quad (20)$$

where $n_k = e^{-\beta \varepsilon_k}$ and the scattering time is given as $\tau_k^{-1} = -2 \text{Im} \Sigma_k(\omega)|_{\omega=\varepsilon_k}$. While the expression for band transport mobility including single-phonon processes only has been previously used (see, e.g., [72]), we are not aware of previous works that include two-phonon processes, which are necessary when $\frac{\omega_0}{2J} > 1$.

3. Polaron band transport

In this section, we derive the expression for the dc mobility and for the imaginary-time current-current correlation function in the polaron band transport regime. This expression is expected to be valid when the electron-phonon coupling is strong and when the temperature is very low. To this end, we perform the Lang-Firsov unitary transformation of the Hamiltonian and work in the basis of polarons that form a narrow band. We treat the remaining interacting part of the Hamiltonian as a perturbation and evaluate the corresponding self-energy. We derive the expression for the current-current correlation function and identify the contributions stemming from (i) processes with no phonon exchange (diagonal/coherent processes) and (ii) phonon-assisted processes (nondiagonal/incoherent processes). Since the processes (i) are the dominant ones in the polaron band transport regime, we include the contribution from these processes only in the expressions for the polaron band transport regime.

First, we perform the Lang-Firsov [73] unitary transformation $\tilde{H} = U^{-1} H U$ with

$$U = e^{\sum_p \frac{G}{\omega_0} a_p^\dagger a_p (b_p - b_p^\dagger)}. \quad (21)$$

The transformed Hamiltonian takes the form $\tilde{H} = \tilde{H}_0 + \tilde{V}$, with

$$\tilde{H}_0 = \sum_k \tilde{\varepsilon}_k a_k^\dagger a_k + \sum_p \omega_0 b_p^\dagger b_p, \quad (22)$$

where

$$\tilde{\varepsilon}_k = -\frac{G^2}{\omega_0} - 2\tilde{J} \cos k \quad (23)$$

is the polaron band dispersion and

$$\tilde{J} = J e^{-(2n_{\text{ph}}+1) \frac{G^2}{\omega_0^2}} \quad (24)$$

is the renormalized electronic transfer integral. The interaction term $\tilde{V}$ in the transformed Hamiltonian reads

$$\tilde{V} = \frac{1}{N} \sum_{k,q} a_{k+q}^\dagger a_k \mathcal{B}_{k,q}, \quad (25)$$

with

$$\mathcal{B}_{k,q} = - \sum_{p,r=p\pm 1} J e^{i[(k+q)p - kr]} [\theta_p^\dagger \theta_r - \theta_0], \quad (26)$$

where $\theta_p = e^{\frac{G}{\omega_0} (b_p - b_p^\dagger)}$ and $\theta_0 = e^{-(2n_{\text{ph}}+1) \frac{G^2}{\omega_0^2}}$, while N is the number of lattice sites.

The current-current correlation function in the independent particle (bubble) approximation [60] is given as (special case of the result from Ref. [72] when the Lang-Firsov transformation is used instead of a more general transformation)

$$C_{jj}(t) = \frac{\sum_{k_1 k_2} \langle a_{k_1}^\dagger(t) a_{k_1}(t) \rangle \langle a_{k_2}(t) a_{k_2}^\dagger(t) \rangle Y_{k_1 k_2}(t)}{\sum_k \langle a_k^\dagger a_k \rangle}. \quad (27)$$

The averages in the previous equation are taken with respect to the transformed Hamiltonian $\tilde{H}$, while

$$Y_{k_1 k_2}(t) = -\frac{\tilde{J}^2}{N} \sum_{\substack{X, Y=\pm 1, \\ Z}} XY e^{ik_1(X+Z)} e^{ik_2(X-Z)} \theta_{XYZ}(t), \quad (28)$$

with

$$\theta_{XYZ}(t) = e^{a_{0,Z,X,Z+Y}[(n_{\text{ph}}+1)e^{-i\omega_0 t} + n_{\text{ph}}e^{i\omega_0 t}]}, \quad (29)$$

and $a_{R_1 R_2 S_1 S_2} = \frac{G^2}{\omega_0^2} (\delta_{R_1 R_2} + \delta_{S_1 S_2} - \delta_{R_1 S_2} - \delta_{R_2 S_1})$. We then divide $\theta_{XYZ}(t) = \theta_{XYZ}^{(0)} + \theta_{XYZ}^{(1)}(t)$, with the two components defined as follows:

$$\begin{aligned} \theta_{XYZ}^{(0)} &= I_0 [2a_{0,Z,X,Z+Y} \sqrt{n_{\text{ph}}(n_{\text{ph}}+1)}], \\ \theta_{XYZ}^{(1)}(t) &= \sum_{l \neq 0} I_l [2a_{0,Z,X,Z+Y} \sqrt{n_{\text{ph}}(n_{\text{ph}}+1)}] \\ &\quad \times e^{il\omega_0 t} e^{-\frac{1}{2}l\omega_0 \beta}. \end{aligned} \quad (30)$$

The term $\theta_{XYZ}^{(1)}(t)$ contains the factor $e^{il\omega_0 t}$ which describes energy exchange with phonons. As polaron band transport is coherent, phonon-scattering processes are absent. Consequently, only the term $\theta_{XYZ}^{(0)}$ is relevant for polaron band transport and we include only this term in what follows. Next, we use the Kubo formula [Eq. (5)] and we exploit the relations

$$\langle a_{k_1}^\dagger(t) a_{k_1} \rangle = \int d\omega e^{i\omega t} \tilde{A}_{k_1}(\omega) e^{-\beta\omega}, \quad (31)$$

$$\langle a_{k_2}(t) a_{k_2}^\dagger \rangle = \int d\omega e^{-i\omega t} \tilde{A}_{k_2}(\omega), \quad (32)$$

where $\tilde{A}$ is the polaron spectral function for the Hamiltonian $\tilde{H}$ and we make use of the fact that $I_0 [2a_{0,Z,X,Z+Y} \sqrt{n_{\text{ph}}(n_{\text{ph}}+1)}] \approx 1$ in the polaron band transport regime, which takes place at low temperature when n_{ph} is close to zero. We then arrive at the expression

$$\mu_{\text{dc}} = \pi \beta \frac{\sum_k \tilde{v}_k^2 \int d\omega \tilde{A}_k(\omega)^2 e^{-\beta\omega}}{\sum_k \tilde{n}_k}, \quad (33)$$

with $\tilde{v}_k = -2\tilde{J} \sin k$ and $\tilde{n}_k = e^{-\beta\tilde{\epsilon}_k}$. Subsequently, we can apply the approximation valid in situations where the spectral function is narrow, as it is here:

$$\int d\omega \tilde{A}_k(\omega)^2 e^{-\beta\omega} = -\frac{e^{-\beta\omega}}{2\pi \text{Im} \Sigma_k(\omega)} \Big|_{\omega=\tilde{\epsilon}_k} = \frac{\tilde{n}_k \tilde{\tau}_k}{\pi}, \quad (34)$$

with the polaron lifetime defined as $\tilde{\tau}_k = \frac{1}{-2\text{Im} \Sigma_k(\omega)} \Big|_{\omega=\tilde{\epsilon}_k}$. The expression for self-energy $\Sigma_k(\omega)$ is derived in Sec. S2 in the Supplemental Material [68]. Finally, the dc mobility for polaron band transport can be expressed using the following formula:

$$\mu_{\text{dc}} = \beta \frac{\sum_k \tilde{n}_k \tilde{\tau}_k \tilde{v}_k^2}{\sum_k \tilde{n}_k}, \quad (35)$$

which takes exactly the same form as the formula for conventional band transport [Eq. (20)] with a difference that the band energies, band velocities, state occupations, and lifetimes should be replaced by their renormalized values. We are not aware of any previous rigorous derivation of this formula.

To evaluate the imaginary-time current-current correlation function in the polaron band transport regime, we make a

further approximation that the spectral function can be approximated with the δ function, $\tilde{A}_k(\omega) \approx \delta(\omega - \tilde{\epsilon}_k)$. We note that such an approximation would not be good enough for a real-time correlation function and the mobility since it does not lead to decay of the correlation function at long real times, but is sufficient for imaginary times. The imaginary-time current-current correlation function is then given as

$$C_{jj}(z) = \frac{\sum_{k_1 k_2} e^{-\beta\tilde{\epsilon}_{k_1}} e^{i(\tilde{\epsilon}_{k_1} - \tilde{\epsilon}_{k_2})z} Y_{k_1 k_2}^{(0)}}{\sum_k e^{-\beta\tilde{\epsilon}_k}}, \quad (36)$$

where $z = -i\tau$ ($0 \leq \tau \leq \beta$) and $Y_{k_1 k_2}^{(0)}$ denotes the contribution to $Y_{k_1 k_2}$ from the term $\theta_{XYZ}^{(0)}$.

4. Selected results in different transport regimes

In this section, we present several results obtained using approximate formulas for the dc mobility and the correlation function presented in previous sections. With this, we get an initial insight about the transport regimes in different parts of parameter space. To present the results, we express all energies in terms of the electronic transfer integral J , while we express the electron-phonon interaction strength through the dimensionless parameter $\lambda = G^2/(2J\omega_0)$.

We start with the hopping regime and discuss the connection between the two different formulas in that regime. In Sec. II C 1, we have presented expressions for hopping mobility and current-current correlation function [Eqs. (15) and (11)] in the case of the Holstein model with a single dispersionless phonon mode with correction that gives finite dc mobility in the whole temperature range. We are also considering expressions for dc mobility [Eq. (9)] and current-current correlation function [Eq. (10)] derived from the Marcus formula for hopping between two sites which are valid in the high-temperature limit. It is expected that the expressions derived within these two approaches give the same result at high enough temperatures.

From Fig. 1, we can see that the curves for mobility obtained with Eq. (15) and Eq. (9) tend to get closer with increasing temperature and eventually converge towards each other when the temperature is high enough. From Fig. 2, we can see that current-current correlation functions follow the same trend as mobility. Mainly, we can see that correlation functions in imaginary time, as well as real parts of correlation functions in real time, match at high temperature and do not match at low temperature. It is also worth commenting on the effect of the phonon frequency. From Figs. 1(a) and 1(b), it is obvious that as the phonon energy ω_0 is larger compared to the transfer integral J , the high-temperature limit is reached at higher temperatures. The same correspondence can be made regarding the electron-phonon interaction strength; the stronger the interaction λ , the high-temperature effects take place at higher temperatures. We must pay attention to the fact that all expressions discussed in this paragraph are derived under the assumption of hopping transport and have a physical sense only for stronger electron-phonon interactions ($\lambda \geq 0.500$). This analysis gives us confidence in the formulas for dc mobility given in Eq. (15) and current-current correlation function given in Eq. (11) derived in Sec. II C 1 with the assumption of strong electron-phonon interaction and

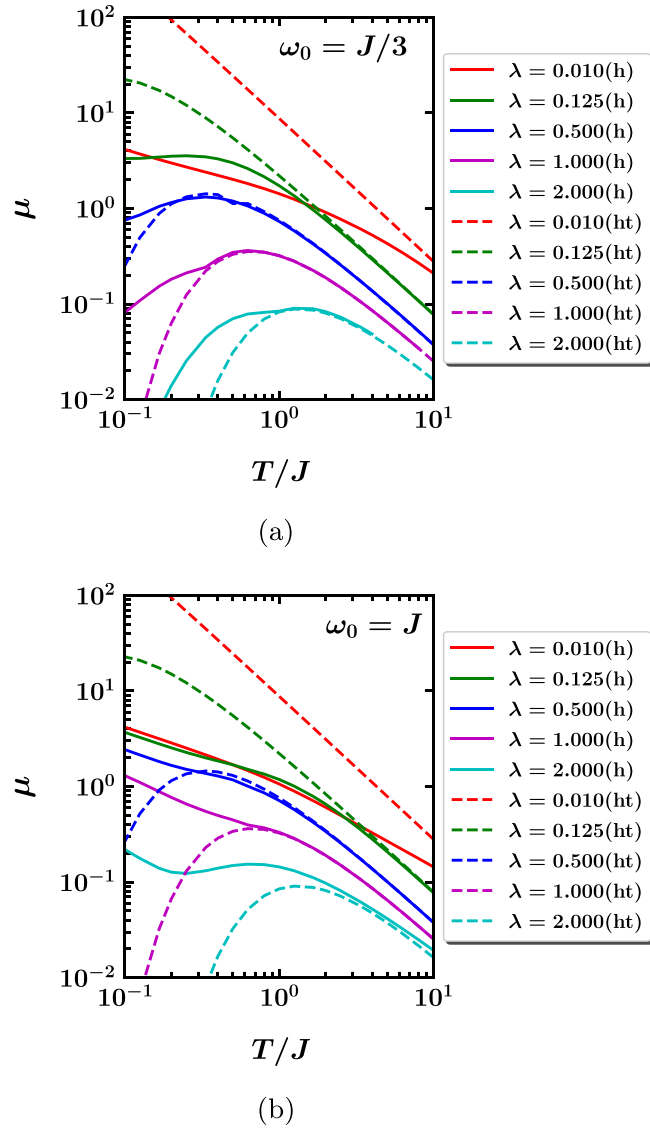


FIG. 1. Hopping mobility obtained using Eq. (15) is shown with full lines and the label “h,” while the mobility obtained from Eq. (9) in the high-temperature limit is shown with dashed lines and the label “ht.” Results are shown for a range of temperatures and various interaction strengths λ . The results for phonon angular frequency $\omega_0 = J/3$ are shown in (a), while the results for $\omega_0 = J$ are shown in (b).

small electron transfer integral since they coincide with the well-known Marcus formula in the high-temperature limit.

Next, we discuss the polaron band transport regime and its crossover to the hopping regime. In Sec. II C 3, we discussed that at very low temperatures and strong electron-phonon interactions, it is expected that polaron band transport will take place. To see exactly at how low temperatures this type of transport occurs, we will compare the results obtained using Eq. (35) for polaron band transport with the results obtained from Eq. (15) for hopping. The intersection of these curves can be considered to be a good estimate at which temperature the transition from polaron band transport to hopping transport occurs. As we can see in Fig. 3, the greater the interaction strength, the intersection of the polaron band transport and

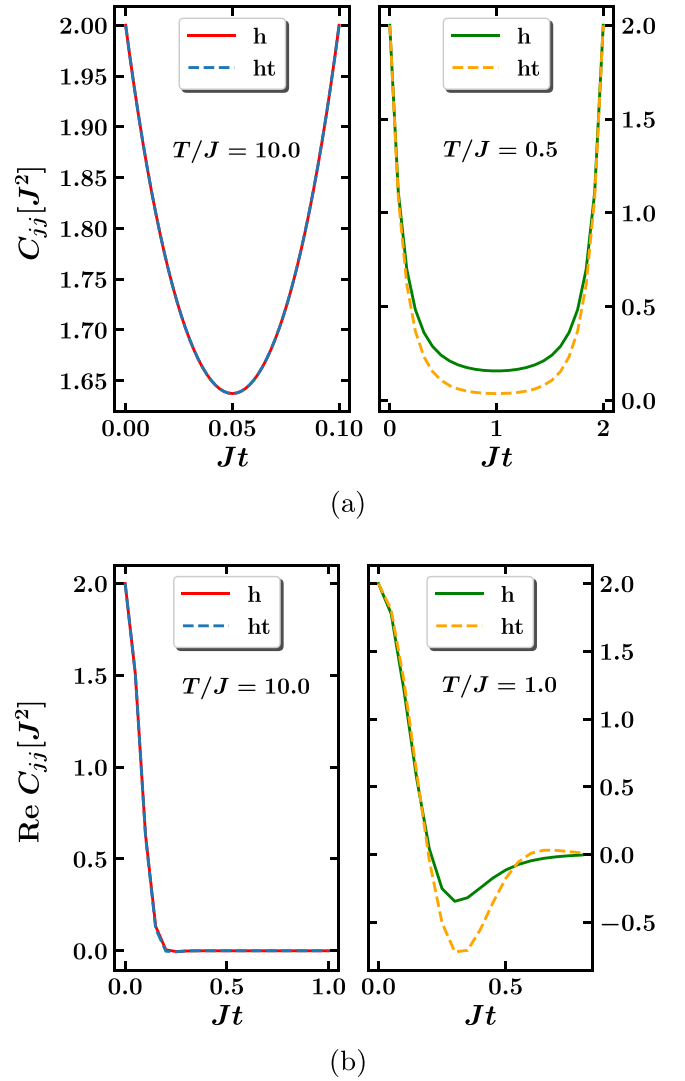
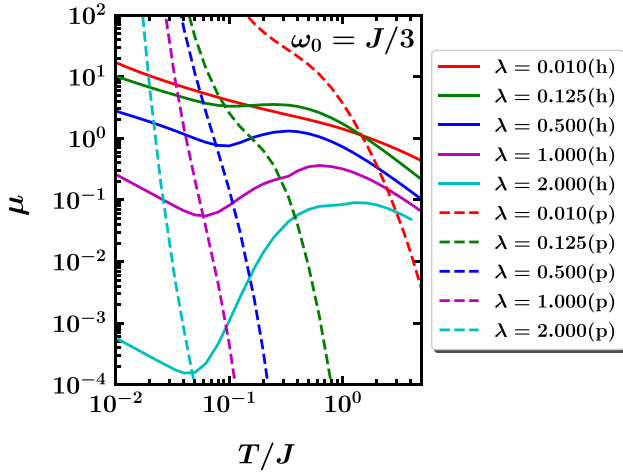
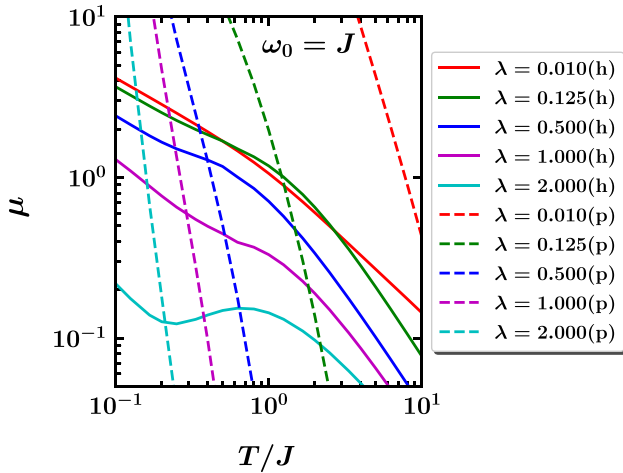


FIG. 2. (a) Current-current correlation function in imaginary time and (b) real part of the current-current correlation function in real time. Results shown with full lines labeled “h” are obtained with Eq. (11) and results obtained with Eq. (10) in the high-temperature limit are shown with dashed lines and labeled “ht.” The results are shown for $\omega_0 = 3J$, $\lambda = 2.000$ and the temperatures $T/J = 10.0$ and $T/J = 0.5$ for imaginary-time correlation functions and $T/J = 10.0$ and $T/J = 1.0$ for real-time correlation functions.

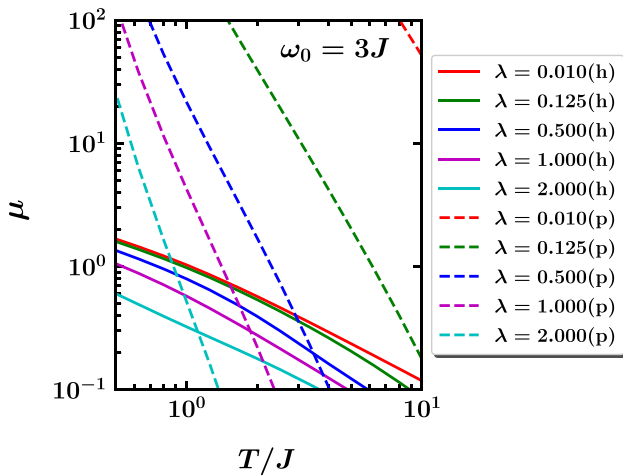
the hopping transport mobilities is at lower temperature. We can conclude that for stronger electron-phonon interactions, the hopping transport will occur at lower temperatures. Also, as we already saw in the analysis before this, with increasing phonon frequency, the high-temperature effects arise at higher temperatures. This can be seen in Fig. 3, as for $\omega_0 = 3J$ the intersections are at higher temperatures compared to the case when $\omega_0 = J/3$. While the results for all interaction strengths are presented in Fig. 3, one should bear in mind that only the results for stronger interactions (say $\lambda \geq 0.5$) should be considered for the analysis of the crossover from polaron band transport to hopping. This analysis gave us an important insight into the range of parameters where we can expect the polaron band transport regime to hold.



(a)



(b)



(c)

FIG. 3. Mobility obtained from Eq. (15) for hopping is shown with a full line and labeled “h.” Mobility for a polaron band transport is shown with a dashed line and labeled “p.” Results are shown for various interaction strengths λ and for phonon angular frequencies (a) $\omega_0 = J/3$, (b) $\omega_0 = J$, and (c) $\omega_0 = 3J$.

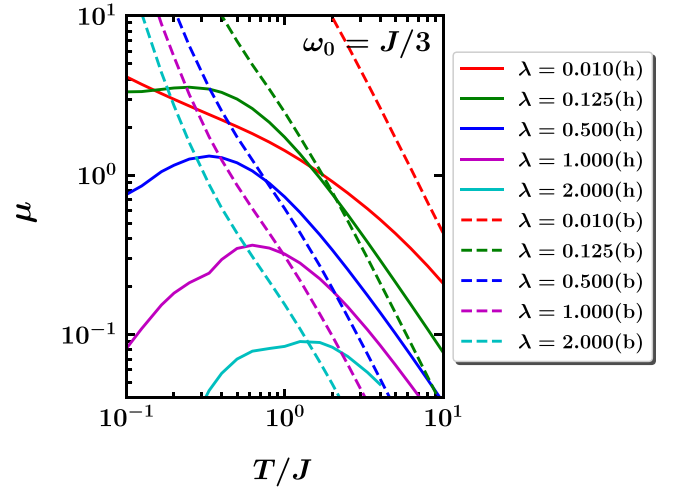


FIG. 4. Temperature dependence of mobility shown for a range of interaction strengths. The full line labeled as “b” stands for band transport and the dashed line labeled as “h” denotes hopping mobility. Results are shown for a range of interaction strengths λ and for phonon angular frequency $\omega_0 = J/3$.

Finally, we discuss the band transport regime and its crossover to the hopping regime. In Sec. II C 3, we presented expressions for the current-current correlation function [Eq. (19)] and the dc mobility [Eq. (20)] in the band transport regime. These expressions are derived under the assumption of weak electron-phonon interaction. The carrier in this transport regime is a large polaron as opposed to the small polaron that is characteristic for hopping transport. A large polaron moves similarly to a free carrier, but with increased effective mass and it sometimes scatters on thermally induced lattice phonons. At high temperatures, due to increased lattice vibrations, the large polaron may turn into a small polaron. Therefore, we may also expect that even in the case of weak electron-phonon interaction, the crossover from band transport to hopping could occur at high enough temperatures. Hopping mobility at higher temperatures experiences a slower decline compared to a fast decrease in band-type mobility as a result of increased phonon scattering with temperature. As can be seen in Fig. 4, with an increase in temperature (for a relatively weak electron-phonon interaction), the hopping mobility tends toward band mobility and they eventually intersect. Although the results for all interaction strengths are presented in Fig. 4, one should bear in mind that only the results for weaker interaction (say, $\lambda \leq 0.500$) should be considered for the analysis of the crossover from band transport to hopping.

Previous analysis gives us an overall expectation for the validity range of relevant transport regimes throughout the parameter space. Namely, at extremely low temperatures and strong electron-phonon interaction, the polaron band transport regime is prevailing. In contrast, when the temperature is high and there is a strong electron-phonon interaction, hopping transport is the dominant mechanism. For weak electron-phonon interactions, conventional band transport is generally the dominant transport mechanism, except possibly at very high temperatures. To put these expectations on a

solid ground, it is essential to compare our findings, derived from equations presented in Sec. II C, with numerically exact results obtained without approximations and assumptions of the transport regime.

III. RESULTS

To reliably identify the transport regimes throughout the parameter space of the Holstein model, we compare numerically exact results for the imaginary-time current-current correlation function obtained using path-integral quantum Monte Carlo with approximate results obtained under the assumption of each of the transport regimes. We performed QMC calculations throughout the parameter space $0.1 \leq T/J \leq 10.0$, $0.01 \leq \lambda \leq 2.0$ for three values of the phonon angular frequency $\omega_0 = J/3$, $\omega_0 = J$, and $\omega_0 = 3J$. While it would be very desirable to have the comparison at the level of the real-time correlation functions or the dc mobility, it is currently not possible to obtain numerically exact results for such a broad range of model parameters. For a limited set of model parameters where numerically exact results for the dc mobility are available, we make such a comparison. Namely, we compare the dc mobility for the three transport regimes with the numerically exact results obtained using the hierarchical equations of motion (HEOM) method in Ref. [54] and with our previous results obtained from real- and imaginary-time QMC in Ref. [59].

A. Comparison of imaginary-time current-current correlation functions

For the comparison of the imaginary-time current-current correlation function with the correlation functions in the band transport and in the hopping regime, we define a numerical criterion that describes how much imaginary-time correlation functions differ from each other. The numerical value that describes how much the function $C_{jj}^{(a)}(t)$ deviates from the numerically exact function $C_{jj}^{\text{QMC}}(t)$ is given by the formula

$$\mathcal{D}_{C_{jj}} = \frac{\int dt |C_{jj}^{\text{QMC}}(t) - C_{jj}^{(a)}(t)|}{\left| \int dt C_{jj}^{\text{QMC}}(t) \right|}, \quad (37)$$

where we have taken C_{jj}^{QMC} to be our reference value. We consider that the two functions are in good agreement if $\mathcal{D}_{C_{jj}} < 0.2$.

In the case of the polaron band transport regime, we choose a different criterion based on the following physical arguments. In the polaron band transport regime, all physically relevant processes happen in a narrow range of energies whose width is given by the renormalized bandwidth $4\tilde{J}$. In the derivations of polaron band transport equations in Sec. II C 3, this range of energies was effectively selected by choosing only the $\theta_{XYZ}^{(0)}$ term in relevant equations. On the other hand, an exact current-current correlation function also contains the information about the processes of multiphonon emission/absorption that happen at energies equal to multiples of the phonon energy. Therefore, one cannot expect an agreement between the numerically exact current-current correlation function C_{jj}^{QMC} and the one obtained under the

assumption of polaron band transport $C_{jj}^{(p)}$, even when the system is in the polaron band transport regime. On the other hand, as discussed in Refs. [74,75], the C_{jj} at imaginary-time $t = -i\frac{\beta}{2}$ contains only the information about the conductivity at low frequencies, which is exactly the frequency range relevant for polaron band transport. Consequently, to identify if the system is in the polaron band transport regime, we evaluate the quantity

$$\mathcal{D}_{C_{jj}} = \frac{|C_{jj}^{\text{QMC}}(t = -i\frac{\beta}{2}) - C_{jj}^{(p)}(t = -i\frac{\beta}{2})|}{|C_{jj}^{\text{QMC}}(t = -i\frac{\beta}{2})|}. \quad (38)$$

When the system is in the polaron band transport regime, the $\theta_{XYZ}^{(0)}$ term dominates over the $\theta_{XYZ}^{(1)}$ term in equations in Sec. II C 3 and therefore $\mathcal{D}_{C_{jj}}$ from Eq. (38) satisfies $\mathcal{D}_{C_{jj}} < 0.5$. Hence, we consider that the system is in the polaron band transport regime if $\mathcal{D}_{C_{jj}} < 0.5$, with $\mathcal{D}_{C_{jj}}$ given in Eq. (38).

We further note that the formulas for imaginary-time C_{jj} in the polaron band transport and in the conventional band transport regime converge to the same value when one sets the electron-phonon interaction to be small. Namely, for a small interaction, $Y_{k_1 k_2}$ in Eq. (28) reduces to $Y_{k_1 k_2} = 4J^2 \delta_{k_1 k_2} \sin^2 k_1$ (because in this limit $\tilde{J} = J$ and $\theta_{XYZ} = 1$) and $C_{jj}(z)$ from Eq. (36) then reduces to

$$C_{jj}(z) = 4J^2 \frac{\sum_k e^{-\beta \varepsilon_k} \sin^2 k}{\sum_k e^{-\beta \varepsilon_k}}. \quad (39)$$

The same result is obtained from Eq. (19) by exploiting that for small interaction $\langle a_k^\dagger(t) a_k \rangle = e^{-(\beta - i t) \varepsilon_k}$, $\langle a_k(t) a_k^\dagger \rangle = e^{-i \varepsilon_k t}$. Hence, the polaron band transport formula contains the band transport formula as its special case. For this reason, whenever our criterion for $\mathcal{D}_{C_{jj}}$ suggests that both polaron band transport and conventional band transport are possible, we assign the conventional band transport regime for these values of parameters.

The results for the quantity $\mathcal{D}_{C_{jj}}$ for all three regimes are presented in Fig. 5. As previously stated, for both hopping and band transport, we have set the threshold for tolerance between functions at a maximum of 20%. To demonstrate what this means, we show an example of current-current correlation functions for parameter values ($\omega_0 = J/3$, $\lambda = 0.500$) in Fig. 6. As can be seen in Fig. 6, there is an obvious matching of the QMC data with the function obtained for hopping transport at a temperature $T/J = 10.0$, which is also visible in Fig. 5 where the numerical value $\mathcal{D}_{C_{jj}}$ is less than 0.2 in the case of hopping transport. On the other hand, neither band transport nor hopping results match the QMC data at a temperature $T/J = 0.1$, as can be seen from Fig. 6. This is also evident in Fig. 5(a), where the numerical value $\mathcal{D}_{C_{jj}}$ is greater than 0.2 for both band and hopping transport. This value is lower in the case of band transport; nevertheless, it remains approximately 0.5, which is considerably higher than our set threshold of 0.2.

Several points are missing in Fig. 5 for the following reasons. It is very challenging to perform QMC calculations at high interaction strengths and low temperatures, as discussed in Sec. II B. Therefore, we could not obtain the data at the lowest temperatures and the strongest interactions for phonon frequencies $\omega_0 = J$ and $\omega_0 = 3J$. It is well known in the

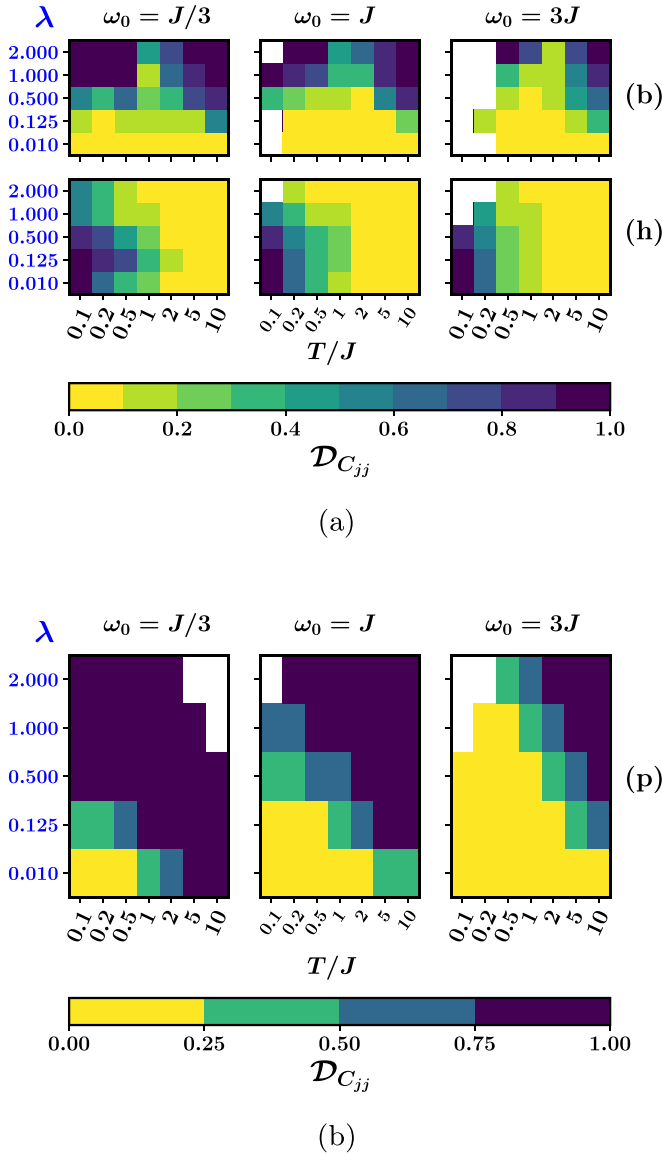


FIG. 5. The relative difference $\mathcal{D}_{C_{jj}}$ of the approximate and QMC imaginary-time current-current correlation functions for different values of the temperature T , the interaction strength λ , and the phonon angular frequency ω_0 . The results are presented for three phonon frequency values across the three respective columns. Each row represents the difference for the specified transport regime. In (a), the results for band transport (“b”) and hopping transport (“h”) are presented, while in (b), the result for polaron band transport (“p”) is presented.

literature that it is challenging to obtain current-current correlation functions at low temperatures and strong interactions, as evidenced, for example, by the fact that numerically exact dc mobilities can be obtained in practice only at temperatures $T \gtrsim 1$ and interactions $\lambda \lesssim 1$ [54,59]. In the case of band transport calculations, the spectral function becomes very narrow at the lowest temperatures, which poses a challenge for the calculation. This prevented us from obtaining converged results for band transport at the lowest temperatures for phonon frequencies $\omega_0 = J$ and $\omega_0 = 3J$. A similar issue was observed in calculations for weak coupling in Ref. [72].

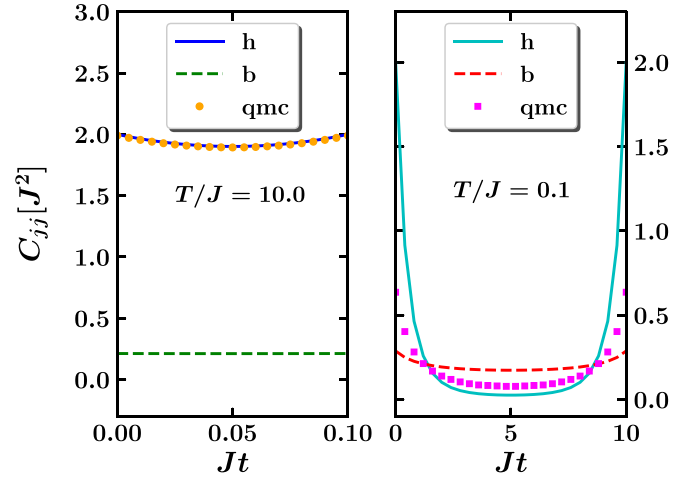


FIG. 6. Current-current correlation functions in imaginary time at temperatures (a) $T/J = 10.0$ and (b) $T/J = 0.1$ for the parameters $\omega_0 = J/3$ and $\lambda = 0.500$. Correlation functions obtained using Eq. (11) for hopping transport are presented in full lines and labeled “h,” while the functions calculated using formulas from Sec. II C 2 for band transport are presented as dashed lines and labeled “b.” QMC results are represented with points.

Lastly, numerical issues in the calculation of Bessel functions arise in calculations that assume the polaron band transport regime for highest temperatures and strongest interactions when $\omega_0 = J/3$ (where it is actually expected that this regime does not take place).

Figure 5 can be, to a significant extent, used to identify the relevant transport regimes throughout the parameter space. However, for certain parameters, we see from the figure that more than one regime is possible, in principle. In such cases, to distinguish which regime is in place, we complement our analysis with dc mobilities and real-time current-current correlation functions when these results are available.

B. Comparison of mobilities

In this section, we compare dc mobilities obtained using the expressions for hopping given by Eq. (15), polaron band transport given by Eq. (35), and conventional band transport given by Eq. (20) with numerically exact mobilities that are obtained using HEOM and path-integral QMC techniques.

Figure 7 shows the mobility calculated for different temperatures and coupling strengths for a phonon energy $\omega_0 = J$. This value of phonon frequency was chosen because of the availability of the most comprehensive and reliable HEOM (Ref. [54]) and QMC (Ref. [59]) results for this chosen set of parameters. The lines show results obtained with expressions from Sec. II C, whereas the points depict the numerical results obtained using HEOM and QMC techniques. As depicted in Fig. 7, there is a noticeable agreement between the numerical data and the results obtained with formulas for certain transport regimes. Specifically, our band transport expression defined by Eq. (20) holds true for the minimal interaction ($\lambda = 0.010$) in Fig. 7 and remains reasonably accurate for the next stronger interaction ($\lambda = 0.125$). Furthermore, in case of stronger interactions ($\lambda \geq 0.500$), the numerical data align

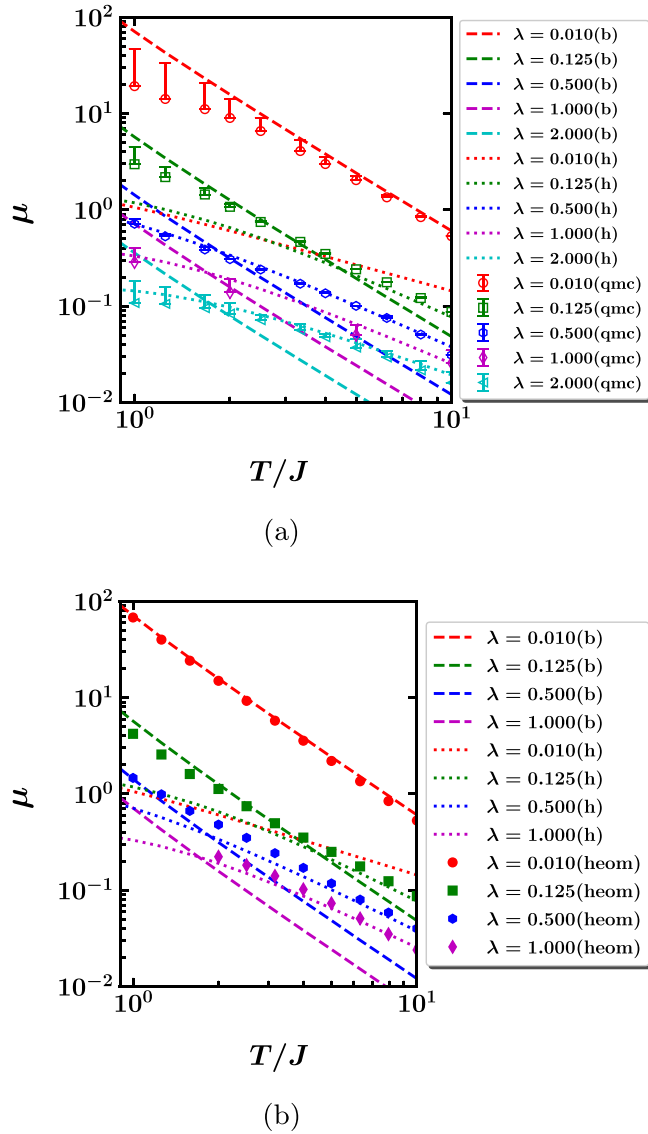


FIG. 7. Temperature dependence of mobility obtained using formulas for hopping (labeled as “h”) and band transport (labeled as “b”) compared with (a) numerically exact QMC data from Ref. [59] and (b) HEOM data from Ref. [54]. Numerical data are presented as points. The upward error bars in QMC data were estimated as described in Ref. [59]. The results are shown for $\omega_0 = J$.

well with the hopping mobility given in Eq. (15). The result in Fig. 7 clearly indicates that for the weakest interaction and high temperatures, the band transport is the correct regime. This is clear from the numerical data in Fig. 7, which are in perfect alignment with the band mobility and, within the temperature range displayed, the band and hopping mobilities do not intersect. Meanwhile, we cannot make such a clear distinction between hopping and band transport regimes based on the results in Fig. 5(a). The challenges associated with numerically exact calculations at extremely low temperatures prevent us from depicting the crossover from polaron band transport to hopping transport in Fig. 7. However, this crossover can be seen in Fig. 8, for the phonon angular frequency of $\omega_0 = 3J$. It is possible to observe this crossover for this value of ω_0

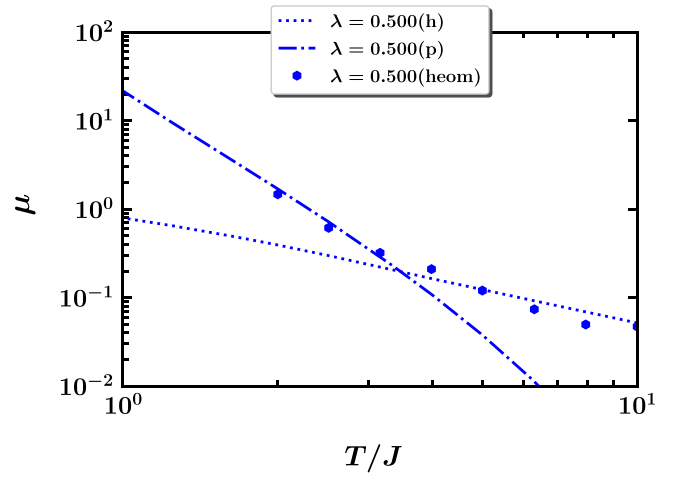


FIG. 8. Temperature dependence of mobility obtained using formulas for hopping (labeled as “h”) and polaron band transport (labeled as “p”) compared with exact mobility obtained using the HEOM method in Ref. [54] (labeled as “heom”). The results are shown for $\omega_0 = 3J$ and $\lambda = 0.500$.

since it takes place at higher temperature, as could have been expected based on the results of Fig. 3(c). This result aligns with the result shown in Fig. 5(b), where it indicates the dominance of the polaron band transport regime up to temperature $T/J = 2.0$ and, based on Fig. 8, the crossover takes place between temperatures $T/J = 2.0$ and $T/J = 3.0$.

C. Transport regime diagram for the one-dimensional Holstein model

The final transport regime diagram based on all the previous results is presented in Fig. 9. In what follows, we explain in detail how this diagram was constructed in the case when the phonon energy ω_0 equals J , while we provide a similar explanation for other values of ω_0 in Secs. S3 and S4 in the Supplemental Material [68]. It is evident from Fig. 5 that the band transport regime prevails in the areas characterized by the two weakest interactions and low temperatures. With an increase in temperature, Fig. 5 indicates that both band and hopping transport mechanisms could be possible. To clarify which transport regime is dominant at high temperatures, we turn our attention to Fig. 7. The figure clearly shows that across the entire temperature range for the weakest interaction, the band transport regime prevails since numerically exact HEOM results fully agree with the band transport results, while the curves for band and hopping mobility do not intersect. For the second interaction strength, $\lambda = 0.125$, it remains difficult to differentiate between band and hopping mobility, as evident in Fig. 7 where both expressions for dc mobility give a result similar to the numerically exact result. Similarly, Fig. 10 shows that distinguishing the real-time correlation functions for the band and hopping regimes is equally challenging in this range of parameters. For these reasons, we depict this range of parameters as an intermediate range at the crossover between band and hopping transport. We eventually assign the result at the highest temperature to the hopping regime since the imaginary-time result for the band regime

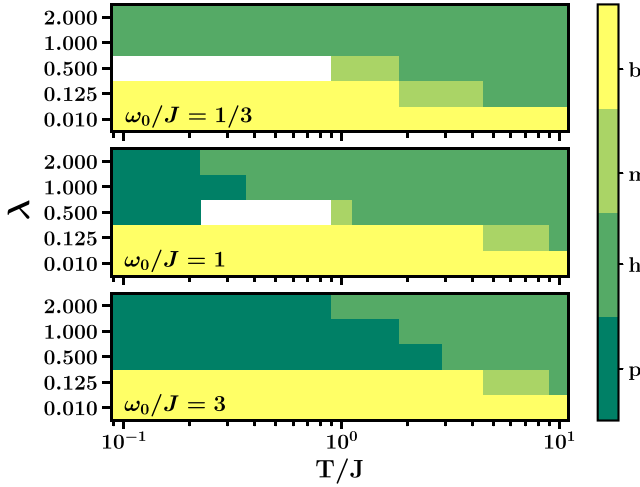


FIG. 9. Transport regime diagram for the Holstein model. The results are shown for three values of phonon angular frequency ω_0/J for the same values of the interaction strength λ and the temperature T/J . Three distinct transport regimes are labeled as “b” for conventional band transport, “h” for hopping transport, and “p” for polaron band transport. The label “m” stands for the intermediate regime between the band and hopping transport. The unlabeled white areas correspond to areas in parameter space where none of the three transport regimes can be applied based on our results.

starts to deviate from the numerically exact result, as seen in Fig. 5. For the interaction strength $\lambda = 0.500$, by looking at Fig. 5, it is evident that hopping transport dominates at temperatures above $T/J = 2.0$. At lowest temperatures (say $T/J = 0.2$ and lower), one sees from Fig. 5 that the system is in the polaron band transport regime. For the intermediate range of temperatures between these extremes, Fig. 5 suggests that the system could be in the band transport regime. Figure 11 shows that in this range of temperatures, real-time

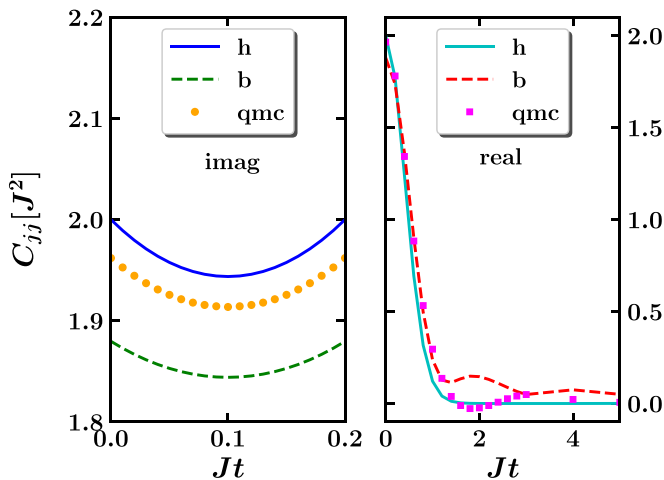


FIG. 10. Imaginary- and real-time current-current correlation functions for $\omega_0 = J$, $\lambda = 0.125$, $T/J = 5.000$. Lines labeled with “h” correspond to functions obtained with Eq. (11) for hopping transport, lines labeled “b” correspond to functions obtained with expression for band transport, and QMC results are represented with points.

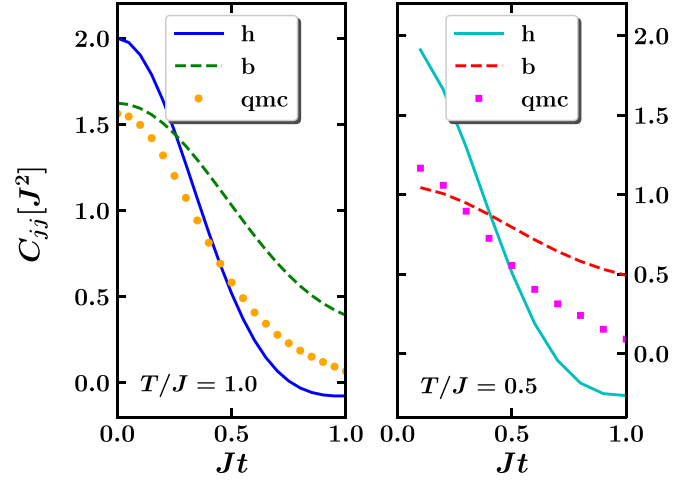


FIG. 11. Real-time current-current correlation functions for $\omega_0 = J$, $\lambda = 0.500$, and the temperatures $T/J = 1.000$ and $T/J = 0.500$. Lines labeled with “h” correspond to functions obtained for hopping transport, lines labeled “b” correspond to functions obtained with expression for band transport, and QMC results are represented with points.

correlation functions obtained under the assumption of band transport are in better agreement with the QMC results than the ones obtained under the assumption of hopping. Nevertheless, there is a noticeable discrepancy of band transport correlation functions and QMC results for temperature $T/J = 0.5$. For these reasons, we do not assign a single regime for these parameters and denote that this is an intermediate range of parameters where none of the mentioned regimes apply. In Fig. 9, this ambiguity is represented by a white area. On the other hand, for a temperature of $T/J = 1.0$, we classify it as an intermediate band transport hopping regime, which is depicted by label “m” in Fig. 9. This classification is due to the QMC correlation function results being more closely aligned with both the hopping and band transport correlation functions. When the interaction strength is set to $\lambda = 1.000$ and the temperature is $T/J = 0.5$ or higher, Fig. 5 clearly indicates that hopping is the appropriate transport regime. The crossover point for mobility curves of hopping and polaron band transport (see Fig. 3) lies between temperatures $T/J = 0.2$ and $T/J = 0.3$. Therefore, we conclude that for temperatures below $T/J = 0.3$, the polaron band transport regime is in place. For an interaction strength of $\lambda = 2.000$ and temperatures less than $T/J = 0.2$, we perform the same assignment for the same reason. Based on previous analysis that combines results obtained with formulas from Sec. II C and numerically exact HEOM and QMC data for imaginary- and real-time current-current correlation functions and dc mobilities, we construct the transport regime diagram in parameter space defined with interaction strength λ and temperature T/J for phonon frequency $\omega_0 = J$ depicted in Fig. 9. In the same manner, we construct the diagrams for phonon frequencies $\omega_0 = J/3$ and $\omega_0 = 3J$ with details given in Secs. S3 and S4 in the Supplemental Material [68].

Next, we discuss other works in the literature where transport regime diagrams of models with electron-phonon interaction were investigated. In Ref. [45], the authors con-

sidered a mixed Holstein-Peierls model relevant for organic semiconductors. They examined possible regimes when the strength of electronic coupling and nonlocal electron-phonon coupling is changed. Due to a different type of Hamiltonian, and the fact that temperature was not varied in Ref. [45], these results are not directly comparable to ours. Nevertheless, the band transport regime (termed bandlike in Ref. [45]) and the hopping regime (termed phonon assisted in Ref. [45]) were clearly identified, respectively, for large and small electronic coupling. In Ref. [46], the authors considered a two-site Holstein model and the crossover between different charge transfer regimes as they evolve over time for different adiabaticity ratios. They identify the regimes they term polaronic, soft-gating, and transient localization. Our study offers complementary insight in comparison to these two works. We study the effects of temperature over a wide range, which were not addressed in Ref. [45]. While we directly address the long-range charge transport quantified by the dc mobilities, Ref. [46] was focused on short-range charge transfer.

IV. CONCLUSION

In conclusion, we studied in detail the transport regimes of a benchmark model with the electron-phonon interaction—the one-dimensional Holstein model. We computed the imaginary-time current-current correlation functions using a numerically exact path-integral-based QMC method for a broad range of model parameters that practically covers the whole parameter space. These were compared with the corresponding functions under the assumptions of the band transport regime, the hopping regime, and the polaron band transport regime. The comparisons were used to establish the range of validity of each of these transport regimes. The analysis was complemented with a comparison of real-time current-current correlation functions and dc mobilities for parameters where these data are available.

In accordance with expectations, the results indicate that band transport occurs at low interaction strengths and low temperatures, hopping transport is present for strong interaction and high temperatures, while polaron band transport takes place for strong interaction and low temperatures. More

importantly, the results indicate that practically the whole parameter space is covered by the three mentioned transport regimes, except for some parts of the space at intermediate electron-phonon coupling strengths. This conclusion is something that one may not have expected. Such a conclusion might have important consequences for modeling charge transport in real materials. It is practically impossible to model charge transport in real materials for arbitrary electron-phonon coupling strength without the assumption of a particular transport regime. On the other hand, as mentioned in Sec. I, it is possible to perform simulations of mobility in real materials assuming the band transport or the hopping transport regime. If our conclusions regarding the applicability of one of the three transport regimes throughout most of the parameter space could be extended from the benchmark Holstein model to models of realistic materials, this would open the way to perform reliable studies of real materials by performing calculations under the assumptions of one of the transport regimes.

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DATA AVAILABILITY

The data that support the findings of this article are openly available [76].

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Supplemental Material: Identification of the transport regimes of the one-dimensional Holstein model

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S1. SELF-ENERGIES IN BAND TRANSPORT REGIME

In this section of Supplemental Material, we give expressions for self-energies in the band transport regime. The self-energy in the Migdal approximation is given as

$$\Sigma_k(\omega) = \frac{G^2}{N} \sum_q \left[(n_{\text{ph}} + 1) G_{k-q}^{(0)}(\omega - \omega_0) + n_{\text{ph}} G_{k-q}^{(0)}(\omega + \omega_0) \right], \quad (\text{S1})$$

where $G_k^{(0)}(\omega) = (\omega - \varepsilon_k + i0^+)^{-1}$ is the Green's function in the absence of interaction. By performing the summation in Eq. (S1) one obtains

$$\Sigma(\omega) = G^2(n_{\text{ph}} + 1)S(\omega - \omega_0) + G^2n_{\text{ph}}S(\omega + \omega_0), \quad (\text{S2})$$

where

$$S(\omega) = \begin{cases} \frac{\text{sgn}(\omega)}{\sqrt{\omega^2 - 4J^2}}, & \text{if } |\frac{\omega}{2J}| > 1 \\ \frac{-i}{\sqrt{4J^2 - \omega^2}}, & \text{if } |\frac{\omega}{2J}| < 1 \end{cases}. \quad (\text{S3})$$

The retarded Green's function is then simply found from the Dyson equation:

$$G_k^R(\omega) = \frac{1}{\omega - \varepsilon_k - \Sigma_k(\omega)}, \quad (\text{S4})$$

the spectral function is given as

$$A_k(\omega) = -\frac{1}{\pi} \text{Im} G_k^R(\omega) \quad (\text{S5})$$

and the averages that enter the expression for current-current correlation function read

$$\langle a_k^\dagger(t) a_k \rangle = \int_{-\infty}^{\infty} d\omega e^{i\omega t} A_k(\omega) e^{-\beta\omega}, \quad (\text{S6})$$

$$\langle a_k(t) a_k^\dagger \rangle = \int_{-\infty}^{\infty} d\omega e^{-i\omega t} A_k(\omega). \quad (\text{S7})$$

In the case when $\frac{\omega_0}{2J} > 1$, we also include the most relevant diagram including two phonon processes. The relevant self-energy is

$$\text{Im} \Sigma(k, \omega) = \frac{g^4}{N^2} n_{\text{ph}}(n_{\text{ph}} + 1) \sum_{k_1} \text{Im} \frac{1}{\omega - \varepsilon_{k_1} + i0^+} \sum_{k_2} \left[\frac{1}{(\varepsilon_{k_2} + \omega_0 - \omega)^2} + \frac{1}{(\varepsilon_{k_2} - \omega_0 - \omega)^2} \right] \quad (\text{S8})$$

We then obtain

$$\text{Im} \Sigma(\omega) = g^4 n_{\text{ph}}(n_{\text{ph}} + 1) S_1 [S_2(\omega - \omega_0) + S_2(\omega + \omega_0)] \quad (\text{S9})$$

where

$$S_1 = \frac{1}{N} \sum_k \text{Im} \frac{1}{\omega - \varepsilon_k + i0^+}, \quad (\text{S10})$$

$$S_2(x) = \frac{1}{N} \sum_k \frac{1}{(\varepsilon_k - x)^2}. \quad (\text{S11})$$

The last two sums can be evaluated analytically and read

$$S_1(\omega) = \begin{cases} \frac{-1}{\sqrt{4J^2 - \omega^2}}, & \text{if } |\frac{\omega}{2J}| < 1 \\ 0, & \text{otherwise} \end{cases} \quad (\text{S12})$$

$$S_2(x) = \begin{cases} -\frac{z_1 + z_2}{J^2(z_1 - z_2)^3}, & \text{if } \frac{x}{2J} > 1 \\ \frac{z_1 + z_2}{J^2(z_1 - z_2)^3}, & \text{if } \frac{x}{2J} < -1 \end{cases} \quad (\text{S13})$$

where

$$z_{1,2} = \frac{1}{2} \left(-\frac{x}{J} \pm \sqrt{\frac{x^2}{J^2} - 4} \right). \quad (\text{S14})$$

S2. SELF-ENERGY IN POLARON BAND TRANSPORT REGIME

The first nonzero term in the retarded self-energy arising from interaction $\tilde{V}$ reads [special case of equations in Ref. [72] when Lang Firsov unitary transformation is used rather than the more general transformation]

$$\Sigma_k(\omega) = \frac{i}{2\pi} \frac{1}{N^2} \sum_q \int d\omega_1 G_{k-q}^R(\omega - \omega_1) D_{k-q,k,q}^>(\omega_1) \quad (\text{S15})$$

with

$$D_{k-q,k,q}^>(\omega) = -i \sum_{R_1 S_1 R_2 S_2} b_{R_1 S_1 R_2 S_2 k q} \int dt e^{i\omega t} \left\{ e^{a_{R_1 R_2 S_1 S_2} [(n_{\text{ph}}+1)e^{-i\omega_0 t} + n_{\text{ph}} e^{i\omega_0 t}] - 1} \right\}, \quad (\text{S16})$$

$$b_{R_1 S_1 R_2 S_2 k q} = J^2 \delta_{R_1, S_1 \pm 1} \delta_{R_2, S_2 \pm 1} e^{i[kR_1 - (k-q)S_1]} e^{i[(k-q)R_2 - kS_2]}. \quad (\text{S17})$$

Making use of

$$e^{a \cos \theta} = \sum_{l=-\infty}^{\infty} I_l(a) e^{il\theta} \quad (\text{S18})$$

and

$$(n_{\text{ph}} + 1)e^{-i\omega_0 t} + n_{\text{ph}} e^{i\omega_0 t} = 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)} \cos \left[\omega_0 \left(t + i\frac{\beta}{2} \right) \right] \quad (\text{S19})$$

we arrive at

$$\begin{aligned} \Sigma_k(\omega) = & \frac{1}{N^2} \sum_q \sum_{R_1 S_1 R_2 S_2} b_{R_1 S_1 R_2 S_2 k q} \\ & \left\{ \left[I_0 \left(a_{R_1 R_2 S_1 S_2} \cdot 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)} \right) - 1 \right] G_{k-q}^R(\omega) + \right. \\ & \left. \sum_{l \neq 0} I_l \left(a_{R_1 R_2 S_1 S_2} \cdot 2\sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)} \right) e^{-\frac{1}{2}l\omega_0\beta} G_{k-q}^R(\omega + l\omega_0) \right\}. \end{aligned} \quad (\text{S20})$$

In the polaron band transport regime, the Green's function has maxima at energies around $\tilde{\varepsilon}_k$. The dispersion $\tilde{\varepsilon}_k$ is rather flat. Relevant arguments of self-energies are then those at around $\tilde{\varepsilon}_k$. On the other hand, the term $G_{k-q}^R(\omega + l\omega_0)$ has maxima at energies around $\tilde{\varepsilon}_k + l\omega_0$. Hence, it is only the $l = 0$ term in previous equation that determines the values of the self-energy at its relevant arguments. By including this term only and introducing the definition

$$S_0(R, \omega, J) = \frac{1}{N} \sum_k \frac{e^{ikR}}{\omega + 2J \cos k + i0^+} \quad (\text{S21})$$

we arrive at

$$\begin{aligned} \Sigma_k(\omega) = & \sum_{R_1=0, S_1, R_2, S_2} J^2 \delta_{R_1, S_1 \pm 1} \delta_{R_2, S_2 \pm 1} e^{-2\left(\frac{q}{\omega_0}\right)^2 (2n_{\text{ph}}+1)} e^{ik(R_1 - S_2)} \\ & S_0(R_2 - S_1, \omega, \tilde{J}) \left[I_0 \left(2a_{R_1 R_2 S_1 S_2} \sqrt{n_{\text{ph}}(n_{\text{ph}} + 1)} \right) - 1 \right]. \end{aligned} \quad (\text{S22})$$

The sum $S_0(R, \omega, J)$ can be evaluated analytically. To write down this expression we introduce the notation $\tau = \frac{\omega}{2J}$, $z_1 = -\tau + \sqrt{\tau^2 - 1}$, $z_2 = -\tau - \sqrt{\tau^2 - 1}$ and obtain

$$S_0(R, \omega, J) = \begin{cases} \frac{z_1^R}{J(z_1 - z_2)} & \tau > -1 \text{ and } R \geq 0 \\ \frac{z_2^R}{J(z_2 - z_1)} & \tau < -1 \text{ and } R \geq 0 \\ \frac{z_1^R}{J(z_1 - z_2)} + \frac{1}{Jz_1 z_2} & \tau > -1 \text{ and } R = -1 \\ \frac{z_2^R}{J(z_2 - z_1)} + \frac{1}{Jz_1 z_2} & \tau < -1 \text{ and } R = -1 \\ \frac{z_1^R}{J(z_1 - z_2)} + \frac{1}{Jz_1 z_2} \left(\frac{1}{z_1} + \frac{1}{z_2} \right) & \tau > -1 \text{ and } R = -2 \\ \frac{z_2^R}{J(z_2 - z_1)} + \frac{1}{Jz_1 z_2} \left(\frac{1}{z_1} + \frac{1}{z_2} \right) & \tau < -1 \text{ and } R = -2 \end{cases} \quad (\text{S23})$$

S3. TRANSPORT REGIME CROSSOVERS IN FIG. 10 FOR $\omega_0 = J/3$.

In this section, we explore further into the regime crossovers depicted in Fig. 10 for $\omega_0 = J/3$.

For the weakest interaction strength where $\lambda = 0.010$, the results from Fig. 5 imply that both band transport and hopping could be possible in principle at higher temperatures. A closer examination of Fig. S1 shows that the numerically exact data align closely with the band mobility, while the hopping mobility remains below the band mobility curve (see also Fig. 4). This observation confirms that we are indeed dealing with band transport regime across the entire temperature range.

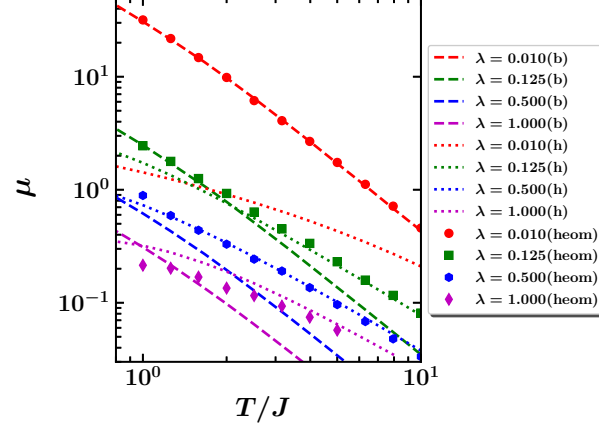


FIG. S1: Mobility obtained from formulas for band transport (labeled "b") and hopping transport (labeled "h") compared with numerically exact HEOM data. Numerical data are presented as points. Results are shown for $\omega_0 = J/3$.

At an interaction strength of $\lambda = 0.125$ and temperatures lower than $T/J = 1.0$, Fig. 5 suggest that band transport is the relevant regime. However, for temperatures of $T/J = 2.0$ and 5.0 , it is unclear whether the correct transport regime is band transport or hopping. Fig. S1 shows mobility data where, in the temperature interval from $T/J = 1.0$ to $T/J = 10.0$, we are unable to distinguish between band and hopping mechanisms. It is also difficult to distinguish between the two mechanism from real-time correlation functions, as illustrated in Fig. S2 where the QMC data show proximity to both the hopping and band transport correlation function. For this reason, we label this region as an intermediate region between band and hopping transport. Using the results from Fig. 5 we assign the hopping mechanism at largest temperature for this interaction strength.

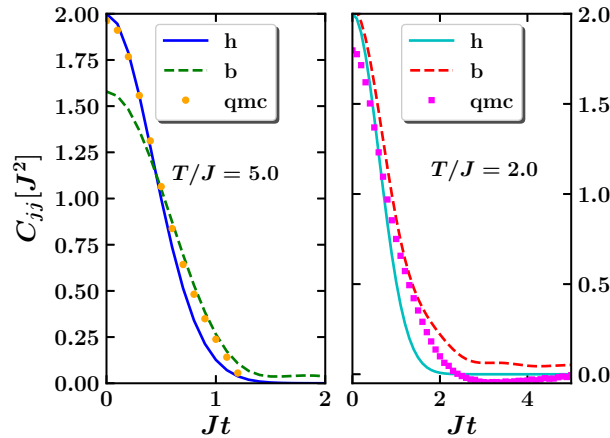


FIG. S2: Real time current-current correlation functions for $\omega_0 = J/3$, $\lambda = 0.125$, and the temperatures $T/J = 2.000$ and $T/J = 5.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

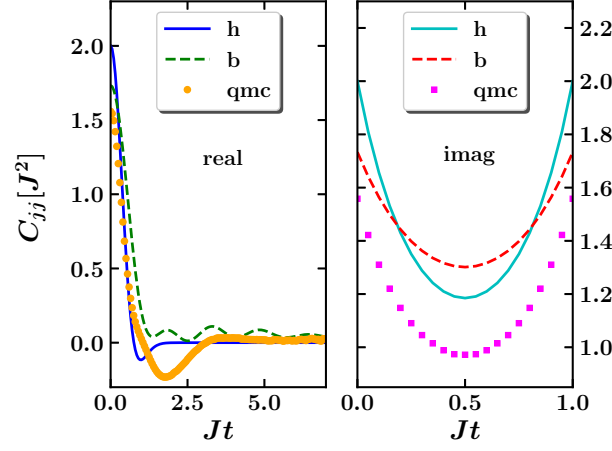


FIG. S3: Real and imaginary time current-current correlation functions for $\omega_0 = J/3$, $\lambda = 0.500$, and $T/J = 1.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

At an interaction strength $\lambda = 0.500$ from Fig. 5 we can deduce that for temperatures greater than $T/J = 1.0$ hopping is the dominant mechanism. Fig. S1 illustrates that the numerically exact results align closely with the curve representing hopping mobility across the temperature range of $T/J = 1.0$ to $T/J = 10.0$. However, upon analyzing the correlation functions, it remains ambiguous whether the appropriate mechanism at $T/J = 1.0$ is hopping or band transport, as shown in Fig. S3. At temperatures below $T/J = 1.0$, the results from Fig. 5 suggest that none of the three regimes is in place. This is depicted in Fig. 10 as a white region.

For an interaction strength of $\lambda = 1.000$, as indicated by Figures 5 and S1 it is clear that within the temperature interval from $T/J = 1.0$ to $T/J = 10.0$, the hopping mechanism is in place. The correlation function data from Fig. 5 suggest that imaginary-time correlation functions correspond most closely to the hopping functions for temperatures below $T/J = 1.0$. Fig. 3 suggests that the polaron band transport regime can occur only at temperatures below $T/J = 0.1$. Consequently, we infer that within the temperature range of $T/J = 0.1$ to $T/J = 10.0$, hopping transport is dominant for this set of parameters. The same can be concluded for an interaction strength of $\lambda = 2.000$.

S4. TRANSPORT REGIME CROSSEOVERS IN FIG. 10 FOR $\omega_0 = 3J$.

Next, we examine Fig. 5 in the case $\omega_0 = 3J$ and $\lambda = 0.010$. It is evident that both band transport and hopping meet the criterion within the temperature range of $T/J = 1.0$ to $T/J = 10.0$. We distinguish between the two through the analysis of real-time current-current correlation functions (see Fig. S4) which imply that within the temperature range $T/J = 0.5$ to $T/J = 10.0$, the proper regime is conventional band transport. This conclusion can be safely extended to lower temperatures based on physical arguments that lowering the temperature for weak interaction reduces the electron-phonon scattering and therefore preserves the band transport mechanism.

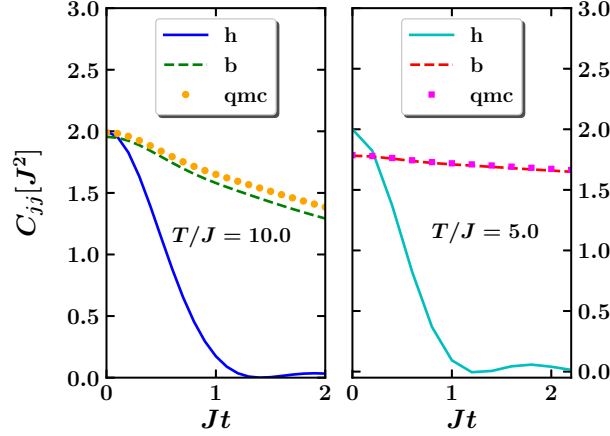


FIG. S4: Real time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.010$, and the temperatures $T/J = 2.000$ and $T/J = 10.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

When considering the subsequent interaction strength of $\lambda = 0.125$, as shown in Fig. 5, the imaginary-time criterion is met for band transport between $T/J = 0.2$ and $T/J = 5$, and for hopping in the temperature range from $T/J = 1$ to $T/J = 10$. The limited mobility data (refer to Fig. S5) indicate that for temperatures lower than $T/J = 5$, the appropriate regime is band transport. This can also be seen from the real time correlation function shown in Fig. S6 for $T/J = 2$, which demonstrates how real-time QMC data more closely follow the curve for band transport. We continue to explore the real-time current-current correlation functions. As illustrated in Fig. S7 at a temperature of $T/J = 5$, the system is in the intermediate regime between band transport and hopping. However, at the higher temperature of $T/J = 10.0$, it is evident from Fig. S7 and 5 that hopping is the relevant regime.

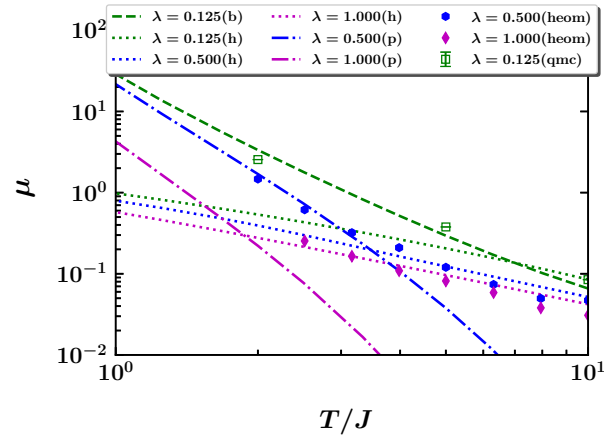


FIG. S5: Mobility obtained from formulas for band transport (labeled "b"), hopping transport (labeled "h") and polaron band transport (labeled "p") compared with numerically exact heom data. Numerical data are presented as points. Results are shown for $\omega_0 = 3J$.

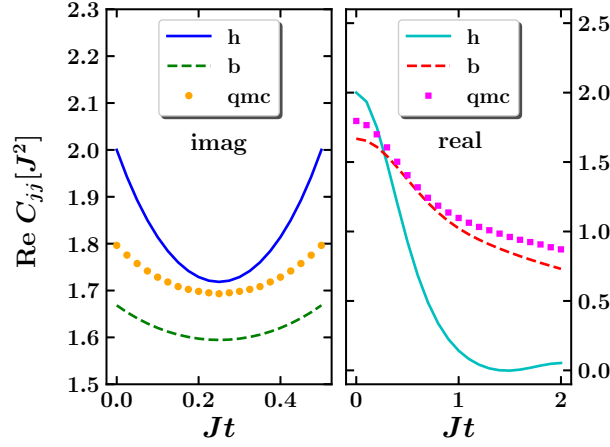


FIG. S6: Imaginary- and real-time current-current correlation functions shown for specified parameters $\omega_0 = 3J$, $\lambda = 0.125$, $T/J = 2.000$. Lines labeled with "h" correspond to functions obtained with Eq. [11](#) for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

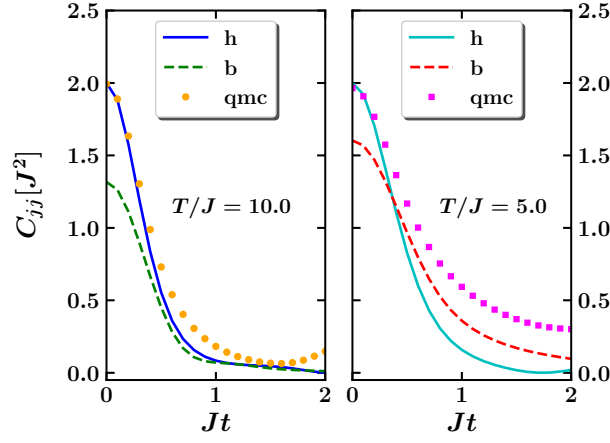


FIG. S7: Real-time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.125$, and the temperatures $T/J = 5.000$ and $T/J = 10.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

Next, we examine the results for the interaction strength $\lambda = 0.500$. We can regard this interaction as moderately strong, suggesting the potential for polaron band transport to occur. As illustrated in Fig. [5](#) the conditions for polaron band transport are met within the temperature range of $T/J = 0.1$ to $T/J = 2$. Furthermore, band transport might be possible from $T/J = 0.5$ to $T/J = 2$, and hopping could occur from $T/J = 1$ to $T/J = 10$. We exclude the likelihood of conventional band transport at any temperature upon analyzing real time current-current correlation functions. Fig. [S8](#) supports this argument as it shows that numerically exact QMC data are equally far from the band transport and hopping regime. Fortunately, there is a limited set of numerically exact HEOM data in this range of parameters, which effectively demonstrate the shift from polaron band transport to hopping, as depicted in Fig. [S5](#) for mobility. This transition aligns with the point where the mobility curves for polaron band transport and hopping intersect.

For the two strongest interactions, $\lambda = 1.000$ and $\lambda = 2.000$, we lack some numerical data at the lowest temperatures. Therefore, our deductions regarding transport regime transitions will be based on previous conclusions. From Fig. [5](#) for an interaction strength of $\lambda = 1.000$, the criterion for polaron band transport is met within the temperature range of $T/J = 0.1$ to $T/J = 1.0$, whereas hopping might be possible from $T/J = 0.5$ up to $T/J = 10$. We dismiss the possibility of conventional band transport for the same reasons as for the previous interaction strength. As depicted in figures [3](#) and [S5](#), the curves for polaron band mobility and hopping mobility intersect around the temperature

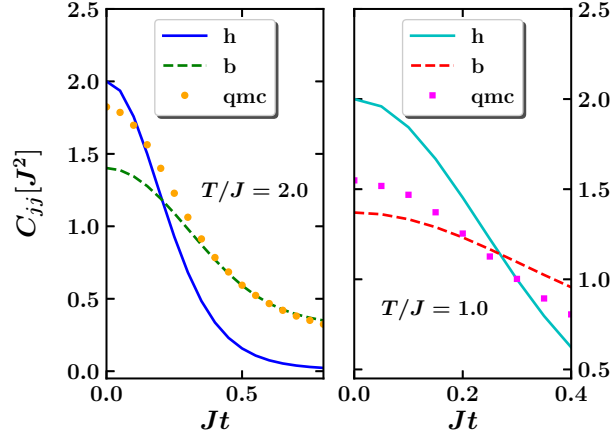


FIG. S8: Real-time current-current correlation functions for $\omega_0 = 3J$, $\lambda = 0.500$, and the temperatures $T/J = 1.000$ and $T/J = 2.000$. Lines labeled with "h" correspond to functions obtained for hopping transport, lines labeled "b" correspond to functions obtained with expression for band transport and QMC results are represented with points.

$T/J = 2$. Thus, we deduce that the appropriate transport mechanism is polaron band transport up to $T/J = 2$, while for temperatures exceeding $T/J = 2$, the hopping mechanism prevails. In a similar manner, when the interaction is $\lambda = 2.000$, the point where the two corresponding curves intersect occurs at approximately $T/J = 1.0$. Thus, we conclude that the appropriate transport mechanism is polaron band transport for temperatures lower than $T/J = 1$, transitioning to hopping transport for temperatures beginning at $T/J = 1.0$ and above.

S5. DETAILS ON QMC CALCULATIONS OF IMAGINARY-TIME CURRENT-CURRENT CORRELATION FUNCTIONS.

In this section we present details on the choice of simulation parameters in QMC calculations of imaginary-time current-current correlation functions in present work. In Fig. S9 the effect of limited system size (number of sites N_d) on result of QMC calculations is shown for the interaction strength $\lambda = 0.010$, the temperature $T/J = 0.1$ and the phonon frequency $\omega_0 = 3J$. We can see that the number of sites needed to reach the thermodynamic limit is 25 in that case.

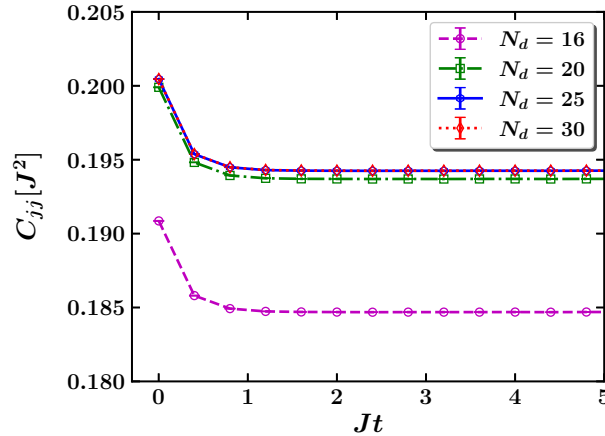


FIG. S9: Imaginary-time current-current correlation function calculated with different number of sites N_d . The results are shown for the interaction strength $\lambda = 0.010$, the temperature $T/J = 0.1$ and the phonon frequency $\omega_0 = 3J$.

In Fig. S10 a table is provided with the values used in our calculations for the time discretization step $J\Delta t$, the number of MC samples N_s and the system size (the number of sites) N_d for each specified temperature T/J ,

interaction strength λ and phonon frequency ω_0 . The table also contains information whether the calculations were completed using the momentum (m) or the electron position (p) basis.

		$\omega_0=J/3$				$\omega_0=J$				$\omega_0=3J$			
λ	T/J	J Δt	N_s	N_d	basis	J Δt	N_s	N_d	basis	J Δt	N_s	N_d	basis
0.010	0.1	0.1	1.0E+06	15	m	0.1	1.0E+06	20	m	0.1	1.0E+05	30	m
	0.2	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m	0.1	1.0E+05	25	m
	0.5	0.08	1.0E+05	10	m	0.08	1.0E+05	15	m	0.08	1.0E+05	20	m
	1.0	0.05	1.0E+02	80	m	0.05	1.0E+03	60	m	0.04	1.0E+05	15	m
	2.0	0.025	1.0E+02	80	m	0.025	1.0E+03	60	m	0.025	1.0E+05	15	m
	5.0	0.01	1.0E+02	80	m	0.01	1.0E+03	60	m	0.01	1.0E+05	15	m
	10.0	0.005	1.0E+02	80	m	0.005	1.0E+03	60	m	0.005	1.0E+05	15	m
0.125	0.1	0.1	1.0E+06	15	m	0.1	1.0E+06	20	m	0.1	1.0E+05	20	m
	0.2	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m
	0.5	0.08	1.0E+05	10	m	0.08	1.0E+05	15	m	0.08	1.0E+05	15	m
	1.0	0.05	1.0E+03	10	m	0.05	1.0E+03	20	m	0.04	1.0E+05	15	m
	2.0	0.025	1.0E+03	10	m	0.025	1.0E+03	20	m	0.025	1.0E+03	10	m
	5.0	0.01	1.0E+03	10	m	0.01	1.0E+03	20	m	0.01	1.0E+03	10	m
	10.0	0.005	1.0E+03	10	m	0.005	1.0E+03	20	m	0.005	1.0E+03	10	m
0.500	0.1	0.1	1.0E+06	15	m	0.1	1.0E+06	20	m	0.1	1.0E+05	20	m
	0.2	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m
	0.5	0.08	1.0E+05	10	m	0.08	1.0E+05	15	m	0.08	1.0E+05	15	m
	1.0	0.05	1.0E+04	7	m	0.05	1.0E+04	10	m	0.05	1.0E+05	15	m
	2.0	0.025	1.0E+04	7	m	0.025	1.0E+04	10	m	0.025	1.0E+03	10	m
	5.0	0.01	1.0E+04	7	m	0.01	1.0E+04	10	m	0.01	1.0E+03	10	m
	10.0	0.005	1.0E+04	7	m	0.005	1.0E+04	10	m	0.005	1.0E+03	10	m
1.000	0.1	0.1	1.0E+06	15	m	0.1	1.0E+06	20	m	0.1	1.0E+06	25	m
	0.2	0.1	1.0E+05	15	m	0.1	1.0E+05	15	m	0.1	1.0E+06	20	m
	0.5	0.08	1.0E+05	10	m	0.08	1.0E+05	15	m	0.08	1.0E+05	15	m
	1.0	0.02	1.0E+05	7	p	0.02	1.0E+05	7	m	0.02	1.0E+05	15	m
	2.0	0.01	1.0E+05	7	p	0.01	1.0E+05	7	m	0.01	1.0E+05	7	p
	5.0	0.004	1.0E+05	7	p	0.004	1.0E+05	7	m	0.004	1.0E+05	7	p
	10.0	0.002	1.0E+05	7	p	0.002	1.0E+05	7	m	0.002	1.0E+05	7	p
2.000	0.1	0.1	1.0E+06	15	m	-	-	-	-	-	-	-	-
	0.2	0.1	1.0E+05	15	m	0.1	1.0E+06	20	m	-	-	-	-
	0.5	0.08	1.0E+05	10	m	0.08	1.0E+05	15	m	0.08	1.0E+05	15	m
	1.0	0.02	1.0E+05	7	p	0.02	1.0E+05	10	p	0.02	1.0E+05	7	p
	2.0	0.01	1.0E+05	7	p	0.01	1.0E+05	10	p	0.01	1.0E+05	7	p
	5.0	0.004	1.0E+05	7	p	0.004	1.0E+05	10	p	0.004	1.0E+05	7	p
	10.0	0.002	1.0E+05	7	p	0.002	1.0E+05	10	p	0.002	1.0E+05	7	p

J Δt - time discretization step N_d - number of sites (system size) N_s - number of MC samples
m - electron momentum states p - electron position states

FIG. S10: The table with values of simulation parameters used in QMC calculations of imaginary-time current-current correlation functions.

Method for obtaining polaron mobility using real and imaginary time path-integral quantum Monte Carlo

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We developed a path-integral quantum Monte Carlo-based methodology for calculation of polaron mobility in systems with electron-phonon interaction. Within the method, the current-current correlation function in both the imaginary and real time is calculated in a numerically exact way. The choice of basis for representation of the path integral enabled us to reduce the sign problem and perform real-time calculations for longer times. The DC polaron mobility was extracted by performing analytic continuation that makes use of both the real and imaginary-time data. The method was applied to the Holstein polaron model in one dimension. We obtained reliable results for the temperature dependence of the Holstein polaron mobility for interactions ranging from weak to strong and temperatures that are not too low.

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I. INTRODUCTION

The electron-phonon interaction is the dominant mechanism that determines the mobility of electrons or holes in semiconducting materials at room temperature [1,2]. There is a significant group of materials where it is sufficiently strong so that its perturbative treatment is not appropriate [3–5]. For such materials, one cannot apply the standard Bloch-Boltzmann theory [6] of electronic transport, nor the methods for mobility calculation based upon this theory that were developed in the last decade [6–12]. It is therefore of great interest to develop methods for the calculation of mobility of an electron interacting with phonons which would be applicable regardless of the strength of interaction.

The simplest model describing an electron interacting with phonons is the Holstein polaron model [13] where each lattice site accommodates one phonon and the electron interacts only locally with the phonon from the same site. This model served in the last several decades as a playground where the methods aiming at describing the systems with electron-phonon interaction were tested. Ground-state and equilibrium finite-temperature properties of the Holstein model are now well understood [14–25] and significant progress was recently made in evaluation of the electronic spectral function [26–30].

Nevertheless, it remains rather challenging to calculate the dynamical response of the system, which is encoded in real-time correlation functions in a numerically exact way; that is, without resorting to additional approximations in addition to those contained in the Hamiltonian. To calculate the DC polaron mobility one needs to calculate the current-current correlation function up to very long times. One of the methods to achieve this is to represent the current-current correlation function using Feynman's path integral formalism [31,32] and perform the calculation of the integral using a Monte Carlo

method [24,33]. The main challenge comes from the fact that the sum obtained this way contains terms of varying phases. The Monte Carlo procedure for calculation of such a sum is then not guaranteed to converge. This issue constitutes the so-called dynamical sign problem [34–39]. The dynamical sign problem is not pronounced at small real times but it becomes severe at long times, making the calculations impossible. Other numerically exact methods that can in principle be used to evaluate real-time correlation functions include the finite-temperature Lanczos method [26], the time-dependent density-matrix renormalization-group method [28,40], and the hierarchical equations of motion method [29,41], whereas each of these exhibits its own challenges. There is also a significant number of approaches where the polaron transport in the Holstein and related models is evaluated by resorting to different types of approximations [42–57].

An approach that is often used to avoid the dynamical sign problem is to calculate the correlation functions in imaginary time or frequency and then perform the analytic continuation to real time or frequency [38,58–68]. However, such analytic continuation is an ill-posed problem and it gives reliable results in some cases only.

In this work, we perform path-integral quantum Monte Carlo calculations of the current-current correlation function in real and imaginary times for the Holstein model and we extract the DC mobility from these calculations. There are two main advances that we introduce in this work. First, we make use of the fact that the dynamical sign problem is basis-dependent [69]. By choosing the appropriate basis for the formulation of the path-integral quantum Monte Carlo method, we reduce the dynamical sign problem and enable the calculation of the current-current correlation function for longer times. Second, we perform the calculation of the current-current correlation function for both imaginary and (short) real times. To obtain the DC mobility, we then perform the analytic continuation, starting from both real and imaginary-time data. It is somewhat surprising that this simple

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idea has rarely been exploited in the literature—we are in fact aware of only one work that exploited this idea [38]. The implementation of these ideas enabled us to obtain the mobility of the Holstein polaron for a broad range of parameters ranging from weak to strong interactions at temperatures that are not too low.

The paper is organized as follows: We briefly introduce the model Hamiltonian in Sec. II A. In Sec. II B we derive the path-integral representation of the current-current correlation function in two different bases and describe the numerical Monte Carlo algorithms for its calculation. In Sec. II C we present the procedure for analytic continuation that makes use of both real and imaginary-time data to obtain the DC mobility. An example of the application of the analytic continuation procedure is presented in Sec. III A. Convergence tests of our numerical calculations are presented in Sec. III B. The final results for the temperature dependence of the Holstein polaron mobility are presented in Sec. III C, while concluding remarks are given in Sec. IV.

II. MODEL AND METHODS

A. Model Hamiltonian

We consider the system described by the Holstein model on an one-dimensional lattice. Each lattice site accommodates one phonon mode. An electron interacts locally with the phonon. The system is described by the Hamiltonian

$$H = \sum_n \left[-J(c_n^\dagger c_{n+1} + c_{n+1}^\dagger c_n) + \left(\frac{P_n^2}{2M} + \frac{1}{2} M \omega_n^2 X_n^2 \right) + \sqrt{2M\omega_n} G c_n^\dagger c_n X_n \right]. \quad (1)$$

The first term describes electron hopping on the lattice, where J is the electronic transfer integral between neighboring sites. The operators $c_n^\dagger$ (c_n) stand for electron creation (annihilation) operators at the n th site. The second term describes the phonon of angular frequency ω_n , while X_n (P_n) are phonon position (momentum) operators at site n . Dispersionless phonons with $\omega_n = \omega_0$ are assumed. The mass M of the oscillator can be set to $M = 1$ without loss of generality. The last term describes the electron-phonon interactions of strength G . We assume periodic boundary conditions. In the derivations throughout the paper we use the system of units where the lattice constant a and the universal physical constants $\hbar$, e_0 , and k_B are equal to 1. We denote the inverse temperature as $\beta = 1/T$.

The Hamiltonian given in Eq. (1) can be written in the following equivalent form, which is more suitable for the derivation of the path integral representation:

$$H = H_0 + H_1 + H_2, \quad (2a)$$

$$H_0 = \sum_n \frac{P_n^2}{2M}, \quad (2b)$$

$$H_1 = \sum_n \left(\sqrt{2M\omega_n} G c_n^\dagger c_n X_n + \frac{1}{2} M \omega_n^2 X_n^2 \right), \quad (2c)$$

$$H_2 = -J \sum_n (c_n^\dagger c_{n+1} + c_{n+1}^\dagger c_n). \quad (2d)$$

The Hamiltonian H_2 is diagonal in electron momentum representation $H_2 = \sum_k \varepsilon(k) c_k^\dagger c_k$, where the bare electronic dispersion is given as $\varepsilon(k) = -2J \cos(k)$ and $c_k^\dagger$ (c_k) are the electron creation (annihilation) operators in the momentum representation.

B. Path-integral representation of time-correlation functions

The central quantity that we consider in this work is the DC mobility which is given by the Kubo formula [42,70]

$$\mu = \frac{\beta}{2} \int_{-\infty}^{\infty} dt \langle j(t) j(0) \rangle, \quad (3)$$

where the current-density operator j for the Holstein model reads

$$j = iJ \sum_n (c_n^\dagger c_{n+1} - c_{n+1}^\dagger c_n). \quad (4)$$

To evaluate the mobility, one needs to calculate the time-correlation function (TCF) $\langle j(t) j(0) \rangle$, where the brackets denote the average in the canonical ensemble.

The TCF that corresponds to arbitrary operators A and B is by definition

$$\langle A(t) B \rangle = Z^{-1} \text{Tr}[e^{-\beta H} e^{itH} A e^{-itH} B], \quad (5)$$

where $Z = \text{Tr}(e^{-\beta H})$ is the partition function and the time dependence of the operators is given as $A(t) = e^{itH} A e^{-itH}$ with $A(0) \equiv A$. To derive a discretized path-integral representation of the TCF given in Eq. (5), we make use of the Trotter-Suzuki expansion in accordance with the ideas from Refs. [24,33]:

$$\begin{aligned} \langle A(t) B \rangle &= \lim_{m, Q \rightarrow \infty} Z_m^{-1} \text{Tr}[(e^{-\tau H_0} e^{-\tau H_1} e^{-\tau H_2})^m (e^{i\Delta t H_0} \\ &\times e^{i\Delta t H_1} e^{i\Delta t H_2})^Q A (e^{-i\Delta t H_0} e^{-i\Delta t H_1} e^{-i\Delta t H_2})^Q B], \end{aligned} \quad (6)$$

The imaginary-time interval of length β was divided into m subintervals of length $\tau = \beta/m$, while the real-time interval of length t was divided into Q subintervals of length $\Delta t = t/Q$. The term Z_m is the partition function that is obtained when the imaginary-time interval is divided into m subintervals.

The trace in Eq. (6) can be evaluated by representing it in any complete basis that spans the Hilbert space of the system. The result of the full summation does not depend on the choice of basis. However, the result and the statistical error of Monte Carlo summation, which includes only a sample of the terms in the sum, depends on the choice of basis. This fact can be exploited to choose a basis where the statistical error of Monte Carlo summation is smaller. In practice, this enables us to perform calculations for longer real times than if only one choice of basis were used. We made use of two possibilities for the choice of basis: (i) the basis obtained as a direct product of electronic momentum states and phonon coordinate eigenstates; (ii) the basis obtained as a direct product of the electronic states with an electron localized at a certain site and phonon coordinate eigenstates. The choice (i) is more natural for weak electron-phonon interaction, while we make use of (ii) for stronger electron-phonon interaction and for

imaginary-time calculations. It should be noted that the choice (ii) allows us to analytically integrate out phononic degrees of freedom.

We consider both the real time correlation function as defined in Eq. (5) and the imaginary time correlation function (obtained by the Wick rotation $t \rightarrow -it$, $t \in \mathbb{R}$) given by

$$\langle A(-it)B \rangle = Z^{-1} \text{Tr}[e^{-\beta H} e^{tH} A e^{-tH} B]. \quad (7)$$

We denote the trace appearing in Eq. (6) as $C_{A,B}^{m,Q}$ and in the next two sections we derive its path-integral representation in the two bases mentioned. In the derivation, we assume that the operators A and B depend on electronic degrees of freedom only, which is the case for the current-density operator for the Holstein model given in Eq. (4).

1. Path integral with momentum representation for electrons

We expand the trace from Eq. (6) in the basis containing the states that are a direct product of electron momentum states and phonon coordinate eigenstates:

$$|k; \{X\}\rangle = |k\rangle |X_0\rangle |X_1\rangle \cdots |X_{N-1}\rangle, \quad (8)$$

where N is the number of sites in the lattice. The electron momentum k takes one of N discrete values from the first Brillouin zone, while phonon coordinates are real numbers. To obtain a discretized representation of the path integral, we evaluate the trace $C_{A,B}^{m,Q}$ in the basis given in Eq. (8). The details of the derivation are given in Sec. I of the Supplemental Material [71]. We arrive at the expression:

$$\begin{aligned} C_{A,B}^{m,Q} = & C'_1 \int \prod_{j=0}^{m-1} \text{D}X^j \prod_{p=m}^{m+Q} \text{D}X^p \prod_{r=m+Q+1}^{m+2Q+1} \text{D}X^r e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^r]} \\ & \times \sum_{\{k\}} \prod_{j=0}^{m-1} f_{k_{j+1}, k_j}(-\tau; X^{j+1}) \prod_{p=m}^{m+Q-1} f_{k_{p+1}, k_p}(i\Delta t; X^{p+1}) \prod_{r=m+Q+1}^{m+2Q} f_{k_{r+1}, k_r}(-i\Delta t; X^{r+1}) \\ & \times \langle X^{m+Q}; k_{m+Q} | A | k_{m+Q+1}; X^{m+Q+1} \rangle \langle X^{m+2Q+1}; k_{m+2Q+1} | B | k_0; X^0 \rangle, \end{aligned} \quad (9)$$

where C'_1 is an irrelevant constant and $\sum_{\{k\}}$ denotes the summation over all k variables. Phonon actions are given by the expressions

$$\begin{aligned} S_1[\tau; X^j] = & \tau \sum_{j=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} \right], \\ S_2[-i\Delta t; X^p] = & -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} \right], \\ S_3[i\Delta t; X^r] = & i\Delta t \sum_{r=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{r+1})^2 + \frac{M}{2} \frac{(X_n^{r+1} - X_n^r)^2}{(i\Delta t)^2} \right]. \end{aligned} \quad (10)$$

The functions $f_{k_i, k_j}(z; x^i)$ are fermion propagators between states k_i and k_j in complex time z and are defined as

$$f_{k_i, k_j}(z; X^i) = e^{z\varepsilon(k_i)} \frac{1}{N} \sum_n e^{in \cdot (k_i - k_j) + zG\sqrt{2M\omega_n} X_n^i}. \quad (11)$$

The estimator for the TCF is given by the expression

$$\langle A(t)B \rangle^{m,Q} = \frac{C_{A,B}^{m,Q}}{C_{1,1}^{m,Q}}, \quad (12)$$

where the term $C_{1,1}^{m,Q}$ denotes $C_{A,B}^{m,Q}$ for $A = B = 1$. The estimator from Eq. (12) closely represents the true correlation function $\langle A(t)B \rangle$ when m and Q are large enough.

We rewrite the trace $C_{A,B}^{m,Q}$ in matrix notation by introducing the vector variable for phonon coordinates:

$$\mathbf{Y} = (Y^0, Y^1, \dots, Y^{m+2Q-1})^T = (X^1, X^2, \dots, X^{m+Q-1}, X^{m+Q+1}, \dots, X^{m+2Q-1}, X^{m+2Q}, X^0)^T, \quad (13)$$

so the trace takes form

$$C_{A,B}^{m,Q} = C'_1 \int \text{D}\mathbf{Y} e^{-\frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y}} F(\mathbf{Y}). \quad (14)$$

The matrix $\mathcal{D}$ is a symmetric matrix that represents the quadratic form in the phonon actions. The function $F(\mathbf{Y})$ is a trace of the product of matrices

$$\begin{aligned} F(\mathbf{Y}) = & \text{Tr}[\mathcal{F}(-\tau; Y^0) \mathcal{F}(-\tau; Y^1) \cdots \mathcal{F}(-\tau; Y^{m-1}) \\ & \times \mathcal{F}(i\Delta t; Y^m) \cdots \mathcal{F}(i\Delta t; Y^{m+Q-2}) \\ & \times \mathcal{G}(i\Delta t; Y^{m+Q-1}) \mathcal{F}(-i\Delta t; Y^{m+Q}) \cdots \\ & \times \mathcal{F}(-i\Delta t; Y^{m+2Q-2}) \mathcal{G}(-i\Delta t; Y^{m+2Q-1})] \end{aligned} \quad (15)$$

When $A = B = j$ the elements of the matrices are given as

$$\begin{aligned} [\mathcal{F}(z; Y^k)]_{l,j} &= e^{z\varepsilon(2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} + zG\sqrt{2\omega_0} Y_n^k}, \\ [\mathcal{G}(i\Delta t; Y^{m+Q-1})]_{l,j} &= -2J \sin(2\pi j/N) e^{i\Delta t \varepsilon(2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} + i\Delta t G\sqrt{2\omega_0} Y_n^{m+Q-1}}, \\ [\mathcal{G}(-i\Delta t; Y^{m+2Q-1})]_{l,j} &= -2J \sin(2\pi j/N) e^{-i\Delta t \varepsilon(2\pi j/N)} \frac{1}{N} \sum_{n=0}^{N-1} e^{-in \cdot (j-l) \frac{2\pi}{N} - i\Delta t G\sqrt{2\omega_0} Y_n^{m+2Q-1}}, \end{aligned} \quad (16)$$

where z is complex time. When $A = B = 1$, the matrices $\mathcal{G}$ should be simply replaced by matrices $\mathcal{F}$.

We calculate the integrals that appear in $C_{A,B}^{m,Q}$ using a Monte Carlo technique by directly sampling from phonon action

$$S[\mathbf{Y}] = \frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y}. \quad (17)$$

Since $\mathcal{D}$ is a complex symmetric matrix, we can diagonalize the quadratic form $\mathbf{Y}^T \mathcal{D} \mathbf{Y}$ by eigen decomposition $\mathcal{D} = Q \Lambda Q^{-1}$, where Λ is a diagonal matrix and Q is an orthogonal matrix $Q^T = Q^{-1}$. The quadratic form then takes the form $\mathbf{Y}^T \mathcal{D} \mathbf{Y} = \mathbf{Z}^T \mathbf{Z}$. We can therefore directly sample the components Z_k from a Gaussian distribution and find the vectors $\mathbf{Y}$ by applying an inverse transformation $\mathbf{Y} = Q^T \Lambda^{-1/2} \mathbf{Z}$.

2. Path integral with position representation for electrons

In this case we make use of the basis consisting of states that are a direct product of electron position states and phonon coordinate eigenstates,

$$|r; \{X\}\rangle = |r\rangle |X_0\rangle |X_1\rangle \cdots |X_{N-1}\rangle, \quad (18)$$

The electron position takes the values $r = 0, \dots, N-1$. Following the same procedure as in Sec. II B 1, we arrive at a similar expression for the trace $C_{A,B}^{m,Q}$ in this basis, where the details of the derivation are given in Sec. II of the Supplemental Material [71]:

$$\begin{aligned} C_{A,B}^{m,Q} &= C'_2 \sum_{\{r\}} \langle r_{m+Q} | A | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | B | r_0 \rangle \\ &\times \prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \prod_{p=m}^{m+Q-1} I(-i\Delta t; r_{p+1} - r_p) \\ &\times \prod_{q=m+Q+1}^{m+2Q} I(i\Delta t; r_{q+1} - r_q) \\ &\times \int \prod_{j=0}^{m-1} DX^j \prod_{p=m}^{m+Q-1} DX^p \prod_{q=m+Q+1}^{m+2Q} DX^q \\ &\times e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^q]}, \end{aligned} \quad (19)$$

where C'_2 is an irrelevant constant, the symbol $\sum_{\{r\}}$ denotes the summation over all r variables and phonon actions are

given by the expressions

$$\begin{aligned} S_1[\tau; X^j] &= \tau \sum_{j=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 \right. \\ &\quad \left. + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} + G\sqrt{2M\omega_n} \delta_{n,r_j} X_n^{j+1} \right], \\ S_2[-i\Delta t; X^p] &= -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 \right. \\ &\quad \left. + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} + G\sqrt{2M\omega_n} \delta_{n,r_p} X_n^{p+1} \right], \\ S_3[i\Delta t; X^q] &= i\Delta t \sum_{q=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{q+1})^2 \right. \\ &\quad \left. + \frac{M}{2} \frac{(X_n^{q+1} - X_n^q)^2}{(i\Delta t)^2} + G\sqrt{2M\omega_n} \delta_{n,r_q} X_n^{q+1} \right]. \end{aligned} \quad (20)$$

The functions $I(z; r_{j+1} - r_j)$ represent Fourier-transformed electron propagators to coordinate space and they are defined as [24]

$$\begin{aligned} I(z; r_{j+1} - r_j) &= \frac{1}{N} \sum_{n=0}^{N-1} \cos\left(\frac{2\pi}{N} n(r_{j+1} - r_j)\right) \\ &\times \exp[2zJ \cos(2\pi n/N)]. \end{aligned} \quad (21)$$

The integral over phonon coordinates in Eq. (19) can be solved analytically. As in the previous section, we introduce the vector variable for phonon coordinates which leads to

$$\begin{aligned} f(\{r\}) &= \int \prod_{j=0}^{m-1} DX^j \prod_{p=m}^{m+Q-1} DX^p \prod_{q=m+Q+1}^{m+2Q} DX^q \\ &\times e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^q]} \\ &= \int D\mathbf{Y} e^{-S[\mathbf{Y}]}, \end{aligned} \quad (22)$$

where $\mathbf{Y}$ is given in Eq. (13) and the action is a quadratic form with an additional linear term

$$S[\mathbf{Y}] = \frac{1}{2} \mathbf{Y}^T \mathcal{D} \mathbf{Y} + \mathbf{Y}^T \cdot \mathbf{d}(\{r\}). \quad (23)$$

The matrix $\mathcal{D}$ is the same as in Sec. II B 1, while the vector $\mathbf{d}(\{r\})$ depends on the configuration of electron position states. After calculating the multidimensional Gaussian integral over phonon states we obtain the function $f(\{r\})$ that depends on electron position states

$$f(\{r\}) = C'_3 \exp\left(\frac{1}{2} \mathbf{d}(\{r\})^T \cdot \mathcal{D}^{-1} \cdot \mathbf{d}(\{r\})\right), \quad (24)$$

where C'_3 is an irrelevant constant that remains after Gaussian integration.

The trace $C_{A,B}^{m,Q}$ is in this case given as

$$C_{A,B}^{m,Q} = C'_2 C'_3 \sum_{\{r\}} w(\{r\}) F(\{r\}), \quad (25)$$

where we introduced the weight function $w(\{r\})$ and the function $F(\{r\})$ given by the expressions

$$w(\{r\}) = \prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \prod_{p=m}^{m+Q-1} |I(-i\Delta t; r_{p+1} - r_p)| \\ \times \prod_{q=m+Q+1}^{m+2Q} |I(i\Delta t; r_{q+1} - r_q)|, \quad (26)$$

$$F(\{r\}) = \langle r_{m+Q} | A | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | B | r_0 \rangle \\ \times \exp\left(\frac{1}{2} \mathbf{d}(\{r\})^T \cdot \mathcal{D}^{-1} \cdot \mathbf{d}(\{r\})\right) \\ \times \prod_{p=m}^{m+Q-1} e^{i\phi(-i\Delta t; r_{p+1} - r_p)} \prod_{q=m+Q+1}^{m+2Q} e^{i\phi(i\Delta t; r_{q+1} - r_q)}, \quad (27)$$

where $\phi(z; r_i - r_j) = \arg[I(z; r_i - r_j)]$.

To calculate the real-time correlation function we use the same estimator $\langle A(t)B \rangle^{m,Q}$ as in Eq. (12). The sum in Eq. (25) over electron position states will be calculated by using the Monte Carlo technique. After a simple change of variables r_j , the weight $w(\{r\})$ becomes a product of single-variable functions. These variables can then be sampled independently to obtain the configuration of electron positions $\{r\}$.

To obtain the path integral in imaginary time, we can simply make the substitution $t \rightarrow -it$ in expressions obtained in real time. The weight from Eq. (26) and the function from Eq. (27) are now completely real and are given by the expressions:

$$w(\{r\}) = \prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \prod_{p=m}^{m+Q-1} I(-\Delta t; r_{p+1} - r_p) \\ \times \prod_{q=m+Q+1}^{m+2Q} I(\Delta t; r_{q+1} - r_q), \quad (28)$$

$$F(\{r\}) = \langle r_{m+Q} | A | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | B | r_0 \rangle \\ \times \exp\left(\frac{1}{2} \mathbf{d}(\{r\})^T \cdot \mathcal{D}^{-1} \cdot \mathbf{d}(\{r\})\right). \quad (29)$$

C. Analytic continuation

The path-integral quantum Monte Carlo methodology described in Sec. II B gives us the current-current correlation function $\langle j(t_c)j(0) \rangle$ either at imaginary times ($t_c = -it$, $0 \leq$

$t \leq \beta$) or at short real times ($t_c = t$). On the other hand, the central quantity that we are interested in is the DC mobility $\mu = \mu(\omega = 0)$. The relation between $\langle j(t_c)j(0) \rangle$ and $\mu(\omega)$ reads

$$\langle j(t_c)j(0) \rangle = \int_{-\infty}^{\infty} d\omega \frac{1}{\pi} \frac{\omega e^{-i\omega t_c}}{1 - e^{-\beta\omega}} \text{Re}\mu(\omega). \quad (30)$$

This type of problem is in the quantum many body community typically addressed by calculating the correlation function [in our case $\langle j(t_c)j(0) \rangle$] at imaginary times where there is no sign problem and then performing analytic continuation to obtain $\text{Re}\mu(\omega)$. The methods that are typically used to perform analytic continuation include the maximum entropy method [38,58,59,63,65–67], the Padé approximation method [59–61], the singular-value decomposition method [59,63,64], etc.

However, one can also make use of the calculations for those real times where the sign problem is not pronounced and accurate values of the current-current correlation function can be obtained. Therefore, we perform analytic continuation by making use of both imaginary-time and real-time data obtained by path-integral Monte Carlo calculations of the current-current correlation function.

We make use of the singular-value decomposition method to perform analytic continuation. The discretized version of Eq. (30) reads

$$\mathbf{j} = \mathbf{K} \cdot \mathbf{m}, \quad (31)$$

where $\mathbf{K}$ is a known linear operator obtained from discretization of Eq. (30). The vector $\mathbf{j}$ contains the current-current correlation function for all (real or imaginary) times at which calculations were performed. The vector $\mathbf{m}$ is unknown and it contains the discrete representation of $\text{Re}\mu(\omega)$. All the elements of $\mathbf{j}$, $\mathbf{K}$, and $\mathbf{m}$ are real if we represent complex numbers as a column of two real numbers—their real and imaginary part. Any real matrix can be transformed to the form known as singular-value decomposition:

$$\mathbf{K} = \mathbf{U} \mathbf{S} \mathbf{V}^T, \quad (32)$$

where $\mathbf{U}$ and $\mathbf{V}$ are orthogonal matrices, while $\mathbf{S}$ is a diagonal matrix whose elements s_k are called the singular values. Within the singular-value decomposition method we find $\mathbf{m}$ as

$$\mathbf{m} = \sum_k \frac{\mathbf{U}_{\cdot,k}^T \cdot \mathbf{j}}{s_k} \mathbf{V}_{\cdot,k}, \quad (33)$$

where $\mathbf{U}_{\cdot,k}^T$ ($\mathbf{V}_{\cdot,k}$) is the k th column vector of matrix $\mathbf{U}^T$ ($\mathbf{V}$).

The challenge in obtaining $\mathbf{m}$ from Eq. (33) comes from the fact that there are many singular values that are close to zero. The presence of such values leads to large multiplication of any noise (stemming from Monte Carlo data or from finite numerical precision). Therefore, in practice one takes only a limited number of terms in Eq. (33) that correspond to largest values of s_k .

We note that analytic continuation that includes both real- and imaginary-time data is by no means limited to the singular-value decomposition method. It can be performed by appropriate modification of any other analytic continuation method. We nevertheless chose the singular-value decompo-

sition method because it most transparently demonstrates the challenges of analytic continuation procedure.

III. RESULTS

A. Examples of analytic continuation procedure

In this section, we present examples of the results obtained from our analytic continuation procedure. To assess the accuracy and limitations of the procedure, it is desirable to know the exact reference result for $\mu(\omega)$ that the procedure should ideally reconstruct. For this reason, here we do not apply the procedure to our Monte Carlo data. Instead, we make use of the frequency dependence of mobility obtained in Ref. [72] that we refer to as the reference dynamic mobility $\mu_{\text{ref}}(\omega)$. From the reference dynamic mobility, we construct the real- and imaginary-time current-current correlation functions using Eq. (30). Next, we add noise to these data whose strength is comparable to the noise present in our Monte Carlo data. Finally, we apply the analytic continuation procedure described in Sec. II C to such data and obtain $\text{Re}\mu_{\text{ac}}(\omega)$. By comparing $\text{Re}\mu_{\text{ac}}(\omega)$ and $\text{Re}\mu_{\text{ref}}(\omega)$ we can estimate the accuracy of the analytic continuation procedure. Since we are mostly interested in DC mobility we make the comparison in particular at $\omega = 0$. We use the relative error

$$\delta = \frac{\text{Re}\mu_{\text{ac}}(\omega = 0) - \text{Re}\mu_{\text{ref}}(\omega = 0)}{\text{Re}\mu_{\text{ref}}(\omega = 0)}$$

as an estimate of the error of analytic continuation procedure.

The results are presented for model parameters $\omega_0/J = 1$, $G/J = 1$ and $T/J = 1$ in Fig. 1(a). These results were obtained from imaginary-time data for times up to $0.6/J$ and real-time data for times up to $1/J$, while the results in Fig. 1(b) are obtained from same imaginary-time data with the addition of real-time data with ranges specified in the caption of the figure.

In Fig. 1(a) we demonstrate how the number of singular values (svs) taken in the sum given by Eq. (33) affects the outcome of analytic continuation. If we take too many svs terms (e.g., svs = 13), we include the term with rather small absolute value of s_k in Eq. (33). The noise in the data $\mathbf{j}$ in Eq. (33) is then strongly multiplied and we get too much noise in the $\text{Re}\mu_{\text{ac}}(\omega)$. On the other hand, if we take too few singular values (e.g., svs = 8, 9) we do not have enough information and $\text{Re}\mu_{\text{ac}}(\omega)$ does not resemble the reference $\text{Re}\mu_{\text{ref}}(\omega)$ at all. The best choice in practice is to take as many singular values as possible before $\text{Re}\mu_{\text{ac}}(\omega)$ becomes too noisy. For the specific case shown in Fig. 1(a) the best choice is the result obtained with 12 singular values. The number of singular values used in typical calculations in this work is reported in the table in Sec. III of the Supplemental Material [71].

In Fig. 1(b) we demonstrate the benefits of performing analytic continuation starting both from real- and imaginary-time data as opposed to using the imaginary-time data only. By adding more relevant data in real time, we get closer to the reference result in comparison with the case when we use imaginary-time data only. We can see that, by combining imaginary- and real-time data, we can get much closer to the reference value of mobility.

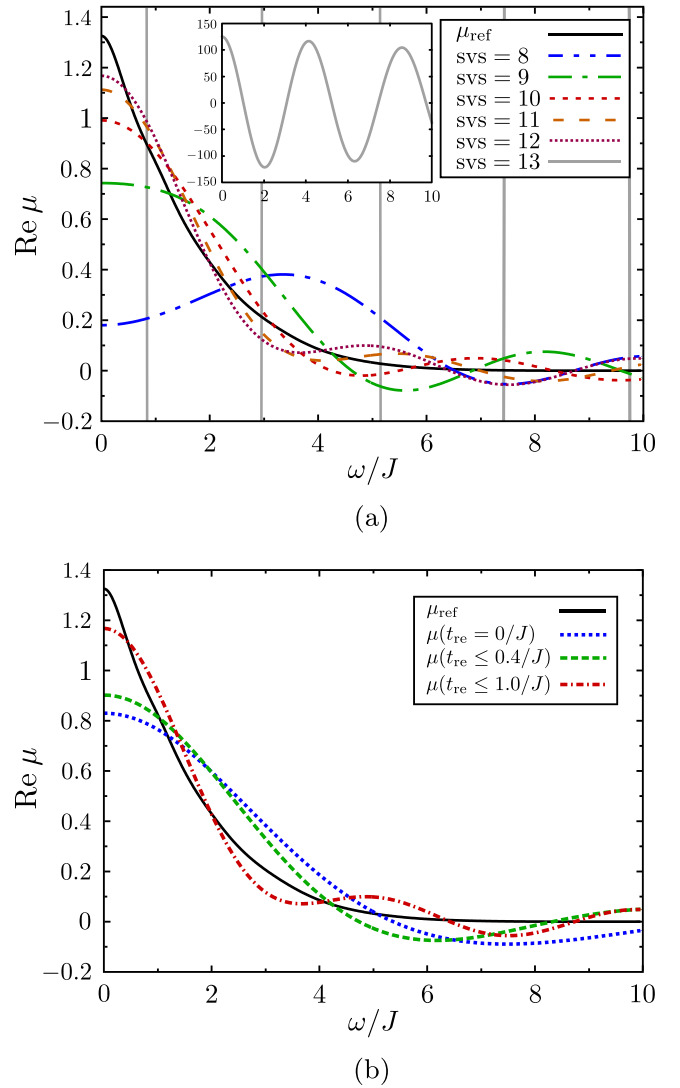


FIG. 1. Examples of the application of the analytic continuation procedure: (a) The reference result (labeled μ_{ref}) and the results obtained using different number of singular values (svs). The inset shows the result obtained using svs = 13 with a full range on the y axis; (b) The reference result (μ_{ref}) and the results obtained using imaginary-time data only [labeled $\mu(t_{\text{re}} = 0)$], using imaginary-time data and real-time data for real times up to $0.4/J$ [labeled $\mu(t_{\text{re}} \leq 0.4/J)$] and using imaginary-time data and real-time data for real times up to $1/J$ [labeled $\mu(t_{\text{re}} \leq 1.0/J)$]. The results are presented for model parameters $\omega_0/J = 1$, $G/J = 1$ and $T/J = 1$. The results are shown for $\omega \geq 0$ because the equality $\text{Re}\mu(\omega) = \text{Re}\mu(-\omega)$ holds.

B. Choice of simulation parameters

To make sure that the results of our quantum Monte Carlo calculations are reliable, we paid particular attention to set the appropriate values of all relevant simulation parameters. Relevant convergence tests were performed to choose these values. Since our goal is to get very precise data such that standard deviation is not greater than 1% of the result, we used 10^4 – 10^6 Monte Carlo samples in a single calculation and we repeat each calculation 100 times to achieve better statistics and to estimate the statistical error. The discretization time

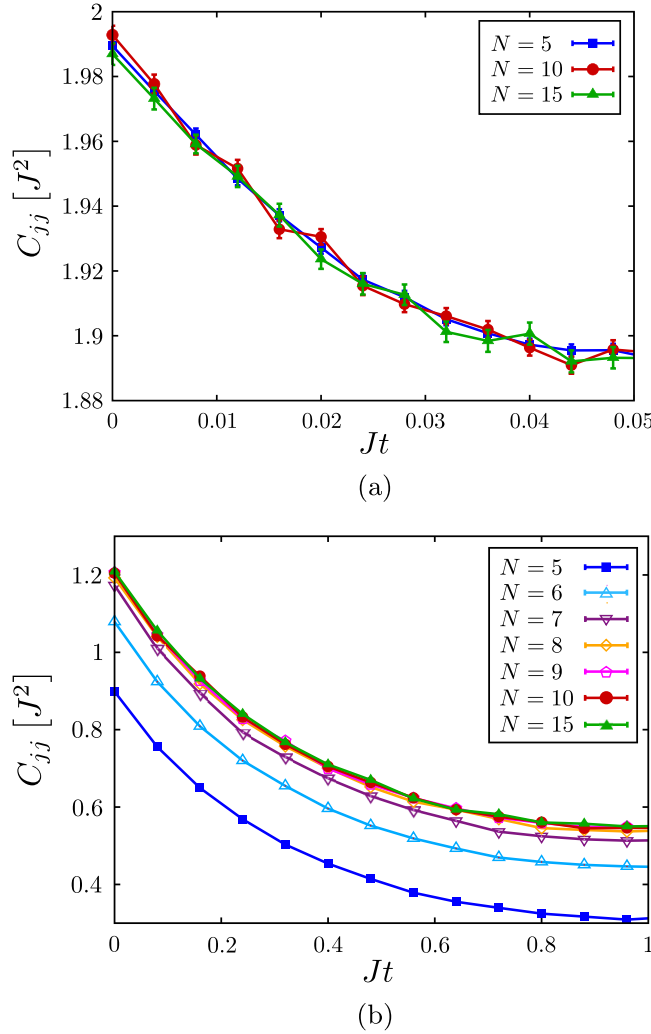


FIG. 2. The dependence of the imaginary-time current-current correlation function on the number of sites N for $\omega_0/J = 1$ and $G/J = 1$: (a) at a high temperature $T/J = 10$, (b) at a low temperature $T/J = 0.5$. The results are shown for imaginary times $0 \leq t \leq \beta/2$ only since the identity $C_{jj}(t) = C_{jj}(\beta - t)$ holds. The error bars in panel (a) of the figure denote the estimated standard deviation of the result, while the error is too small to be visible in panel (b) of the graph.

steps τ and Δt also have to be set to particular values. From appropriate convergence tests, we found that the values $\tau = \Delta t = \frac{0.1}{J}$ are small enough as taking smaller time steps does not make a significant change in the result. Time discretization steps and the number of Monte Carlo samples used in typical calculations in this work are given in the table in Sec. III of the Supplemental Material [71].

Another relevant parameter is the number N of sites that determines the system size. Our goal is to obtain the results representative of the thermodynamic limit $N \rightarrow \infty$. In practice, we thus choose N which is large enough so that further increase in the number of sites does not change the result. In Figs. 2(a) and 2(b) we present the imaginary-time current-current correlation function for $\omega_0/J = 1$ and $G/J = 1$ at a high temperature $T/J = 10$ and a low temperature $T/J = 0.5$ for a different number N of sites. We see that, for these

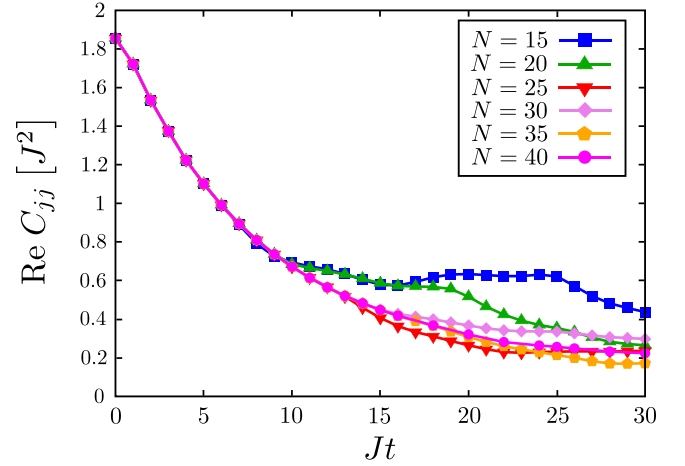


FIG. 3. Real part of real-time current-current correlation function for different number N of sites for $G/J = 0.141$, $\omega_0/J = 1$, and $T/J = 2.5$.

parameters, $N = 5$ sites are sufficient at a high temperature, while $N = 10$ sites are needed at a low temperature. Such behavior is expected since the increase in temperature reduces spatial correlations. For this reason, the system becomes more local at a higher temperature and a smaller number of sites is needed to reach the thermodynamic limit.

In Fig. 3 we present the time dependence of the real part of current-current correlation function in real time obtained through Monte Carlo calculations for various system sizes in the case of weak electron-phonon interaction $G/J = 0.141$, $\omega_0/J = 1$, and $T/J = 2.5$. We see from the figure that a system of $N = 30$ sites is needed for accurate calculation for times up to $Jt = 15$. Such a large N is needed in this case because the carrier mean-free path is large for weak electron-phonon interaction and the system size larger than the carrier mean-free path is needed to obtain the result representative of the thermodynamic limit. To reduce the computational effort we performed the calculation for smaller times with

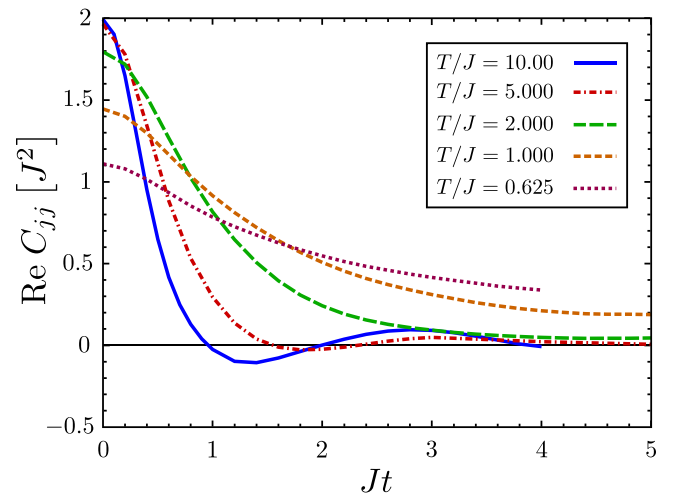


FIG. 4. Time decay of the real part of real-time current-current correlation function at various temperatures for $\omega_0/J = 1$ and $G/J = 0.5$.

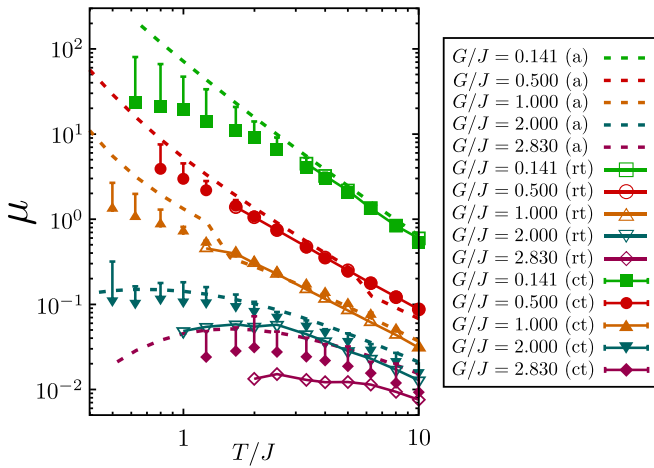


FIG. 5. Temperature dependence of Holstein polaron mobility for different electron-phonon interaction strengths and $\omega_0/J = 1$. The label “ct” stands for the results obtained by analytic continuation from real- and imaginary-time data. Results labeled “rt” are obtained by direct integration of current-current correlation function in real time (full lines connecting the dots are guide to the eye). The results labeled “a” are approximate results from Ref. [72].

adequately smaller N . In particular, we used $N = 20$ for times from $Jt = 5$ to 10 and $N = 30$ for times from $Jt = 10$ to 15.

In Fig. 4 we present the decay of the real part of current-current correlation function in real time for $\omega_0/J = 1$, $G/J = 0.5$ and a range of temperatures. We see that for higher temperatures ($T/J \gtrsim 2$) we fully capture the time decay of the current-current correlation function. In that case, it is possible to calculate the mobility by direct integration using the Kubo formula given in Eq. (3). This approach gives us the most accurate results for polaron mobility where the only uncertainty comes from statistical errors of Monte Carlo calculations, which are rather small. The time decay of current-current correlation function for lower temperatures ($T/J < 2$ in this case) is slower and we cannot obtain reliable results at larger times when the dynamical sign problem becomes severe and Monte Carlo statistical errors become significant. In this case, we resort to analytic continuation procedure described in Sec. II C to obtain the result for polaron mobility. That procedure gives results with systematic error that can appear to be significant, especially in the case of low temperatures. In this case, longer real times become more relevant and analytic continuation that makes use only of imaginary-time and short real-time data becomes less successful.

C. Temperature dependence of polaron mobility

We present the final results of our work in this section. The temperature dependence of mobility for one-dimensional Holstein model is presented in Fig. 5. The results are given for electron-phonon interactions ranging from weak ($G/J = 0.141$) to strong ($G/J = 2.830$) and $\omega_0/J = 1$.

The results labeled “ct” in Fig. 5 were obtained from analytic continuation procedure that makes use of imaginary-time data and real-time data up to times where it is possible to obtain Monte Carlo results with small error. The error bars were estimated as follows: We first calculate the relative error

that the analytic continuation procedure introduces to real and imaginary-time data generated from dynamic mobility calculated using an approximate method in Ref. [72], as described in Sec. III A. We then assume that the relative error of analytic continuation procedure applied to Monte Carlo data for the same parameter set is the same. This is a good estimate since the current-current correlation functions obtained in Ref. [72] and in this work largely resemble each other. Hence, it is expected that analytic continuation performs equally well for both of these current-current correlation functions. From the relative error, we eventually calculate the estimate of the absolute error of the analytic continuation procedure applied to Monte Carlo data. We find that analytic continuation typically tends to underestimate the mobility. For this reason, we present one-sided errors in Fig. 5.

The results obtained by direct integration in real time for times where reliable current-current correlation function is available are labeled “rt.” For reference, we present also the results obtained using an approximate method of Ref. [72] (these are labeled “a”).

The most accurate results in this work are the results obtained for relatively weak electron-phonon interactions $G/J \lesssim 1$ and higher temperatures $T/J \gtrsim 2$. For these parameters, we can capture the full time decay of the current-current correlation function and the results obtained by direct integration are therefore accurate. For these parameters, analytic continuation also gives essentially the same results as direct integration.

The path integral for $G/J < 1$ was calculated using the momentum representation for electronic states (see Sec. II B 1). The alternating phase that remains in the integrand is proportional to the factor $\Delta t G$ [see Eq. (16)]. For this reason, the approach works well for weaker interactions, while for large interactions the dynamical sign problem becomes quite severe. We also note that it is a significant challenge to obtain reliable results at low temperatures, because longer times become relevant then, as already discussed in Sec. III B. The other approach based on position representation (described in Sec. II B 2) of electronic states was used to calculate the current-current correlation function in imaginary time, and in real time for interactions $G/J \gtrsim 1$.

To illustrate the importance of the choice of basis, we present in Fig. 6(a) the ratio of the standard deviation of the current-current correlation function $C_{jj}(t)$ and its absolute value $|C_{jj}(t)|$ obtained from the calculations using either the position or momentum basis for electronic states. The results are presented up to times when the standard deviation becomes comparable to the result (except for $G/J = 0.5$ and the position basis, where longer times can be reached). As can be seen from the figure, in the case of weak interaction ($G/J = 0.5$), the standard deviation is much smaller when the momentum basis is used, while for strong interaction ($G/J = 2$), the standard deviation is significantly smaller when the position basis is used. To demonstrate that such a behavior originates from variations of phases of the terms in Monte Carlo summation (known as the sign problem in the literature), we present in Fig. 6(b) the average sign of the Monte Carlo sum used to evaluate the nominator in Eq. (12) for the same parameters as in Fig. 6(a). For the sum $\sum_i A_i$ the average sign is defined as $s_{av} = |\langle A_i / |A_i| \rangle|$. It takes the value of one when there is no sign problem and it is equal to zero

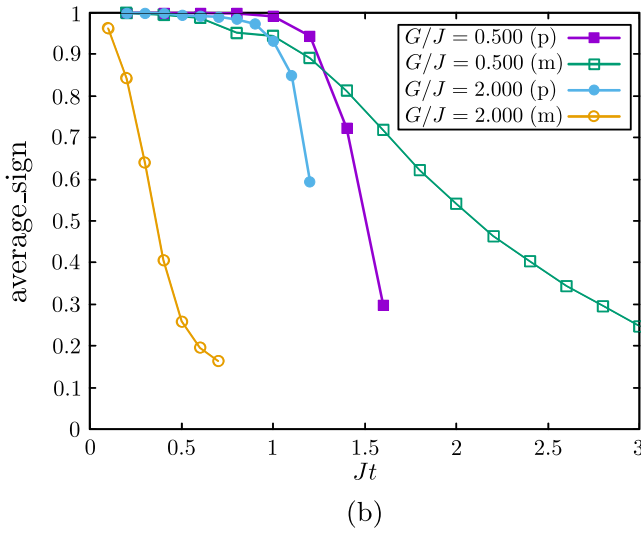
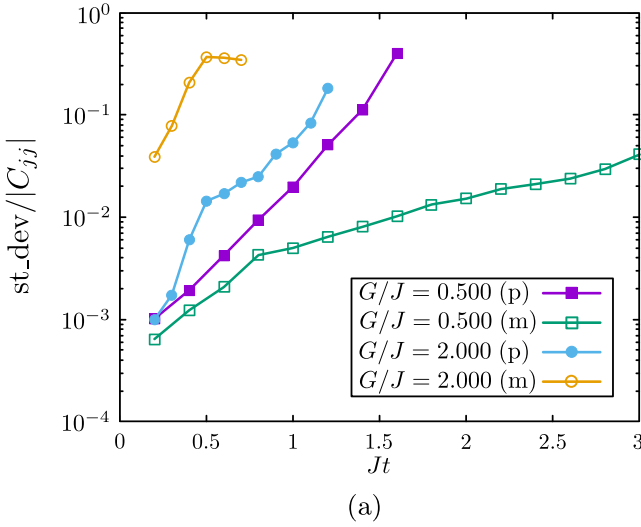


FIG. 6. The real-time dependence of (a) the relative standard deviation and (b) the average sign of the real-time current-current correlation function for $\omega_0/J = 1$ and $T/J = 2$. The label “m” denotes the results obtained with the momentum representation for electrons and the label “p” denotes the results obtained with the position representation for electrons.

when the sign problem is most severe. We see from Figs. 6(b) and 6(a) that the average sign is close to one in cases where standard deviation is small and that it decreases towards zero at times when standard deviation starts to be comparable to the result.

In Fig. 7 we present the current-current correlation function in imaginary time for $T/J = 1$, $\omega_0/J = 1$, and various values of interaction. We see that it is much more sensitive with respect to (imaginary) time variable for stronger electron-phonon interactions, while for weak electron-phonon interactions it appears to have almost a constant value. Therefore, for weak interactions and low temperatures the results obtained from analytic continuation have large error since the input data on current-current correlation function have very little information (they are almost constant in imaginary time and exhibit a slow decay up to the largest real

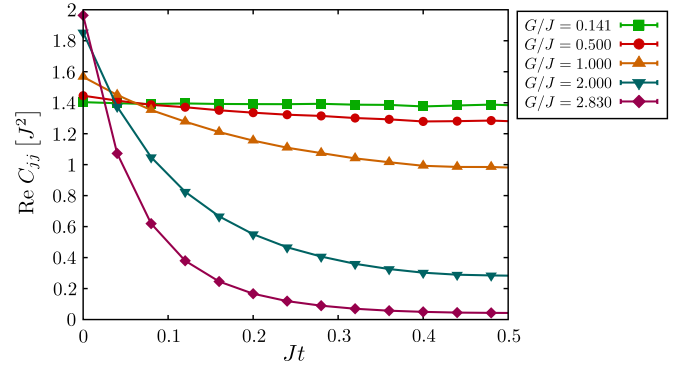


FIG. 7. Imaginary time current-current correlation function for $T/J = 1$, $\omega_0/J = 1$ and for various interaction strengths. The results are shown for imaginary times $0 \leq t \leq \beta/2$ only since the identity $C_{jj}(t) = C_{jj}(\beta - t)$ holds.

times for which data are available). For weak interactions and high temperatures, the real-time data already contains almost full information on the current-current correlation function. Consequently, analytic continuation gives rather accurate results for these parameters. Analytic continuation also works reasonably well for stronger interactions ($G/J \geq 1$). In that case, the current-current correlation function data have a pronounced dependence in imaginary time and for short real times, which gives good enough information to obtain reasonable results from analytic continuation. We note that, for stronger interactions, the mobility obtained by direct integration noticeably underestimates the mobility from analytic continuation. The reason for this is the presence of additional peaks in $C_{jj}(t)$ at times $t_n = n \frac{2\pi}{\omega_0}$ ($n \geq 1$) which are not captured by direct integration, as can be seen in Fig. 8.

To summarize for which parameters the methodology presented works best, one can inspect Fig. 5. It can be seen that the error is rather small for relatively weak interactions $G/J \lesssim 1$ and relatively high temperatures $T/J \gtrsim 2$.

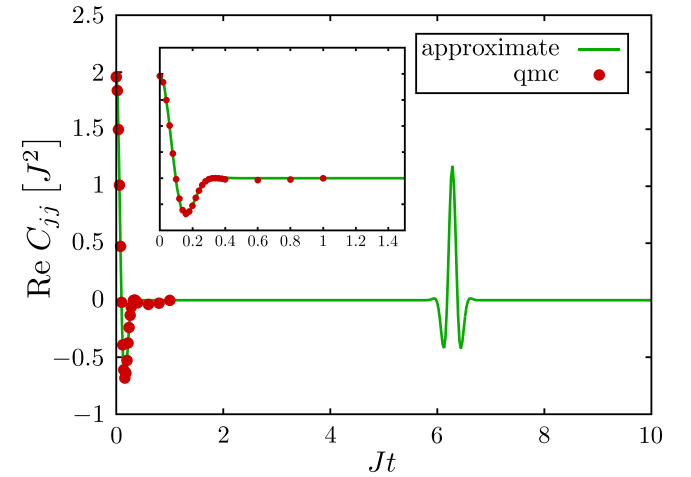


FIG. 8. Time dependence of real part of real-time current-current correlation function for $G/J = 2.83$ and $T/J = 2$ obtained by approximate method from Ref. [72] (labeled “approximate”) and by our QMC calculations (labeled “qmc”). The inset shows a detailed view for times $Jt \leq 1.5$.

Reasonably accurate results can be also obtained for stronger interactions $G/J > 1$ and relatively high temperatures $T/J \gtrsim 2$. On the other hand, it is quite challenging to obtain the results at low temperatures $T/J < 1$.

It is interesting to compare the results obtained in this work with the results of Ref. [72] obtained using an approximate method. For almost all values of the parameters studied, the results of Ref. [72] fall within the error bar range of the results obtained in this work. Such an agreement establishes the approach of Ref. [72] as a method to obtain reasonably good temperature dependence of the mobility.

We also compare our results to the results of Ref. [68] which is the only reference where the results for temperature dependence of Holstein polaron mobility were reported based on the calculation using the methodology that should be in principle numerically exact. The results of Ref. [68] agree with our results for weakest interaction $G/J = 0.141$ and the temperatures when our estimated error is relatively small. However, for stronger interactions $G/J = 1$, $G/J = 2$, and $G/J = 2.83$ the results of Ref. [68] give lower values of mobility than our results. For example, at $G/J = 2.83$, $\omega_0/J = 1$ and $T/J = 2$ the range of mobility reported in Ref. [68] is $\mu \in (2.8 \times 10^{-3}, 8.1 \times 10^{-3})$, while in our case it is $\mu \in (3.1 \times 10^{-2}, 7.2 \times 10^{-2})$. For these parameters, direct integration around the first peak in current-current correlation function (in the range $0 \leq Jt \leq 1$ in Fig. 8) gives already $\mu \approx 1.5 \times 10^{-2}$ and the integration around subsequent peaks could only increase this value. The results of Ref. [68] were obtained using analytic continuation of imaginary-time data only and we believe that this analytic continuation might not be sufficiently reliable for all parameter values. This could potentially explain the difference between the results of Ref. [68] and our results.

All the calculations and examples presented in this paper are for a phonon frequency of $\omega_0/J = 1$. We next discuss the effect of phonon frequency on the accuracy and applicability of the methodology. As discussed previously, the methodology performs best when it is possible to perform calculations for real times which are sufficiently long that the current-current correlation function decays toward zero and it is difficult to perform simulations for low temperatures

since the correlation function decays rather slowly then. The current-current correlation function is expected to decay more rapidly to zero when the average number of phonons is larger, which happens for smaller phonon energies. Hence, it is expected that it will be possible to reach even lower temperatures in the simulations for smaller phonon energies. On the other hand, for larger phonon energies, the lowest temperature for which simulations can be performed is expected to be larger.

IV. CONCLUSION

In conclusion, we developed the path-integral quantum Monte Carlo methodology for a numerically exact calculation of real- and imaginary-time current-current correlation functions and for the extraction of polaron mobility from these data in systems consisting of an electron interacting with phonons. The appropriate choice of basis for representation of the path-integral-enabled calculations for longer real times. The use of both real- and imaginary-time data enabled more reliable analytic continuation in comparison with the traditional approach where only the imaginary-time data are used. The methodology was applied to the Holstein polaron model and enabled us to obtain reliable results for the temperature dependence of polaron mobility for interactions ranging from weak to strong and for temperatures that are not too low. The overall ideas of the methodology are not restricted to the Holstein polaron model and can be in principle applied to any Hamiltonian describing an electron interacting with phonons.

ACKNOWLEDGMENTS

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Supplemental material for: A method for obtaining polaron mobility using real and imaginary time path-integral quantum Monte Carlo

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In this Supplemental material we present the details of the derivation of the expression for

$$C_{A,B}^{m,Q} = \text{Tr} \left[\left(e^{-\tau H_0} e^{-\tau H_1} e^{-\tau H_2} \right)^m \left(e^{i\Delta t H_0} e^{i\Delta t H_1} e^{i\Delta t H_2} \right)^Q A \left(e^{-i\Delta t H_0} e^{-i\Delta t H_1} e^{-i\Delta t H_2} \right)^Q B \right] \quad (1)$$

in the two representations and present the table with the parameters of the simulations.

I. PATH INTEGRAL EXPRESSION FOR $C_{A,B}^{m,Q}$ WITH ELECTRONS IN THE MOMENTUM REPRESENTATION

By expressing the trace from Eq. (1) in the basis $|k; \{X\}\rangle$ defined in the main part of the paper, we obtain

$$C_{A,B}^{m,Q} = \sum_{k_0} \int \left(\prod_{n=0}^{N-1} dX_n^0 \right) \langle \{X^0\}; k_0 | \rho(-\tau)^m \rho(i\Delta t)^Q A \rho(-i\Delta t)^Q B | k_0; \{X^0\} \rangle, \quad (2)$$

where we introduced the index "0" on electron momentum and phonon coordinate variables and we introduced the shorthand notation

$$\rho(z) = e^{zH_0} e^{zH_1} e^{zH_2}. \quad (3)$$

We make use of the relation for the resolution of identity

$$1 = \sum_k \int \left(\prod_{n=0}^{N-1} dX_n \right) |k; \{X\}\rangle \langle \{X\}; k| \quad (4)$$

and insert the resolution of identity between each two subsequent operators in Eq. (2) to obtain

$$\begin{aligned} C_{A,B}^{m,Q} = & \sum_{k_0, \dots, k_{m+2Q+1}} \int \prod_{j=0}^{m-1} DX^j \prod_{p=m}^{m+Q} DX^p \prod_{q=m+Q+1}^{m+2Q+1} DX^q \left(\prod_{j=0}^{m-1} \langle X^j; k_j | \rho(-\tau) | k_{j+1}; X^{j+1} \rangle \right) \\ & \left(\prod_{p=m}^{m+Q-1} \langle X^p; k_p | \rho(i\Delta t) | k_{p+1}; X^{p+1} \rangle \right) \langle X^{m+Q}; k_{m+Q} | A | k_{m+Q+1}; X^{m+Q+1} \rangle \\ & \left(\prod_{r=m+Q+1}^{m+2Q} \langle X^r; k_r | \rho(-i\Delta t) | k_{r+1}; X^{r+1} \rangle \right) \langle X^{m+2Q+1}; k_{m+2Q+1} | B | k_0; X^0 \rangle. \end{aligned} \quad (5)$$

The basis states that enter the expression for the resolution of identity were indexed as "1", "2", ..., "m + 2Q + 1" in increasing order from left to right and we introduced the notation

$$\{X^j\} \rightarrow X^j,$$

$$\prod_{n=0}^{N-1} dX_n^j \rightarrow DX^j.$$

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To calculate the matrix elements $\langle X^j; k_j | \rho(z) | k_{j+1}; X^{j+1} \rangle$ we need to find how exponential operators act on the basis states. The operator e^{zH_2} acts trivially as:

$$e^{zH_2} |k_j; X^j\rangle = e^{z\varepsilon(k_j)} |k_j; X^j\rangle. \quad (6)$$

The operator e^{zH_1} acts as:

$$e^{zH_1} |k_j; X^j\rangle = e^{z\frac{M}{2} \sum_n \omega_n^2 (X_n^j)^2} \frac{1}{N} \sum_{k,m} e^{im \cdot (k_j - k) + z\sqrt{2M\omega_m} G X_m^j} |k; X^j\rangle. \quad (7)$$

The operator e^{zH_0} depends on phonon momentum only and its matrix element is given as

$$\langle X^j; k_j | e^{zH_0} | k_{j+1}; X^{j+1} \rangle = \delta_{k_j, k_{j+1}} \left(\frac{M}{-2\pi z} \right)^{\frac{N}{2}} e^{\sum_n \frac{M(X_n^{j+1} - X_n^j)^2}{2z}}. \quad (8)$$

Making use of Eqs. (6)-(8) we get the expressions for matrix elements that appear in $C_{A,B}^{m,Q}$:

$$\langle X^j; k_j | \rho(-\tau) | k_{j+1}; X^{j+1} \rangle = C_1 f_{k_{j+1}, k_j}(-\tau; X^{j+1}) \exp \left(-\tau \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} \right) \right), \quad (9)$$

$$\langle X^p; k_p | \rho(i\Delta t) | k_{p+1}; X^{p+1} \rangle = C_2 f_{k_{p+1}, k_p}(i\Delta t; X^{p+1}) \exp \left(i\Delta t \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} \right) \right), \quad (10)$$

$$\langle X^r; k_r | \rho(-i\Delta t) | k_{r+1}; X^{r+1} \rangle = C_3 f_{k_{r+1}, k_r}(-i\Delta t; X^{r+1}) \exp \left(-i\Delta t \sum_n \left(\frac{M}{2} \omega_n^2 (X_n^{r+1})^2 + \frac{M}{2} \frac{(X_n^{r+1} - X_n^r)^2}{(i\Delta t)^2} \right) \right), \quad (11)$$

where C_1, C_2 and C_3 are irrelevant constants that originate from the prefactor in Eq. (8), while the functions $f_{k_i, k_j}(z; X^i)$ are fermion propagators between states k_i and k_j in imaginary or real time defined as:

$$f_{k_i, k_j}(z; X^i) = e^{z\varepsilon(k_i)} \frac{1}{N} \sum_m e^{im \cdot (k_i - k_j) + z\sqrt{2M\omega_m} G X_m^i}. \quad (12)$$

We then obtain the expression from the main part of the paper:

$$\begin{aligned} C_{A,B}^{m,Q} = & C'_1 \int \prod_{j=0}^{m-1} DX^j \prod_{p=m}^{m+Q} DX^p \prod_{r=m+Q+1}^{m+2Q+1} DX^r e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^r]} \times \\ & \times \sum_{\{k\}} \prod_{j=0}^{m-1} f_{k_{j+1}, k_j}(-\tau; X^{j+1}) \prod_{p=m}^{m+Q-1} f_{k_{p+1}, k_p}(i\Delta t; X^{p+1}) \prod_{r=m+Q+1}^{m+2Q} f_{k_{r+1}, k_r}(-i\Delta t; X^{r+1}) \times \\ & \times \langle X^{m+Q}; k_{m+Q} | A | k_{m+Q+1}; X^{m+Q+1} \rangle \langle X^{m+2Q+1}; k_{m+2Q+1} | B | k_0; X^0 \rangle, \end{aligned} \quad (13)$$

where $C'_1 = C_1 C_2 C_3$ is an irrelevant constant, the symbol $\sum_{\{k\}}$ denotes the summation over all k variables, while phonon actions are given by expressions:

$$\begin{aligned} S_1[\tau; X^j] = & \tau \sum_{j=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} \right], \\ S_2[-i\Delta t; X^p] = & -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} \right], \\ S_3[i\Delta t; X^r] = & i\Delta t \sum_{r=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{r+1})^2 + \frac{M}{2} \frac{(X_n^{r+1} - X_n^r)^2}{(i\Delta t)^2} \right]. \end{aligned} \quad (14)$$

II. PATH INTEGRAL EXPRESSION FOR $C_{A,B}^{m,Q}$ WITH ELECTRONS IN THE POSITION REPRESENTATION

In this case, we express the trace from Eq. (1) in the basis $|r; \{X\}\rangle$ defined in the main part of the paper and obtain

$$C_{A,B}^{m,Q} = \sum_{r_0} \int \left(\prod_{n=0}^{N-1} dX_n^0 \right) \langle \{X^0\}; r_0 | \rho(-\tau)^m \rho(i\Delta t)^Q A \rho(-i\Delta t)^Q B | r_0; \{X^0\} \rangle. \quad (15)$$

We make use of the following resolution of identity

$$1 = \sum_r \int \left(\prod_{n=0}^{N-1} dX_n \right) |r; \{X\}\rangle \langle \{X\}; r| \quad (16)$$

and follow the same procedure as in the previous section to arrive at the expression analogous to Eq. (5):

$$\begin{aligned} C_{A,B}^{m,Q} = & \sum_{r_0, \dots, r_{m+2Q+1}} \int \left(\prod_{j=0}^{m-1} DX^j \right) \left(\prod_{p=m}^{m+Q} DX^p \right) \left(\prod_{q=m+Q+1}^{m+2Q+1} DX^q \right) \left(\prod_{j=0}^{m-1} \langle X^j; r_j | \rho(-\tau) | r_{j+1}; X^{j+1} \rangle \right) \times \\ & \times \left(\prod_{p=m}^{m+Q-1} \langle X^p; r_p | \rho(i\Delta t) | r_{p+1}; X^{p+1} \rangle \right) \langle X^{m+Q}; r_{m+Q} | A | r_{m+Q+1}; X^{m+Q+1} \rangle \times \\ & \times \left(\prod_{q=m+Q+1}^{m+2Q} \langle X^q; r_q | \rho(-i\Delta t) | r_{q+1}; X^{q+1} \rangle \right) \langle X^{m+2Q+1}; r_{m+2Q+1} | B | r_0; X^0 \rangle \end{aligned} \quad (17)$$

The relevant matrix elements are now given as

$$\langle X^a; r_a | e^{zH_0} | r_b; X^b \rangle = \delta_{r_a, r_b} \left(\frac{M}{-2\pi z} \right)^{\frac{N}{2}} e^{\sum_n \frac{M(X_n^b - X_n^a)^2}{2z}}, \quad (18)$$

$$\langle X^a; r_a | e^{zH_1} | r_b; X^b \rangle = \delta_{r_a, r_b} e^{z \sum_n G \sqrt{2M\omega_n} \delta_{n, r_b} X_n^b} e^{z \frac{M}{2} \sum_n \omega_n^2 (X_n^b)^2} \prod_{n=0}^{N-1} \delta(X_n^a - X_n^b), \quad (19)$$

$$\langle X^a; r_a | e^{zH_2} | r_b; X^b \rangle = I(-z, r_a - r_b) \prod_{n=0}^{N-1} \delta(X_n^a - X_n^b), \quad (20)$$

with $I(z, r) \equiv \frac{1}{N} \sum_k \cos(kr) e^{-z\varepsilon(k)}$. Making use of Eqs. (18)-(20) and taking into account that operators A and B act only on electron states we get the expression for $C_{A,B}^{m,Q}$ from main part of the paper:

$$\begin{aligned} C_{A,B}^{m,Q} = & C'_2 \sum_{\{r\}} \langle r_{m+Q} | A | r_{m+Q+1} \rangle \langle r_{m+2Q+1} | B | r_0 \rangle \left(\prod_{j=0}^{m-1} I(\tau; r_{j+1} - r_j) \right) \times \\ & \times \left(\prod_{p=m}^{m+Q-1} I(-i\Delta t; r_{p+1} - r_p) \right) \left(\prod_{q=m+Q+1}^{m+2Q} I(i\Delta t; r_{q+1} - r_q) \right) \times \\ & \times \int \left(\prod_{j=0}^{m-1} DX^j \right) \left(\prod_{p=m}^{m+Q-1} DX^p \right) \left(\prod_{q=m+Q+1}^{m+2Q} DX^q \right) e^{-S_1[\tau; X^j]} e^{-S_2[-i\Delta t; X^p]} e^{-S_3[i\Delta t; X^q]}, \end{aligned} \quad (21)$$

where C'_2 is an irrelevant constant, the symbol $\sum_{\{r\}}$ denotes the summation over all r variables and the actions are given as

$$\begin{aligned}
S_1[\tau; X^j] &= \tau \sum_{j=0}^{m-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{j+1})^2 + \frac{M}{2} \frac{(X_n^{j+1} - X_n^j)^2}{\tau^2} + G \sqrt{2M\omega_n} \delta_{n,r_j} X_n^{j+1} \right], \\
S_2[-i\Delta t; X^p] &= -i\Delta t \sum_{p=m}^{m+Q-1} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{p+1})^2 + \frac{M}{2} \frac{(X_n^{p+1} - X_n^p)^2}{(i\Delta t)^2} + G \sqrt{2M\omega_n} \delta_{n,r_p} X_n^{p+1} \right], \\
S_3[i\Delta t; X^q] &= i\Delta t \sum_{q=m+Q+1}^{m+2Q} \sum_n \left[\frac{M}{2} \omega_n^2 (X_n^{q+1})^2 + \frac{M}{2} \frac{(X_n^{q+1} - X_n^q)^2}{(i\Delta t)^2} + G \sqrt{2M\omega_n} \delta_{n,r_q} X_n^{q+1} \right].
\end{aligned} \tag{22}$$

III. TABLE WITH SIMULATION PARAMETERS

G/J	T/J	Real time QMC					Imaginary time QMC					Analytic continuation	
		$J \cdot t_{\max}$	$J \cdot \Delta t$	N_s	electron basis	N	$J \cdot t_{\max}$	$J \cdot \tau$	N_s	electron basis	N	$\omega_{\max}/J$	svs
0.141	10	30	0.1	10^4	momentum	15	0.06	0.002	10^5	position	10	5	23
	5	30	0.1	10^4		25	0.12	0.004	10^5			5	40
	2	30	0.1	10^4		55	0.3	0.01	10^5			5	40
	1	30	0.1	10^4		55	0.6	0.02	10^5			5	43
	0.5	30	0.1	10^4		55	1.2	0.04	10^5			/	/
0.5	10	4	0.1	10^4	momentum	10	0.06	0.002	10^5	position	10	10	13
	5	5	0.1	10^4			0.12	0.004	10^5			10	17
	2	5	0.1	10^4			0.3	0.01	10^5			10	20
	1	5	0.1	10^4			0.6	0.02	10^5			10	20
	0.5	1	0.1	10^4			1.2	0.04	10^5			/	/
1	10	1.6	0.02	10^6	position	10	0.06	0.002	10^5	position	10	20	11
	5	1.6	0.02	10^6			0.12	0.004	10^5			20	10
	2	1.6	0.05	10^6			0.3	0.01	10^5			20	11
	1	1	0.1	10^6			0.6	0.02	10^5			20	10
	0.5	1	0.1	10^6			1.2	0.04	10^5			20	10
2	10	1	0.01	10^6	position	10	0.06	0.002	10^5	position	10	80	25
	5	1.2	0.01	10^6			0.12	0.004	10^5			150	48
	2	1.3	0.025	10^6			0.3	0.01	10^5			200	55
	1	1.3	0.025	10^6			0.6	0.02	10^5			200	54
	0.5	1.4	0.05	10^6			1.2	0.04	10^5			200	40
2.83	10	1	0.01	10^6	position	10	0.06	0.002	10^5	position	10	200	24
	5	1	0.01	10^6			0.12	0.004	10^5			300	34
	2	1	0.02	10^6			0.3	0.01	10^5			360	51
	1	1	0.025	10^6			0.6	0.02	10^5			/	/
	0.5	1	0.025	10^6			1.2	0.04	10^5			/	/

The table with simulation parameters for typical values of Holstein model parameters G/J and T/J . $t_{\max}$ denotes the maximal real or imaginary time for which quantum Monte Carlo (QMC) simulation was performed, Δt is the time step in real time simulation, τ is the time step in imaginary time simulation, N_s is the number of samples in the Monte Carlo simulation, N is the number of lattice sites in the system, the parameter $\omega_{\max}$ denotes the range $[-\omega_{\max}, \omega_{\max}]$ of frequencies for representation of $\text{Re} \mu(\omega)$, while svs denotes the number of singular values used in analytic continuation. For the analytic continuation procedure $\text{Re} \mu(\omega)$ was represented on a frequency grid of $100\omega_{\max}/J$ points in the range $[-\omega_{\max}, \omega_{\max}]$. Real and imaginary time data were calculated at time points that are multiples of the time step and lie in the range $(0, t_{\max})$. When $G/J = 0.141$ the number of sites N denotes the number of sites needed to perform converged calculation for $t = t_{\max}$.

Electrical control of a spin qubit in InSb nanowire quantum dots: Strongly suppressed spin relaxation in high magnetic field

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In this paper we investigate the impact of gating potential and magnetic field on phonon induced spin relaxation rate and the speed of the electrically driven single-qubit operations inside the InSb nanowire spin qubit. We show that a strong g factor and high magnetic field strength lead to the prevailing influence of electron-phonon scattering due to deformation potential, considered irrelevant for materials with a weak g factor, like GaAs or Si/SiGe. In this regime we find that spin relaxation between qubit states is significantly suppressed due to the confinement perpendicular to the nanowire axis. We also find that maximization of the number of single-qubit operations that can be performed during the lifetime of the spin qubit requires single quantum dot gating potential.

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I. INTRODUCTION

Spin of an electron confined in a semiconductor quantum dot (QD) can act as a carrier of quantum information [1] and a building block of quantum computers. In order to manipulate electron spin, usage of the external magnetic [2,3] and electric [4–6] field was suggested. Although spin control by means of a magnetic field is straightforward, electrical control of spin qubit through electric-dipole spin resonance (EDSR) is technologically more desirable [7–10].

Spin-orbit coupling (SOC) plays an essential role in the EDSR spin qubit scheme, since it allows transitions between qubit states using the spin-independent driving, such as electric-dipole interaction. On the other hand, the presence of SOC induces undesired phonon mediated transitions between qubit states [11–21]. In order to suppress the coupling to phonons, approaches like the optimal design of QDs [22,23] or the control of system size [24] was suggested.

Relaxation rates are dependent on the full three-dimensional QD potential, but in most cases contribution of the confinement along the direction(s) perpendicular to the substrate in which QDs are embedded can be neglected. Assuming magnetic fields up to several tesla, this reduction is justified in material with a weak effective Landé g factor. A typical example that satisfies this assumption are lateral GaAs QDs [25], while in the opposite direction lies an InSb nanowire, having two orders of magnitude stronger g factor [26]. Having also very strong SOC, spin qubits in InSb nanowires [27–31] have attracted much attention due to the observed [28] fast electric-dipole induced transition between qubit states, whose speed is equal to the strength of Rabi frequency.

Since both Rabi frequency and phonon induced relaxation rates are dependent on the magnetic field orientation and strength, design of the gating potential, and SOC, there is

a wide range of possibility to tune their strength, with the goal of obtaining as much as possible single-qubit operations during its lifetime.

In this paper we search for the optimal regime in which electrical control of the InSb spin qubit can be achieved. We analyze both single and double quantum dot (DQD) potential and discuss its positive features and negative drawbacks on the spin qubit. In the case of double quantum dot potential, there is the possibility to tune the distance between the dots and to analyze the effects of the asymmetric gating potential. Also, we address the situations in which full three-dimensional confinement has nontrivial influence on spin relaxation rates. We will show that scattering by deformation potential dominates in this regime. Finally, to offer a quantitative insight into the spin qubit quality, we define a figure of merit as the ratio of Rabi frequency and the overall spin relaxation rate and discuss the obtained results in terms of this measure.

This paper is organized as follows. In Sec. II the single-electron Hamiltonian model of the InSb nanowire is introduced. In Sec. III we start with the definition of Rabi frequency and phonon induced spin relaxation rate between spin qubit states. After that, we independently study their dependence on tunable parameters of the system. Using the obtained results, quality of the spin qubit is discussed with the help of the figure of merit as a quantitative measure. In the end we finish the paper with a short conclusion and the impact of the presented results.

II. NANOWIRE SPIN QUBIT MODEL

We start with the Hamiltonian describing the electron confined in an InSb nanowire [30]

$$H = \frac{p^2}{2m^*} + V(x) + H_{\text{so}} + H_z, \quad (1)$$

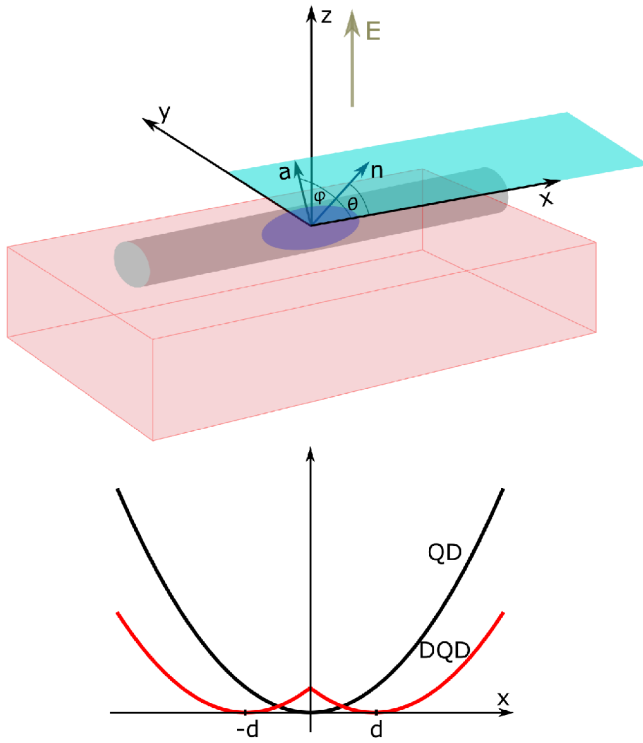


FIG. 1. (Upper panel) *Nanowire QD—schematic view.* Electron dynamics along the nanowire (x) axis is described by the Hamiltonian H , given in Eq. (1). Angle between the nanowire x axis and magnetic field direction $\mathbf{n} = (\cos \theta, \sin \theta, 0)$ is equal to θ , while the spin-orbit vector $\mathbf{a} = (\cos \varphi, \sin \varphi, 0)$ builds an angle φ with the x axis. (Lower panel) Confining potential used in Eq. (1): QD and DQD potential. In the case of a DQD potential [Eq. (6)] symmetric confinement is depicted ($\omega_L = \omega_R$), with distance between the dots equal to $2d$.

where m^* is the effective mass, $p = -i\hbar\partial/\partial x$ momentum in x direction, $V(x)$ is the gating potential used to localize the electron, while H_{so} represents the spin-orbit interaction Hamiltonian consisting of two terms: Dresselhaus [32] and Rashba [33]. The presence of the Dresselhaus SOC is due to the material in which an electron is embedded. On the other hand, Rashba SOC appears when an electric field E in the z direction is applied (see Fig. 1). In an InSb nanowire, a spin-orbit interaction Hamiltonian is equal to [30]

$$H_{\text{so}} = (\alpha_D \sigma_x + \alpha_R \sigma_y) p, \quad (2)$$

where σ_x and σ_y are Pauli matrices, while α_D and α_R are Dresselhaus and Rashba spin-orbit coupling strengths. Suitable change of parameters α_R and α_D with $\alpha = \sqrt{\alpha_D^2 + \alpha_R^2}$ and $\varphi = \arctan(\alpha_R/\alpha_D)$ allows us to write Eq. (2) as

$$H_{\text{so}} = \alpha \mathbf{a} \cdot \boldsymbol{\sigma} p, \quad (3)$$

using the unit spin-orbit vector $\mathbf{a} = (\cos \varphi, \sin \varphi, 0)$ and the vector $\boldsymbol{\sigma}$ made of Pauli matrices. Finally, H_z is the Zeeman term, describing the coupling of spin and magnetic field

$$H_z = \frac{g}{2} \mu_B \mathbf{B} \cdot \boldsymbol{\sigma}, \quad (4)$$

where g is the effective Landé factor, μ_B is the Bohr magneton, while $\mathbf{B} = B\mathbf{n}$ is the applied magnetic field in the plane of the substrate, building an angle θ with the growth x axis of the nanowire (see the upper panel of Fig. 1). In this work a magnetic field is considered to be in-plane to minimize the orbital effects [22,34–36]. In Appendix A we have shown that for B up to 3 T, orbital effects of a magnetic field are small and can be neglected.

Typical gating that confines a single electron in experimental setups [37] can be modeled as a harmonic oscillator quantum dot (QD) [38] or double quantum dot (DQD) [29] potential. Corresponding potentials are equal to (see the lower panel of Fig. 1 as an illustration)

$$V^{\text{QD}}(x) = \frac{1}{2} m^* \omega^2 x^2, \quad (5)$$

$$V^{\text{DQD}}(x) = \frac{1}{2} m^* \min\{\omega_L^2(x+d)^2, \omega_R^2(x-d)^2\}. \quad (6)$$

In the case of a QD potential, the only degree of freedom is the harmonic potential frequency ω , while in the DQD case frequencies ω_L and ω_R can be tuned, as well as the distance $2d$ between the dots. Since DQD potential allows asymmetric confinement, we introduce asymmetry parameter δ , equal to the ratio of frequencies in the left and right dot, $\delta = \omega_L/\omega_R$. Impact of the DQD confinement will be discussed in terms of δ , $2d$, and $\omega_R = \omega$ (more detailed explanation can be found in Sec. III A).

The Hamiltonian of the electron in different potential types and magnetic field strengths can be solved using the numerical diagonalization [39], although perturbative approaches in the study of spin qubit properties are common [21,27,30]. In this work we follow the numerical approach; the numerical procedure used in obtaining the eigenvalues and eigenvectors of the Hamiltonian given in Eq. (1) is explained in Appendix B. In order to successfully diagonalize the Hamiltonian, orbital $x_0 = \sqrt{\hbar/m^*\omega}$ and spin-orbit $x_{\text{so}} = \hbar/m^*\alpha$ lengths are defined. In our calculations we have used $m^* = 0.014 m_e$ [29], $x_0 = 30$ nm [29], and $x_{\text{so}} = 165$ nm [40] parameters for both QD and DQD potentials (recall that $\omega_R = \omega$ in the DQD case), related to the experimental reports on InSb nanowires. On the other hand, we have used g factor in bulk InSb material, $g = -51.3$ [41], being in the range of the experimentally reported values [38,42]. Initial check of the numerical recipe presented in Appendix B were exact analytical results obtained in the special case of the infinite square well [43]. In this case we were able to reproduce the results concerning the angular dependence of the energy splitting between Zeeman sublevels, Rabi frequency, and the relaxation rate.

The nanowire Hamiltonian [Eq. (1)] describes the single-electron dynamics in the x direction only. To ensure the validity of the one-dimensional approximation and to suppress the dynamics in the yz plane, a much stronger yz plane confinement than in the x direction is needed. In this case, a wave function along both directions, y and z , will correspond to the respective ground state. To take into account the wire geometry of the system, the same confinement length $y_0 = z_0 = 10$ nm in the $y(z)$ direction is assumed. We model the confinement potential as harmonic [39], to which the ground state wave function $\psi(y) = e^{-y^2/2y_0^2}/\sqrt{\sqrt{\pi}y_0}$ corresponds. In the z direction an additional potential eEz ($z > 0$; $z = 0$

corresponds to the position of the substrate) is present due to the applied electric field. Finally, the substrate acts as an infinite potential barrier for the confined electron, forbidding him to propagate in the $z < 0$ region [44]. The ground state $\psi(z)$ of the Hamiltonian in the z direction is found using the same numerical method as for the Hamiltonian in the x direction. Thus, the ground state wave function in the yz plane is equal to $\Psi(y, z) = \psi(y)\psi(z)$.

III. EDSR AND SPIN RELAXATION IN NANOWIRE SPIN QUBIT

In order to achieve electrical control of the nanowire spin qubit, an oscillating electric field in the x direction should be switched on, resulting in the Rabi Hamiltonian $H_R = eE_0x \cos(\omega_E t)$. When the applied electric field is in resonance with our quantum system, Rabi frequency Ω_{01} is defined as

$$\Omega_{01} = \frac{eE_0}{\hbar} |\langle 0|x|1 \rangle|, \quad (7)$$

measuring the speed of the single-qubit rotations. In Eq. (7) states $|0\rangle$ and $|1\rangle$ correspond to the ground and first excited state of the single electron Hamiltonian H , while $e|\langle 0|x|1 \rangle|$ is the dipole matrix element. We are particularly interested in the case where qubit states are Zeeman sublevels of the orbital ground state, since in this regime strength of the Rabi frequency can be manipulated by changing the magnetic field orientation [30].

Besides providing the opportunity to electrically control the spin qubit, SOC triggers the undesired phonon induced transition between qubit states, setting up a limit on the qubit lifetime. Rate of spin relaxation can be determined from the Fermi golden rule

$$\Gamma_{01} = \frac{2\pi}{\hbar} \sum_{\nu\mathbf{q}} |M_\nu(\mathbf{q})|^2 |\langle \psi_0 | e^{i\mathbf{q}\cdot\mathbf{r}} | \psi_1 \rangle|^2 \delta(\Delta E_{01} - \hbar\omega_{\nu\mathbf{q}}). \quad (8)$$

Transition is triggered by acoustic phonons of energy $\hbar\omega_{\nu\mathbf{q}}$ that correspond to the energy separation between qubit states, $\Delta E_{01} = |E_0 - E_1|$. We assume a linear dispersion relation of acoustic phonons with respect to the intensity of wave vector $\mathbf{q}$, $\omega_{\nu\mathbf{q}} = c_\nu |\mathbf{q}|$, yielding $|\mathbf{q}| = \Delta E_{01}/\hbar c_\nu$.

Next, three different geometric factors $|M_\nu(\mathbf{q})|^2$ entering spin relaxation rates originate from different types of electron-phonon scattering: electron-longitudinal phonon scattering due to the deformation potential [45]

$$|M_{\text{LA-DP}}(\mathbf{q})|^2 = \frac{\hbar D^2}{2\rho c_{\text{LA}} V} |\mathbf{q}|, \quad (9)$$

electron-longitudinal phonon scattering due to the piezoelectric field [45]

$$|M_{\text{LA-PZ}}(\mathbf{q})|^2 = \frac{32\pi^2 \hbar (eh_{14})^2 (3q_x q_y q_z)^2}{\epsilon^2 \rho c_{\text{LA}} V |\mathbf{q}|^7}, \quad (10)$$

where h_{14} is piezoelectric constant, and electron-transverse phonon scattering due to the piezoelectric field [45]

$$|M_{\text{TA-PZ}}(\mathbf{q})|^2 = 2 \frac{32\pi^2 \hbar (eh_{14})^2}{\epsilon^2 \rho c_{\text{TA}} V} \times \left| \frac{q_x^2 q_y^2 + q_x^2 q_z^2 + q_y^2 q_z^2}{|\mathbf{q}|^5} - \frac{(3q_x q_y q_z)^2}{|\mathbf{q}|^7} \right|. \quad (11)$$

Finally, spin relaxation rates are dependent on the transition matrix element $|\langle \psi_0 | e^{i\mathbf{q}\cdot\mathbf{r}} | \psi_1 \rangle|^2$ which depends on the full three-dimensional confinement. In order to divide the contribution of confinements along the nanowire axis and the yz plane, we write the transition matrix element as $|\langle 0 | e^{iq_x x} | 1 \rangle|^2 |T_{yz}|^2$, where $|\langle 0 | e^{iq_x x} | 1 \rangle|^2$ is the contribution along the nanowire direction, while

$$|T_{yz}|^2 = \left| \iint dy dz \Psi(y, z) e^{i(q_y y + q_z z)} \right|^2 \quad (12)$$

represents scattering in a plane perpendicular to the nanowire axis.

The role of $|T_{yz}|^2$ in the spin relaxation rate depends on the regime in which spin qubit operates. At low magnetic fields, when $|\mathbf{q}|z_0 \ll 1$ and $|\mathbf{q}|y_0 \ll 1$, dipole approximation $e^{i\mathbf{q}\cdot\mathbf{r}} \approx 1 + i\mathbf{q} \cdot \mathbf{r}$ is valid [22] and $|T_{yz}|^2$ can be replaced with $(1 + |\mathbf{q}|^2 z_0^2 \cos^2 \theta) \approx 1$, implying that one-dimensional approximation is justified. However, at higher magnetic fields, dipole approximation is not valid and confinement in the yz direction can play a significant role. To determine its role in the spin relaxation rate, we have numerically calculated $|T_{yz}|^2$ beyond the dipole approximation.

Magnetic field strengths for which the system operates outside of the dipole approximation ($|\mathbf{q}|y_0 \geq 1$) can be roughly estimated; assuming energy separation between qubit states proportional to $g\mu_B B$, Fermi golden rule determines phonon wave number $|\mathbf{q}| = g\mu_B B/(\hbar c_\lambda)$, where $c_{\text{LA}} = 3800$ m/s [46] and $c_{\text{TA}} = 1900$ m/s [47], giving us magnetic field strengths for the electron-phonon scattering in the longitudinal (0.084 T) and transverse (0.042 T) direction above which we are outside of the dipole approximation.

Before we continue, we provide necessary parameters for the calculation of the spin relaxation rate: $eh_{14} = 1.41 \times 10^9$ eV/m [45], $\epsilon = 16.5$, $D = 7$ eV [48], $\rho = 5775$ kg/m³ [49].

A. Rabi frequency

We start the discussion of obtained results with the analysis of Rabi frequency dependence on the parameters of interest.

In Fig. 2(a), dependence of Ω_{01} (in $eE_0 x_0/\hbar$ units) on $\theta - \varphi$ and magnetic field strength is presented for the QD confinement potential. Our results confirm the expected π periodic behavior with respect to $\theta - \varphi$ [30]. Depending on the magnetic field strength, results can be divided into two classes. In the first class qubit states represent Zeeman sublevels of the orbital ground state; in this regime zero Rabi frequency can be found for special magnetic field orientations ($\theta - \varphi = 0, \pi$), since these qubit states have orthogonal spin components. In the second class, magnetic field strengths have led to rearrangement of energy levels, such that qubit states originate from the ground and the first excited orbital state. In this situation, an orbital qubit is constructed, with a very weak dependence of Ω_{01} on $\theta - \varphi$ ($\Omega_{01} \neq 0$ in the orbital qubit regime for any $\theta - \varphi$). Critical magnetic field value B_c of spin to orbital qubit transition is almost independent on $\theta - \varphi$ and can be easily determined from the eigenspectrum analysis. Alternatively, for $\theta - \varphi = 0, \pi$, abrupt switch of Ω_{01} from zero to the nonzero value at B_c is a fingerprint of the

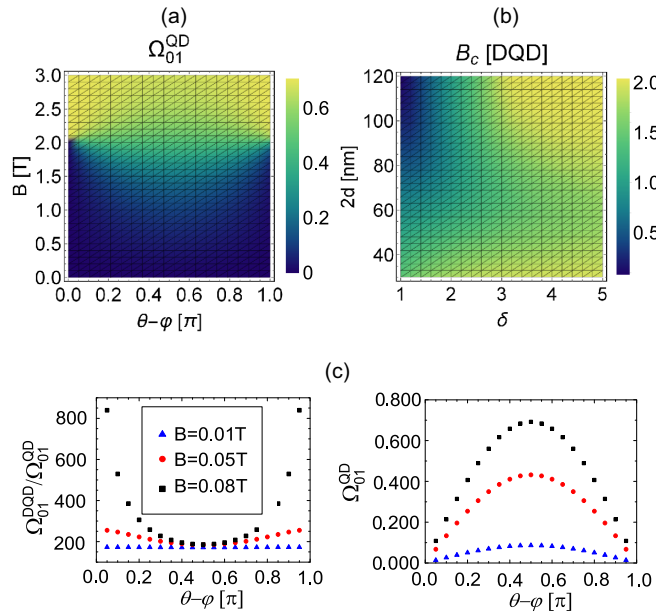


FIG. 2. (a) Dependence of Rabi frequency Ω_{01}^{QD} (in eE_0x_0/h units) on $\theta - \varphi \in (0, \pi)$ and $B \in (0, 3)$ T for QD gating potential. (b) In the case of DQD confinement, dependence of B_c on the asymmetry parameter $\delta \in (1, 5)$ and distance between the dots $2d \in (30, 120)$ nm is given. (c) Dependence of the ratio $\Omega_{01}^{\text{DQD}}/\Omega_{01}^{\text{QD}}$ on $\theta - \varphi \in (0.05, 0.95)\pi$ and magnetic field strengths $B = 0.01$ T, $B = 0.05$ T, and $B = 0.08$ T is presented for the symmetric DQD potential; distance between the dots is equal to $2d = 120$ nm. For the same angle range and magnetic field values Ω_{01}^{QD} in eE_0x_0/h units is presented.

transition. In the case of the QD potential, we extract the critical magnetic field value $B_c \approx 2.04$ T.

Gating with DQD potential gives a qualitatively similar dependence of Ω_{01} on B and $\theta - \varphi$. Being interested in the qualitative comparison of the impacts of QD and DQD potentials, we first establish a basis for comparison between them. To this end, we assume the same frequency of the QD potential and the right dot of the DQD potential, $\omega = \omega_R$, and vary the asymmetry parameter δ and the distance between the dots $2d$. For highly asymmetric DQD confinement and the large interdot distance, the electron will reside on only one dot, i.e., this potential is effectively the same as the single QD potential. The qualitative similarity of the single and double QD potential is checked through the comparison of the probability density of the ground and first excited state (qubit states); similar probability density profiles of the qubit states directly correspond to the similar Rabi frequency values of the two systems. Using the numerical comparison of the probability densities and the Rabi frequency in the case of QD and DQD potential, it can be concluded that for $2d \geq 120$ nm and $\delta \geq 5$ there is no effective difference between the results arising from two potentials. In other words, one should use $\delta < 5$ and $2d < 120$ nm to test the genuine effects of the DQD potential.

Figure 2(b) depicts the dependence of B_c in the DQD case on $\delta \in (1, 5)$ and $2d \in (30, 120)$ nm. When compared to the B_c value in the QD case, drastically lower values are found, especially in the case of symmetric confinement with well

separated left and right QD. As an example, critical magnetic field value $B_c \approx 0.085$ T for the symmetric DQD confinement with $2d = 120$ nm is roughly 24 times smaller than in the QD case.

Lower B_c for the symmetric DQD confinement is followed by at most factor 3 increase of $\Omega_{01}(B_c^{\text{DQD}})$, when compared to $\Omega_{01}(B_c^{\text{QD}})$. This slight increase, followed by lower B_c below which symmetric DQD operates, indicates a steeper rise of Rabi frequency for symmetric DQD confinements and the possibility to induce an even bigger difference between Ω_{01}^{DQD} and Ω_{01}^{QD} for the optimal magnetic field configuration. To investigate this possibility, we have performed a numerical analysis of the Rabi frequency ratio $\Omega_{01}^{\text{DQD}}/\Omega_{01}^{\text{QD}}$ for a wide range of DQD confinements and different magnetic field strengths/orientations, such that both systems operate as spin qubits. Our results confirm that symmetric DQD confinement maximally enhances this ratio when operating at magnetic field strengths close to B_c for the DQD potential, while the field orientation should be chosen such that $\theta - \varphi$ is close to 0 or π . In order to illustrate this conclusion, in the left panel of Fig. 2(c) we present the ratio $\Omega_{01}^{\text{DQD}}/\Omega_{01}^{\text{QD}}$ for $2d = 120$ nm and $\delta = 1$ in the DQD case, assuming field orientations $\theta - \varphi \in (0.05, 0.95)\pi$ and magnetic field strengths $B = 0.01$ T, $B = 0.05$ T, and $B = 0.08$ T ($B_c^{\text{DQD}} \approx 0.085$ T for this setup). Since angles $\theta - \varphi = 0, \pi$ should be excluded from the analysis because they correspond to zero Rabi frequency, we have restricted our plots to a $\theta - \varphi$ region smaller than π [see the right panel of Fig. 2(c) for the Ω_{01}^{QD} values], obtaining the highest ratio of around 800. It should be noticed that for angles closer to $0/\pi$ even bigger ratios (10^4) can be obtained, but at the cost of lowering the value of Rabi frequency.

B. Spin relaxation

Another important component for determining spin qubit quality is the spin relaxation rate. Similarly as Rabi frequency, Γ_{01} is dependent on the magnetic field and gating potential. However, Γ_{01} can be additionally dependent on the confinement in yz plane. In order to compare the influence of three-dimensional confinement with the confinement along the nanowire axis solely, we define one-dimensional approximation of the relaxation rate Γ_{01}^{1D} by changing the transition matrix element $|\langle \psi_0 | e^{iq \cdot r} | \psi_1 \rangle|^2$ with $|\langle 0 | e^{iq_x x} | 1 \rangle|^2$ in Eq. (8).

It has been known that in lateral GaAs QDs spin relaxation rates are dominated by piezoelectric field [50,51]. In our case, we wish to analyze the influence of each relaxation channel; thus, the overall spin relaxation rate will be divided into three contributions:

$$\Gamma_{01} = \Gamma_{01}^{\text{LA-DP}} + \Gamma_{01}^{\text{LA-PZ}} + \Gamma_{01}^{\text{TA-PZ}}, \quad (13)$$

each dependent on a different geometric factor, see Eqs. (9)–(11).

Before presenting the numerical results, conclusions independent on the choice of gating potentials are provided. First, Γ_{01} shows oscillatory dependence on the $\theta - \varphi$ angle, being equal to zero for $\theta - \varphi = 0, \pi$ and reaching the maximum for $\theta - \varphi = \pi/2$ in the spin qubit regime [21]. Second, for weak magnetic field strengths ($B < 0.1$ T), piezoelectric fields dominate relaxation rates. At the same time, yz confinement can be ignored.

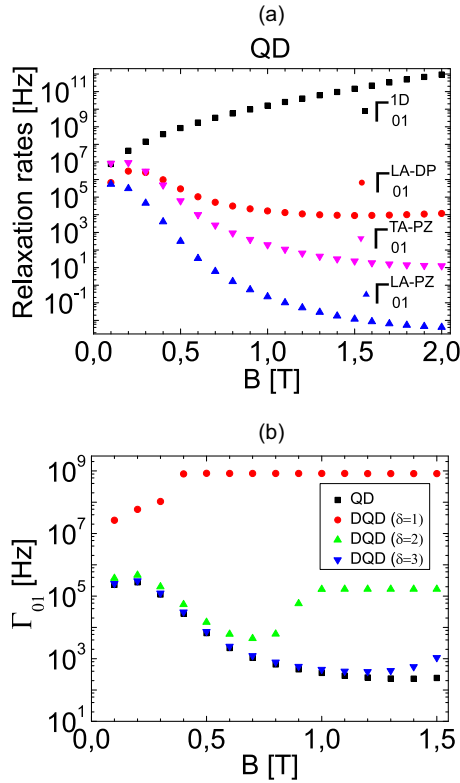


FIG. 3. (a) Dependence of the relaxation rates on the magnetic field strength $B \in (0.1, 2)$ T for $\theta - \varphi = \pi/2$. Red circles represent the contribution of deformation potential in the scattering rates, while inverted pink (blue) triangles show the contribution of piezoelectric field for the electron-phonon scattering in the transverse (longitudinal) direction. Finally, black squares represent relaxation rates in the one-dimensional approximation, in which the contribution of the confinement perpendicular to the nanowire axis is neglected. (b) Dependence of Γ_{01} on the magnetic field strength $B \in (0.1, 1.5)$ T in the case of QD and DQD confinement potential. Magnetic field orientation is chosen such that $\theta - \varphi = 0.05\pi$. In the DQD case, the distance between the dots is set at 90 nm, while the asymmetry parameter is varied.

To explore a new type of behavior accessible in InSb spin qubits, we focus our attention on stronger magnetic fields and investigate its impact on each relaxation channel and one-dimensional approximation of the total relaxation rate Γ_{01}^{1D} . We start from the QD potential. In Fig. 3(a), dependence of relaxation rates on $B \in (0.1, 2)$ T for the fixed angle $\theta - \varphi = \pi/2$ is given [52]. Red circles represent the contribution of deformation potential, pink inverse (blue) triangles denote the impact of piezoelectric field in the electron-phonon scattering along the transverse (longitudinal) direction. Graphs show that relaxation rate Γ_{01}^{LA-PZ} can safely be ignored, while Γ_{01}^{LA-DP} and Γ_{01}^{TA-PZ} have nontrivial influence on Γ_{01} . For weak magnetic fields Γ_{01}^{TA-PZ} term is dominant, while for large magnetic fields Γ_{01}^{LA-DP} should be considered solely [39]. A different influence of Γ_{01}^{TA-PZ} and Γ_{01}^{LA-DP} lies in the opposite behavior of the corresponding geometric factors: $|M_{TA-PZ}(\mathbf{q})|^2$ [$|M_{LA-DP}(\mathbf{q})|^2$] is inversely (directly) proportional to the energy splitting between the Zeeman levels and decreases (increases) with the magnetic field rise.

Contribution of the yz plane confinement on the spin relaxation rate can be determined by comparing the Γ_{01}^{1D} with relaxation rate channels. The comparison is illustrated in Fig. 3(a), clearly demonstrating that one-dimensional approximation of the spin relaxation rate is valid only for weak magnetic fields, below 0.1 T. At higher fields, due to the strong g factor of the InSb material, both $|\mathbf{q}|_{y0}$ and $|\mathbf{q}|_{z0}$ are greater than one, triggering the effects of the yz plane confinement for each relaxation rate channel. Thus, suppressed spin relaxation represents a fingerprint of a material with a strong g factor.

In the case of DQD potentials, dependence of B_c on the form of gating presents a serious limitation on the regimes that can be accessed. For example, if the B_c value is sufficiently weak, $B_c < 0.1$ T, the spin qubit operates under the dominant influence of the piezoelectric field. A strong magnetic field regime is beneficial for spin qubit operation due to strong Rabi frequency and suppressed spin relaxation. In order to operate in this regime, asymmetric DQD potential should be used. To compare the influence of QD and DQD potential on Γ_{01} , in Fig. 3(b), we plot the dependence of the spin relaxation rate in the case of QD and DQD confinement on the magnetic field strength $B \in (0.1, 1.5)$ T, assuming $\theta - \varphi = \pi/2$ and $2d = 90$ nm. Besides the symmetric $\delta = 1$ confinement, asymmetric DQD confinements ($\delta = 2, 3$) were analyzed as well. The presented results show that DQD gating leads to increased relaxation rates, when compared to the QD potential. This difference is minimized for highly asymmetric gating potentials. Note that B independent Γ_{01} values suggest that orbital qubit is created: energy difference between the states with the same spin component (representing the orbital qubit states in our case) is independent on B and triggers phonons on the same energy, leading to the observed effect. Consequently, these points should be excluded from the spin qubit analysis.

Finally, we emphasize that in the special case of the asymmetric DQD potential with $\delta = 1.5$ a similar trend of the spin relaxation rate is ascertained [21], i.e., after the increase of the spin relaxation rate in the dominant regime of the piezoelectric field, suppression of spin relaxation is observed, followed by the increase up to magnetic field independent saturation value [see the green triangles in Fig. 3(b) as a comparison].

C. Spin qubit quality

Quantitative estimate of the spin qubit quality can be given with the help of the figure of merit ξ [22],

$$\xi = \frac{\Omega_{01}}{\Gamma_{01} + \Gamma_o}, \quad (14)$$

measuring the number of qubit operations that can be implemented during the qubit lifetime. In Eq. (14) Γ_o represents relaxation rate of decay channels different from phonons. To divide the contribution of decay channels from them, we rewrite ξ in terms of the phonon figure of merit $\xi_{ph} = \Omega_{01}/\Gamma_{01}$ and relative influence of other channels with respect to phonons Γ_o/Γ_{01} . Thus,

$$\xi = \frac{\xi_{ph}}{1 + \frac{\Gamma_o}{\Gamma_{01}}}. \quad (15)$$

We first analyze ξ_{ph} for the QD confinement. Neglecting the weak magnetic field regime [53], in Fig. 4 we

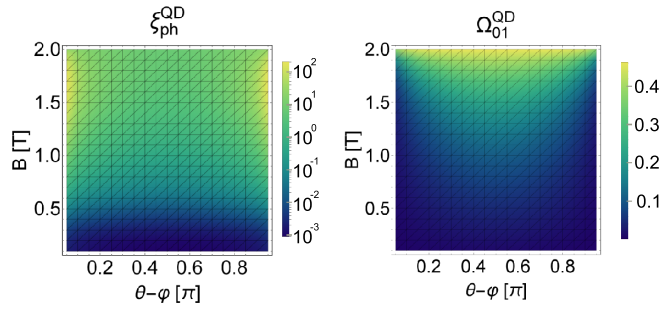


FIG. 4. For the QD confining potential, dependence of the figure of merit $\xi_{\text{ph}}^{\text{QD}}$ (given in dimensionless unit $7.25 \frac{m}{V} \times E_0$) and Rabi frequency (in eE_0x_0/h units) on the relative angle $\theta - \varphi \in (0.05, 0.95)\pi$ and magnetic field strength $B \in (0.1, 2)$ T is presented.

present the dependence of $\xi_{\text{ph}}^{\text{QD}}$ on $B \in (0.1, 2)$ T and $\theta - \varphi \in (0.05, 0.95)\pi$. The restricted $\theta - \varphi$ domain plotted is due to the *a priori* exclusion of $\theta - \varphi = 0, \pi$ values ($\Gamma_{01}^{\text{QD}} = 0$ in these situations). Plots show that to maximal value of $\xi_{\text{ph}}^{\text{QD}}$ correspond relative angles $\theta - \varphi = 0.05\pi, 0.95\pi$. This result suggests that for $\theta - \varphi$ closer to 0 or π than presented even bigger ξ_{QD} values can be obtained, at the cost of lowering the Rabi frequency. In other words, Γ_{01}^{QD} has a steeper decline to zero than Ω_{01}^{QD} , when $\theta - \varphi$ goes from $\pi/2$ to 0 or π .

Magnetic field orientation isotropy of Γ_0 [51] implies that shift from $\theta - \varphi = \pi/2$ increases $\Gamma_0/\Gamma_{01}^{\text{QD}}$ also. Thus, in order to maximize ξ , optimization of both $\xi_{\text{ph}}^{\text{QD}}$ and $\Gamma_0/\Gamma_{01}^{\text{QD}}$ is needed. Since at high magnetic fields phonon induced relaxation dominates [51], deviation of $\theta - \varphi$ from $\pi/2$ improves the spin qubit quality until $\Gamma_0/\Gamma_{01}^{\text{QD}}$ drops below 1. This sets up the optimal magnetic field orientation.

Finally, we compare the impacts of DQD and QD potentials on the spin qubit quality. As discussed in Sec. III A, Rabi frequency in the DQD case can be three orders of magnitude greater than in the QD case. Enhanced Rabi frequency suggests that SOC effects are more pronounced; thus, phonon induced spin relaxation rate should be enhanced. When compared to the QD case, an increase of Γ_{01}^{DQD} followed by the negative trend of $\xi_{\text{ph}}^{\text{DQD}}$ ensures that spin qubit quality decreases; symmetric DQD confinements give the poorest results, while highly asymmetric DQD potentials provide similar values as for QD gating.

IV. CONCLUSIONS

We have investigated the influence of gating potentials, magnetic field strength and orientation on Rabi frequency and spin relaxation rate in a single electron InSb nanowire spin qubit. Due to the strong Landé g factor, we were able to show that InSb spin qubit can operate in the regime in which deformation potential of acoustic phonons dominate relaxation rate. Qualitatively new behavior of spin relaxation rate comes from the confinement perpendicular to the nanowire axis, offering a new regime in which spin qubit can successfully operate. We have shown that gating potential has a crucial role in enabling such a situation, additionally pointing out simple harmonic potential as beneficial for the optimal definition of a spin qubit. Although presented for InSb

nanowire spin qubits, conclusions remain valid for spin qubits in other materials with a strong g factor. Thus, modifications of g due to different effects, e.g., strong in-plane magnetic field [54], do not interfere with the conclusions stated in this work.

ACKNOWLEDGMENTS

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APPENDIX A: DERIVATION OF THE EFFECTIVE ONE-DIMENSIONAL HAMILTONIAN

Here we derive the effective one-dimensional Hamiltonian H of the electron in an InSb quantum wire, by averaging the three-dimensional kinetic energy term T_{3D} and two-dimensional spin-orbit Hamiltonian H_{so}^{2D} over y and z direction. Thus, we start from the three-dimensional Hamiltonian

$$H_{3D} = T_{3D} + V(x) + H_{\text{so}}^{2D} + H_z, \quad (\text{A1})$$

where $T_{3D} = \sum_{i=x,y,z} p_i^2/2m^*$ ($p_i = p_i + eA_i$),

$$H_{\text{so}}^{2D} = \alpha_R(P_x\sigma_y - P_y\sigma_x) + \alpha_D(P_x\sigma_x - P_y\sigma_y), \quad (\text{A2})$$

while $V(x)$ and H_z are the gating potential and the Zeeman term, defined in Eq. (4) and Eqs. (5) and (6), respectively. The choice of the vector potential components $A_x = -Bz \sin \theta$, $A_y = 0$, $A_z = -By \cos \theta$ is such that it corresponds to the applied in-plane magnetic field $\mathbf{B} = B(\cos \theta, \sin \theta, 0)$. After averaging the kinetic energy operator over the y and z direction using the ground state wave function $\Psi(y, z) = \psi(y)\psi(z)$, we get

$$\langle T \rangle = \frac{p_x^2}{2m^*} - \frac{eB\langle z \rangle \sin \theta}{m^*} p_x + \left[\frac{\langle p_y^2 \rangle}{2m^*} + \frac{\langle (p_z - eBy \cos \theta)^2 \rangle}{2m^*} + \frac{e^2 B^2 \sin^2 \theta \langle z^2 \rangle}{2m^*} \right]. \quad (\text{A3})$$

In the previous equation, only the first and second term affect the dynamics in the x direction, while all terms in the square brackets can be considered the constant shift of energy and, therefore, can be neglected.

Next, effective one-dimensional spin-orbit interaction Hamiltonian is equal to

$$\begin{aligned} \langle H_{\text{so}} \rangle &= \alpha_R((p_x - eB\langle z \rangle \sin \theta)\sigma_y - \langle p_y \rangle \sigma_x) \\ &\quad + \alpha_D((p_x - eB\langle z \rangle \sin \theta)\sigma_x - \langle p_y \rangle \sigma_y) \\ &= (p_x - eB\langle z \rangle \sin \theta)(\alpha_R\sigma_y + \alpha_D\sigma_x), \end{aligned} \quad (\text{A4})$$

where we have used the fact that expectation value of the momentum p_y , $\langle p_y \rangle = \int_{-\infty}^{\infty} \Psi^*(y, z) p_y \Psi(y, z)$, is explicitly equal to zero.

A further simplification of the effective Hamiltonian can be made by neglecting the term $eB\langle z \rangle \sin \theta p_x/m^*$ from Eq. (A3) and $eB\langle z \rangle \sin \theta$ from Eq. (A4). Assuming that intensity of p_x

is proportional to $\hbar/x_0$, magnetic field dependent terms can be neglected if the relation

$$\frac{\hbar}{x_0} \gg eB\langle z \rangle \quad (\text{A5})$$

is satisfied. More concretely, when the $\hbar/x_0$ is for a factor of 10 stronger than the magnetic field dependent term, orbital effects of the magnetic field are small and can be discarded. In our calculations, the magnetic field strengths of interest are up to 3 T, yielding the relation for the z expectation value

$$\langle z \rangle \leq 0.1 \frac{\hbar}{ex_0 \times 3 \text{ T}} \quad (\text{A6})$$

that has to be satisfied to successfully operate in this regime. As discussed in Sec. II, the wave function $\psi(z)$ is dependent on the strength of the applied electric field E : with the increase of the electric field strength $\langle z \rangle$ increases. In other words, the strength of the electric field is limited from above. Numerical estimate for the critical value of electric field is 6.5×10^6 V/m, going to be used in our numerical calculations. Under these assumptions, the effective one-dimensional Hamiltonian resembles the one defined in Eq. (1), used in the rest of the paper.

APPENDIX B: NUMERICAL SOLUTION OF THE ONE-DIMENSIONAL SCHRÖDINGER EQUATION

In order to find eigenvectors and eigenenergies of the Hamiltonian H , given in Eq. (1), numerical diagonalization is performed. After defining orbital and spin-orbit lengths as x_0 and $x_{\text{so}} = \hbar/m\alpha$, respectively, such that $x = x_0u$, where u is dimensionless variable, H can be written in the following form:

$$H = \frac{\hbar^2}{2m^*x_0^2} H_{\text{red}}. \quad (\text{B1})$$

Eigenvectors of H are the same as of H_{red} , while eigenvalues of H and H_{red} differ for the factor $\hbar^2/2m^*x_0^2$, having the energy units. The benefits of using H_{red} instead of H stems from the transfer into dimensionless units, more suitable for numerical manipulation. The concrete form of H_{red} is equal to

$$H_{\text{red}} = -\frac{d^2}{du^2} - 2i\frac{x_0}{x_{\text{so}}} \mathbf{a} \cdot \boldsymbol{\sigma} \frac{d}{du} + V_{\text{eff}}(u) + g_{\text{eff}} \mathbf{n} \cdot \boldsymbol{\sigma}, \quad (\text{B2})$$

where g_{eff} and $V_{\text{eff}}(u)$ are effective Landé factor and effective potential, respectively,

$$g_{\text{eff}} = g \frac{m^*x_0^2\mu_B B}{\hbar^2}, \quad V_{\text{eff}}(u) = \frac{2m^*x_0^2}{\hbar^2} V(x_0u), \quad (\text{B3})$$

while vectors $\mathbf{a}$ and $\mathbf{n}$ are spin-orbit and magnetic field unit vectors, respectively, defined in the main text. The form of effective potential depends on the choice of gating potential (5) and (6), while effective Landé factor is linearly dependent on the magnetic field strength B .

To numerically solve the eigenproblem of H_{red} , orbital space is discretized with a uniform grid. First and second derivative of a wave function are approximated by finite difference uniform grid formulas [55]

$$\frac{d\psi(u)}{du} = \frac{\psi_{-4}}{280h} - \frac{4\psi_{-3}}{105h} + \frac{\psi_{-2}}{5h} - \frac{4\psi_{-1}}{5h} - \frac{\psi_4}{280h} + \frac{4\psi_3}{105h} - \frac{\psi_2}{5h} + \frac{4\psi_1}{5h} + O(h^8), \quad (\text{B4})$$

$$\frac{d^2\psi(u)}{du^2} = -\frac{\psi_{-4}}{560h^2} + \frac{8\psi_{-3}}{315h^2} - \frac{\psi_{-2}}{5h^2} + \frac{8\psi_{-1}}{5h^2} - \frac{205\psi_0}{72h^2} - \frac{\psi_4}{560h^2} + \frac{8\psi_3}{315h^2} - \frac{\psi_2}{5h^2} + \frac{8\psi_1}{5h^2} + O(h^8), \quad (\text{B5})$$

with accuracy to the h^8 order, where h is the uniform grid step. By definition, $\psi_{\pm n} = \psi(u \pm nh)$ represent wave functions shifted in the left/right ($-/+$) direction of the coordinate space for nh .

Uniform grid formulas allow us to represent the Hamiltonian as a square matrix. Effective potential is represented as a diagonal matrix, while matrix representation of the first and second order derivative have nondiagonal terms in addition. Since H_{red} is dependent on spin degrees of freedom also, the orbital part of the Hamiltonian is trivially extended in the spin space. Also, the Zeeman Hamiltonian is trivially extended in the orbital space, while the matrix form of the spin-orbit Hamiltonian is obtained as a tensor product of the first derivative matrix and spin Hamiltonian $\mathbf{a} \cdot \boldsymbol{\sigma}$.

In the QD case, harmonic potential is centered at $u = 0$, while in the case of DQD potential numerical calculations assumed each QD center range from $u = \pm 1/2$ to $u = \pm 2$. We have checked that for all studied situations the choice of u from the interval $(-8, 8)$ is enough to capture the smooth decline of the orbital wave function to 0 at $u = \pm 8$. Also, the division of the orbital space into $N = 2000$ parts was enough to ensure convergence of the results, i.e., for the increase of N to 4000 the relative difference between the results is below 10^{-4} .

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S06-CMPSP-217 / **Poster presentation**

Mobility of Holstein polaron from real and imaginary time quantum Monte Carlo calculations

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Electron-phonon (e-ph) interaction is responsible for majority of transport phenomena in condensed matter. In this work, we consider the short-range (localized) e-ph interaction described by the Holstein Hamiltonian. We develop numerically exact path integral Monte Carlo (PIMC) methods to obtain current-current correlation functions (CFs) and polaron mobility of one-dimensional Holstein model.

Generally, several challenges need to be overcome to reliably calculate dynamical properties using the PIMC methods. First one is the dynamical sign-problem of real time CFs which can be eliminated by doing calculations in imaginary time and then analytically continuing to real time. The other challenge is that there is not a reliable method for analytic continuation of numerically obtained values. We overcome these limitations by combining real time and imaginary time calculations with singular value decomposition method for analytical continuation.

For weaker e-ph interaction strengths we were able to calculate CFs in real time for a range of temperatures by using a Monte Carlo algorithm derived from momentum representation of electronic degrees of freedom and coordinate representation of phonons. For stronger interactions such an algorithm leads to a significant sign-problem for longer times and better results are obtained by using a different algorithm. This algorithm is derived from site representation of electronic degrees of freedom and coordinate representation of phonons. The phonon coordinates are then integrated out analytically and Monte Carlo summation over electronic states is performed. In the case of stronger interactions, where real time calculations cannot be used to obtain CFs at longer times, doing analytic continuation of both real time and imaginary time data gives much better results. The methods described enabled us to calculate polaron mobility for a range of temperatures and e-ph interaction strengths.

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Current-Current Correlation Functions of the Holstein Model from Real and Imaginary Time Path Integral Quantum Monte Carlo

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The electron-phonon (e-ph) interaction is responsible for majority of transport phenomena in condensed matter. In our work we consider the short-range (localized) e-ph interaction described by the Holstein Hamiltonian. We develop numerically exact path integral Monte Carlo (PIMC) method to obtain current-current correlation functions (CFs) and polaron mobility of one-dimensional Holstein model.

Generally, several challenges need to be overcome to reliably calculate dynamical properties using the PIMC methods. First one is the dynamical sign-problem of real time CFs which limits the real time QMC calculations to short real times. We were able to reduce the sign-problem to some extent by appropriate choice of basis for representation of path integral which enabled us to calculate the real time CFs for longer times. On the other hand, the sign-problem can be completely eliminated by doing calculations in imaginary time and then analytically continuing to real time. The other challenge is that there is not a reliable method for analytic continuation of such numerically obtained values. We overcome these limitations by performing analytic continuation from imaginary and real time data combined which provides us with more reliable results compared to analytic continuation from purely imaginary-time data.

The method described allowed us to calculate real- and imaginary-time current-current CFs for a range of temperatures and e-ph interaction strengths with great accuracy. For weak e-ph interactions and temperatures that are not too low, we were able to obtain real time CFs for long enough times and to calculate polaron mobility by direct integration according to Kubo formula. For stronger interactions, polaron mobility is obtained from real and imaginary time CFs by singular value decomposition method with a reasonably small error [1]. The obtained data for current-current CFs also serve as a great benchmark for numerically inexpensive approximate methods that are derived under the assumption of weak or strong e-ph interaction. By comparing our QMC results with CFs obtained through approximate formulas we can estimate the range of validity of such approximations in terms of interaction strength and temperature. We further use these comparisons to identify the range of parameters where well known transport regimes such as band transport, small polaron hopping and polaron band transport are valid.

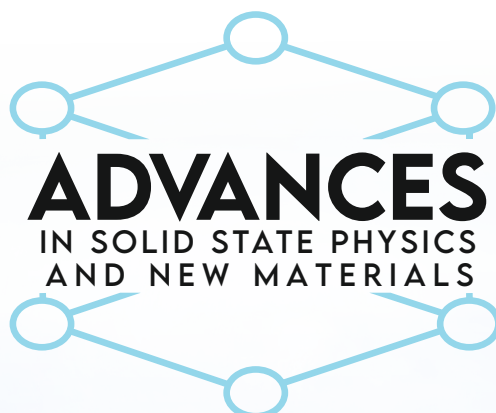
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Transport Regimes of Holstein Polaron

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Abstract.

The transport characteristics of semiconducting materials are predominantly determined by the electron-phonon interaction. Different transport regimes can occur depending on the strength of this interaction and the temperature. There are three distinct regimes that manifest in specific scenarios. In the case when the electron-phonon interaction is weak, the carriers are delocalized and sometimes scatter on the phonons, placing the system within the conventional band transport regime. In contrast, when the electron-phonon interaction is strong and temperatures are high, the carriers become completely localized, and they occasionally hop from site to site, which is a phonon-activated process. If the electron-phonon interaction is strong but the temperature is very low, the carriers delocalize and form a very narrow band. This is known as the polaron band transport regime.

Numerous methods have been developed to calculate the carrier mobility in real materials. These methods typically rely on the assumption of either band transport or hopping transport. Consequently, these methods are occasionally used under conditions where the presence of any of the mentioned transport regimes is uncertain. Therefore, it is crucial to identify the range of validity of different transport regimes within the parameter space. Furthermore, it is important to determine if there are areas in the parameter space where carrier transport cannot be described by any of the three mentioned regimes.

This research tackles these questions by examining a prototype model with electron-phonon interaction, the Holstein model. In this work, we performed numerically exact calculations of the imaginary-time current-current correlation function of the Holstein Hamiltonian for a broad range of model parameters. These calculations were performed using a path-integral based Quantum Monte Carlo method [1]. We compared these results with the results obtained under the assumption of conventional band transport, small polaron hopping and polaron band transport. From this comparison, we identify the regions in parameter space where each of these transport regimes is valid. In some instances where examining current-current correlation functions in imaginary time is inconclusive, we enhance our analysis by utilizing real-time comparisons or by referencing published data on numerically exact dc mobilities [1, 2]. In summary, we observe that the parameter space is nearly entirely covered by the three specified transport regimes [3].

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